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Foreword

This Technical Specification has been produced by the 3rd Generation Partnership Project (3GPP).

The contents of the present document are subject to continuing work within the TSG and may change following formal TSG approval. Should the TSG modify the contents of the present document, it will be re-released by the TSG with an identifying change of release date and an increase in version number as follows:

Version x.y.z

where:

- x the first digit:
 - 1 presented to TSG for information;
 - 2 presented to TSG for approval;
 - 3 or greater indicates TSG approved document under change control.
- y the second digit is incremented for all changes of substance, i.e. technical enhancements, corrections, updates, etc.
- z the third digit is incremented when editorial only changes have been incorporated in the document.

In the present document, modal verbs have the following meanings:

shall indicates a mandatory requirement to do something

shall not indicates an interdiction (prohibition) to do something

The constructions "shall" and "shall not" are confined to the context of normative provisions, and do not appear in Technical Reports.

The constructions "must" and "must not" are not used as substitutes for "shall" and "shall not". Their use is avoided insofar as possible, and they are not used in a normative context except in a direct citation from an external, referenced, non-3GPP document, or so as to maintain continuity of style when extending or modifying the provisions of such a referenced document.

should	indicates a recommendation to do something
should not	indicates a recommendation not to do something
may	indicates permission to do something
need not	indicates permission not to do something

The construction "may not" is ambiguous and is not used in normative elements. The unambiguous constructions "might not" or "shall not" are used instead, depending upon the meaning intended.

can	indicates that something is possible
cannot	indicates that something is impossible

The constructions "can" and "cannot" are not substitutes for "may" and "need not".

will	indicates that something is certain or expected to happen as a result of action taken by an agency the behaviour of which is outside the scope of the present document
will not	indicates that something is certain or expected not to happen as a result of action taken by an agency the behaviour of which is outside the scope of the present document
might	indicates a likelihood that something will happen as a result of action taken by some agency the behaviour of which is outside the scope of the present document

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might not indicates a likelihood that something will not happen as a result of action taken by some agency the behaviour of which is outside the scope of the present document

In addition:

- is (or any other verb in the indicative mood) indicates a statement of fact
- is not (or any other negative verb in the indicative mood) indicates a statement of fact

The constructions "is" and "is not" do not indicate requirements.

1 Scope

The present document establishes the minimum RF requirements for NR User Equipment (UE) operating on frequency Range 2.

2 References

The following documents contain provisions which, through reference in this text, constitute provisions of the present document.

- References are either specific (identified by date of publication, edition number, version number, etc.) or non-specific.
- For a specific reference, subsequent revisions do not apply.
- For a non-specific reference, the latest version applies. In the case of a reference to a 3GPP document (including a GSM document), a non-specific reference implicitly refers to the latest version of that document *in the same Release as the present document*.
- [1] 3GPP TR 21.905: "Vocabulary for 3GPP Specifications".
- [2] 3GPP TS 38.101-1: "NR; User Equipment (UE) radio transmission and reception; Part 1: Range 1 Standalone"
- [3] 3GPP TS 38.101-3: "NR; User Equipment (UE) radio transmission and reception; Part 3: Range 1 and Range 2 Interworking operation with other radios"
- [4] Void
- [5] 3GPP TS 38.521-2: "NR; User Equipment (UE) conformance specification; Radio transmission and reception; Part 2: Range 2 Standalone"
- [6] Recommendation ITU-R M.1545: "Measurement uncertainty as it applies to test limits for the terrestrial component of International Mobile Telecommunications-2000"
- [7] ITU-R Recommendation SM.329-10, "Unwanted emissions in the spurious domain"
- [8] 47 CFR Part 30, "UPPER MICROWAVE FLEXIBLE USE SERVICE, §30.202 Power limits", FCC.
- [9] 3GPP TS 38.211: "NR; Physical channels and modulation".
- [10] 3GPP TS 38.213: "NR; Physical layer procedures for control".
- [11] 3GPP TS 38.215: "NR; Physical layer measurements".
- [12] 3GPP TS 38.133: "NR; Requirements for support of radio resource management".
- [13] 3GPP TS 38.331: "NR; Radio Resource Control (RRC); Protocol specification".
- [14] 3GPP TS 38.306: "NR; User Equipment (UE) radio access capabilities".
- [15] IEEE Std 149: "IEEE Standard Test Procedures for Antennas", IEEE.

3 Definitions, symbols and abbreviations

3.1 Definitions

For the purposes of the present document, the terms and definitions given in 3GPP TR 21.905 [1] and the following apply. A term defined in the present document takes precedence over the definition of the same term, if any, in 3GPP TR 21.905 [1].

Aggregated Channel Bandwidth: The RF bandwidth in which a UE is configured to transmit and receive multiple contiguously aggregated carriers.

Bidirectional spectrum: UL/DL common spectrum in which the UE supports the configuration of uplink or downlink CCs.

Beam correspondence: the ability of the UE to select a suitable beam for UL transmission based on DL measurements with or without relying on UL beam sweeping.

Carrier aggregation: Aggregation of two or more component carriers in order to support wider transmission bandwidths.

Carrier aggregation band: A set of one or more operating bands across which multiple carriers are aggregated with a specific set of technical requirements.

Carrier aggregation bandwidth class: A class defined by the aggregated transmission bandwidth configuration and maximum number of component carriers supported by a UE.

Carrier aggregation configuration: A combination of CA operating band(s) and CA bandwidth class(es) supported by a UE.

NOTE: Carriers aggregated in each band can be contiguous or non-contiguous.

Cumulative aggregated channel bandwidth: The cumulative aggregated channel bandwidth is defined as the frequency band from the lowest edge of the lowest CC to the upper edge of the highest CC of all UL and DL configured CCs inside the bidirectional spectrum of the UE.

EIRP(Link=Link angle, Meas=Link angle): measurement of the UE such that the link angle is aligned with the measurement angle. EIRP (indicator to be measured) can be replaced by EIS, Frequency, EVM, carrier Leakage, Inband eission and OBW.

EIRP(Link=TX beam peak direction, Meas=Link angle): measurement of the EIRP of the UE such that the measurement angle is aligned with the beam peak direction within an acceptable measurement error uncertainty. EIRP (indicator to be measured) can be replaced by Frequency, EVM, carrier Leakage, In-band emission and OBW

EIRP(Link=Spherical coverage grid, Meas=Link angle): measurement of the EIRP spherical coverage of the UE such that the EIRP link and measurement angles are aligned with the directions along the spherical coverage grid within an acceptable measurement error uncertainty. Alternatively, the spherical coverage grid can be replaced by the beam peak search grid as the results from the beam peak search can be re-used for spherical coverage.

EIS (effective isotropic sensitivity): sensitivity for an isotropic directivity device equivalent to the sensitivity of the discussed device exposed to an incoming wave from a defined AoA

EIS(Link=RX beam peak direction, Meas=Link angle): measurement of the EIS of the UE such that the measurement angle is aligned with the RX beam peak direction within an acceptable measurement error uncertainty.

NOTE 1: The sensitivity is the minimum received power level at which specific requirement is met.

NOTE 2: Isotropic directivity is equal in all directions (i.e. 0 dBi).

Fallback group: Group of carrier aggregation bandwidth classes for which it is mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration. It is not mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration that belong to a different fallback group

IBM(**Independent Beam Management**): A UE that supports inter-band CA with IBM selects its DL and UL beam(s) for all CCs in each configured band based on DL reference signals measurements made in that band.

Inter-band carrier aggregation: Carrier aggregation of component carriers in different operating bands.

NOTE: Carriers aggregated in each band can be contiguous or non-contiguous.

Intra-band contiguous carrier aggregation: Contiguous carriers aggregated in the same operating band.

Intra-band non-contiguous carrier aggregation: Non-contiguous carriers aggregated in the same operating band.

Link angle: a DL-signal AoA from the view point of the UE, as described in Annex J. If the beam lock function is used to lock the UE beam(s), the link angle can become any arbitrary AoA once the beam lock has been activated.

Measurement angle: the angle of measurement of the desired metric from the view point of the UE, as described in Annex J

radiated interface boundary: operating band specific radiated requirements reference point where the radiated requirements apply

radiated requirements reference point: for the RF measurement setup, the radiated requirements reference point is located at the centre of the quiet zone. From the UE perspective the reference point is the input of the UE antenna array

RX beam peak direction: direction where the maximum total component of RSRP and thus best total component of EIS is found

Sub-block: This is one contiguous allocated block of spectrum for transmission and reception by the same UE. There may be multiple instances of sub-blocks within an RF bandwidth.

TX beam peak direction: direction where the maximum total component of EIRP is found

TRP(Link=TX beam peak direction, Meas=TRP grid): measurement of the TRP of the UE such that the measurement angles are aligned with the directions of the TRP grid points within an acceptable measurement uncertainty while the link angle is aligned with the TX beam peak direction

NOTE: For requirements based on EIRP/EIS, the radiated interface boundary is associated to the far-field region

UE transmission bandwidth configuration: Set of resource blocks located within the UE channel bandwidth which may be used for transmitting or receiving by the UE.

Vehicular UE: A UE embedded in a vehicle

3.2 Symbols

For the purposes of the present document, the following symbols apply:

$\begin{array}{l} \Delta EIRP_{BC} \\ \Delta F_{Global} \\ \Delta F_{Raster} \\ \Delta f_{OOB} \end{array}$	The beam correspondence tolerance, where $\Delta EIRP_{BC} = EIRP_2 - EIRP_1$ Granularity of the global frequency raster Band dependent channel raster granularity Δ Frequency of Out Of Band emission
$\Delta_{\rm RB}$	The starting frequency offset between the allocated RB and the measured non-allocated RB
ΔR_{IB}	Allowed reference sensitivity relaxation due to support for inter-band CA operation
ΔR_{IBC}	Allowed reference sensitivity relaxation due to support for intra-band contiguous CA operation
ΔR_{IBNC}	Allowed reference sensitivity relaxation due to support for intra-band non-contiguous CA operation
$\Delta R_{IB,P,n}$	Allowed relaxation to reference sensitivity due to support for inter-band CA operation, per supported band in a combination.
$\Delta R_{IB,S,n}$	Allowed relaxation to EIS spherical coverage due to support for inter-band CA operation, per supported band in a combination.
ΔT_{IB}	Allowed relaxation to EIRP requirements due to support for inter-band CA operation
$\Delta T_{IB,P,n}$	Allowed relaxation to peak EIRP requirements due to support for inter-band CA operation, per supported band in a combination.
$\Delta T_{IB,S,n}$	Allowed relaxation to EIRP spherical coverage due to support for inter-band CA operation, per supported band in a combination.

$\Delta MB_{P,n}$	Allowed relaxation to each, minimum peak EIRP and reference sensitivity due to support for
	multi-band operation, per supported band in a combination.
$\Delta MB_{S,n}$	Allowed relaxation to each, EIRP spherical coverage and EIS spherical coverage due to support
	for multi-band operation, per supported band in a combination.
BW _{Channel}	Channel bandwidth
$BW_{Channel_CA}$	Aggregated channel bandwidth, expressed in MHz
BW_{GB}	max(BWGB,Channel(k))
$BW_{GB,Channel(k)}$	Minimum guard band defined in sub-clause 5.3A.2 of carrier k
BWinterferer	Bandwidth of the interferer
Ceil(x)	Rounding upwards; ceil(x) is the smallest integer such that $ceil(x) \ge x$
EIRP ₁	The measured total EIRP based on the beam the UE chooses autonomously (corresponding beam)
	to transmit in the direction of the incoming DL signal, which is based on beam correspondence
EIDD	without relying on UL beam sweeping
EIRP ₂	The measured total EIRP based on the beam yielding highest EIRP in a given direction, which is
FIDD	based on beam correspondence with relying on UL beam sweeping
EIRP _{max}	The applicable maximum EIRP as specified in sub-clause 6.2.1
Floor(x)	Rounding downwards; floor(x) is the greatest integer such that floor(x) \leq x
F_center F _C	The center frequency of an allocated block of PRBs
	<i>RF reference frequency</i> for the carrier center on the channel raster, given in table 5.4.2.2-1 Fc of the highest transmitted/received carrier in a sub-block.
F _{C,block, high} F _{C,block, low}	Fc of the lowest transmitted/received carrier in a sub-block.
F _{C, low}	The Fc of the lowest carrier, expressed in MHz.
F _{C, high}	The Fc of the highest carrier, expressed in MHz.
F _{DL_low}	The lowest frequency of the downlink <i>operating band</i>
F _{DL_high}	The highest frequency of the downlink <i>operating band</i>
F _{edge,block,low}	The lower sub-block edge, where $F_{edge,block,low} = F_{C,block,low} - F_{offset, low}$.
F _{edge,block,high}	The upper sub-block edge, where $F_{edge,block,high} = F_{C,block,high} + F_{offset, high}$
F _{edge, low}	The lower edge of Aggregated Channel Bandwidth, expressed in MHz. $F_{edge, low} = F_{C, low} - F_{offset, low}$.
Fedge, high	The upper edge of Aggregated Channel Bandwidth, expressed in MHz. $F_{edge, high} = F_{C, high} + F_{offset,}$
	high.
FInterferer	Frequency of the interferer
F _{Interferer} (offset)	Frequency offset of the interferer (between the center frequency of the interferer and the carrier
	frequency of the carrier measured)
F _{Ioffset}	Frequency offset of the interferer (between the center frequency of the interferer and the closest
	edge of the carrier measured)
Floor(x)	Rounding downwards; floor(x) is the greatest integer such that floor(x) \leq x
F _{OOB}	The boundary between the NR out of band emission and spurious emission domains
F _{REF}	RF reference frequency
F _{REF-Offs}	Offset used for calculating F_{REF} The lowest frequency of the uplink <i>operating band</i>
F _{UL_low}	The highest frequency of the uplink <i>operating band</i>
$\begin{array}{l} F_{UL_high} \\ F_{UL_Meas} \end{array}$	The sub-carrier frequency for which the equalizer coefficient is evaluated
GB _{Channel}	Minimum guard band defined in sub-clause 5.3.3
L _{CRB}	Transmission bandwidth which represents the length of a contiguous resource block allocation
LCKB	expressed in units of resources blocks
L _{CRB,Max}	Maximum number of RB for a given Channel bandwidth and sub-carrier spacing
Max()	The largest of given numbers
Min()	The smallest of given numbers
MPR _{f,c}	Maximum output power reduction for carrier f of serving cell c
MPR _{narrow}	Maximum output power reduction due to narrow PRB allocation
MPR _{WT}	Maximum power reduction due to modulation orders, transmit bandwidth configurations,
	waveform types
$n_{\rm PRB}$	Physical resource block number
NR _{ACLR}	NR ACLR
N _{RB}	Transmission bandwidth configuration, expressed in units of resource blocks
$N_{RB,low}$	Transmission bandwidth configurations according to Table 5.3.2-1 for the lowest assigned
	component carrier in clause 5.3A.1
$N_{RB,high}$	Transmission bandwidth configurations according to Table 5.3.2-1 for the highest assigned
N T	component carrier in clause 5.3A.1
N _{REF}	NR Absolute Radio Frequency Channel Number (NR-ARFCN)
N _{REF-Offs}	Offset used for calculating N _{REF}
PCMAX	The configured maximum UE output power

$P_{CMAX, f, c}$	The configured maximum UE output power for carrier f of serving cell c
P _{int}	The intermediate power point as defined in table 6.3.4.2-2
PInterferer	Modulated mean power of the interferer
P _{max}	The maximum UE output power as specified in sub-clause 6.2.1
P _{min}	The minimum UE output power as specified in sub-clause 6.3.1
P-MPR _{f,c}	The Power Management UE Maximum Power Reduction for carrier f of serving cell c
P _{PowerClass}	Nominal UE power class (i.e., no tolerance) as specified in sub-clause 6.2.1
P _{RB}	The transmitted power per allocated RB, measured in dBm
P _{TMAX,f,c}	The measured total radiated power for carrier f of serving cell c
PUMAX	The measured configured maximum UE output power
Pw	Power of a wanted DL signal
RB _{start}	Indicates the lowest RB index of transmitted resource blocks
SCS_{low}	SCS for the lowest assigned component carrier in clause 5.3A.1
SCS _{high}	SCS for the highest assigned component carrier in clause 5.3A.1
SSREF	SS block reference frequency position
$T(\Delta P)$	The tolerance $T(\Delta P)$ for applicable values of ΔP (values in dB)
TRP _{max}	The maximum TRP for the UE power class as specified in sub-clause 6.2.1

3.3 Abbreviations

For the purposes of the present document, the abbreviations given in 3GPP TR 21.905 [1] and the following apply. An abbreviation defined in the present document takes precedence over the definition of the same abbreviation, if any, in 3GPP TR 21.905 [1].

ACLR	Adjacent Channel Leakage Ratio
ACS	Adjacent Channel Selectivity
A-MPR	Additional Maximum Power Reduction
AoA	Angle of Arrival
BCS	Bandwidth Combination Set
BPSK	Binary Phase-Shift Keying
BS	Base Station
BW	Bandwidth
BWP	Bandwidth Part
CA	Carrier aggregation
CABW	Cumulative Aggregated Channel Bandwidth
CA_nX-nY	Inter-band CA of component carrier(s) in one sub-block within Band X and component carrier(s)
	in one sub-block within Band Y where X and Y are the applicable NR operating band
CC	Component carrier
CDF	Cumulative Distribution Function
CP-OFDM	Cyclic Prefix-OFDM
CW	Continuous Wave
DFT-s-OFDM	Discrete Fourier Transform-spread-OFDM
DM-RS	Demodulation Reference Signal
DTX	Discontinuous Transmission
EIRP	Effective Isotropic Radiated Power
EIS	Effective Isotropic Sensitivity
EVM	Error Vector Magnitude
FR	Frequency Range
FWA	Fixed Wireless Access
GSCN	Global Synchronization Channel Number
IBB	In-band Blocking
IBM	Independent Beam Management
IDFT	Inverse Discrete Fourier Transformation
ITU-R	Radiocommunication Sector of the International Telecommunication Union
MBW	Measurement bandwidth defined for the protected band
MPR	Allowed maximum power reduction
NR	New Radio
NR-ARFCN	NR Absolute Radio Frequency Channel Number
OCNG	OFDMA Channel Noise Generator
OOB	Out-of-band
OTA	Over The Air

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P-MPR	Power Management Maximum Power Reduction
PRB	Physical Resource Block
QAM	Quadrature Amplitude Modulation
RF	Radio Frequency
REFSENS	Reference Sensitivity
RedCap	Reduced CapabilityRIB Radiated Interface Boundary
RMS	Root Mean Square (value)
RSRP	Reference Signal Receiving Power
Rx	Receiver
SCS	Subcarrier spacing
SEM	Spectrum Emission Mask
SRS	Sounding Reference Symbol
SS	Synchronization Symbol
TPC	Transimission Power Control
TRP	Total Radiated Power
Tx	Transmitter
UE	User Equipment
UL MIMO	Uplink Multiple Antenna transmission
ULFPTx	Uplink Full Power Transmission

4 General

4.1 Relationship between minimum requirements and test requirements

The present document is a Single-RAT specification for NR UE, covering RF characteristics and minimum performance requirements. Conformance to the present specification is demonstrated by fulfilling the test requirements specified in the conformance specification 3GPP TS 38.521-2 [5].

The Minimum Requirements given in this specification make no allowance for measurement uncertainty. The test specification TS 38.521-2 [5] defines test tolerances. These test tolerances are individually calculated for each test. The test tolerances are used to relax the minimum requirements in this specification to create test requirements. For some requirements, including regulatory requirements, the test tolerance is set to zero.

The measurement results returned by the test system are compared - without any modification - against the test requirements as defined in 3GPP TS 38.521-2 [5].

4.2 Applicability of minimum requirements

- a) In this specification the Minimum Requirements are specified as general requirements and additional requirements. Where the Requirement is specified as a general requirement, the requirement is mandated to be met in all scenarios
- b) For specific scenarios for which an additional requirement is specified, in addition to meeting the general requirement, the UE is mandated to meet the additional requirements.
- c) The spurious emissions power requirements are for the long-term average of the power. For the purpose of reducing measurement uncertainty it is acceptable to average the measured power over a period of time sufficient to reduce the uncertainty due to the statistical nature of the signal
- d) All the requirements for intra-band contiguous and non-contiguous CA apply under the assumption of the same slot format indicated by *TDD-UL-DL-ConfigurationCommon and TDD-UL-DL-ConfigurationDedicated* in the PCell and SCells for NR SA.

For FR2 intra-band CA configurations with multiple FR2 sub-blocks, where at least one of the sub-blocks is a contiguous CA configuration:

- if the field *partialFR2-FallbackRX-Req* is not present, the UE shall meet all applicable UE RF requirements for the highest order CA configuration and all associated fallback CA configurations;
- if the field *partialFR2-FallbackRX-Req* is present, for each FR2 intra-band CA configuration with multiple subblocks that the UE indicates support for explicitly in UE capability signalling: the in-gap UE RF requirements in clauses 7.5A, 7.5D, 7.6A, 7.6D apply as the equivalent requirements for the associated fallback CA configurations with the same number of sub-blocks, where at least one of the sub-blocks consists of a contiguous CA configuration. The UE shall meet all applicable UE RF requirements for fallback CA configurations with a lesser number of sub-blocks;
- regardless of the field *partialFR2-FallbackRX-Req*, the UE shall meet all DL out-of-gap requirements for all lower order fallback CA configurations.

4.3 Specification suffix information

Unless stated otherwise the following suffixes are used for indicating at 2nd level clause, shown in Table 4.3-1.

Clause suffix	Variant			
None	Single Carrier			
A	Carrier Aggregation (CA)			
В	Dual-Connectivity (DC)			
С	Supplement Uplink (SUL)			
D	UL MIMO			
NOTE: Suffix D in this specification represents either polarized UL MIMO or spatial UL MIMO. RF requirements are same. If UE supports both kinds of UL MIMO, then RF requirements only need to be verified under either polarized or spatial UL MIMO.				

Table 4.3-1: Definition of suffixes

5 Operating bands and channel arrangement

5.1 General

The channel arrangements presented in this clause are based on the operating bands and channel bandwidths defined in the present release of specifications.

NOTE: Other operating bands and channel bandwidths may be considered in future releases.

Requirements throughout the RF specifications are in many cases defined separately for different frequency ranges (FR). The frequency ranges in which NR can operate according to this version of the specification are identified as described in Table 5.1-1. Whenever the FR2 is referred, both FR2-1 and FR2-2 frequency sub-ranges shall be considered, unless otherwise stated.

Frequency range designation		Corresponding frequency range
FR1		410 MHz – 7125 MHz
FR2	FR2-1	24250 MHz – 52600 MHz
	FR2-2	52600 MHz – 71000 MHz

Table 5.1-1: Definition of frequency ranges

The present specification covers FR2 operating bands.

5.2 Operating bands

NR is designed to operate in the FR2 operating bands defined in Table 5.2-1.

Operating Band	Uplink (UL) operating band BS receive UE transmit	Downlink (DL) operating band BS transmit UE receive	Duplex Mode		
	Ful_low – Ful_high	F _{DL_low} – F _{DL_high}			
n257	26500 MHz – 29500 MHz	26500 MHz – 29500 MHz	TDD		
n258	24250 MHz – 27500 MHz	24250 MHz – 27500 MHz	TDD		
n259	39500 MHz – 43500 MHz	39500 MHz – 43500 MHz	TDD		
n260	37000 MHz – 40000 MHz	37000 MHz – 40000 MHz	TDD		
n261	27500 MHz – 28350 MHz	27500 MHz – 28350 MHz	TDD		
n262	47200 MHz – 48200 MHz	47200 MHz – 48200 MHz	TDD		
n263	57000 MHz – 71000 MHz	57000 MHz – 71000 MHz	TDD ¹		
NOTE 1: This band is for unlicensed operation and subject to regional and/or country specific regulatory requirements.					

Table 5.2-1: NR operating bands in FR2

5.2A Operating bands for CA

5.2A.1 Intra-band CA

NR intra-band contiguous and non-contiguous carrier aggregation is designed to operate in the operating bands defined in Table 5.2A.1-1, where all operating bands are within FR2.

NR CA Band	NR Band (Table 5.2-1)			
CA_n257	n257			
CA_n258	n258			
CA_n259	n259			
CA_n260	n260			
CA_n261	n261			
CA_n263	n263			
NOTE 1: In this release of the specification, only				
contiguous CA is applicable for this operating				
band.				

Table 5.2A.1-1: Intra-band contiguous and non-contiguous CA operating bands in FR2

5.2A.2 Inter-band CA

NR inter-band carrier aggregation is designed to operate in the operating bands defined in Table 5.2A.2-1, where all operating bands are within FR2.

Beam management type is according to UE capability declaration *IE beamManagementType-r16 or beamManagementType-CBM-r17*. The requirements in the following clauses are only applicable to inter-band CA with IBM type.

Table 5.2A.2-1: Inter-band CA operating bands in FR2

NR CA Band	NR Band (Table 5.2-1)			
CA_n257-n259 ¹	n257, n259			
CA_n258-n260 ¹	n258, n260			
CA_n258-n261 ¹	n258, n261			
CA_n260-n261 ¹	n260, n261			
NOTE 1: The minimum requirements apply only when there is non-simultaneous Rx/Tx operation between inter-band NR carriers in the current version of this specification.				

5.2D Operating bands for UL MIMO

NR UL MIMO is designed to operate in the operating bands defined in Table 5.2D-1.

Table 5.2D-1: NR UL MIMO operating bands

UL MIMO operating band (Table 5.2-1)
n257
n258
n259
n260
n261
n262

5.3 UE Channel bandwidth

5.3.1 General

The UE channel bandwidth supports a single NR RF carrier in the uplink or downlink at the UE. From a BS perspective, different UE channel bandwidths may be supported within the same spectrum for transmitting to and receiving from UEs connected to the BS. Transmission of multiple carriers to the same UE (CA) or multiple carriers to different UEs within the BS channel bandwidth can be supported.

From a UE perspective, the UE is configured with one or more BWP / carriers, each with its own UE channel bandwidth. The UE does not need to be aware of the BS channel bandwidth or how the BS allocates bandwidth to different UEs.

The placement of the UE channel bandwidth for each UE carrier is flexible but can only be completely within the BS channel bandwidth.

The relationship between the channel bandwidth, the guardband and the transmission bandwidth configuration is shown in Figure 5.3.1-1.

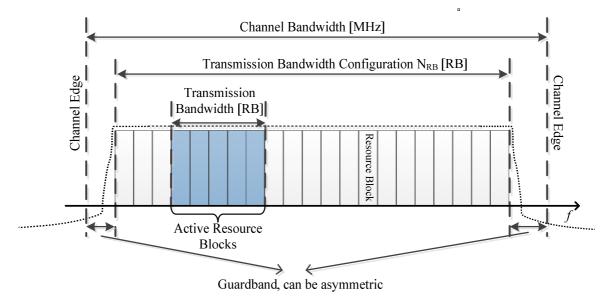


Figure 5.3.1-1: Definition of channel bandwidth and transmission bandwidth configuration for one NR channel

5.3.2 Maximum transmission bandwidth configuration

The maximum transmission bandwidth configuration N_{RB} for each UE channel bandwidth and subcarrier spacing is specified in Table 5.3.2-1

SCS (kHz)	50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
	N _{RB}	N _{RB}	Nrb	Nrb	N _{RB}	N _{RB}	N _{RB}
60	66	132	264	N/A	N/A	N/A	N/A
120	32	66	132	264	N/A	N/A	N/A
480 ¹	N/A	N/A	N/A	66	124	248	N/A
960 ¹	N/A	N/A	N/A	33	62	124	148
Note 1: This SCS is optional in this release of the specification.							

Table 5.3.2-1: Maximum transmission bandwidth configuration N_{RB}

5.3.3 Minimum guardband and transmission bandwidth configuration

The minimum guardband for each UE channel bandwidth and SCS is specified in Table 5.3.3-1.

Table 5.3.3-1: Minimum guardband for each UE channel bandwidth and SCS (kHz)

SCS (kHz)	50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
60	1210	2450	4930	N/A	N/A	N/A	N/A
120	1900	2420	4900	9860	N/A	N/A	N/A
480	N/A	N/A	N/A	9680	42640	85520	N/A
960	N/A	N/A	N/A	9440	42400	85280	147040

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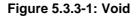
NOTE: The minimum guardbands have been calculated using the following equation: $(BW_{Channel} \times 1000 \text{ (kHz)} - N_{RB} \times SCS \times 12) / 2 - SCS/2$, where N_{RB} are from Table 5.3.2-1.

The minimum guardband of receiving BS SCS 240 kHz SS/PBCH block for each UE channel bandwidth is specified in table 5.3.3-2 for FR2.

Table: 5.3.3-2: Minimum guardband (kHz) of SCS 240 kHz SS/PBCH block in FR2-1

SCS (kHz)	100 MHz	200 MHz	400 MHz
240	3800	7720	15560

NOTE: In FR2-1, the minimum guardband in Table 5.3.3-2 is applicable only when the SCS 240 kHz SS/PBCH block is received adjacent to the edge of the UE channel bandwidth within which the SS/PBCH block is located.



The number of RBs configured in any channel bandwidth shall ensure that the minimum guardband specified in this clause is met.

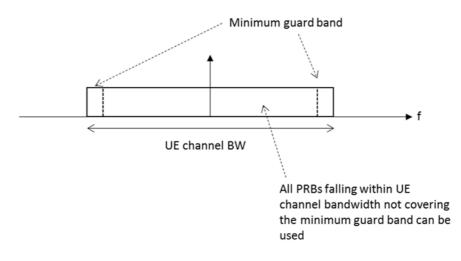


Figure 5.3.3-2 UE PRB utilization

In the case that multiple numerologies are multiplexed in the same symbol due to BS transmission of SSB, the minimum guardband on each side of the carrier is the guardband applied at the configured channel bandwidth for the numerology that is transmitted immediately adjacent to the guard band.

If multiple numerologies are multiplexed in the same symbol and the UE channel bandwidth is > 200 MHz, the minimum guardband applied adjacent to 60 kHz SCS shall be the same as the minimum guardband defined for 120 kHz SCS for the same UE channel bandwidth.

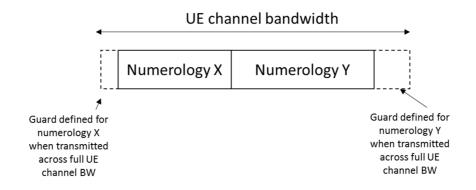


Figure 5.3.3-3 Guard band definition when transmitting multiple numerologies

Note: Figure 5.3.3-3 is not intended to imply the size of any guard between the two numerologies. Internumerology guard band within the carrier is implementation dependent.

5.3.4 RB alignment

For each numerology, its common resource blocks are specified in Clause 4.4.4.3 in [9], and the starting point of its transmission bandwidth configuration on the common resource block grid for a given channel bandwidth is indicated by an offset to "Reference point A" in the unit of the numerology. The *UE transmission bandwidth configuration* is indicated by the higher layer parameter *carrierBandwidth* [13] and will fulfil the minimum UE guardband requirement specified in Clause 5.3.3.

5.3.5 Channel bandwidth per operating band

The requirements in this specification apply to the combination of channel bandwidths, SCS and operating bands shown in Table 5.3.5-1. The transmission bandwidth configuration in Table 5.3.2-1 shall be supported for each of the specified channel bandwidths. The channel bandwidths are specified for both the Tx and Rx path.

Operating	SCS			UE chani	nel bandw	vidth (MHz	<u>z)</u>	
band	(kHz)	50	100	200	400	800	1600	2000
n257	60	50	100	200				
	120	50	100	200	400 ¹			
n258	60	50	100	200				
	120	50	100	200	400 ¹			
n259	60	50	100	200				
	120	50	100	200	400 ¹			
n260	60	50	100	200				
	120	50	100	200	400 ¹			
n261	60	50	100	200				
	120	50	100	200	400 ¹			
n262	60	50	100	200				
	120	50	100	200	400 ¹			
	120		100		400			
n263	480 ²				400	800 ¹	1600 ¹	
	960 ²				400	800 ¹	1600 ¹	2000 ¹
NOTE 1: T NOTE 2: T					in this rele		specificati	ion.

Table 5.3.5-1: Channel bandwidths for each NR band

5.3A UE channel bandwidth for CA

5.3A.1 General

5.3A.2 Minimum guardband and transmission bandwidth configuration for CA

For intra-band contiguous carrier aggregation, *Aggregated Channel Bandwidth* and *Guard Bands* are defined as follows, see Figure 5.3A.2-1.

Aggregated Channel Bandwidth, BW_{channel_CA} (MHz)

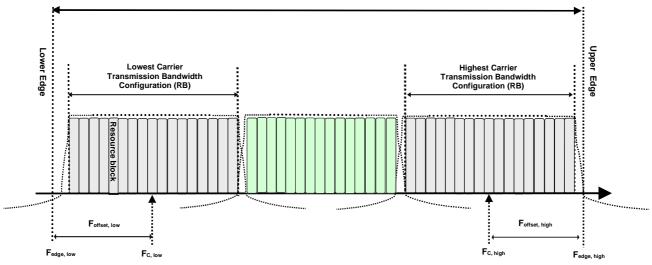


Figure 5.3A.2-1: Definition of Aggregated Channel Bandwidth for intra-band carrier aggregation

The aggregated channel bandwidth, BW_{Channel_CA}, is defined as

 $BW_{Channel_CA} = F_{edge,high} - F_{edge,low} (MHz).$

The lower bandwidth edge $F_{edge, low}$ and the upper bandwidth edge $F_{edge, high}$ of the aggregated channel bandwidth are used as frequency reference points for transmitter and receiver requirements and are defined by

 $F_{edge,low} = F_{C,low} - F_{offset,low}$ $F_{edge,high} = F_{C,high} + F_{offset,high}$

The lower and upper frequency offsets depend on the transmission bandwidth configurations of the lowest and highest assigned edge component carrier and are defined as

$$\begin{split} F_{offset,low} &= (N_{RB,low}*12+1)*SCS_{low}/2 + BW_{GB} \ (MHz) \\ F_{offset,high} &= (N_{RB,high}*12 - 1)*SCS_{high}/2 + BW_{GB} \ (MHz) \\ BW_{GB} &= max(BW_{GB,Channel(k)}) \end{split}$$

 $N_{RB,low}$ and $N_{RB,high}$ are the transmission bandwidth configurations according to Table 5.3.2-1 for the lowest and highest assigned component carrier, SCS_{low} and SCS_{high} are the sub-carrier spacing for the lowest and highest assigned component carrier respectively. SCS_{low} , SCS_{high} , $N_{RB,low}$, $N_{RB,high}$, and $BW_{GB,Channel(k)}$ use the largest μ value among the subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1 and $BW_{GB,Channel(k)}$ is the minimum guard band for carrier k according to Table 5.3.3-1 for the said μ value.

For intra-band non-contiguous carrier aggregation *Sub-block Bandwidth* and *Sub-block edges* are defined as follows, see Figure 5.3A.2-2.

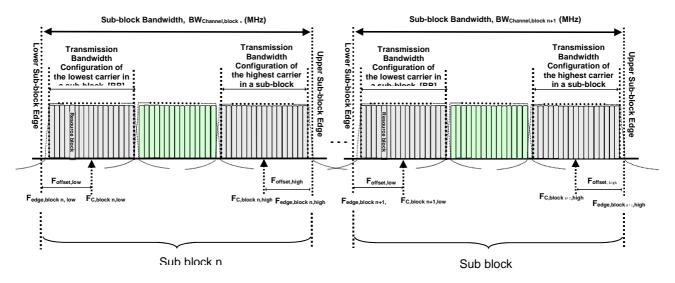


Figure 5.3A.2-2: Definition of sub-block bandwidth for intra-band non-contiguous spectrum

The lower sub-block edge of the Sub-block Bandwidth (BW_{Channel,block}) is defined as

 $F_{edge,block, low} = F_{C,block,low} - F_{offset, low}$

The upper sub-block edge of the Sub-block Bandwidth is defined as

 $F_{edge,block,high} = F_{C,block,high} + F_{offset, high}$

The Sub-block Bandwidth, BW_{Channel,block}, is defined as follows:

 $BW_{Channel,block} = F_{edge,block,high} - F_{edge,block,low} (MHz)$

The lower and upper frequency offsets F_{offset,block,low} and F_{offset,block,high} depend on the transmission bandwidth configurations of the lowest and highest assigned edge component carriers within a sub-block and are defined as

$$\begin{split} F_{offset,block,low} &= (N_{RB,low}*12+1)*SCS_{low}/2 + BW_{GB} \, (MHz) \\ F_{offset,block,high} &= (N_{RB,high}*12 - 1)*SCS_{high}/2 + BW_{GB} \, (MHz) \\ BW_{GB} &= max(BW_{GB,Channel(k)}) \end{split}$$

where $N_{RB,low}$ and $N_{RB,high}$ are the transmission bandwidth configurations according to Table 5.3.2-1 for the lowest and highest assigned component carrier within a sub-block, respectively. SCS_{low} and SCS_{high} are the sub-carrier spacing for the lowest and highest assigned component carrier within a sub-block, respectively. SCS_{low} , SCS_{high} , $N_{RB,low}$, $N_{RB,high}$, and $BW_{GB,Channel(k)}$ use the largest μ value among the subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1 and $BW_{GB,Channel(k)}$ is the minimum guard band for carrier k according to Table 5.3.3-1 for the said μ value.

The sub-block gap size between two consecutive sub-blocks W_{gap} is defined as

 $W_{gap} = F_{edge, block n+1, low} - F_{edge, block n, high} (MHz)$

5.3A.3 RB alignment with different numerologies for CA

5.3A.4 UE channel bandwidth per operating band for CA

For intra-band contiguous carrier aggregation, a carrier aggregation configuration is a single operating band supporting a carrier aggregation bandwidth class with associated bandwidth combination sets specified in clause 5.5A.1. For each carrier aggregation configuration, requirements are specified for all aggregated channel bandwidths contained in a bandwidth combination set, UE can indicate support of several bandwidth combination sets per carrier aggregation configuration. The requirements are applicable only when Uplink CCs are configured within the frequency range between lower edge of lowest downlink component carrier and upper edge of highest downlink component carrier.

For intra-band non-contiguous carrier aggregation, a carrier aggregation configuration is a single operating band supporting two or more sub-blocks, each supporting a carrier aggregation bandwidth class. The requirements are applicable only when Uplink CCs in each UL sub-block are configured within the frequency range between lower edge of lowest downlink component carrier and upper edge of highest downlink component carrier of a DL sub-block.

Frequency separation class (Fs) specified in Table 5.3A.4-2 indicates the maximum frequency span between lower edge of lowest component carrier and upper edge of highest component carrier that UE can support per band in downlink or uplink (DL Fs or UL Fs) respectively in non-contiguous intra-band operation within the bidirectional spectrum.

The DL-only frequency spectrum is the width of UE frequency spectrum available to network to configure DL CCs only, and it extends on one-side of the bidirectional spectrum in contiguous manner with no frequency gap between the two. Frequency separation class for DL-only spectrum (Fsd) specified in Table 5.3A.4-3 and is declared per band. The frequency separation class for DL-only spectrum (Fsd) can be equal but not larger than the frequency separation (DL Fs). The combined downlink spectrum (DL Fs + Fsd) cannot exceed 2400 MHz. A UE may configure DL-only spectrum only if the combined downlink spectrum (DL Fs + Fsd) exceeds 1400 MHz. When a UE configures DL-only spectrum, it shall not expect a CC to be configured across the boundary between bidirectional spectrum and DL-only spectrum UE can support respectively.

For inter-band carrier aggregation, a carrier aggregation configuration is a combination of operating bands, each supporting a carrier aggregation bandwidth class.

NR CA bandwidth class	Aggregated channel bandwidth	Number of contiguous CC	Fallback group
А	BW _{Channel} ≤ 400 MHz	1	1,2,3,4,5
В	400 MHz < BW _{Channel_CA} ≤ 800 MHz	2	1
С	800 MHz < BW _{Channel_CA} ≤ 1200 MHz	3	
D	200 MHz < BW _{Channel_CA} ≤ 400 MHz	2	2
E	400 MHz < BW _{Channel_CA} ≤ 600 MHz	3	
F	600 MHz < BW _{Channel_CA} ≤ 800 MHz	4	
R	800 MHz < BW _{Channel_CA} ≤ 1000 MHz	5	
S	1000 MHz < BW _{Channel_CA} ≤ 1200 MHz	6	
Т	1200 MHz < BW _{Channel_CA} ≤ 1400 MHz	7	
U	1400 MHz < BW _{Channel_CA} ≤ 1600 MHz	8	
G	100 MHz < BW _{Channel_CA} ≤ 200 MHz	2	3
Н	200 MHz < BW _{Channel_CA} ≤ 300 MHz	3	
I	300 MHz < BW _{Channel_CA} ≤ 400 MHz	4	
J	400 MHz < BW _{Channel_CA} ≤ 500 MHz	5	
К	500 MHz < BW _{Channel_CA} ≤ 600 MHz	6	
L	600 MHz < BW _{Channel_CA} ≤ 700 MHz	7	
М	700 MHz < BW _{Channel CA} ≤ 800 MHz	8	
0	100 MHz ≤ BW _{Channel_CA} ≤ 200 MHz	2	4
Р	150 MHz ≤ BW _{Channel_CA} ≤ 300 MHz	3	
Q	200 MHz ≤ BW _{Channel_CA} ≤ 400 MHz	4	
R2	200 MHz ≤ BW _{Channel_CA} ≤ 400 MHz	2	5
R3	300 MHz ≤ BW _{Channel_CA} ≤ 600 MHz	3	
R4	400 MHz ≤ BW _{Channel_CA} ≤ 800 MHz	4	
R5	500 MHz ≤ BW _{Channel_CA} ≤ 1000 MHz	5	
R6	600 MHz ≤ BW _{Channel_CA} ≤ 1200 MHz	6	
R7	700 MHz ≤ BW _{Channel_CA} ≤ 1400 MHz	7	
R8	800 MHz ≤ BW _{Channel_CA} ≤ 1600 MHz	8	
R9	900 MHz ≤ BW _{Channel_CA} ≤ 1800 MHz	9	
R10	1000 MHz ≤ BW _{Channel_CA} ≤ 2000 MHz	10	
R11	1100 MHz ≤ BW _{Channel_CA} ≤ 2200 MHz	11	
R12	1200 MHz ≤ BW _{Channel_CA} ≤ 2400 MHz	12	
MHz, 100 MH classes of fall bandwidths (e carriers of a s NOTE 2: It is mandator fallback group configuration NOTE 3: In this release	ported component carrier bandwidths for fa lz, 100 MHz and 200 MHz respectively exce back group 5, requirements apply for non-in each CA bandwidth class consisting of up to single channel bandwidth). Ty for a UE to be able to fallback to lower orc b. It is not mandatory for a UE to be able to f that belong to a different fallback group. The of the specification, the minimum requirem regated channel bandwidths up to 1600 MHz	pt for CA bandwidth class A. terlaced 100 MHz and 200 M two contiguous sub-blocks e ler CA bandwidth class confi allback to lower order CA ba ents for intra-band contiguou	For CA bandwidth IHz channel each with component guration within a ndwidth class us CA configurations

Table 5.3A.4-1: CA bandwidth classes

Frequency separation class	Max. allowed frequency separation (Fs)
I	800 MHz
II	1200 MHz
III	1400 MHz
IV	1000 MHz
V	1600 MHz
VI	1800 MHz
VII	2000 MHz
VIII	2200 MHz
IX	2400 MHz
Х	400 MHz
XI	600 MHz
NOTE 1: Fs values larger than 14 downlink frequency separation.	400 MHz apply only to

Table 5.3A.4-2: Frequency separation classes for non-contiguous intra-band operation

downlink nequency separation.

Table 5.3A.4-3:	Frequency	separation	classes f	or DL-only	y spectrum

Frequency separation class	Max. allowed frequency separation (Fsd)
I	200 MHz
II	400 MHz
III	600 MHz
IV	800 MHz
V	1000 MHz
VI	1200 MHz

5.3D Channel bandwidth for UL MIMO

The requirements specified in clause 5.3 are applicable to UE supporting UL MIMO.

5.4 Channel arrangement

5.4.1 Channel spacing

5.4.1.1 Channel spacing for adjacent NR carriers

The spacing between carriers will depend on the deployment scenario, the size of the frequency block available and the channel bandwidths. The nominal channel spacing between two adjacent NR carriers is defined as following:

For NR operating bands with 60 kHz channel raster,

- Nominal Channel spacing = $(BW_{Channel(1)} + BW_{Channel(2)})/2 + \{-20 \text{ kHz}, 0 \text{ kHz}, 20 \text{ kHz}\}$ for ΔF_{Raster} equals to 60 kHz
- Nominal Channel spacing = $(BW_{Channel(1)} + BW_{Channel(2)})/2 + \{-40 \text{ kHz}, 0 \text{ kHz}, 40 \text{ kHz}\}$ for ΔF_{Raster} equals to 120 kHz

For operating band n263,

Nominal Channel spacing = $ceil((BW_{Channel(1)} + BW_{Channel(2)})/100.8)*50.4$ MHz,

where $BW_{Channel(1)}$ and $BW_{Channel(2)}$ are the channel bandwidths of the two respective NR carriers. The channel spacing can be adjusted depending on the channel raster to optimize performance in a particular deployment scenario.

5.4.2 Channel raster

5.4.2.1 NR-ARFCN and channel raster

The global frequency raster defines a set of RF reference frequencies F_{REF} . The RF reference frequency is used in signalling to identify the position of RF channels, SS blocks and other elements.

The global frequency raster is defined for all frequencies from 0 to 100 GHz. The granularity of the global frequency raster is ΔF_{Global} .

RF reference frequency is designated by an NR Absolute Radio Frequency Channel Number (NR-ARFCN) in the range [2016667...3279165] on the global frequency raster. The relation between the NR-ARFCN and the RF reference frequency F_{REF} in MHz is given by the following equation, where $F_{REF-Offs}$ and $N_{Ref-Offs}$ are given in table 5.4.2.1-1 and N_{REF} is the NR-ARFCN

 $F_{REF} = F_{REF-Offs} + \Delta F_{Global} (N_{REF} - N_{REF-Offs})$

Table 5.4.2.1-1: NR-ARFCN parameters for the global frequency raster

Frequency range (MHz)	ΔF _{Global} (kHz)	FREF-Offs [MHz]	N REF-Offs	Range of NREF
24250 - 100000	60	24250.08	2016667	2016667 - 3279165

The *channel raster* defines a subset of *RF reference frequencies* that can be used to identify the RF channel position in the uplink and downlink. The *RF reference frequency* for an RF channel maps to a resource element on the carrier. For each operating band, a subset of frequencies from the global frequency raster are applicable for that band and forms a channel raster with a granularity ΔF_{Raster} , which may be equal to or larger than ΔF_{Global} .

The mapping between the channel raster and corresponding resource element is given in Clause 5.4.2.2. The applicable entries for each operating band are defined in clause 5.4.2.3

5.4.2.2 Channel raster to resource element mapping

The mapping between the RF reference frequency on channel raster and the corresponding resource element is given in Table 5.4.2.2-1 and can be used to identify the RF channel position. The mapping depends on the total number of RBs that are allocated in the channel and applies to both UL and DL. The mapping must apply to at least one numerology supported by the UE.

	$N_{RB} \mod 2 = 0$	$N_{RB} \mod 2 = 1$
Resource element index k	0	6
Physical resource block number <i>n_{PRB}</i>	$n_{\rm PRB} = \left\lfloor \frac{N_{\rm RB}}{2} \right\rfloor$	$n_{\rm PRB} = \left\lfloor \frac{N_{\rm RB}}{2} \right\rfloor$

k, n_{RB} , N_{RB} are as defined in TS 38.211 [9].

5.4.2.3 Channel raster entries for each operating band

The RF channel positions on the channel raster in each NR operating band are given through the applicable NR-ARFCN in Table 5.4.2.3-1, using the channel raster to resource element mapping in clause 5.4.2.2.

- For NR operating bands with 60 kHz channel raster above 24 GHz, $\Delta F_{Raster} = I \times \Delta F_{Global}$, where $I \in \{1,2\}$. Every I^{th} NR-ARFCN within the operating band are applicable for the channel raster within the operating band and the step size for the channel raster in table 5.4.2.3-1 is given as $\langle I \rangle$.
- In frequency bands with two ΔF_{Raster} , the higher ΔF_{Raster} applies to channels using only the SCS that equals the higher ΔF_{Raster} and the SSB SCS that is equal to or larger than the higher ΔF_{Raster} .

Operating Band	ΔF _{Raster} (kHz)	Uplink and Downlink Range of N _{REF} (First – <step size=""> – Last)</step>
n257	60	2054166 - <1> - 2104165
	120	2054167 - <2> - 2104165
n258	60	2016667 - <1> - 2070832
	120	2016667 - <2> - 2070831
n259	60	2270833 - <1> - 2337499
	120	2270833 - <2> - 2337499
n260	60	2229166 - <1> - 2279165
	120	2229167 - <2> - 2279165
n261	60	2070833 - <1> - 2084999
	120	2070833 - <2> - 2084999
n262	60	2399166 - <1> - 2415832
	120	2399167 - <2> - 2415831
n263	120	See Table 5.4.2.3-2
	480	
	960	

Table 5.4.2.3-1: Applicable NR-ARFCN per operating band

Table 5.4.2.3-2: Applicable NR-ARFCN for operation in band n263

Channel Bandwidth		
100 MHz	2564083 + 1680 * N, N = 0:137	
400 MHz	2566603 + 6720 * N, N = 0:33	
800 MHz	2569963 + 6720 * N, N = 0:32	
1600 MHz	2576683 + 6720 * N, N =0:30	
2000 MHz	2580043 + 6720 * N, N=0:29,	
	2585083, 2655643, 2692603, 2764843	

5.4.3 Synchronization raster

5.4.3.1 Synchronization raster and numbering

The synchronization raster indicates the frequency positions of the synchronization block that can be used by the UE for system acquisition when explicit signalling of the synchronization block position is not present.

A global synchronization raster is defined for all frequencies. The frequency position of the SS block is defined as SS_{REF} with corresponding number GSCN. The parameters defining the SS_{REF} and GSCN for all the frequency ranges are in Table 5.4.3.1-1.

The resource element corresponding to the SS block reference frequency SS_{REF} is given in clause 5.4.3.2. The synchronization raster and the subcarrier spacing of the synchronization block is defined separately for each band.

Frequency range	SS block frequency position SSREF	GSCN	Range of GSCN
24250 – 100000 MHz	24250.08 MHz + N * 17.28 MHz,	22256 + N	22256 - 26639
	N = 0:4383		

5.4.3.2 Synchronization raster to synchronization block resource element mapping

The mapping between the synchronization raster and the corresponding resource element of the SS block is given in Table 5.4.3.2-1.

Table 5.4.3.2-1: Synchronization raster to SS block resource element mapping

Resource element index k	120

k is the subcarrier number of SS/PBCH block defined in TS 38.211 clause 7.4.3.1 [9].

5.4.3.3 Synchronization raster entries for each operating band

The synchronization raster for each band is give in Table 5.4.3.3-1. The distance between applicable GSCN entries is given by the <Step size> indicated in Table 5.4.3.3-1.

NR Operating Band	SS Block SCS	SS Block pattern ¹	Range of GSCN (First – <step size=""> – Last)</step>	
n257	120 kHz	Case D	22388 - <1> - 22558	
	240 kHz	Case E	22390 - <2> - 22556	
n258	120 kHz	Case D	22257 - <1> - 22443	
	240 kHz	Case E	22258 - <2> - 22442	
n259	120 kHz	Case D	23140 - <1> - 23369	
	240 kHz	Case E	23142 - <2> - 23368	
n260	120 kHz	Case D	22995 - <1> - 23166	
	240 kHz	Case E	22996 - <2> - 23164	
n261	120 kHz	Case D	22446 - <1> - 22492	
	240 kHz	Case E	22446 - <2> - 22490	
n262	120 kHz	Case D	23586 - <1> - 23641	
	240 kHz	Case E	23588 - <2> - 23640	
	120 kHz	Case D	Table 5 4 2 2 2	
n263	480 kHz	Case F	- Table 5.4.3.3-2	
	960 kHz ²	Case G	24162 - <6> - 24954	

Table 5.4.3.3-1: Applicable SS raster entries per operating band

NOTE 2: SS Block SCS of 960 kHz is not used for initial access.

Table 5.4.3.3-2: Allowed GSCN for operation in band n263 for 120 kHz and 480 kHz

SS Block SCS	Range of GSCN	
120 kHz	24156 + 6 * N – 3 * floor((N+5)/18), N=0:137	
480 kHz	24162 + 24 * N - 12 * floor((N+4)/18), N=0:33	

5.4A Channel arrangement for CA

5.4A.1 Channel spacing for CA

For intra-band contiguous carrier aggregation with two or more component carriers, the nominal channel spacing between two adjacent NR component carriers is defined as the following unless stated otherwise:

For NR operating bands with 60kHz channel raster:

Nominal channel spacing =
$$\left[\frac{BW_{Channel (1)} + BW_{Channel (2)} - 2\left|GB_{Channel (1)} - GB_{Channel (2)}\right|}{0.06 * 2^{n+1}}\right] 0.06 * 2^{n} [MHz]$$

with

$$n = \mu_0 - 2$$

and for operating band n263:

Nominal Channel spacing = $ceil((BW_{Channel(1)} + BW_{Channel(2)})/100.8)*50.4$ MHz.

where BW_{Channel(1)} and BW_{Channel(2)} are the channel bandwidths of the two respective NR component carriers according to Table 5.3.2-1 with values in MHz, μ_0 is the largest μ value among the subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1, and *GB_{Channel(i)}* is the minimum guard band for channel bandwidth *i* according to Table 5.3.3-1 for the said μ value, with μ as defined in TS 38.211 [9].

The channel spacing for intra-band contiguous carrier aggregation can be adjusted to any multiple of least common multiple of channel raster and sub-carrier spacing less than the nominal channel spacing to optimize performance in a particular deployment scenario.

For intra-band non-contiguous carrier aggregation, the channel spacing between two NR component carriers in different sub-blocks shall be larger than the nominal channel spacing defined in this clause.

5.5 Configurations

- 5.5A Configurations for CA
- 5.5A.1 Configurations for intra-band contiguous CA

Table 5.5A.1-1: NR CA configurations, bandwidth combination sets, and fallback group defined for intra-band contiguous CA

			NR CA con	figuration /	Bandwidth	combinatio	n set / Fallba	ack group				
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group							
CA_n257B	CA_n257B	50, 100, 200, 400	400							800	0	1
CA_n257C	CA_n257B	50, 100, 200, 400	400	400						1200	0	
CA_n257D	CA_n257D	50, 100, 200	200							400	0	2
CA_n257E	CA_n257D CA_n257E	50, 100, 200	200	200						600	0	
CA_n257F	CA_n257D CA_n257E CA_n257F	50, 100, 200	200	200	200					800	0	
CA_n257G	CA_n257G	50, 100	100							200	0	3
CA_n257H	CA_n257G CA_n257H	50, 100	100	100						300	0	
CA_n257I	CA_n257G CA_n257H CA_n257I	50, 100	100	100	100					400	0	
CA_n257J	CA_n257G CA_n257H CA_n257I CA_n257J	50, 100	100	100	100	100				500	0	
CA_n257K	CA_n257G CA_n257H CA_n257I CA_n257J CA_n257J CA_n257K	50, 100	100	100	100	100	100			600	0	
CA_n257L	CA_n257G CA_n257H CA_n257H CA_n257J CA_n257J CA_n257K CA_n257L	50, 100	100	100	100	100	100	100		700	0	
CA_n257M	CA_n257G CA_n257H CA_n257H CA_n257J CA_n257J CA_n257K CA_n257L CA_n257M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n258B	 CA_n258B	50, 100, 200, 400	400							800	0	1

					Bandwidth							
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group							
CA_n258C	CA_n258B CA_n258C	50, 100, 200, 400	400	400						1200	0	
CA_n258D	CA_n258D	50, 100, 200	200							400	0	2
CA_n258E	CA_n258D CA_n258E	50, 100, 200	200	200						600	0	
CA_n258F	CA_n258D CA_n258E CA_n258F	50, 100, 200	200	200	200					800	0	
CA_n258G	CA_n258G	50, 100	100							200	0	3
 CA_n258H	CA_n258G CA_n258H	50, 100	100	100						300	0	
CA_n258I	CA_n258G CA_n258H CA_n258H CA_n258I	50, 100	100	100	100					400	0	
CA_n258J	CA_n258G CA_n258H CA_n258I CA_n258J	50, 100	100	100	100	100				500	0	
CA_n258K	CA_n258G CA_n258H CA_n258I CA_n258J CA_n258J CA_n258K	50, 100	100	100	100	100	100			600	0	
CA_n258L	CA_n258G CA_n258H CA_n258I CA_n258J CA_n258J CA_n258K CA_n258L	50, 100	100	100	100	100	100	100		700	0	
CA_n258M	CA_n258G CA_n258H CA_n258I CA_n258J CA_n258K CA_n258K CA_n258L CA_n258M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n258O	CA_n258O	50, 100	50, 100							200	0	4
CA_n258P	CA_n258O CA_n258P	50, 100	50, 100	50, 100						300	0	

			NR CA con	figuration /	Bandwidth	combinatio	n set / Fallba	ack group				
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group							
CA_n258Q	CA_n258O CA_n258P CA_n258Q	50, 100	50, 100	50, 100	50, 100					400	0	
CA_n259B	CA_n259B	50, 100, 200, 400	400							800	0	1
CA_n259C	CA_n259B	50, 100, 200, 400	400	400						1200	0	
CA_n259G	CA_n259G	50, 100	100							200	0	3
CA_n259H	CA_n259G CA_n259H	50, 100	100	100						300	0	
CA_n259I	CA_n259G CA_n259H CA_n259I	50, 100	100	100	100					400	0	
CA_n259J	CA_n259G CA_n259H CA_n259I CA_n259J	50, 100	100	100	100	100				500	0	
CA_n259K	CA_n259G CA_n259H CA_n259I CA_n259J CA_n259J CA_n259K	50, 100	100	100	100	100	100			600	0	
CA_n259L	CA_n259G CA_n259H CA_n259I CA_n259J CA_n259J CA_n259K CA_n259L	50, 100	100	100	100	100	100	100		700	0	
CA_n259M	CA_n259G CA_n259H CA_n259H CA_n259J CA_n259J CA_n259K CA_n259L CA_n259M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n260B	CA_n260B	50, 100, 200, 400	400							800	0	1
CA_n260C	CA_n260B	50, 100, 200, 400	400	400						1200	0	
CA_n260D	CA_n260D	50, 100, 200	200							400	0	2

			NR CA con	figuration /	Bandwidth	combinatio	n set / Fallba	ack group				
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group							
CA_n260E	CA_n260D CA_n260E	50, 100, 200	200	200						600	0	
CA_n260F	CA_n260D CA_n260E CA_n260F	50, 100, 200	200	200	200					800	0	
CA_n260G	CA_n260G	50, 100	100							200	0	3
CA_n260H	CA_n260G CA_n260H	50, 100	100	100						300	0	
CA_n260I	CA_n260G CA_n260H CA_n260I	50, 100	100	100	100					400	0	
CA_n260J	CA_n260G CA_n260H CA_n260I CA_n260J	50, 100	100	100	100	100				500	0	
CA_n260K	CA_n260G CA_n260H CA_n260I CA_n260J CA_n260K	50, 100	100	100	100	100	100			600	0	
CA_n260L	CA_n260G CA_n260H CA_n260I CA_n260J CA_n260K CA_n260L	50, 100	100	100	100	100	100	100		700	0	
CA_n260M	CA_n260G CA_n260H CA_n260I CA_n260J CA_n260K CA_n260L CA_n260L CA_n260M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n260O	CA_n260O	50, 100	50, 100							200	0	4
CA_n260P	CA_n2600 CA_n260P	50, 100	50, 100	50, 100						300	0	
CA_n260Q	CA_n260O CA_n260P CA_n260Q	50, 100	50, 100	50, 100	50, 100					400	0	
CA_n261B	CA_n261B	50, 100, 200, 400	400							800	0	1
CA_n261C	CA_n261B	50	400	400						850	0	

			NR CA con	figuration /	Bandwidth	combinatio		ack group				
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group							
CA_n261D	CA_n261D	50, 100, 200	200							400	0	2
CA_n261E	CA_n261D CA_n261E	50, 100, 200	200	200						600	0	
CA_n261F	CA_n261D CA_n261E CA_n261F	50, 100, 200	200	200	200					800	0	-
CA_n261G	CA_n261G	50, 100	100							200	0	3
 CA_n261H	CA_n261G CA_n261H	50, 100	100	100						300	0	
CA_n261I	CA_n261G CA_n261H CA_n261I	50, 100	100	100	100					400	0	
CA_n261J	CA_n261G CA_n261H CA_n261I CA_n261J	50, 100	100	100	100	100				500	0	
CA_n261K	CA_n261G CA_n261H CA_n261I CA_n261J CA_n261J CA_n261K	50, 100	100	100	100	100	100			600	0	
CA_n261L	CA_n261G CA_n261H CA_n261I CA_n261J CA_n261J CA_n261K CA_n261L	50, 100	100	100	100	100	100	100		700	0	
CA_n261M	CA_n261G CA_n261H CA_n261I CA_n261J CA_n261J CA_n261K CA_n261L CA_n261M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n261O	CA_n2610	50, 100	50, 100							200	0	4
CA_n261P	CA_n2610 CA_n2610 CA_n261P	50, 100	50, 100	50, 100						300	0	•
CA_n261Q	CA_n2610 CA_n261P CA_n261Q	50, 100	50, 100	50, 100	50, 100					400	0	
CA_n262G	CA_n262G	50, 100	100							200	0	3

NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	BW _{Channel} (MHz)	figuration / BW _{Channel} (MHz)	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group				
CA_n262H	CA_n262G CA_n262H	50, 100	100	100						300	0	
CA_n262I	CA_n262G CA_n262H CA_n262I	50, 100	100	100	100					400	0	
CA_n262J	CA_n262G CA_n262H CA_n262I CA_n262J	50, 100	100	100	100	100				500	0	
CA_n262K	CA_n262G CA_n262H CA_n262I CA_n262J CA_n262J CA_n262K	50, 100	100	100	100	100	100			600	0	
CA_n262L	CA_n262G CA_n262H CA_n262I CA_n262I CA_n262J CA_n262K CA_n262L	50, 100	100	100	100	100	100	100		700	0	
CA_n262M	CA_n262G CA_n262H CA_n262I CA_n262J CA_n262K CA_n262L CA_n262L CA_n262M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n263B	CA_n263A	400	400							800	0	1
CA_n263C	CA_n263A	400	400	400						1200	0	1
CA_n263G	CA_n263A	100	100							200	0	3
CA_n263H	CA_n263A	100	100	100						300	0	3
CA_n263I	CA_n263A	100	100	100	100					400	0	3
CA_n263J	CA_n263A	100	100	100	100	100				500	0	3
CA_n263K	CA_n263A	100	100	100	100	100	100			600	0	3
CA_n263L	CA_n263A	100	100	100	100	100	100	100		700	0	3
CA_n263M	CA_n263A	100	100	100	100	100	100	100	100	800	0	3

unintentionally should be listed in a row separately. NOTE 3: In this release of the specification, contiguous DL CA configurations within FR2-2 may only contain multiples of the same channel bandwidth.

5.5A.2 Configurations for intra-band non-contiguous CA

Configurations listed in this clause apply to downlink carrier aggregation only.

NOTE: Sub-blocks belonging to a CA configuration can be in any order. In other words certain CA configuration acronym includes all sub-block arrangements which have exactly the same sub-block set. As an example, CA_n260(2G-3O) denotes CA_n260(2O-2G-O), CA_n260(G-3O-G) etc. but these are not listed in tables separately.

Table 5.5A.2-1: NR CA configurations with single CA bandwidth class defined for intra-band noncontiguous CA

NF	NR CA configuration / Bandwidth combination set							
NR	NR Uplink CA Σ(BW _{Channel,block}) BCS							
configuration	configurations	(MHz)						

CA_n257(2A)	I - I	800	0
CA_n258(2A)	_	800	0
CA_n258(3A)	_	1200	0
CA_n258(4A)	-	1600	0
CA_n258(5A)		2000	0
CA_n258(2G)	CA_n258G	400	0
			0
CA_n260(2A)	CA_n260(2A)	800	
CA_n260(3A)	CA_n260(3A)	1200	0
CA_n260(4A)	-	1600	0
CA_n260(5A)	-	2000	0
CA_n260(6A)	-	2400	0
CA_n260(7A)	-	2800	0
CA_n260(8A)	-	2900	0
CA_n260(9A)	-	2950	0
CA_n260(10A)	-	2950	0
CA_n260(2D)	-	800	0
CA_n260(2G)	CA_n260G	400	0
CA_n260(3G)	-	600	0
CA_n260(4G)	-	800	0
			0
CA_n260(2H)	CA_n260G CA_n260H	600	U
CA_n260(2O)		400	0
CA_n260(3O)	-	600	0
CA_n260(4O)	-	800	0
CA_n260(40)		600	0
	-	900	0
CA_n260(3P)	-		
CA_n260(4P)	-	1200	0
CA_n260(2Q)	-	800	0
CA_n261(2A)	-	800	0
CA_n261(3A)	-	800	0
CA_n261(4A)	-	800	0
CA_n261(5A)	-	800	0
CA_n261(6A)	-	800	0
CA_n261(7A)	-	800	0
CA_n261(8A)	-	800	0
CA_n261(2D)	-	800	0
CA_n261(2G)	CA_n261G	400	0
CA_n261(3G)	-	600	0
CA_n261(4G)	-	800	0
CA_n261(2H)	CA_n261G	600	0
CA_11201(2H)	CA_1261G CA_1261H	800	0
CA_n261(2I)	CA_n261G	800	0
	CA_12010 CA_1261H	000	U
	CA_120111 CA_n2611		
CA = 261(20)	- CA_112011	400	٥
CA_n261(2O)	ł – – – – – – – – – – – – – – – – – – –	400	0
CA_n261(3O)	-	600	0
CA_n261(4O)	-	800	0
CA_n261(5O)	-	800	0
CA_n261(6O)	-	800	0
CA_n261(7O)	-	800	0
CA_n261(2P)	-	600	0
CA_n261(2Q)	-	800	0
NOTE 1: Void			
NOTE 2: Void			
NOTE 3: Void			
NOTE 4: Void			
	l bandwidth per ope	erating band define	d in Table 5 3 5-1
			each constituent CA
configur			
		o movimum total h	andwidth from the
	annel,block) denotes th		
Summa	ION OF THE SUD-DIOC		hall be less than the
	of the operating	band	

 Table 5.5A.2-2: NR CA configurations with multiple CA bandwidth classes defined for intra-band noncontiguous CA

NR CA configuration / Bandwidth combination set								
CA configuration	Uplink CA configurations	Σ(BW _{Channel,block}) (MHz)	BCS					
CA_n258(A-G)	CA_n258G	600	0					
CA_n258(A-H)	CA_n258G CA_n258H	700	0					
CA_n258(G-H)	CA_n258G CA_n258H	500	0					
CA_n260(A-D)	-	800	0					
CA_n260(A-E)	-	1000	0					
CA_n260(2A-D)	-	1200	0					
CA_n260(3A-D)	-	1600	0					
CA_n260(4A-D)	-	2000	0					
CA_n260(A-2D)	-	1200	0					
CA_n260(2A-2D)	-	1600	0					
CA_n260(A-D-O)	-	1000	0					
CA_n260(A-D-G)	-	1000	0					
CA_n260(2A-D-O)	-	1400	0					
CA_n260(3A-D-O)		1800	0					
CA_n260(3A-D-20)		1200	0					
CA_n260(2A-D-2O)	-	1600	0					
CA_1260(2A-D-2O) CA_n260(A-G)	 CA_n260G	600	0					
CA_n260(A-G) CA_n260(A-G-H)		900	0					
CA_n260(2A-G)	 CA_n260G	1000	0					
CA_n260(2A-G) CA_n260(A-2G)	CA_1260G CA_1260G		0					
_ / /		800						
CA_n260(A-3G)	-	1000	0					
CA_n260(A-4G)	-	1200	0					
CA_n260(2A-2G)	CA_n260G	1200	0					
CA_n260(2A-3G)	-	1400	0					
CA_n260(2A-2G-O)	-	1400	0					
CA_n260(2A-2G-2O)	-	1600	0					
CA_n260(3A-2G)	-	1600	0					
CA_n260(3A-2G-O)	-	1800	0					
CA_n260(4A-G)	-	1800	0					
CA_n260(4A-G-O)	-	2000	0					
CA_n260(4A-2G)	-	2000	0					
CA_n260(5A-G)	-	2200	0					
CA_n260(A-2G-2O)	-	1200	0					
CA_n260(A-2G-3O)	-	1400	0					
CA_n260(2A-G-H)	-	1300	0					
CA_n260(2A-G-2O)	-	1400	0					
CA_n260(2A-G-3O)	-	1600	0					
CA_n260(3A-G)	CA_n260G	1400	0					
CA_n260(3A-G-O)	-	1600	0					
CA_n260(3A-G-2O)	-	1800	0					
CA_n260(A-2H)	-	1000	0					
CA_n260(2A-H)	-	1100	0					
CA_n260(3A-H)	-	1500	0					
CA_n260(2A-2H)	-	1400	0					
CA_n260(A-H)	CA_n260G CA_n260H	700	0					
CA_n260(A-H-O)	-	900	0					
CA_n260(A-O)	-	600	0					
CA_n260(A-O-P)	-	900	0					
CA_n260(A-O-P-Q)	-	1300	0					
CA_n260(A-O-2P)	-	1200	0					
CA_n260(A-O-3P)	-	1500	0					
CA_n260(2A-O-P)	-	1300	0					
CA_n260(2A-O-P-Q)	-	1700	0					
CA_n260(2A-O-2P)	-	1600	0					
CA_n260(2A-O-3P)	-	1900	0					
CA_n260(2A-2O-P)	-	1500	0					
CA_n260(2A-2O-P-Q)	-	1900	0					
CA_n260(A-O-Q)	-	1000	0					
CA_n260(A-O-2Q)	-	1400	0					

CA_n260(2A-O-Q)	-	1400	0
CA_n260(2A-O-2Q)	-	1800	0
CA_n260(2A-2O-Q)	-	1600	0
CA_n260(2A-O)	-	1000	0
CA_n260(A-20)	-	800	0
CA_n260(A-2O-P)	-	1100	0
CA_n260(A-2O-P-Q)	-	1500	0
CA_n260(A-20-1-Q)	-	1400	0
CA n260(A-20-2P)		1200	0
	-		
CA_n260(A-2O-2Q)	-	1600	0
CA_n260(A-3O-P)	-	1300	0
CA_n260(A-3O-Q)		1400	0
CA_n260(2A-2O)	-	1200	0
CA_n260(2A-2O-2P)	-	1800	0
CA_n260(2A-2O-2Q)	-	2000	0
CA_n260(2A-3O)	-	1400	0
CA_n260(2A-3O-P)	-	1700	0
CA_n260(2A-3O-Q)	-	1800	0
CA_n260(3A-2O)	-	1600	0
CA_n260(3A-2O-P)	-	1900	0
CA_n260(3A-2O-Q)	-	2000	0
CA_n260(4A-O)		1800	0
	-		
CA_n260(4A-O-P)	-	2100	0
CA_n260(4A-O-Q)	-	2200	0
CA_n260(5A-O-P)	-	2500	0
CA_n260(6A-O-P)	-	2900	0
CA_n260(4A-3O)	-	2200	0
CA_n260(5A-O)	-	2200	0
CA_n260(6A-O)	-	2600	0
CA_n260(7A-O)	-	2950	0
CA_n260(8A-O)	-	2950	0
CA_n260(4A-2O)	-	2000	0
CA_n260(4A-2Q)	-	2400	0
	-		0
CA_n260(3A-3O)		1800	
CA_n260(A-G-O)	-	800	0
CA_n260(A-G-2O)	-	1000	0
CA_n260(A-G-3O)	-	1200	0
CA_n260(A-G-4O)	-	1400	0
CA_n260(2A-G-O)	-	1200	0
CA_n260(A-2G-O)	-	1000	0
CA_n260(A-3G-O)	-	1200	0
CA_n260(A-30)	-	1000	0
CA_n260(3A-O)	-	1400	0
CA_n260(3A-O-P)	CA_n260O	1700	0
	CA_n260P		č
CA_n260(3A-O-P-Q)		2100	0
CA_n260(3A-O-2P)	-	2000	
	-		0
CA_n260(3A-O-Q)	-	1800	0
CA_n260(3A-O-2Q)	-	2200	0
CA_n260(A-4O)	-	1200	0
CA_n260(2A-4O)	-	1600	0
CA_n260(3A-4O)	-	2000	0
CA_n260(4A-4O)	-	2400	0
CA_n260(5A-4O)	-	2800	0
CA_n260(A-P)	-	700	0
CA_n260(A-3P)	-	1300	0
CA_n260(A-3P)		1600	0
	- CA p260D		
CA_n260(A-P-Q)	CA_n260P CA_n260Q	1100	0
CA_n260(2A-P)	-	1100	0
CA_n260(2A-P-Q)	-	1500	0
CA_n260(3A-P)	-	1500	0
CA_n260(3A-P-Q)	-	1900	0
		1900	0
CA_n260(4A-P)	-		
CA_n260(4A-P-Q)	-	2300	0

CA_n260(5A-P)	-	2300	0
CA_n260(6A-P)	-	2700	0
CA_n260(7A-P)	-	3000?	0
CA_n260(A-2P)	-	1000	0
CA_n260(2A-2P)	-	1400	0
CA_n260(2A-3P)	-	1700	0
CA_n260(2A-4P)		2000	0
	-		0
CA_n260(3A-2P)		1800	
CA_n260(3A-3P)	-	2100	0
CA_n260(4A-2P)	-	2200	0
CA_n260(5A-2P)	-	2600	0
CA_n260(5A-2O)	-	2400	0
CA_n260(6A-2O)	-	2800	0
CA_n260(5A-3O)	-	2600	0
CA_n260(6A-3O)	-	2950	0
CA_n260(7A-2O)	-	2950	0
CA_n260(7A-30)	-	2950	0
CA_n260(6A-2P)	-	2950	0
CA_n260(8A-2O)	-	2550	0
CA_n260(9A-O)	-	3000?	0
CA_11260(9A-O) CA_11260(A-Q)	-	800	0
		1200	0
CA_n260(A-2Q)	-		
CA_n260(2A-Q)	-	1200	0
CA_n260(2A-2Q)	-	1600	0
CA_n260(3A-Q)	-	1600	0
CA_n260(3A-2Q)	-	2000	0
CA_n260(4A-Q)	-	2000	0
CA_n260(5A-Q)	-	2400	0
CA_n260(D-2G)	-	800	0
CA_n260(2D-O)	-	1000	0
CA_n260(D-20)	-	800	0
CA_n260(A-I)	CA_n260I	800	0
CA_n260(D-G)	CA_n260D	600	0
6/(_1200(B C)	CA_n260G	000	0
		700	
CA_n260(D-H)	CA_n260D	700	0
	CA_n260H		
CA_n260(D-I)	CA_n260D	800	0
	CA_n260I		
CA_n260(D-O)	 CA_n260D	600	0
CA_11200(D-C)	CA_1200D CA_n260O	000	0
CA_n260(D-P)	CA_n260D	700	0
	CA_n260P		
CA_n260(D-Q)	CA_n260D	800	0
	CA_n260Q		C C
			<u>^</u>
CA_n260(E-O)	CA_n260E	800	0
	CA_n260O		
CA_n260(E-P)	CA_n260E	800	0
. ,	CA_n260P		
CA_n260(E-Q)	 CA_n260E	1000	0
Un_11∠00(E-Q)	CA_n260Q	1000	U
CA_n260(G-H)	CA_n260G	500	0
	CA_n260H		
CA_n260(G-H-O)	-	700	0
CA_n260(G-I)	CA_n260G	600	0
	CA_n260I		
CA_n260(G-O)	-	400	0
CA_n260(G-20)	-	600	0
			0
CA_n260(2G-O)	-	600	
CA_n260(2G-2O)	-	800	0
CA_n260(G-30)	-	800	0
CA_n260(3G-O)	-	800	0
CA_n260(2G-3O)	-	1000	0
CA_n260(G-4O)		1000	0

CA_n260(2G-4O)	- 1	1200	0
CA_n260(4G-O)	-	1000	0
CA_n260(H-O)	-	500	0
CA_n260(2H-O)	-	800	0
CA_n260(O-2P)	-	800	0
CA_n260(O-3P)	-	1100	0
CA_n260(O-2Q)	-	1000	0
CA_n260(O-2Q)	-	500	0
		900	
CA_n260(O-P-Q)	-		0
CA_n260(2O-P)	-	700	0
CA_n260(2O-P-Q)	-	1100	0
CA_n260(2O-2P)	-	1000	0
CA_n260(3O-P)		900	0
CA_n260(3O-Q)		1000	0
CA_n260(O-Q)	-	600	0
CA_n260(2O-Q)	-	800	0
CA_n260(2O-2Q)	-	1200	0
CA_n260(P-Q)	-	700	0
CA_n261(A-D)	-	800	0
CA_n261(A-E)	-	800	0
CA_n261(2A-D)	-	800	0
CA_n261(2A-D-O)	-	800	0
CA_n261(A-2D)	-	800	0
CA_n261(A-D-G)	-	800	0
CA_n261(A-D-H)	-	800	0
CA_n261(A-D-O)	-	800	0
CA_n261(A-D-20)	-	800	0
CA_n261(A-G)	CA_n261G	600	0
CA_n261(A-G-H)	CA_n261G	800	0
CA_11201(A-G-11)	CA_n261H	800	0
CA_n261(A-G-I)	CA_n261G	800	0
CA_11261(A-G-I)		800	0
	CA_n261H		
	CA_n261I	800	0
CA_n261(A-G-O)	-	800	0
CA_n261(2A-G-O)	-	800	0
CA_n261(A-G-2O)	-	800	0
CA_n261(2A-G-2O)	-	800	0
CA_n261(A-2G-O)	-	800	0
CA_n261(A-2G-2O)	-	800	0
CA_n261(A-3G)	-	800	0
CA_n261(A-3G-O)	-	800	0
CA_n261(A-2G)	CA_n261G	800	0
CA_n261(A-4G)	-	800	0
CA_n261(A-H)	CA_n261G	700	0
	CA_n261H		
CA_n261(A-2H)	-	800	0
CA_n261(A-H-I)	-	800	0
CA_n261(A-I)	CA_n261G	800	0
	CA_n261H		
	CA_n261I		
CA_n261(A-2I)	-	800	0
CA_n261(A-J)	CA_n261G	700	0
~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~	CA_n261H		-
	CA_n261I		
CA_n261(A-K)	CA_n261G	800	0
	CA_n261H		-
	CA_n2611		
CA_n261(A-L)	CA_n261A	800	0
	CA_n261G		-
	CA_n261H		
	CA_n2611		
CA_n261(A-O)	-	600	0
CA_n261(A-O-P)	-	800	0
CA_n261(A-O-Q)	_	800	0
CA_n261(2A-O)	-	800	0
		000	0
CA_n261(A-20)	-	800	0

CA_n261(A-3O)	-	800	0
CA_n261(A-4O)	-	800	0
CA_n261(A-5O)	-	800	0
CA_n261(A-6O)	-	800	0
CA_n261(A-7O)	-	800	0
CA_n261(A-P)	-	700	0
CA_n261(A-P-Q)	-	800	0
CA_n261(2A-P)	-	800	0
CA_n261(A-2P)	-	800	0
CA_n261(A-Q)	-	800	0
CA_n261(2A-Q)	-	800	0
CA_n261(A-2Q)	-	800	0
CA_n261(2A-G)	CA_n261G	800	0
CA_n261(2A-2G)	-	800	0
CA_n261(2A-2G-O)	-	800	0
CA_n261(2A-3G)	-	800	0
CA_n261(2A-2O)	-	800	0
CA_n261(2A-30)	-	800	0
CA_n261(2A-3O)	-	800	0
CA_n261(2A-40)		800	0
· · · · · · · · · · · · · · · · · · ·	-		
CA_n261(2A-6O)	-	800	0
CA_n261(2A-H)	CA_n261G	800	0
	CA_n261H	000	0
CA_n261(2A-I)	CA_n261G	800	0
	CA_n261H		
	CA_n261I		
CA_n261(3A-G)	CA_n261G	800	0
CA_n261(3A-G-O)	-	800	0
CA_n261(3A-2G)	-	800	0
CA_n261(3A-D)	-	800	0
CA_n261(3A-O)	-	800	0
CA_n261(3A-2O)	-	800	0
CA_n261(3A-3O)	-	800	0
CA_n261(3A-4O)	-	800	0
CA_n261(3A-5O)	-	800	0
CA_n261(4A-G)	-	800	0
CA_n261(4A-O)	-	800	0
CA_n261(4A-2O)	-	800	0
CA_n261(4A-3O)	-	800	0
CA_n261(4A-4O)	-	800	0
CA_n261(5A-O)	-	800	0
CA_n261(5A-2O)	-	800	0
CA_n261(5A-3O)	-	800	0
CA_n261(6A-O)	-	800	0
CA_n261(6A-2O)	-	800	0
CA_n261(7A-O)	-	800	0
CA_n261(D-G)	CA_n261D	600	0
	CA_n261G		, v
		700	0
CA_n261(D-H)	CA_n261D	700	0
	CA_n261H		
CA_n261(D-I)	CA_n261D	800	0
	CA_n261I		
CA_n261(D-O)	CA_n261D	600	0
	CA_n2610		_
		800	0
CA n261(D 2O)	_		U
CA_n261(D-20)	- CA n261D		Δ
CA_n261(D-2O) CA_n261(D-P)	CA_n261D	700	0
CA_n261(D-P)	CA_n261D CA_n261P	700	
	CA_n261D CA_n261P CA_n261D		0
CA_n261(D-P)	CA_n261D CA_n261P	700	
CA_n261(D-P)	CA_n261D CA_n261P CA_n261D	700	
CA_n261(D-P) CA_n261(D-Q)	CA_n261D CA_n261P CA_n261D CA_n261D CA_n261Q	700 800	0
CA_n261(D-P) CA_n261(D-Q) CA_n261(E-O)	CA_n261D CA_n261P CA_n261D CA_n261Q CA_n261E CA_n261O	700 800 800	0
CA_n261(D-P) CA_n261(D-Q)	CA_n261D CA_n261P CA_n261D CA_n261Q CA_n261C CA_n261C CA_n261C	700 800	0
CA_n261(D-P) CA_n261(D-Q) CA_n261(E-O)	CA_n261D CA_n261P CA_n261D CA_n261Q CA_n261E CA_n261O	700 800 800	0

	CA_n261E CA_n261Q		
CA_n261(G-I)	CA_n261G CA_n261H	600	0
	CA_n261I		
CA_n261(G-H)	CA_n261G	500	0
	CA_n261H		
CA_n261(G-J)	CA_n261A	700	0
	CA_n261G		
	CA_n261H		
	CA_n261I		
CA_n261(2G-2O)	-	800	0
CA_n261(G-O)	-	400	0
CA_n261(G-20)	-	600	0
CA_n261(2G-O)	-	600	0
CA_n261(3G-O)	-	800	0
CA_n261(H-I)	CA_n261G CA_n261H	700	0
	CA_n261I		
CA_n261(O-P)	-	500	0
CA_n261(O-Q)	-	600	0
CA n261(P-Q)	-	700	0
NOTE 1: Void			
NOTE 2: Void			
NOTE 3: Channel band	width per operating ba	and defined in Table 5.3.5-1	
		uous CA defined in Table 5.5	5A.1-1
		ontiguous CA defined in Tabl	
NOTE 6: Void			
NOTE 7. Unless other	vise stated BCS0 is re	oferred in each constituent C	A configuration

NOTE 7: Unless otherwise stated, BCS0 is referred in each constituent CA configuration.

NOTE 8: $\Sigma(BW_{Channel,block})$ denotes the maximum total bandwidth from the summation of the sub-block bandwidths and shall be less than the bandwidth of the operating band.

5.5A.3 Configurations for inter-band CA

Table 5.5A.3-1: NR CA configurations for inter-band CA

NR CA configuration	Uplink CA configuration	NR Band	Channel bandwidth (MHz) (NOTE 1)	Bandwidth combination se	
CA_n257A-n259A	CA_n257A-n259A ³	n257	50, 100, 200, 400	0	
		n259	50, 100, 200, 400		
CA_n257A-n259G	CA_n257A-n259A ³	n257	50, 100, 200, 400	0	
		n259	CA_n259G		
CA_n257A-n259H	CA_n257A-n259A ³	n257	50, 100, 200, 400	0	
		n259	CA_n259H		
CA_n257A-n259I	CA_n257A-n259A ³	n257	50, 100, 200, 400	0	
_		n259	CA_n259I		
CA_n257A-n259J	CA_n257A-n259A ³	n257	50, 100, 200, 400	0	
_		n259	CA_n259J		
CA_n257A-n259K	CA_n257A-n259A ³	n257	50, 100, 200, 400	0	
-	-	n259	CA_n259K		
CA_n257A-n259L	CA_n257A-n259A ³	n257	50, 100, 200, 400	0	
—	-	n259	CA_n259L		
CA_n257A-n259M	CA_n257A-n259A ³	n257	50, 100, 200, 400	0	
		n259	CA_n259M	-	
CA_n257G-n259A	CA_n257A-n259A ³	n257	CA_n257G	0	
•••_••••		n259	50, 100, 200, 400		
CA_n257G-n259G	CA_n257A-n259A ³	n257	CA_n257G	0	
0.1_11201 0 112000	0.1_11201.1 11200.1	n259	CA_n259G		
CA_n257G-n259H	CA_n257A-n259A ³	n257	CA_n257G	0	
	0/(_120//(1200/(n259	CA_n259H	-	
CA_n257G-n259I	CA n257A-n259A ³	n257	CA_n257G	0	
07_11207 0-112001	0A_11207A-11209A	n259	CA_n259I		
CA_n257G-n259J	CA_n257A-n259A ³	n257	CA_n257G	0	
0A_11237 0-112333	0A_11237A-11233A	n259	CA_n259J	- 0	
CA_n257G-n259K	CA_n257A-n259A ³	n259 n257	CA_n2595 CA_n257G	0	
CA_II257G-II259K	CA_11257A-11259A	n259	CA_n259K	- 0	
CA_n257G-n259L	CA_n257A-n259A ³	n257		0	
CA_N257G-N259L	CA_n257A-n259A°		CA_n257G	0	
CA = 257C = 250M		n259	CA_n259L	0	
CA_n257G-n259M	CA_n257A-n259A ³	n257	<u>CA_n257G</u>	0	
CA_n257H-n259A	CA_n257A-n259A ³	n259	CA_n259M	0	
CA_1257H-1259A	CA_n25/A-n259A°	n257	CA_n257H	0	
04 = 25711 = 2500		n259	50, 100, 200, 400	0	
CA_n257H-n259G	CA_n257A-n259A ³	n257	CA_n257H	0	
04	04	n259	CA_n259G		
CA_n257H-n259H	CA_n257A-n259A ³	n257	CA_n257H	0	
0.4 05711 0501	0.0 0570 050.03	n259	CA_n259H		
CA_n257H-n259I	CA_n257A-n259A ³	n257	CA_n257H	0	
0.4 0.5714 0.501	0.0.057.050.03	n259	CA_n2591		
CA_n257H-n259J	CA_n257A-n259A ³	n257	CA_n257H	0	
0 • • • • • • • • • • • • • • • • • • •	0	n259	CA_n259J		
CA_n257H-n259K	CA_n257A-n259A ³	n257	CA_n257H	0	
	• • • • • • • • •	n259	CA_n259K		
CA_n257H-n259L	CA_n257A-n259A ³	n257	CA_n257H	0	
	•	n259	CA_n259L		
CA_n257H-n259M	CA_n257A-n259A ³	n257	CA_n257H	0	
		n259	CA_n259M		
CA_n257I-n259A	CA_n257A-n259A ³	n257	CA_n257I	0	
		n259	50, 100, 200, 400		
CA_n257I-n259G	CA_n257A-n259A ³	n257	CA_n257I	0	
		n259	CA_n259G		
CA_n257I-n259H	CA_n257A-n259A ³	n257	CA_n257I	0	
		n259	CA_n259H		
CA_n257I-n259I	CA_n257A-n259A ³	n257	CA_n257I	0	
	n259		CA_n259I		
CA_n257I-n259J	CA_n257A-n259A ³	n257	CA_n257I	0	
	n259 CA_n259J		7		
CA_n257I-n259K	CA_n257A-n259A ³	n257	CA_n257I	0	
		n259	CA_n259K	- ĭ	
CA_n257I-n259L	CA_n257A-n259A ³	n257	CA_n257I	0	
		n259	CA_n259L	1	
CA_n257I-n259M	CA_n257A-n259A ³	n257	CA_n257I	0	

		n259	CA_n259M	
CA_n258A-n260A	-	n258	50, 100, 200, 400	0
		n260	50, 100, 200, 400	
CA_n258A-n261A	-	n258	50, 100, 200, 400	0
<u>.</u>		n261	50, 100, 200, 400	
CA_n260A-n261A	CA_n260A-n261A ³	n260	50, 100, 200, 400	0
		n261	50, 100, 200, 400	
CA_n260A-n261G		n260	50, 100, 200, 400	0
		n261	CA_n261G	
CA_n260A-n261H		n260	50, 100, 200, 400	0
	CA_n260A-n261A ³	n261	CA_n261H	
CA_n260A-n261I	CA_n261G	n260	50, 100, 200, 400	0
	CA_n261H	n261	CA_n261I	
CA_n260A-n261J	CA_n261I	n260	50, 100, 200, 400	0
	CA_n261J	n261	CA_n261J	
CA_n260A-n261K	CA_n261K	n260	50, 100, 200, 400	0
	CA_n261L	n261	CA_n261K	
CA n260A-n261L	CA_n261M	n260	50, 100, 200, 400	0
		n261	CA_n261L	
CA n260A-n261M		n260	50, 100, 200, 400	0
0.1_11200.111201111		n261	CA_n261M	Ũ
CA_n260G-n261A		n260	CA_n260G	0
		n260	50, 100, 200, 400	U
CA_n260G-n261G	4			0
CA_1260G-1261G		n260	CA_n260G	0
	CA n260A-n261A ³	n261	CA_n261G	
CA_n260G-n261H	CA_n260G	n260	CA_n260G	0
	CA_n261G	n261	CA_n261H	
CA_n260G-n261I	CA_n261H	n260	CA_n260G	0
	CA_120111 CA_n2611	n261	CA_n261I	
CA_n260G-n261J	CA_n261J	n260	CA_n260G	0
	CA_112013 CA_112013	n261	CA_n261J	
CA_n260G-n261K	CA_1261K CA_1261L	n260	CA_n260G	0
_	CA_1261L CA_1261M	n261	 CA_n261K	
CA_n260G-n261L	CA_II201M	n260	CA_n260G	0
		n261	CA_n261L	C C
CA_n260G-n261M	-	n260	CA_n260G	0
0A_112000-112011		n261	CA_n260C	0
CA_n260H-n261A		n260	CA_n260H	0
		n260	50, 100, 200, 400	0
04 = 20011 = 2010	4			0
CA_n260H-n261G		n260	CA_n260H	0
	CA_n260A-n261A ³	n261	CA_n261G	
CA_n260H-n261H	CA_n260G	n260	CA_n260H	0
	CA_n260H	n261	CA_n261H	
CA_n260H-n261I	CA_n261G	n260	CA_n260H	0
	CA_n261H	n261	CA_n261I	
CA_n260H-n261J	CA_n261I	n260	CA_n260H	0
	CA_n261J	n261	CA_n261J	
CA_n260H-n261K	CA_n261K	n260	CA_n260H	0
	CA_n261L	n261	 CA_n261K	
CA_n260H-n261L	CA_n261M	n260	CA_n260H	0
		n261	CA_n261L	2
CA_n260H-n261M	1	n260	CA_n260H	0
		n261	CA_n261M	Ū
CA_n260I-n261A		n260	CA_n260I	0
	CA_n260A-n261A ³	n260	50, 100, 200, 400	U
CA_n260I-n261G	CA_n260G			0
GA_112001-11201G	CA_n260H	n260	CA_n260I	U
04	CA_n260I	n261	CA_n261G	~
CA_n260I-n261H	CA_n261G	n260	CA_n260I	0
	CA_n261H	n261	CA_n261H	
CA_n260I-n261I	CA_n261I	n260	CA_n260I	0
	- CA_n261J	n261	CA_n261I	
CA_n260I-n261J	CA_n261K	n260	CA_n260I	0
	CA_1261K CA_n261L	n261	CA_n261J	
CA_n260I-n261K	CA_n261M	n260	CA_n260I	0

CA_n260I-n261L		n260	CA_n260I	0
•••		n261	CA_n261L	-
CA_n260I-n261M		n260	CA_n260I	0
		n261	CA_n261M	-
CA_n260J-n261A		n260	CA_n260J	0
		n261	50, 100, 200, 400	
CA_n260J-n261G	CA_n260A-n261A ³	n260	CA_n260J	0
	CA_n260G	n261	CA_n261G	
CA_n260J-n261H	CA_n260H	n260	CA_n260J	0
0.4 0.00 1 0.00 1	CA_n260I	n261	CA_n261H	
CA_n260J-n261I	CA_n260J	n260	CA_n260J	0
CA n260J-n261J	CA_n261G	n261	CA_n261I	0
CA_n260J-n261J	CA_n261H CA_n261I	n260	CA_n260J	0
CA_n260J-n261K	CA_n261J	n261	CA_n261J	0
CA_11200J-11201K	CA_n261K	n260 n261	CA_n260J CA_n261K	0
CA_n260J-n261L	CA_n261L	n260	CA_n260J	0
CA_11200J-11201L	CA_n261M	n261	CA_12605 CA_n261L	0
CA n260J-n261M	-	n260	CA_n260J	0
CA_112003-112011vi		n261	CA_12005 CA_n261M	0
CA n260K-n261A		n260	CA_1260K	0
		n261	50, 100, 200, 400	0
CA_n260K-n261G	CA n260A-n261A ³	n260	CA_n260K	0
	CA_n260G	n261	CA_1200K CA_n261G	0
CA_n260K-n261H	CA_n260H	n260	CA_n260K	0
	CA_n260I	n261	CA n261H	0
CA_n260K-n261I	CA_n260J	n260	CA_n260K	0
0/_12001(112011	CA_n260K	n261	CA_n261I	
CA_n260K-n261J	CA_n261G	n260	CA_n260K	0
	CA_n261H	n261	CA_n261J	
CA_n260K-n261K	- CA_n261I	n260	CA_n260K	0
0/(_1/2001(11/2011(CA_n261J	n261	CA_n261K	
CA_n260K-n261L	_ CA_n261K	n260	CA_n260K	0
	CA_n261L CA_n261M	n261	CA_n261L	
CA_n260K-n261M		n260	CA_n260K	0
		n261	CA_n261M	Ĩ
CA_n260L-n261A		n260	CA_n260L	0
	CA_n260A-n261A ³	n261	50, 100, 200, 400	
CA_n260L-n261G	CA_1260A-1261A	n260	CA_n260L	0
-	CA_1200G	n261	 CA_n261G	
CA_n260L-n261H	CA_n260I	n260	 CA_n260L	0
	CA_n260J	n261	CA_n261H	
CA_n260L-n261I	CA_n260K	n260	CA_n260L	0
	CA_n260L	n261	CA_n261I	
CA_n260L-n261J	CA_n261G	n260	CA_n260L	0
	CA_n261H	n261	CA_n261J	
CA_n260L-n261K	CA_n261I	n260	CA_n260L	0
	CA_n261J	n261	CA_n261K	
CA_n260L-n261L	CA_n261K	n260	CA_n260L	0
	CA_n261L	n261	CA_n261L	
CA_n260L-n261M	CA_n261M	n260	CA_n260L	0
		n261	CA_n261M	
CA_n260M-n261A		n260	CA_n260M	0
		n261	50, 100, 200, 400	
CA_n260M-n261G		n260	CA_n260M	0
		n261	CA_n261G	
CA_n260M-n261H		n260	CA_n260M	0
		n261	CA_n261H	
CA_n260M-n261I		n260	CA_n260M	0
		n261	CA_n261I	
CA_n260M-n261J		n260	CA_n260M	0
		n261	CA_n261J	
CA_n260M-n261K	A_n260M-n261K n260 CA_n260M		0	
		n261	CA_n261K	
CA_n260M-n261L	1	n260	CA_n260M	0

	CA_n260A-n261A ³	n261	CA_n261L	
CA_n260M-n261M	CA_n260G	n260	CA_n260M	0
	CA_n260H			
	CA_n260I			
	CA_n260J			
	CA_n260K			
	CA_n260L			
	CA_n260M			
	CA_n261G	n261		
	CA_n261H			
	CA_n261I			
	CA_n261J			
	CA_n261K			
	CA_n261L			
	CA_n261M		CA_n261M	
NOTE 1: The SCS of each channel bandwidth for NR band refers to Table 5.3.5-1.				
NOTE 2: Unless otherwise stated, BCS0 is referred in each constituent CA configuration				
NOTE 3: UL CA combination applicable to power classes 1, 2 and 5 only				

5.5D Configurations for UL MIMO

The requirements specified in clause 5.5 are applicable to UE supporting UL MIMO.

6 Transmitter characteristics

6.1 General

Unless otherwise stated, the transmitter characteristics are specified over the air (OTA) with a single or multiple transmit chains.

Unless otherwise stated, for power class 3 UEs, the beam correspondence side condition for SSB and CSI-RS specified in clause 6.6.4 shall apply to the transmission tests.

Transmitter requirements for CA operation apply only when the DMRS initialization parameters (including the case when the UE applies cell ID as DMRS scrambling ID) are different across all CCs. The UE may use higher MPR values outside this limitation.

For a UE that supports 'UL full power transmission' and is configured to transmit a single layer with *nrofSRS-Ports* = 2, the requirements for UL MIMO operation apply only when it is configured for any of its declared full power modes in IE *FullPowerTransmission-r16* (as defined in TS 38.331[13]).

For a UE configured to transmit 2 layers, transmitter requirements for UL MIMO operation apply when the UE transmits on 2 ports on the same CDM group. The UE may use higher MPR values outside this limitation.

6.2 Transmitter power

6.2.1 UE maximum output power

6.2.1.0 General

NOTE: Power classes are specified based on the assumption of certain UE types with specific device architectures. The UE types can be found in Table 6.2.1.0-1.

UE Power class	UE type		
1	Fixed wireless access (FWA) UE		
2	Vehicular UE		
3	Handheld UE		
4	High power non-handheld UE		
5	Fixed wireless access (FWA) UE		
6	High Speed Train Roof-Mounted UE		
7	RedCap UE		
Note: RedCap variants of non-RedCap UEs are not precluded			

Table 6.2.1.0-1: Assumption of UE Types

Power class 3 is default power class.

6.2.1.1 UE maximum output power for power class 1

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.1-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)	
n257	40.0	
n258	40.0	
n260	38.0	
n261	40.0	
n262	34.2	
n263 30.6		
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance		

Table 6.2.1.1-1: UE minimum peak EIRP for power class 1

The maximum output power values for TRP and EIRP are found in Table 6.2.1.1-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.1-2: UE maximum output power limits for power class 1

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	35	55
n258	35	55
n260	35	55
n261	35	55
n262	35	55

The minimum EIRP at the 85th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.1-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Operating band	Min EIRP at 85 %-tile CDF (dBm)	
n257	32.0	
n258	32.0	
n260	30.0	
n261	32.0	
n262 26.0		
n263 19.1		
NOTE 1: Minimum EIRP at 85 %-tile CDF is defined as		
the lower limit without tolerance		

The requirements in this table are verified only under normal temperature conditions as

Table 6.2.1.1-3: UE spherical coverage for power class 1

6.2.1.2 UE maximum output power for power class 2

NOTE 2:

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.2-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

defined in Annex E.2.1.

Operating band	Min peak EIRP (dBm)	
n257	29	
n258	29	
n259	25	
n261	29	
n262	22.9	
n263 22.7		
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance		

Table 6.2.1.2-1: UE minimum peak EIRP for power class 2

The maximum output power values for TRP and EIRP are found in Table 6.2.1.2-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

 Table 6.2.1.2-2: UE maximum output power limits for power class 2

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n259	23	43
n261	23	43
n262	23	43
n263	23	43

The minimum EIRP at the 60th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.2-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Operating band	Min EIRP at 60 %-tile CDF (dBm)	
n257	18.0	
n258	18.0	
n259	12.5	
n261	18.0	
n262	11.0	
n263 7.6		
NOTE 1: Minimum	Minimum EIRP at 60 %-tile CDF is defined as	
the lower	the lower limit without tolerance	
	The requirements in this table are verified only	
under nor	under normal temperature conditions as	
defined in	defined in Annex E.2.1.	

Table 6.2.1.2-3: UE spherical coverage for power class 2

6.2.1.3 UE maximum output power for power class 3

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.3-1. The requirement is verified with the test metric of total component of EIRP (Link=TX beam peak direction, Meas=Link angle). The requirement for the UE which supports a single FR2 band is specified in Table 6.2.1.3-1. The requirement for the UE which supports a specified in both Table 6.2.1.3-1 and Table 6.2.1.3-4.

Operating band	Min peak EIRP (dBm)	
n257	22.4	
n258	22.4	
n259	18.7	
n260	20.6	
n261	22.4	
n262	16.0	
n263	14.1	
NOTE 1: Minimum	Minimum peak EIRP is defined as the	
lower limit	lower limit without tolerance	
NOTE 2: Void	Void	

 Table 6.2.1.3-1: UE minimum peak EIRP for power class 3

The maximum output power values for TRP and EIRP are found on the Table 6.2.1.3-2. The max allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and the total component of EIRP (Link=TX beam peak direction, Meas=Link angle.

Table 6.2.1.3-2: UE maximum output power limits for power class 3

Operating band	Max TRP (dBm)	Max EIRP (dBm)	Max EIRP (dBm/MHz)	Notes
n257	23	43		
n258	23	43		
n259	23	43		
n260	23	43		
n261	23	43		
n262	23	43		
n263	FFS	FFS		[Default for NS_200]
	27	40 (NOTE1)	23	Applies when "NS_204" is indicated in the cell
				NOTE 1: it is max average EIRP

The minimum EIRP at the 50th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.3-3 below. The requirement is verified with the test metric of the total component of EIRP (Link=Beam peak search grids, Meas=Link angle). The requirement for the UE which supports a single FR2 band is specified in Table 6.2.1.3-3. The requirement for the UE which supports multiple FR2 bands is specified in both Table 6.2.1.3-3 and Table 6.2.1.3-4.

Oţ	perating band	Min EIRP at 50 %-tile CDF (dBm)
	n257	11.5
	n258	11.5
	n259	5.8
n260		8
n261 11.5		11.5
n262		2.9
n263		2.3
NOTE 1:	Minimum EIRP at 50 %-tile CDF is defined as the lower limit without tolerance	
NOTE 2:	NOTE 2: Void	
NOTE 3:	NOTE 3: The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.	

For the UEs that support multiple FR2 bands, minimum requirement for peak EIRP and EIRP spherical coverage in Tables 6.2.1.3-1 and 6.2.1.3-3 shall be decreased per band, respectively, by the peak EIRP relaxation parameter $\Delta MB_{P,n}$ and EIRP spherical coverage relaxation parameter $\Delta MB_{S,n}$, as defined in Table 6.2.1.3-4..

Band	∆MB _{P,n} (dB)	∆MB _{s,n} (dB)
n257	0.7 ³	0.7 ³
n258	0.6	0.7
n259	0.5	0.4
n260	0.5 ¹	0.4 ¹
n261	0.5 ^{2,4}	0.74
n262	0.7	0.7
n263	1.0	1.0
Note 1: n260 peak and spherical relaxations are 0 dB for UE that exclusively supports		
n261+n260		
Note 2: n261 peak relaxation is 0 dB for UE that exclusively supports n261+n260		
Note 3: n257 peak and spherical relaxations are 0 dB for UE that exclusively supports		
n261+n257		
Note 4: n261 peak and spherical relaxations are 0 dB for UE that exclusively supports		
n261+n257		

6.2.1.4 UE maximum output power for power class 4

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.4-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)	
n257	34	
n258	34	
n260	31	
n261	34	
n262 28.3		
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance		

The maximum output power values for TRP and EIRP are found in Table 6.2.1.4-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.4-2: UE maximum out	put power limits for power class 4

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43
n262	23	43

The minimum EIRP at the 20th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.4-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Operati	ing band Min EIRP at 20 %-tile CDF (dB	
n2	57	25
n2	58	25
n2	60	19
n261		25
n2	262 16.2	
NOTE 1:	Minimum EIRP at 20 %-tile CDF is defined as the lower limit without tolerance	
NOTE 2:	The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.	

Table 6.2.1.4-3: UE spherical coverage for power class 4

6.2.1.5 UE maximum output power for power class 5

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.5-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.5-1: UE minimum p	eak EIRP for power class 5
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Operating band	Min peak EIRP (dBm)
n257	30
n258	30.4
n259	27.7
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance	

The maximum output power values for TRP and EIRP are found in Table 6.2.1.5-2 below. The maximum allowed EIRP is derived from regulatory requirements. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.5-2: UE maximum output power limits for power class 5

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n259	23	43

The minimum EIRP at the 85th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.5-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2.1.4-3: UE spherical coverage for power class 5

Operati	ting band Min EIRP at 85 %-tile CDF (dBm	
n2	257	22
n2	258	22.4
n2	259 19.7	
NOTE 1:		EIRP at 85 %-tile CDF is defined as imit without tolerance
NOTE 2:	The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.	

For the UEs that support multiple FR2 bands, minimum requirement for peak EIRP and EIRP spherical coverage in Tables 6.2.1.5-1 and 6.2.1.5-3 shall be decreased per band, respectively, by the peak EIRP relaxation parameter $\Delta MB_{P,n}$ and EIRP spherical coverage relaxation parameter $\Delta MB_{S,n}$, as defined in Table 6.2.1.5-4..

Band	ΔMB _{P,n} (dB)	ΔMB _{S,n} (dB)
n257	0.7	0.7
n258	0.7	0.7
n259	0.5	0,5

Table 6.2.1.5-4: UE multi-band relaxation factors for	nower class 5

6.2.1.6 UE maximum output power for power class 6

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.6-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)	
n257	30	
n258	30.4	
n261 30		
NOTE 1: Minimum peak EIRP is defined as the		
lower limit without tolerance		

The maximum output power values for TRP and EIRP are found in Table 6.2.1.6-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43

The minimum EIRP measured over the spherical coverage evaluation areas specified below is defined as the spherical coverage requirement and is found in Table 6.2.1.6-3 below. UE spherical coverage evaluation areas are found in Table 6.2.1.6-3a below, by consisting of Area-1 and Area-2, in the reference coordinate system in Annex J.1. The requirement is verified with the test metric of EIRP (Link= Spherical coverage grid, Meas=Link angle).

Table 6.2.1.6-3: UE spherical coverage for power class	pherical coverage for power c	er class 6
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Operati	ting band Min EIRP over UE spherical coverage evaluation areas (dBm)	
n2	57	20
n2	58	20.4
n2	61	20
	Minimum EIRP over UE spherical coverage evaluation areas is defined as the lower limit without tolerance The requirements in this table are verified only under normal temperature conditions as defined in Annex	
NOTE 3:	E.2.1. The requirements in this table are applicable to FR2 PC6 UE with the network signalling [highSpeedMeasFlag-r17] configured as [set2].	

		θ range (degree)	φ range (degree)	
Area-1		90 to 60	- 37.5 to + 37.5	
Area-2		90 to 60	142.5to 217.5	
NOTE 1:	When testing power class 6 UEs, DUT orientation can be determined according to the UE spherical coverage evaluation areas, not necessarily following default alignment in Figure J.1-2 or positioning guidelines in clause J.3.			
NOTE 2:	High speed train deployment is expected to be w.r.t. the reference coordination system: θ = 90 (degree) corresponds to the ground plane the train is running on, and ϕ = 0 or 180 with θ = 90 are the train track directions.			

Table 6.2.1.6-3a: UE spherical coverage evaluation areas for power class 6

For the UEs that support multiple FR2 bands, minimum requirement for peak EIRP and EIRP spherical coverage in Tables 6.2.1.6-1 and 6.2.1.6-3 shall be decreased per band, respectively, by the peak EIRP relaxation parameter $\Delta MB_{P,n}$ and EIRP spherical coverage relaxation parameter $\Delta MB_{S,n}$, as defined in Table 6.2.1.6-4.

Table 6.2.1.6-4: UE multi-band relaxation factors for power class 6

Band	ΔMB _{P,n} (dB)	∆MB _{s,n} (dB)
n257	0.7	0.7
n258	0.7	0.7
n261	0.7	0.7

6.2.1.7 UE maximum output power for power class 7

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.7-1. The requirement is verified with the test metric of total component of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)
n257	16.4
n258	16.4
n261	16.4
	beak EIRP is defined as the without tolerance
NOTE 2: Void	

The maximum output power values for TRP and EIRP are found on the Table 6.2.1.7-2. The max allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and the total component of EIRP (Link=TX beam peak direction, Meas=Link angle.

Table 6.2.1.7-2: UE maximum output power limits for power class 7

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43

The minimum EIRP at the 50th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.7-3 below. The requirement is verified with the test metric of the total component of EIRP (Link=Beam peak search grids, Meas=Link angle).

Operating band		Min EIRP at 50 %-tile CDF (dBm)	
	n257	5.5	
n258		5.5	
n261		5.5	
	Minimum EIRP at 50 %-tile CDF is defined as the lower limit without tolerance		
	2: The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.		

 Table 6.2.1.7-3: UE spherical coverage for power class 7

For power class 7 UEs that support multiple FR2 bands, minimum requirement for peak EIRP and EIRP spherical coverage in Tables 6.2.1.7-1 and 6.2.1.7-3 shall be decreased per band, respectively, by the peak EIRP relaxation parameter $\Delta MB_{P,n}$ and EIRP spherical coverage relaxation parameter $\Delta MB_{S,n}$, as defined for power class 3 in Table 6.2.1.3-4.

6.2.2 UE maximum output power reduction

6.2.2.0 General

The requirements in clause 6.2.2 only apply when both UL and DL of a UE are configured for single CC operation, and they are of the same bandwidth. A UE may reduce its maximum output power due to modulation orders, transmit bandwidth configurations, waveform types and narrow allocations. This Maximum Power Reduction (MPR) is defined in clauses below. The allowed MPR for SRS, PUCCH formats 0, 1, 3 and 4, and PRACH shall be as specified for QPSK modulated DFT-s-OFDM of equivalent RB allocation. The allowed MPR for PUCCH format 2 shall be as specified for QPSK modulated CP-OFDM of equivalent RB allocation. When the maximum output power of a UE is modified by MPR, the power limits specified in clause 6.2.4 apply.

For a UE that is configured for single CC operation with different channel bandwidths in UL and DL, the requirements in clause 6.2A.2 apply.

For all power classes, the waveform defined by BW = 100 MHz, SCS = 120 kHz, DFT-S-OFDM QPSK, 20RB23 is the reference waveform with 0 dB MPR and is used for the power class definition.

6.2.2.1 UE maximum output power reduction for power class 1

For power class 1, MPR for contiguous allocations is defined as:

$$MPR = max(MPR_{WT}, MPR_{narrow})$$

Where,

 $MPR_{narrow} = 14.4 \text{ dB}$, when $BW_{alloc,RB} \le 1.44 \text{ MHz}$, $MPR_{narrow} = 10 \text{ dB}$, when $1.44 \text{ MHz} < BW_{alloc,RB} \le 10.8 \text{ MHz}$, where $BW_{alloc,RB}$ is the bandwidth of the RB allocation size.

 MPR_{WT} is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in table 5.3.2-1, and waveform types. MPR_{WT} is defined in Tables 6.2.2.1-1 and 6.2.2.1-2 for FR2-1 and in Tables 6.2.2.1-3 and 6.2.2.1-4 for FR2-2.

Modulation		MPRwτ (dB), BW _{channel} ≤ 200 MHz		
		Outer RB allocations	Inner RB allocations	
			Region 1	Region 2
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5	0.0	≤ 3.0
	QPSK	≤ 6.5	0.0	≤ 3.0
	16 QAM	≤ 6.5	≤ 4.0	≤ 4.0
	64 QAM	≤ 6.5	≤ 5.0	≤ 5.0
CP-OFDM	QPSK	≤ 7.0	≤ 4.5	≤ 4.5
	16 QAM	≤ 7.0	≤ 5.5	≤ 5.5
	64 QAM	≤ 7.5	≤ 7.5	≤ 7.5

Table 6.2.2.1-1 MPR_{WT} for power class 1, BW_{channel} ≤ 200 MHz

Table 6.2.2.1-2 MPR_{WT} for power class 1, BW_{channel} = 400 MHz

Modulation		MPRwt (dB), BW _{channel} = 400 MHz		
		Outer RB allocations	Inner RB allocations	
			Region 1	Region 2
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5	0.0	≤ 3.0
	QPSK	≤ 6.5	0.0	≤ 3.5
	16 QAM	≤ 6.5	≤ 4.5	≤ 4.5
	64 QAM	≤ 6.5	≤ 6.5	≤ 6.5
CP-OFDM	QPSK	≤ 7.0	≤ 5.0	≤ 5.0
	16 QAM	≤ 7.0	≤ 6.5	≤ 6.5
	64 QAM	≤ 9.0	≤ 9.0	≤ 9.0

Table 6.2.2.1-3 MPR_{WT} for power class 1, BW_{channel} = 100 MHz in FR2-2

Modulation		MPR _{WT} (dB), BW _{channel} = 100 MHz		
		Outer RB allocations	Inner RB allocations	
			Region 1	Region 2
DFT-s-OFDM	Pi/2 BPSK	≤ [5.5]	[0.0]	≤ [3.5]
	QPSK	≤ [6.5]	[0.0]	≤ [3.5]
	16 QAM	≤ [7.0]	≤ [2.5]	≤ [2.5]
	64 QAM	≤ [8.0]	≤ [8.0]	≤ [8.0]
CP-OFDM	QPSK	≤ [8.0]	≤ [1.5]	≤ [3.5]
	16 QAM	≤ [8.0]	≤ [3.5]	≤ [4.0]
	64 QAM	≤ [9.5]	≤ [9.5]	≤ [9.5]

Modulation		MPRwt (dB), BW _{channel} = 400, 800, 1600, 2000 MHz		
		Outer RB allocations	Inner RB allocations	
			Region 1	Region 2
DFT-s-OFDM	Pi/2 BPSK	≤ [6.0]	≤ [1.0]	≤ [3.5]
	QPSK	≤ [6.0]	≤ [1.0]	≤ [4.0]
	16 QAM	≤ [4.5]	≤ [3.0]	≤ [3.0]
	64 QAM	≤ [8.0]	≤ [8.0]	≤ [8.0]
CP-OFDM	QPSK	≤ [6.0]	≤ [1.5]	≤ [3.5]
	16 QAM	≤ [6.0]	≤ [4.0]	≤ [5.5]
	64 QAM	≤ [10.0]	≤ [10.0]	≤ [10.0]

Where the following parameters are defined to specify valid RB allocation ranges for the RB allocations regions in Tables 6.2.2.1-1, 6.2.2.1-2, 6.2.2.1-3, and 6.2.2.1-4:

N_{RB} is the maximum number of RBs for a given Channel bandwidth and sub-carrier spacing defined in Table 5.3.2-1.

 $RB_{end} = RB_{Start} + L_{CRB}$ - 1

 $RB_{Start,Low} = Max(1, Floor(L_{CRB}/2))$

 $RB_{Start,High} = N_{RB} - RB_{Start,Low} - L_{CRB}$

An RB allocation is an Outer RB allocation if

$$RB_{Start} < RB_{Start,Low} OR RB_{Start} > RB_{Start,High} OR L_{CRB} > Ceil(N_{RB}/2)$$

An RB allocation belonging to table 6.2.2.1-1 is a Region 1 inner RB allocation if

 $RB_{start} \ge Ceil(1/3 N_{RB}) AND RB_{end} < Ceil(2/3 N_{RB})$

An RB allocation belonging to table 6.2.2.1-2 is a Region 1 inner RB allocation if

 $RB_{start} \ge Ceil(1/4 N_{RB}) AND RB_{end} < Ceil(3/4 N_{RB}) AND L_{CRB} \le Ceil(1/4 N_{RB})$

An RB allocation is a Region 2 inner allocation if it is NOT an Outer allocation AND NOT a Region 1 inner allocation

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2.4 apply.

6.2.2.2 UE maximum output power reduction for power class 2

For power class 2, MPR for FR2-1 and FR2-2 as specified in clause 6.2.2.3 applies.

Table 6.2.2.2-1: Void

6.2.2.3 UE maximum output power reduction for power class 3

For power class 3, MPR for contiguous allocations is defined as:

 $MPR = max(MPR_{WT}, MPR_{narrow})$

For transmission bandwidth configuration less than or equal to 200MHz, and $0 \le RB_{start} < Ceil(1/3 N_{RB})$ or

 $Ceil((2/3N_{RB})\text{-} L_{CRB}) < RB_{start} \leq N_{RB}\text{-}L_{CRB}$

- $MPR_{narrow} = 2.5 \text{ dB}$, when $BW_{alloc,RB}$ is less than or equal to 1.44 MHz,
- $MPR_{narrow} = 2.0 \text{ dB}$, when $1.44 \text{ MHz} < BW_{alloc,RB} <= 4.32 \text{ MHz}$,
- otherwise $MPR_{narrow} = 0 dB$.

 MPR_{WT} is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in Table 5.3.2-1, and waveform types. MPR_{WT} is defined for FR2-1 in Table 6.2.2.3-1.

Table 6.2.2.3-1 MPR_{WT} for power class 3, BWchannel ≤ 200 MHz, FR2-1

Modula	tion	MPRw⊤, BW _{channel} ≤ 200 MHz		
		Inner RB allocations, Region 1	Edge RB allocations	
DFT-s-OFDM	Pi/2 BPSK	0.0	≤ 2.0	
	QPSK	0.0	≤ 2.0	
	16 QAM	≤ 3.0	≤ 3.5	
	64 QAM	≤ 5.0	≤ 5.5	
CP-OFDM	QPSK	≤ 3.5	≤ 4.0	
	16 QAM	≤ 5.0	≤ 5.0	
	64 QAM	≤ 7.5	≤ 7.5	

MPR_{WT} is defined for FR2-2 in Table 6.2.2.3-1b.

Modulation		MPR _{WT} , BW _{channel} = 100 MHz			
		Inner RB allocations, Region 1	Edge RB allocations		
DFT-s-OFDM	Pi/2 BPSK	0.0	≤ [0.5]		
	QPSK	0.0	≤ [0.5]		
	16 QAM	≤ [3.0]	≤ [3.0]		
	64 QAM	≤ [8.5]	≤ [8.5]		
CP-OFDM	QPSK	≤ [1.5]	≤ [1.5]		
	16 QAM	≤ [4.0]	≤ [4.0]		
	64 QAM	≤ [10.0]	≤ [10.0]		

Table 6.2.2.3-1b MPR_{wT} for power class 3, BWchannel = 100 MHz, FR2-2

Where the following parameters are defined to specify valid RB allocation ranges for RB allocations in Table 6.2.2.3-1:

- $RB_{Start,Low} = max(1, L_{CRB})$, where max() indicates the largest value of all arguments.
- $RB_{Start,High} = N_{RB} RB_{Start,Low} L_{CRB}$,

An RB allocation belonging to table 6.2.2.3-1 is a Region 1 inner RB allocation if:

- $RB_{Start,Low} \leq RB_{Start} \leq RB_{Start,High}$, and $L_{CRB} \leq ceil(N_{RB}/3)$, where ceil(x) is the smallest integer greater than or equal to x.

For transmission bandwidth configuration equal to 400MHz,

 $MPR_{narrow} = 2.5 \text{ dB}$, when $BW_{alloc,RB}$ is less than or equal to 1.44 MHz, and $0 \le RB_{start} < Ceil(1/3 N_{RB})$ or $Ceil(2/3N_{RB}) \le RB_{start} \le N_{RB}-L_{CRB}$, where $BW_{alloc,RB}$ is the bandwidth of the RB allocation size.

 MPR_{WT} is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in Table 5.3.2-1, and waveform types. MPR_{WT} is defined for FR2-1 in Table 6.2.2.3-2.

Modulation		MPR _{WT} , BW _{channel} = 400 MHz			
		Inner RB allocations, Region 1	Edge RB allocations		
DFT-s-OFDM	Pi/2 BPSK	0.0	≤ 3.0		
	QPSK	0.0	≤ 3.0		
	16 QAM	≤ 4.5	≤ 4.5		
	64 QAM	≤ 6.5	≤ 6.5		
CP-OFDM	QPSK	≤ 5.0	≤ 5.0		
	16 QAM	≤ 6.5	≤ 6.5		
	64 QAM	≤ 9.0	≤ 9.0		

Table 6.2.2.3-2 MPR_{WT} for power class 3, BW_{channel} = 400 MHz, FR2-1

MPR_{WT} is defined for FR2-2 in Table 6.2.2.3-2b and 6.2.2.3-2c.

Table 6.2.2.3-2b MPR_{WT} for power class 3, BW_{channel} = 400 MHz, FR2-2

Modulation		MPR _{WT} , BW _{channel} = 400 MHz			
		Inner RB allocations, Region 1	Edge RB allocations		
DFT-s-OFDM	Pi/2 BPSK	≤ [1.0]	≤ 3.0		
	QPSK	≤ [1.0]	≤ 3.0		
	16 QAM	≤ 4.5	≤ 4.5		
	64 QAM	≤ [9.5]	≤ [9.0]		
CP-OFDM	QPSK	≤ 5.0	≤ 5.0		
	16 QAM	≤ 6.5	≤ 6.5		
	64 QAM	≤ 10.0	≤ 10.0		

Modulation		MPR _{WT} , BW _{channel} = 400 MHz			
		Inner RB allocations, Region 1	Edge RB allocations		
DFT-s-OFDM	Pi/2 BPSK	≤ [1.0]	≤ 4.0		
	QPSK	≤ [1.0]	≤ 4.0		
	16 QAM	≤ 6.0	≤ 6.0		
	64 QAM	≤ [9.5]	≤ [9.0]		
CP-OFDM	QPSK	≤ 6.5	≤ 6.5		
	16 QAM	≤ 8.0	≤ 8.0		
	64 QAM	≤ 10.5	≤ 10.5		

Table 6.2.2.3-2c MPR_{WT} for power class 3, BW_{channel} >= 800 MHz, FR2-2

Where the following parameters are defined to specify valid RB allocation ranges for RB allocations in Table 6.2.2.3-2:

N_{RB} is the maximum number of RBs for a given Channel bandwidth and sub-carrier spacing defined in Table 5.3.2-1.

$$RB_{end} = RB_{Start} + L_{CRB} - 1$$

An RB allocation belonging to table 6.2.2.3-2 is a Region 1 inner RB allocation if

 $RB_{start} \ge Ceil(1/4 N_{RB}) \text{ AND } RB_{end} < Ceil(3/4 N_{RB}) \text{ AND } L_{CRB} \le Ceil(1/4 N_{RB})$

For all transmission bandwidth configurations, an RB allocation is an Edge allocation if it is NOT a Region 1 inner allocation.

6.2.2.4 UE maximum output power reduction for power class 4

For power class 4, MPR specified in sub-clause 6.2.2.3 applies.

Table 6.2.2.4-1: Void

6.2.2.5 UE maximum output power reduction for power class 5

For power class 5, MPR specified in sub-clause 6.2.2.3 applies.

6.2.2.6 UE maximum output power reduction for power class 6

For power class 6, MPR specified in sub-clause 6.2.2.3 applies.

6.2.2.7 UE maximum output power reduction for power class 7

For power class 7, MPR specified in sub-clause 6.2.2.3 for channel bandwidth less than or equal to 200MHz applies.

6.2.3 UE maximum output power with additional requirements

6.2.3.1 General

Additional emission requirements can be signalled by the network. Each additional emission requirement is associated with a unique network signalling (NS) value indicated in RRC signalling by an NR frequency band number of the applicable operating band and an associated value in the field *additionalSpectrumEmission*. Throughout this specification, the notion of indication or signalling of an NS value refers to the corresponding indication of an NR frequency band number of the applicable operating band (the IE field *freqBandIndicatorNR*) and an associated value of *additionalSpectrumEmission* in the relevant RRC information elements.

To meet these additional requirements, additional maximum power reduction (A-MPR) is allowed for the maximum output power as specified in clause 6.2.1. Unless stated otherwise, an A-MPR of 0 dB shall be used.

Table 6.2.3.1-1 specifies the additional requirements with their associated network signalling values and the allowed A-MPR and applicable operating band(s) for each NS value. The mapping of NR frequency band numbers and values of the *additionalSpectrumEmission* to network signalling labels is specified in Table 6.2.3.1-2. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in clause 6.2.2.

Network Signalling Iabel	Requirements (clause)	NR Band	Channel bandwidth (MHz)	Resources Blocks (<i>N</i> _{RB})	A-MPR (dB)	
NS_200					N/A	
NS_201 (NOTE 1)	6.5.3.2.2	n258			6.2.3.2	
NS_202	6.5.3.2.3	n257, n258	50, 100, 200, 400	Table 5.3.2-1	6.2.3.3	
NS_203	6.5.3.2.4	n258	50, 100, 200, 400	Table 5.3.2-1	6.2.3.4	
NOTE 1: NS_201 is obsolete, the associated additional spurious emission requirements are not applicable.						

Table 6.2.3.1-1: Additional maximum power reduction (A-MPR)

NR Band	Value of additionalSpectrumEmission							
	0	1	2	3	4	5	6	7
n257	NS_200	NS_202						
n258	NS_200	NS_201 (NOTE 2)	NS_202	NS_203				
n259	NS_200							
n260	NS_200							
n261	NS_200							
n263	NS_200							
NOTE 1: a	NOTE 1: additionalSpectrumEmission corresponds to an information element of the same name defined in							
sub-clause 6.3.2 of TS 38.331 [13].								
NOTE 2: N	NOTE 2: NS_201 is obsolete, the associated additional spurious emission requirements are not applicable.							

- 6.2.3.2 Void
- 6.2.3.2.1 Void

Table 6.2.3.2.1-1: (Void)

6.2.3.2.2 Void

Table 6.2.3.2.2-1: (Void)

6.2.3.2.3 Void

Table 6.2.3.2.3-1: (Void)

- 6.2.3.2.4 Void
- 6.2.3.2.5 Void

6.2.3.3 A-MPR for NS_202

6.2.3.3.1 A-MPR for NS_202 for power class 1

For power class 1, A-MPR for NS_202 shall be 11.0 dB.

6.2.3.3.2 A-MPR for NS_202 for power class 2

For power class 2, A-MPR for NS_202 specified in clause 6.2.3.3.3 applies.

6.2.3.3.3 A-MPR for NS_202 for power class 3

For power class 3, A-MPR for NS_202 shall be 1.0 dB.

6.2.3.3.4 A-MPR for NS_202 for power class 4

For power class 4, A-MPR for NS_202 specified in clause 6.2.3.3.3 applies.

6.2.3.3.5 A-MPR for NS_202 for power class 5

For power class 5, A-MPR for NS_202 specified in clause 6.2.3.3.3 applies.

6.2.3.3.6 A-MPR for NS_202 for power class 6

For power class 6, A-MPR for NS_202 specified in clause 6.2.3.3.3 applies.

6.2.3.3.7 A-MPR for NS_202 for power class 7

For power class 7, A-MPR for NS_202 specified in clause 6.2.3.3.3 applies.

6.2.3.4 A-MPR for NS_203

6.2.3.4.1 A-MPR for NS_203 for power class 1

For power class 1, A-MPR for NS_203 shall be 3.0 dB if Offset frequency $< BW_{channel}$, 0.0 dB otherwise. The Offset frequency is defined as the frequency from 24.25 GHz to the lower edge of the channel bandwidth.

6.2.3.4.2 A-MPR for NS_203 for power class 2

For power class 2, A-MPR for NS_203 specified in subclause 6.2.3.4.3 applies.

6.2.3.4.3 A-MPR for NS_203 for power class 3

For power class 3, A-MPR for NS_203 shall be 0 dB.

6.2.3.4.4 A-MPR for NS_203 for power class 4

For power class 4, A-MPR for NS_203 specified in subclause 6.2.3.4.3 applies.

6.2.3.4.5 A-MPR for NS_203 for power class 5

For power class 5, A-MPR for NS_203 specified in subclause 6.2.3.4.3 applies.

6.2.3.4.6 A-MPR for NS_203 for power class 6

For power class 6, A-MPR for NS_203 specified in subclause 6.2.3.4.3 applies.

6.2.3.4.7 A-MPR for NS_203 for power class 7

For power class 7, AMPR for NS_203 specified in subclause 6.2.3.4.3 applies.

6.2.4 Configured transmitted power

The UE can configure its maximum output power. The configured UE maximum output power $P_{CMAX,f,c}$ for carrier f of a serving cell c is defined as that available to the reference point of a given transmitter branch that corresponds to the reference point of the higher-layer filtered RSRP measurement as specified in TS 38.215 [11].

The configured UE maximum output power $P_{CMAX,f,c}$ for carrier *f* of a serving cell *c* shall be set such that the corresponding measured peak EIRP $P_{UMAX,f,c}$ is within the following bounds

$$\begin{split} P_{Powerclass} + \Delta P_{IBE} - MAX(MAX(MPR_{f,c}, \text{A-} MPR_{f,c},) + \Delta MB_{P,n}, P-MPR_{f,c}) - MAX\{T(MAX(MPR_{f,c}, \text{A-} MPR_{f,c},)), T(P-MPR_{f,c})\} \leq P_{UMAX,f,c} \leq EIRP_{max} \end{split}$$

while the corresponding measured total radiated power $P_{\text{TMAX},f,c}$ is bounded by

$$P_{TMAX,f,c} \leq TRP_{max}$$

with $P_{Powerclass}$ the UE minimum peak EIRP as specified in sub-clause 6.2.1, EIRP_{max} the applicable maximum EIRP as specified in sub-clause 6.2.1, MPR_{f,c} as specified in sub-clause 6.2.2, A-MPR_{f,c} as specified in sub-clause 6.2.3, $\Delta MB_{P,n}$ the peak EIRP relaxation as specified in clause 6.2.1 and TRP_{max} the maximum TRP for the UE power class as specified in sub-clause 6.2.1. ΔP_{IBE} is 1.0 dB if UE declares support for *mpr-PowerBoost-FR2-r16*, UL transmission is QPSK, MPR_{f,c} = 0 and when NS_200 applies and the network configures the UE to operate with *mpr-PowerBoost-FR2-r16* of the requirement is verified in beam peak direction.

maxUplinkDutyCycle-FR2, as defined in TS 38.306 [14], is a UE capability to facilitate electromagnetic power density exposure requirements. This UE capability is applicable to all FR2 power classes.

If the field of UE capability *maxUplinkDutyCycle-FR2* is present and the percentage of uplink symbols transmitted within any 1 s evaluation period is larger than *maxUplinkDutyCycle-FR2*, the UE follows the uplink scheduling and can apply P-MPR_{f,c}.

If the field of UE capability *maxUplinkDutyCycle-FR2* is absent, the compliance to electromagnetic power density exposure requirements are ensured by means of scaling down the power density or by other means.

 $P-MPR_{f,c}$ is the power management maximum output power reduction. The UE shall apply $P-MPR_{f,c}$ for carrier f of serving cell c only for the cases described below. For UE conformance testing $P-MPR_{f,c}$ shall be 0 dB, except for the testing of UL gap for Tx power management, where $P-MPR_{f,c}$ may be non-zero dB.

- a) ensuring compliance with applicable electromagnetic power density exposure requirements and addressing unwanted emissions / self desense requirements in case of simultaneous transmissions on multiple RAT(s) for scenarios not in scope of 3GPP RAN specifications;
- b) ensuring compliance with applicable electromagnetic power density exposure requirements in case of proximity detection is used to address such requirements that require a lower maximum output power.
- NOTE 1: P-MPR_{f,c} was introduced in the P_{CMAX,f,c} equation such that the UE can report to the gNB the available maximum output transmit power. This information can be used by the gNB for scheduling decisions.
- NOTE 2: P-MPR_{f,c} and *maxUplinkDutyCycle-FR2* may impact the maximum uplink performance for the selected UL transmission path.

NOTE 3: MPE P-MPR Reporting capability *tdd-MPE-P-MPR-Reporting-r16*, as defined in TS 38.306 [14], is used to report P-MPR_{f,c} when the reporting conditions configured by gNB are met. This UE capability is applicable to all FR2 power classes.

The tolerance $T(\Delta P)$ for applicable values of ΔP (values in dB) is specified in Tables 6.2.4-1 and 6.2.4-2.

 $\Delta P (dB)$ Tolerance T(ΔP) **Operating Band** (dB) n257, n258, n259, $\Delta P = 0$ 0 n260, n261, n262 $0 < \Delta P \leq 2$ 1.5 2.0 $2 < \Delta P \leq 3$ $3 < \Delta P \leq 4$ 3.0 $4 < \Delta P \le 5$ 4.0 $5 < \Delta P \le 10$ 5.0 7.0 $10 < \Delta P \le 15$ 8.0 $15 < \Delta P \le X$ NOTE: X is the value such that Pumax, f,c lower bound, PPowerclass - $\Delta P - T(\Delta P)$ = minimum output power specified in clause 6.3.1

Table 6.2.4-1: PUMAX,f,c tolerance for FR2-1

Table 6.2.4-2: PUMAX, f, c tolerance for FR2-2

Operating Band	∆ P (dB)	Tolerance T(∆P) (dB)		
n263	$\Delta P = 0$	[0]		
	0 < ∆P ≤ 2	[1.5]		
	2 < ∆P ≤ 3	[2.0]		
	3 < ∆P ≤ 4	[3.0]		
	4 < ∆P ≤ 5	[4.0]		
	5 < ∆P ≤ 10	[5.0]		
	10 < ∆P ≤ 15	[7.0]		
	15 < ∆P ≤ X	[8.0]		
NOTE: X is the value	X is the value such that Pumax,f,c lower bound, PPowerclass -			
$\Delta P - T(\Delta P)$	$\Delta P - T(\Delta P)$ = minimum output power specified in clause			
6.3.1				

6.2.5 Requirements for UL gap (*ul-GapFR2-r17*) for TX power management

The difference of the measured peak EIRP P_{UMAX,f,c_GAP_ON} when UL gap for TX power management is configured and activated, and the measured peak EIRP P_{UMAX,f,c_GAP_OFF} when UL gap is not configured or de-activated, shall meet the following requirement:

 $P_{\text{UMAX,f,c}_\text{GAP}_\text{ON}} - P_{\text{UMAX,f,c}_\text{GAP}_\text{OFF}} \ge \max((\text{EIRP}_{\text{meas}_\text{peak}} - 23) + 10 * \log 10(\mathbb{Z}/20), 3) \text{dB}$

where EIRP_{meas_peak} is the measured UE peak EIRP with zero MPR/A-MPR/P-MPR as specified in clause 6.2.1 for the corresponding power class, and Z% is duty cycle of the reference measurement channel. P_{UMAX,f,c_GAP_ON} shall be measured outside of the UL gap symbol(s). The period of measurement shall be at least 4 seconds. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle) and in the test Z is set to 20 when maxUplinkDutyCycle-FR2 is less than 20 or not reported, and should be larger than maxUplinkDutyCycle-FR2 when maxUplinkDutyCycle-FR2 is equal to or greater than 20. The reference measurement channel is specified in Annex A.2.3.

When UL gap for Tx power management is configured and activated, the reported P-MPR_{f,c} shall be less than 3dB. When UL gap for Tx power management is not configured and activated at the duty cycle percentage value Z of the

reference measurement channel larger than *maxUplinkDutyCycle-FR2*, UE shall set the P bit in PHR to 1 in the test when PHR is configured. P-bit is defined in TS 38.321 clause 6.1.3.8 and 6.1.3.9.

6.2A Transmitter power for CA

6.2A.1 UE maximum output power for CA

For downlink intra-band contiguous and non-contiguous carrier aggregation with a single uplink component carrier configured in the NR band, the maximum output power is specified in clause 6.2.1.

For uplink intra-band contiguous and non-contiguous carrier aggregation for any CA bandwidth class, the maximum output power is specified in clause 6.2.1.

For inter-band uplink CA with two NR bands with each UL band configured with a single CC, the maximum power requirements are applicable per band, with both carriers active with non-zero power UL RB allocation. The maximum output power values for TRP and EIRP are applicable per carrier and are specified in tables 6.2.1.x-2. The minimum peak values for EIRP are defined in Tables 6.2.1.x-1 and further relaxed by $\Delta T_{IB,P,n}$ specified in Table 6.2A.1-x. The peak EIRP requirements are verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

The inter-band ULCA spherical coverage requirement for each power class is met if the intersection set of spherical coverage areas exceeds the common coverage requirement for that power class. For inter-band ULCA, the spherical coverage area for each band is the region of the sphere measured around the UE where the measured EIRP exceeds the EIRP level specified in Tables 6.2.1.x-3 and further reduced by the parameter $\Delta T_{IB,S,n}$ specified in Table 6.2A.1-x. The intersection set of spherical coverage areas is defined as a fraction of area of full sphere measured around the UE where both bands meet their individual EIRP spherical coverage requirements for inter-band CA operation. The common coverage requirement is determined as <100-percentile rank> %, where 'percentile rank' is the percentile value in the specification of spherical coverage for that power class from Tables 6.2.1.x-3. The spherical coverage EIRP requirements are verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

The ΔT_{IB} parameters are specified in tables 6.2A.1-x.

Table 6.2A.1-1: ΔT _{IB} EIRP relaxations for inter-band UL CA for power of

NR CA configuration	NR band	ΔT _{IB,P,n} (dB)	ΔT _{IB,S,n} (dB)
CA_n260A-n261A	n260	[1.5]	2.5
	n261	[1.5]	2.5

Table 6.2A.1-2: ΔT_{IB} EIRP relaxations for inter-band UL CA for power class 2

NR CA configuration	NR band	ΔT _{IB,P,n} (dB)	ΔT _{IB,S,n} (dB)
CA_n257A-n259A	n257	2.5	2.5
	n259	2.5	2.5

Table 6.2A.1-3: reserved for future use

Table 6.2A.1-4: reserved for future use

NR CA configuration	NR band	ΔT _{IB,P,n} (dB)	ΔT _{IB,S,n} (dB)	
CA_n257A-n259A	n257	[1.5]	2.5	
	n259	[1.5]	2.5	

Power class 3 is default power class.

NOTE: UL carrier aggregation within FR2 is defined only within FR2-1 in this release of the specification.

6.2A.2 UE maximum output power reduction for CA

6.2A.2.1 General

The UE is defined to be configured for CA operation when it has at least one of UL or DL configured for CA. In CA operation, the UE may reduce its maximum output power due to higher order modulations and transmit bandwidth configurations. This Maximum Power Reduction (MPR) is defined in clauses below. The allowed MPR for SRS, PUCCH formats 0, 1, 3 and 4, shall be as specified for QPSK modulated DFT-s-OFDM of equivalent RB allocation. The allowed MPR for PUCCH format 2, shall be as specified for QPSK modulated CP-OFDM of equivalent RB allocation.

When the maximum output power of a UE is modified by MPR, the power limits specified in clause 6.2A.4 applyThe requirements in the following clauses are applicable to the following CA configurations:

- intra-band contiguous uplink CA, with the aggregated channel bandwidth no greater than 800 MHz.
- intra-band non-contiguous uplink CA with UL frequency separation no greater than 1400 MHz, and no more than 3 sub-blocks. A sub-block may consist of single CC or multiple contiguous CCs.
- inter-band uplink CA with two NR bands, and each UL band is configured with a single CC.
- In case the CA configuration consists of a single UL CC, MPR for contiguous UL CA applies and where necessary, BW_{channel} shall be used as BW_{channel_CA}.

6.2A.2.2 Maximum output power reduction for power class 1

6.2A.2.2.1 Maximum output power reduction for power class 1 intra-band contiguous UL CA

For power class 1, MPR for intra-band contiguous UL CA with contiguous allocations within the cumulative aggregated bandwidth is defined as:

$$MPR_{C_CA} = max(MPR_{WT_C_CA}, MPR_{narrow})$$

Where,

 $MPR_{narrow} = 14.4 \text{ dB}$, when $BW_{alloc,RB}$ is less than or equal to 1.44 MHz, $MPR_{narrow} = 10 \text{ dB}$, when 1.44 MHz < $BW_{alloc,RB} \le 10.8 \text{ MHz}$, where $BW_{alloc,RB}$ is the bandwidth of the RB allocation size.

 $MPR_{WT_C_CA}$ is the maximum power reduction due to modulation orders, transmit bandwidth configurations, and waveform types. $MPR_{WT_C_CA}$ is defined in Tables 6.2A.2.2-1 and 6.2A.2.2-2.

Waveform Type		Cumulative aggregated channel bandwidth			
		< 400 MHz	≥ 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5 ¹	7.7 ¹	8.2	≤ 8.7
	QPSK	≤ 6.5 ¹	8.7 ¹	9.7	≤ 9.7
	16 QAM	≤ 6.5	8.7	9.2	≤ 9.7
	64 QAM	≤ 9.0	10.7	11.2	≤ 11.7
CP-OFDM	QPSK	≤ 6.5	8.7	8.7	≤ 9.7
	16 QAM	≤ 6.5	8.7	8.7	≤ 9.7
	64 QAM	≤ 9.0	10.7	11.2	≤ 11.7
NOTE 1: (Void)	•				

Waveform	Cumulative aggregated channel bandwidth			
Туре	< 400 MHz	≥ 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2000 MHz
Pi/2 BPSK	≤ [7.0]	≤ [5.0]	≤ [2.0]	≤ [2.0]
QPSK	≤ [8.0]	≤ [6.0]	≤ [3.0]	≤ [3.0]
16 QAM	≤ [8.0]	≤ [6.0]	≤ [4.0]	≤ [4.0]
64 QAM	≤ [10.0]	≤ [10.0]	≤ [10.0]	≤ [10.0]

Table 6.2A.2.2-2: Maximum power reduction (MPR_{WT_C_CA}) for UE power class 1 in FR2-2

In case of a contiguous RB, DFT-s-BPSK or DFT-s-QPSK UL allocation in a single CC of a CA configuration with contiguous CCs, and whose cumulative aggregated BW \leq 400 MHz, MPR_{WT_C_CA} shall be derived instead as MAX(MPR₁, MPR₂), where:

MPR₁ shall be determined from Table 6.2.2.1-1 if CABW \leq 200 MHz, from Table 6.2.2.1-2 if CABW > 200 MHz.

MPR₂ shall be determined from Table 6.2.2.1-1 if UL BW_{channel_CA} \leq 200 MHz, from Table 6.2.2.1-2 if UL BW_{channel_CA} > 200 MHz.

and assume all UL CCs use the same SCS for the purpose of determination of inner and outer RB allocations in Table 6.2.2.1-1 and Table 6.2.2.1-2:

 N_{RB} shall be chosen as the sum of N_{RB} of all constituent UL CCs in the CA configuration.

L_{CRB} shall be chosen as BW_{alloc,RB}

 $RB_{start}\ shall \ be \ derived \ as: \ RB_{start_allocatedCC} + N_{RB_unallocatedCC_low}$

RB_{start_allocatedCC} is the index of the first allocated RB in the CC with allocation

N_{RB_unallocatedCC_low} is the sum of N_{RB} in all UL CCs lower in frequency compared to the CC with allocation

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the largest $MPR_{C_{CA}}$.

For intra-band contiguous UL CA with non-contiguous RB allocations, the following rule for MPR applies:

 $MPR = max(MPR_{C_{CA}}, -10*A + 14.4)$

Where:

 $A = N_{RB_alloc} \ / \ N_{RB_agg_C.}$

 N_{RB_alloc} is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs

6.2A.2.2.2 Maximum output power reduction for power class 1 intra-band non-contiguous UL CA

For intra-band non-contiguous UL CA, the following rule for MPR applies:

 $MPR = max(MPRNC_CA, -10*A + 14.4)$

Where:

MPR_{NC_CA} is derived from table 6.2A.2.2-1

Waveform Type		Cumulative aggregated channel bandwidth (CABW)			
		< 400 MHz	≥ 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz
DFT-s-OFDM	Pi/2 BPSK	≤ 6	≤ 7.7	≤ 8.2	≤ 8.7
	QPSK	≤ 7	≤ 8.7	≤ 9.2	≤ 9.7
	16 QAM	≤ 7	≤ 8.7	≤ 9.2	≤ 9.7
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7
CP-OFDM	QPSK	≤ 7	≤ 8.7	≤ 9.2	≤ 9.7
	16 QAM	≤ 7	≤ 8.7	≤ 9.2	≤ 9.7
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7

Table 6.2A.2.2.2-1: MPR_{NC_CA} for UE power class 1

6.2A.2.2.3 Maximum output power reduction for power class 1 inter-band CA

For inter-band carrier aggregation with uplink assigned to two NR bands, the MPR for each configured UL band in the UL CA band combination is:

 $MPR_{inter-band_CA} = max(MPR_{SingleBand}, MPR_{PA-PA})$

Where:

MPR_{SingleBand} is the MPR specified in clause 6.2.2.1 for the allocation and modulation type in that band

 MPR_{PA-PA} is MAX(MPR1, MPR2), where MPR1 and MPR2 are specified per band combination in Table 6.2A.2.2.3-1 and applies only when both bands have non-zero power UL RB allocations, 0 dB otherwise.

Table 6.2A.2.2.3-1: MPR_{PA-PA} for Inter-band ULCA in FR2 for PC1

NR CA Band	MPR	Value (dB)	Condition
CA_n260A-n261A	MPR1	Max(0, 10 - 10*log ₁₀ (Max(1.0,	$L_{RB,min} = Min (L_{RB,n260}, L_{RB,n261})$, where $L_{RB,n}$ is the
		L _{RB,min} *12*SCS/1e6)))	number of non-zero power UL RBs in band 'n'
	MPR2	6.0 if condition satisfied, 0.0	47.2 GHz <= 2*f _{n260} - f _{n261} <= 48.2 GHz
		otherwise	Where fn is any frequency inside the UL allocation
			in band 'n'

6.2A.2.3 Maximum output power reduction for power class 2

For power class 2, MPR specified in sub-clause 6.2A.2.4.1 applies for intra-band contiguous UL CA and sub-clause 6.2A.2.4.2 applies for intra-band non-contiguous UL CA.

Table 6.2A.2.3-1: (Void)

For inter-band carrier aggregation with uplink assigned to two NR bands, the MPR for each configured UL band in the UL CA band combination is:

 $MPR_{inter-band}CA = max(MPR_{SingleBand}, MPR_{PA-PA})$

Where:

MPR_{SingleBand} is the MPR specified in clause 6.2.2.2 for the allocation and modulation type in that band

 MPR_{PA-PA} is specified in Table 6.2A.2.3-2 and applies only when both bands have non-zero UL RB allocations, 0 dB otherwise.

NR CA Band	Value (dB)	Condition
CA_n257A-n259A	Max(0, 6 - 10*log ₁₀ (Max(1.0,	$L_{RB,min} = Min (L_{RB,n257}, L_{RB,n259})$, where $L_{RB,n}$ is the
	L _{RB,min} *12*SCS/1e6)))	number of non-zero power UL RBs in band 'n'

6.2A.2.4 Maximum output power reduction for power class 3

6.2A.2.4.1 Maximum output power reduction for power class 3 intra-band contiguous CA

For power class 3, MPR for intra-band contiguous UL CA with contiguous allocations within the cumulative aggregated bandwidth is denoted as $MPR_{C_{CA}}$ and is defined in Tables 6.2A.2.4-1 and 6.2A.2.4-2.

Table 6.2A.2.4-1: Maximum power reduction (MPR_{C_CA}) for UE power class 3 in FR2-1

		Cumulative aggregated channel bandwidth (CABW)				
		≤ 400 MHz	> 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz	
DFT-s-OFDM	Pi/2 BPSK	≤ 5.0 ¹	≤ 7.7 ¹	≤ 8.2	≤ 8.7	
	QPSK	≤ 5.0 ¹	≤ 7.7 ¹	≤ 8.2	≤ 9.7	
	16 QAM	≤ 6.5	≤ 8.7	≤ 9.3	≤ 9.7	
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7	
CP-OFDM	QPSK	≤ 5.0	≤ 7.5	≤ 8.0	≤ 9.7	
-	16 QAM	≤ 6.5	≤ 8.7	≤ 9.2	≤ 9.7	
-	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7	
NOTE 1: (Void).						

Table 6.2A.2.4-2: Maximum power reduction (MPR_{WT_C_CA}) for UE power class 3 in FR2-2

Waveform		Cumulative aggregated channel bandwidth					
Туре	< 400 MHz	≥ 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2000 MHz			
Pi/2 BPSK	≤ [1.0]	≤ [1.0]	≤ [1.0]	≤ [1.0]			
QPSK	≤ [2.0]	≤ [2.0]	≤ [2.0]	≤ [2.0]			
16 QAM	≤ [4.0]	≤ [4.0]	≤ [4.0]	≤ [4.0]			
64 QAM	≤ [10.0]	≤ [10.0]	≤ [10.0]	≤ [10.0]			

In case of a contiguous RB, DFT-s-BPSK or DFT-s-QPSK UL allocation in a single CC of a CA configuration with contiguous CCs, and whose cumulative aggregated $BW \le 400$ MHz, MPR_{C_CA} shall be derived instead as MAX(MPR₁, MPR₂), where:

MPR₁ shall be determined from Table 6.2.2.3-1 if CABW \leq 200 MHz, from Table 6.2.2.3-2 if CABW > 200 MHz.

MPR₂ shall be determined from Table 6.2.2.3-1 if UL BW_{channel_CA} \leq 200 MHz, from Table 6.2.2.3-2 if UL BW_{channel_CA} > 200 MHz.

and assume all UL CCs use the same SCS for the purpose of determination of inner and outer RB allocations in Table 6.2.2.3-1 and Table 6.2.2.3-2:

N_{RB} shall be chosen as the sum of N_{RB} of all constituent UL CCs in the CA configuration.

L_{CRB} shall be chosen as BW_{alloc,RB}

 $RB_{start} \ shall \ be \ derived \ as: \ RB_{start_allocatedCC} + N_{RB_unallocatedCC_low}$

 $RB_{start_allocatedCC}$ is the index of the first allocated RB in the CC with allocation

N_{RB_unallocatedCC_low} is the sum of N_{RB} in all UL CCs lower in frequency compared to the CC with allocation

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the highest contiguous MPR.

For intra-band contiguous UL CA with non-contiguous RB allocations, the following rule for MPR applies:

 $MPR = max(MPR_{C_{CA}}, -10*A + 7.0)$

Where:

 $A = N_{RB_alloc} / N_{RB_agg_C.}$

 N_{RB_alloc} is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs

6.2A.2.4.2 Maximum output power reduction for power class 3 intra-band non-contiguous CA

For intra-band non-contiguous UL CA, the following rule for MPR applies:

 $MPR = max(MPRNC_CA, -8*A + 10.0)$

Where:

MPR_{NC_CA} is derived from table 6.2A.2.4.2-1

		Cumulative aggregated channel bandwidth (CABW)				
		≤ 400 MHz	> 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz	
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5	≤ 7.7	≤ 8.2	≤ 8.7	
	QPSK	≤ 6	≤ 7.7	≤ 8.2	≤ 8.7	
	16 QAM	≤7	≤ 8.7	≤ 9.3	≤ 9.8	
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7	
CP-OFDM	QPSK	≤ 6	≤ 7.5	≤ 8.0	≤ 8.5	
	16 QAM	≤7	≤ 8.7	≤ 9.2	≤ 9.7	
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7	

Table 6.2A.2.4.2-1: MPR_{NC_CA} for UE power class 3

6.2A.2.5 Maximum output power reduction for power class 4

For power class 4, MPR specified in sub-clause 6.2A.2.4.1 applies for intra-band contiguous UL CA and sub-clause 6.2A.2.4.2 applies for intra-band non-contiguous UL CA.

6.2A.2.6 Maximum output power reduction for power class 5

For power class 5, MPR specified in sub-clause 6.2A.2.4.1 applies for intra-band contiguous UL CA and sub-clause 6.2A.2.4.2 applies for intra-band non-contiguous UL CA.

For inter-band carrier aggregation with uplink assigned to two NR bands, MPR for each configured UL band in the UL CA band combination is:

$$MPR_{inter-band}_{CA} = max(MPR_{SingleBand}, MPR_{PA-PA})$$

Where:

MPR_{SingleBand} is the MPR specified in clause 6.2.2.5 for the allocation and modulation type in that band

 MPR_{PA-PA} is the maximum of the MPR values specified per band combination in Table 6.2A.2.5-1 and applies only when both bands have non-zero UL RB allocations, 0 dB otherwise.

NR CA Band	Value (dB)	Condition
CA_n257A-n259A	Max(0, 6 - 10*log ₁₀ (Max(1.0,	$L_{RB,min} = Min (L_{RB,n257}, L_{RB,n259})$, where $L_{RB,n}$ is the
	L _{RB,min} *12*SCS/1e6)))	number of non-zero power UL RBs in band 'n'

Table 6.2A.2.5-1: MPR_{PA-PA} for Inter-band CA in FR2 for PC5

6.2A.3 UE maximum output power with additional requirements for CA

6.2A.3.1 General

Additional emission requirements can be signalled by the network with network signalling value indicated by the field *additionalSpectrumEmission*. To meet these additional requirements, additional maximum power reduction (A-MPR) is allowed for the maximum output power as specified in clause 6.2A.1. Unless stated otherwise, an A-MPR of 0 dB shall be used. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in clause 6.2A.2.

For intra-band contiguous aggregation with the UE configured for transmissions on two serving cells, the maximum output power reduction specified in Table 6.2A.3.1-1 is allowed for all serving cells of the applicable uplink contiguous CA configurations according to the CA network signalling value indicated by the field *additionalSpectrumEmissionSCell*.

Table 6.2A.3.1-1 specifies the additional requirements and allowed A-MPR with corresponding network signalling label and operating band. The mapping between network signalling labels and the *additionalSpectrumEmission* IE defined in TS 38.331 [13] is specified in Table 6.2A.3.1-2. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in clause 6.2A.2.

Network Signalling value	Requirements (clause)	NR Band	Channel bandwidth (MHz)	Resources Blocks (<i>N</i> _{RB})	A-MPR (dB)
CA_NS_200					N/A
CA_NS_201	6.5.3.2.2	n258			6.2A.3.2
CA_NS_202	6.5.3.2.3	n257, n258			6.2A.3.3
CA_NS_203	6.5.3.2.4	n258			6.2A.3.4
NOTE: CA_NS_201 is obsolete, the associated additional spurious emission requirements					
are not applicable.					

Table 6.2A.3.1-1: Additional maximum power reduction (A-MPR)

NR Band		Value of additionalSpectrumEmission / NS number						
	0	1	2	3	4	5	6	7
n257	CA_NS_200	CA_NS_202						
n258	CA_NS_200	CA_NS_201	CA_NS_202	CA_NS_203				
n259	CA_NS_200							
n260	CA_NS_200							
n261	CA_NS_200							
NOTE 1: addition	nalSpectrumEmission	corresponds to an ir	nformation element of	of the same name	defin	ed in	clause	6.3.2 of
TS 38.331 [13].								
NOTE 2: CA NS 201 is obsolete, the associated additional spurious emission requirements are not applicable.								

- 6.2A.3.2 Void
- 6.2A.3.2.1 Void

Table 6.2A.3.2.1-1: (Void)

6.2A.3.2.2 Void

Table 6.2A.3.2.2-1: (Void)

6.2A.3.2.3 Void

Table 6.2A.3.2.3-1: Void

6.2A.3.2.4 Void

6.2A.3.2.5 Void

6.2A.3.3 A-MPR for CA_NS_202

6.2A.3.3.1 A-MPR for CA_NS_202 for power class 1

For intra-band contiguous CA, A-MPR for CA_NS_202 shall be 11.0 dB.

6.2A.3.3.2 A-MPR for CA_NS_202 for power class 2

For intra-band contiguous CA, A-MPR for CA_NS_202 specified in sub-clause 6.2A.3.3.3 applies.

6.2A.3.3.3 A-MPR for CA_NS_202 for power class 3

For intra-band contiguous CA, A-MPR for CA_NS_202 shall be 2.0 dB.

6.2A.3.3.4 A-MPR for CA_NS_202 for power class 4

For intra-band contiguous CA, A-MPR for CA_NS_202 specified in sub-clause 6.2A.3.3.3 applies.

6.2A.3.3.5 A-MPR for CA_NS_202 for power class 5

For intra-band contiguous CA, A-MPR for CA_NS_202 specified in sub-clause 6.2A.3.3.3 applies.

6.2A.3.4 A-MPR for CA_NS_203

6.2A.3.4.1 A-MPR for CA_NS_203 for power class 1

For intra-band contiguous CA, A-MPR for CA_NS_203 shall be 6.5 dB, if Offset frequency $< BW_{Channel_CA}$ of the UL CA configuration, 0.0 dB, otherwise The Offset frequency is defined as the frequency from 24.25 GHz to the lower edge of the lowest CC among the

The Offset frequency is defined as the frequency from 24.25 GHz to the lower edge of the lowest CC among the configured UL CA.

6.2A.3.4.2 A-MPR for CA_NS_203 for power class 2

For intra-band contiguous CA, AMPR specified in sub-clause 6.2A.3.4.3 applies.

6.2A.3.4.3 A-MPR for CA_NS_203 for power class 3

For intra-band contiguous CA, A-MPR for CA_NS_203 shall be 2.5 dB, if Offset frequency < BW_{Channel_CA} of the UL CA configuration, 0.0 dB otherwise.

The Offset frequency is defined as the frequency from 24.25 GHz to to the lower edge of the lowest CC among the configured UL CA.

6.2A.3.4.4 A-MPR for CA_NS_203 for power class 4

For intra-band contiguous CA, AMPR specified in sub-clause 6.2A.3.4.3 applies.

6.2A.3.4.5 A-MPR for CA_NS_203 for power class 5

For intra-band contiguous CA, AMPR specified in sub-clause 6.2A.3.4.3 applies.

6.2A.4 Configured transmitted power for CA

6.2A.4.1 Configured transmitted power for intra-band UL CA

A UE configured with carrier aggregation can configure its maximum output power for each uplink activated serving cell c and its total configured maximum output power $P_{CMAX,f,c}$ for each carrier f of a serving cell c is used for power headroom reporting for carrier f of serving cell c only and is in accordance with that specified in clause 6.2.4 with parameters MPR, A-MPR and P-MPR replaced with those specified in subclause 6.2A.2, 6.2A.3 and 6.2.4, respectively. The UE maximum configured power P_{CMAX} in a transmission occasion is determined by the UL grants for carriers f of all serving cells c with non-zero granted power in the respective reference point.

For uplink intra-band contiguous carrier aggregation, MPR is specified in clause 6.2A.2. P_{CMAX} is calculated under the assumption that power spectral density for each RB in each component carrier is same.

The configured UE maximum output power P_{CMAX} shall be set such that the corresponding measured total peak EIRP P_{UMAX} is within the following bounds

$$\begin{array}{l} P_{Powerclass} - MAX(MAX(MPR, A-MPR) + \Delta MB_{P,n}, P-MPR) - MAX\{T(MAX(MPR, A-MPR)), T(P-MPR)\} \leq P_{UMAX} \leq EIRP_{max} \end{array}$$

with $P_{Powerclass}$ the UE minimum peak EIRP as specified in sub-clause 6.2A.1, EIRP_{max} the applicable maximum EIRP as specified in sub-clause 6.2A.1, MPR as specified in sub-clause 6.2A.2, A-MPR as specified in sub-clause 6.2A.3, $\Delta MB_{P,n}$ the peak EIRP relaxation as specified in clause 6.2.1, P-MPR the power management term for the UE as described in 6.2.4.

The measured configured power PUMAX for carrier aggregation is defined as

$$P_{UMAX} = 10 \log_{10} \sum_{c,f(c)} p_{UMAX,f,c}$$

where $p_{UMAX,f,c}$ is the linear value of the measured power $P_{UMAX,f,c}$ for carrier f=f(c) of serving cell c. The measured total radiated power P_{TMAX} for carrier aggregation is defined as

$$P_{TMAX} = 10 \log_{10} \sum_{c,f(c)} p_{TMAX,f,c}$$

where $p_{TMAX,f,c}$ is the linear value of the measured total radiated power $P_{TMAX,f,c}$ for carrier f = f(c) of serving cell c. The total radiated power P_{TMAX} is bounded by

$$P_{TMAX} \leq TRP_{max}$$

where TRP_{max} the maximum TRP for the UE power class as specified in sub-clause 6.2A.1.

The tolerance $T(\Delta P)$ for applicable values of ΔP (values in dB) is specified in Table 6.2A.4.1-1 and Table 6.2A.4.1-2.

Table 6.2A.4.1-1: PUMAX tolerance for FR2-1

Operating Band	∆ P (dB)	Tolerance T(∆P) (dB)			
n257, n258, n259, n260, n261, n262	$\Delta P = 0$	0			
	0 < ∆P ≤ 2	1.5			
	2 < ∆P ≤ 3	2.0			
	3 < ∆P ≤ 4	3.0			
	4 < ∆P ≤ 5	4.0			
	5 < ∆P ≤ 10	5.0			
	10 < ∆P ≤ 15	7.0			
	15 < ∆P ≤ X	8.0			
NOTE: X is the value	OTE: X is the value such that P_{umax} lower bound, $P_{Powerclass}$ - ΔP				
$-T(\Delta P) = m$	$- T(\Delta P) = minimum output power specified in clause$				
6.3A.1					

Operating Band	∆ P (dB)	Tolerance T(∆P) (dB)			
n263	$\Delta P = 0$	[0]			
	0 < ∆P ≤ 2	[1.5]			
	2 < ∆P ≤ 3	[2.0]			
	3 < ∆P ≤ 4	[3.0]			
	4 < ∆P ≤ 5	[4.0]			
	5 < ∆P ≤ 10	[5.0]			
	10 < ∆P ≤ 15	[7.0]			
	15 < ∆P ≤ X	[8.0]			
NOTE: X is the value such that P_{umax} lower bound, $P_{Powerclass}$ - ΔP					
$- T(\Delta P) = minimum output power specified in clause$					
6.3A.1					

Table 6.2A.4.1-2: PUMAX tolerance for FR2-2

6.2A.4.2 Configured transmitted power for inter-band UL CA

A UE can configure its maximum output power for each uplink band when it is configured for inter-band UL carrier aggregation with two NR bands each with a single UL CC. For each uplink band *n*, the configured UE maximum output power $P_{CMAX,f,c,n}$ for carrier *f* of a serving cell *c* is defined as that available to the reference point of a given transmitter branch that corresponds to the reference point of the higher-layer filtered RSRP measurement as specified in TS 38.215 [11].

The configured UE maximum output power $P_{CMAX,f,c,n}$ for carrier *f* of a serving cell *c* in band *n* shall be set such that the corresponding measured peak EIRP $P_{UMAX,f,c,n}$ is within the following bounds

$$\begin{split} P_{Powerclass} + \Delta P_{IBE} - MAX(MAX(MPR_{f,c,n}, A-MPR_{f,c,n}) + \Delta T_{IB,P,n}, P-MPR_{f,c,n}) - MAX\{T(MAX(MPR_{f,c,n}, A-MPR_{f,c,n})), \\ T(P-MPR_{f,c,n})\} \leq P_{UMAX,f,c,n} \leq EIRP_{max,n} \end{split}$$

while the corresponding measured total radiated power in uplink band n, P_{TMAX,f,c,n}, is bounded by

 $P_{TMAX,f,c,n} \leq TRP_{max,n}$

with $P_{Powerclass}$ the UE minimum peak EIRP as specified in sub-clause 6.2A.1, EIRP_{max,n} the applicable maximum EIRP as specified in sub-clause 6.2A.1 for uplink band *n* and TRP_{max,n} the applicable maximum TRP as specified in sub-clause 6.2A.1 for uplink band *n*. MPR_{f,c,n} as specified in sub-clause 6.2A.2 for uplink band *n*, A-MPR_{f,c,n} as specified in sub-clause 6.2A.3 for uplink band *n*, $\Delta T_{IB,P,n}$ the peak EIRP relaxation as specified in clause 6.2A.1. The requirement is verified in beam peak direction.

 $\Delta P_{IBE, mpr-PowerBoost-FR2-r16}$ and maxUplinkDutyCycle-FR2 are described in clause 6.2.4.

P-MPR_{f,c,n} is the power management maximum output power reduction P-MPR_{f,c} in band *n*. P-MPR_{f,c} is defined in clause 6.2.4.

The tolerance $T(\Delta P)$ for applicable values of ΔP (values in dB) in each band is specified in Table 6.2.4-1.

6.2A.5 Requirements for UL gap (*ul-GapFR2-r17*) for TX power management in CA

The difference of the measured peak EIRP $P_{UMAX_GAP_ON}$ for CA when UL gap for TX power management is configured and activated, and the measured peak EIRP $P_{UMAX_GAP_OFF}$ when UL gap is not configured or de-activated, shall meet the following requirement:

 $P_{\text{UMAX}_\text{GAP}_\text{ON}} - P_{\text{UMAX}_\text{GAP}_\text{OFF}} \ge \max((\text{EIRP}_{\text{meas}_\text{peak}} - 23) + 10 * \log 10(\mathbb{Z}/20), 3) \text{dB}$

where EIRP_{meas_peak} is the measured UE peak EIRP with zero MPR/A-MPR/P-MPR in clause 6.2A.1 for the corresponding power class, and Z% is duty cycle of the reference measurement channel. P_{UMAX,f,c_GAP_ON} shall be measured outside of the UL gap symbol(s). The period of measurement shall be at least 4 seconds. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle) and in the test Z is set to 20

when *maxUplinkDutyCycle-FR2* is less than 20 or not reported, and should be larger than *maxUplinkDutyCycle-FR2* when *maxUplinkDutyCycle-FR2* is equal to or greater than 20, assuming all CCs share the same TX beam peak direction. The reference measurement channel is specified in Annex A.2.3.

When UL gap for Tx power management is configured and activated, the reported P-MPR_{f,c} shall be less than 3dB. When UL gap for Tx power management is not configured and activated, UE shall set the P bit in PHR to 1 in the test when PHR is configured. P-bit is defined in TS 38.321 clause 6.1.3.8 and 6.1.3.9.

6.2D Transmitter power for UL MIMO

6.2D.1 UE maximum output power for UL MIMO

6.2D.1.0 General

The requirements in the following clauses define the maximum output power radiated by the UE with *nrofSRS-Ports* set to 2, for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. MPR shall be applied as specified in clause 6.2D.2

For the maximum output power requirement for 2-layer UL MIMO operation, a UE shall be configured for 2-layer UL MIMO transmission as specified in Table 6.2D.1.0-1.

Table 6.2D.1.0-1: UL MIMO configuration

Transmission scheme	DCI format	Number of layers	TPMI index
Codebook based uplink	DCI format 0_1	2	0

The maximum output power requirement for single layer transmission shall apply to a UE that supports ULFPTx feature and is configured for single layer transmission in its declared full power mode [10, TS 38.213] as specified in Table 6.2D.1.0-2.

Table 6.2D.1.0-2: PUSCH Configuration for uplin	nk full power transmission (ULFPTx)
---	-------------------------------------

ULFPTx Mode	Transmission scheme	DCI format	Modulation	Number of layers	TPMI index
Mode-1	Codebook based uplink	DCI format 0_1	DFT-s-OFDM, CP-OFDM ¹	1	2
Mode-2	Codebook based uplink	DCI format 0_1	DFT-s-OFDM, CP-OFDM	1	0 or 1 ²
Mode-full	Codebook based uplink	DCI format 0_1	DFT-s-OFDM, CP-OFDM	1	0,1
power					
NOTE 1: For PUSCH configured with ULFPTxModes set to Mode-1, all requirements for 1-layer CP-OFDM based					
modulation in subsection 6.2D are assumed to be met if the requirement for 2-layer UL MIMO has been validated.					
NOTE 2:	TPMI index selected shall be based upon the full power TPMI reported by the UE [10, TS 38.213].				

NOTE: UL MIMO for FR2 is defined only for FR2-1 in this release of the specification.

6.2D.1.1 UE maximum output power for UL MIMO for power class 1

The following requirements define the maximum output power radiated by the PC1 UE. Requirements apply to UEs when configured for 2-layer transmission as well as when configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.1-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle). Power class 1 UE is used for fixed wireless access (FWA).

Operating band	Min peak EIRP (dBm)	
n257	40.0	
n258	40.0	
n260	38.0	
n261	40.0	
n262	34.2	
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance		

Table 6.2D.1.1-1: UE minimum peak EIRP for UL MIMO for power class 1

Table 6.2D.1.1-2: (void)

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.1-3 below for UE with UL MIMO. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	35	55
n258	35	55
n260	35	55
n261	35	55
n262	35	55

The minimum EIRP at the 85th percentile of the distribution of radiated power measured over the full sphere around the UE with UL MIMO is defined as the spherical coverage requirement and is found in Table 6.2D.1.1-4 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Operating band	Min EIRP at 85 %-tile CDF (dBm)	
n257	32.0	
n258	32.0	
n260	30.0	
n261	32.0	
n262	26.0	
NOTE 1: Minimum E	EIRP at 85 %-tile CDF is defined as	
the lower limit without tolerance		

6.2D.1.2 UE maximum output power for UL MIMO for power class 2

The following requirements define the maximum output power radiated by the PC2 UE. Requirements apply to UEs when configured for 2-layer transmission as well as when configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.2-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band		Min peak EIRP (dBm)	
n2	57	29	
n2	58	29	
n2	61	29	
n2	62	22.9	
NOTE 1:	Minimum peak EIRP is defined as the		
lower limit without tolerance. NOTE 2: Min Peak EIRP refers to the total EIRP for the UL beams peaks.			

 Table 6.2D.1.2-1: UE minimum peak EIRP for UL MIMO for power class 2

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.2-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.2-2: UE maximum output power limits for UL MIMO for power class 2

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43
n262	23	43

Table 6.2D.1.2-3: (void)

The minimum EIRP at the 60th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.2-4 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Operating band	Min EIRP at 60 %-tile CDF (dBm)	
n257	18.0	
n258	18.0	
n261	18.0	
n262	11.0	
NOTE 1: Minimum EIRP at 60 %-tile CDF is defined as the lower limit without tolerance		

6.2D.1.3 UE maximum output power for UL MIMO for power class 3

The following requirements define the maximum output power radiated by the PC3 UE.. Requirements apply to UEs when configured for 2-layer transmission as well as when configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.3-1 below. The period of measurement shall be at least one sub frame (1 ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)		
n257	22.4		
n258	22.4		
n259	18.7		
n260	20.6		
n261	22.4		
n262	16.0		
NOTE 1: Minimum peak Elf tolerance.	Minimum peak EIRP is defined as the lower limit without tolerance.		
NOTE 2: Min Peak EIRP re peaks.	E 2: Min Peak EIRP refers to the total EIRP for the UL beams peaks.		

Table 6.2D.1.3-1: UE minimum peak EIRP for UL MIMO for power class 3

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.3-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n259	23	43
n260	23	43
n261	23	43
n262	23	43

Table 6.2D.1.3-2: UE maximum output power limits for UL MIMO for power class 3

Table 6.2D.1.3-3: (void)

The minimum EIRP at the 50th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.3-4 below. The requirement is verified with the test metric of EIRP (Link=spherical coverage grid, Meas=Link angle).

Operating band	Min EIRP at 50 %-tile CDF (dBm)	
n257	11.5	
n258	11.5	
n259	5.8	
n260	8	
n261	11.5	
NOTE 1: Minimum EIRP at 50 %-tile without tolerance	CDF is defined as the lower limit	
NOTE 2: The requirements in this table are only applicable for UE which supports single band in FR2		

6.2D.1.4 UE maximum output power for UL MIMO for power class 4

The following requirements define the maximum output power radiated by the PC4 UE. Requirements apply to UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.4-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)
n257	34
n258	34
n260	31
n261	34
n262	28.3
NOTE 1: Minimum peak Elf tolerance.	RP is defined as the lower limit without
NOTE 2: Min Peak EIRP re peaks.	fers to the total EIRP for the UL beams

 Table 6.2D.1.4-1: UE minimum peak EIRP for UL MIMO for power class 4

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.4-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.4-2: UE maximum out	nut	nower li	imite f	or III	MIMO for	nower	class 4
	pul	hower u	111111111111111111111111111111111111111			power	LIA33 4

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43
n262	23	43

Table 6.2D.1.4-3: (void)

The minimum EIRP at the 20th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.4-4 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Operating band	Min EIRP at 20 %-tile CDF (dBm)
n257	25
n258	25
n260	19
n261	25
n262	16.2
NOTE 1: Minimum	EIRP at 20 %-tile CDF is defined as

Table 6.2D.1.4-4: UE spherical coverage for UL MIMO for power class 4

the lower limit without tolerance

6.2D.1.5 UE maximum output power for UL MIMO for power class 5

The following requirements define the maximum output power radiated by the PC4 UE. Requirements apply to UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.5-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle). Power class 5 UE is used for fixed wireless access (FWA).

Operating band	Min peak EIRP (dBm)
n257	30
n258	30.4
n259	27.7
NOTE 1: Minimum peak EIRP is	s defined as the lower limit without tolerance

Table 6.2D.1.5-1: UE minimum peak EIRP for UL MIMO for power class 5

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.5-3 below for UE with UL MIMO. The maximum allowed EIRP is derived from regulatory requirements. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.5-2: UE maximum output power limits for UL MIMO for power class 5

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n259	23	43

The minimum EIRP at the 85th percentile of the distribution of radiated power measured over the full sphere around the UE with UL MIMO is defined as the spherical coverage requirement and is found in Table 6.2D.1.5-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2D.1.5-3: UE spherical coverage for UL MIMO for power class 5

Operating band	Min EIRP at 85 %-tile CDF (dBm)
n257	22
n258	22.4
n259	19.7
NOTE 1: Minimum EIRP at 85 %-tile CDF is defined as	
the lower limit without tolerance	

6.2D.1.6 UE maximum output power for UL MIMO for power class 6

The following requirements define the maximum output power radiated by the PC6 UE. Requirements apply to UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.6-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)
n257	30
n258	30.4
n261	30
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance	

Table 6.2D.1.6-1: UE minimum peak EIRP for UL MIMO for power class 6

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.5-2 below for UE with UL MIMO. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43

Table 6.2D.1.6-2: UE maximum output power limits for UL MIMO for power class 6

The minimum EIRP measured over the spherical coverage evaluation areas is defined as the spherical coverage requirement and is found in Table 6.2D.1.6-3 below. UE spherical coverage evaluation areas are found in Table 6.2.1.6-3a in clause 6.2.1.6, by consisting of Area-1 and Area-2, in the reference coordinate system in Annex J.1. The requirement is verified with the test metric of EIRP (Link= Spherical coverage grid, Meas=Link angle).

Table 6.2D.1.6-3: UE spherical coverage for UL MIMO for power class 6

Operating band Min EIRP over UE spherical coverage evaluation areas (dBm)		Min EIRP over UE spherical coverage evaluation areas (dBm)
n2	57	20
n258		20.4
n2	261	20
NOTE 1:	Minimum EIRP over UE spherical coverage evaluation areas is defined as the lower limit without tolerance	
NOTE 2:	The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.	
NOTE 3: The requirements in this table are applicable to FR2 PC6 UE with the network signalling [highSpeedMeasFlag-r17] configured as [set2].		

6.2D.2 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO

6.2D.2.1 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 1

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.1-1 is specified in sub-clause 6.2.2.1. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.2 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 2

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.2-1 is specified in sub-clause 6.2.2.2. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.3 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 3

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.3-1 is specified in sub-clause 6.2.2.3. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.4 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 4

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.4-1 is specified in sub-clause 6.2.2.4. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.5 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 5

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.4-1 is specified in sub-clause 6.2.2.4. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.6 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 6

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.6-1 is specified in sub-clause 6.2.2.6. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.6 apply.

6.2D.3 UE maximum output power reduction with additional requirements for UL MIMO

6.2D.3.1 UE maximum output power reduction with additional requirements for UL MIMO for power class 1

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.1-1. The requirements shall be met with the configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by A-MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3.2 UE maximum output power reduction with additional requirements for UL MIMO for power class 2

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.2-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

For the UE maximum output power modified by A-MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3.3 UE maximum output power reduction with additional requirements for UL MIMO for power class 3

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.3-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

For the UE maximum output power modified by A-MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3.4 UE maximum output power reduction with additional requirements for UL MIMO for power class 4

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.4-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

6.2D.3.5 UE maximum output power reduction with additional requirements for UL MIMO for power class 5

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.4-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

6.2D.3.6 UE maximum output power reduction with additional requirements for UL MIMO for power class 6

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.6-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

6.2D.4 Configured transmitted power for UL MIMO

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the configured maximum output power $P_{CMAX,c}$ for serving cell *c* is defined as sum of all streams and is bound by limits set in clause 6.2.4.

6.3 Output power dynamics

6.3.1 Minimum output power

6.3.1.0 General

The minimum controlled output power of the UE is defined as the EIRP in the channel bandwidth for all transmit bandwidth configurations (resource blocks) when the power is set to a minimum value.

The minimum output power is defined as the mean power in at least one sub frame (1ms).

6.3.1.1 Minimum output power for power class 1

For power class 1 UE, the minimum output power shall not exceed the values specified in Table 6.3.1.1-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n260, n261,	50	4	47.58
n262	100	4	95.16
Ī	200	4	190.20
	400	4	380.28
n263	100	4	95.16
	400	4	381.12
Γ	800	4	715.20
	1600	4	1429.44
Γ	2000	4	1705.92

Table 6.3.1.1-1: Minimum output power for power class 1

6.3.1.2 Minimum output power for power class 2, 3, and 4

The minimum output power shall not exceed the values specified in Table 6.3.1.2-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3.1.2-1: Minimum output power for power class 2, 3, and 4

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n259, n260, n261, n262	50	-13	47.58
	100	-13	95.16
Γ	200	-13	190.20
Γ	400	-13	380.28
n263	100	-13	95.16
Γ	400	-13	381.12
Γ	800	-13	715.20
	1600	-13	1429.44
	2000	-13	1705.92
NOTE 1: n260 is not appli	ied for power class 2.		
NOTE 2: n259 is not appli			
NOTE 3: power class 4 is	not applicable to n263		

6.3.1.3 Minimum output power for power class 5 and 6

The minimum output power shall not exceed the values specified in Table 6.3.1.3-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

 Table 6.3.1.3-1: Minimum output power for power class 5 and 6

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n259, n261	50	-6	47.52
	100	-6	95.04
	200	-6	190.08
	400	-6	380.16

6.3.1.4 Minimum output power for power class 7

The minimum output power shall not exceed the values specified in Table 6.3.1.4-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n261	50	-13	47.58
	100	-13	95.16

Table 6.3.1.4-1: Minimum output power for power class 7

6.3.2 Transmit OFF power

The transmit OFF power is defined as the TRP in the channel bandwidth when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of its ports.

The transmit OFF power shall not exceed the values specified in Tables 6.3.2-1 and 6.3.2-2 for each operating band supported. The requirement is verified with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

Operating band	Channel band	Channel bandwidth / Transmit OFF power (dBm) / measurement bandwidth		
	50 MHz	100 MHz	200 MHz	400 MHz
n257, n258, n259, n260, n261, n262	-35	-35	-35	-35
	47.58 MHz	95.16 MHz	190.20 MHz	380.28 MHz

Table 6.3.2-1: Transmit OFF power for FR2-1

Table 6.3.2-2: Transmit OFF power for FR2-2

Operating band		Channel k	oandwidth / Tra measuremer	nsmit OFF pow nt bandwidth	er (dBm) /
	100 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
n263	-35	-35	-35	-35	-35
	95.16 MHz	381.12 MHz	715.20	1429.44	1705.92

For UE indicating [IE UL Gap], UE will meet OFF power requirement defined in this clause for the band for which UL transmission is stopped in the activated UL gap.

6.3.3 Transmit ON/OFF time mask

6.3.3.1 General

The transmit ON/OFF time mask defines the transient period(s) allowed

- between transmit OFF power and transmit ON power symbols (transmit ON/OFF)
- between continuous ON-power transmissions when power change or RB hopping is applied.

In case of RB hopping, transition period is shared symmetrically.

Unless otherwise stated the minimum requirements in clause 6.5 apply also in transient periods.

The transmit ON/OFF time mask is defined as a directional requirement. The requirement is verified in beam locked mode at beam peak direction. The maximum allowed EIRP OFF power level is -30dBm at beam peak direction. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

In the following sub-clauses, following definitions apply:

- A slot transmission is a Type A transmission.
- A long subslot transmission is a Type B transmission with more than 2 symbols.

- A short subslot transmission is a Type B transmission with 1 or 2 symbols.

6.3.3.2 General ON/OFF time mask

The general ON/OFF time mask defines the observation period allowed between transmit OFF and ON power. ON/OFF scenarios include: contiguous, and non-contiguous transmission, etc

The OFF power measurement period is defined in a duration of at least one slot excluding any transient periods. The ON power is defined as the mean power over one slot excluding any transient period.



Figure 6.3.3.2-1: General ON/OFF time mask for NR UL transmission in FR2

6.3.3.3 Transmit power time mask for slot and short or long subslot boundaries

The transmit power time mask for slot and a long subslot transmission boundaries defines the transient periods allowed between slot and long subslot PUSCH transmissions. For PUSCH-PUCCH and PUSCH-SRS transitions and multiplexing the time masks in sub-clause 6.3.3.7 apply.

The transmit power time mask for slot or long subslot and short subslot transmission boundaries defines the transient periods allowed between slot or long subslot and short subslot transmissions. The time masks in sub-clause 6.3.3.8 apply.

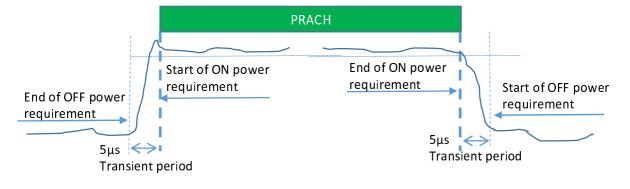
The transmit power time mask for short subslot transmissiona boundaries defines the transient periods allowed between short subslot transmissions. The time masks in sub-clause 6.3.3.9 apply.

6.3.3.4 PRACH time mask

The PRACH ON power is specified as the mean power over the PRACH measurement period excluding any transient periods as shown in Figure 6.3.3.4-1. The measurement period for different PRACH preamble format is specified in Table 6.3.3.4-1.

Format	SCS	Measurement period
A1	60 kHz	0.035677 ms
	120 kHz	0.017839 ms
A ₂	60 kHz	0.071354 ms
	120 kHz	0.035677 ms
A ₃	60 kHz	0.107031 ms
	120 kHz	0.053516 ms
B ₁	60 kHz	0.035091 ms
	120 kHz	0.0175455 ms
B4	60 kHz	0.207617 ms
	120 kHz	0.103809 ms
A ₁ /B ₁	60 kHz	0.035677 ms for front X1 occasion
		0.035091 ms for last occasion
		X1 = [2,5]
	120 kHz	0.017839 ms for front X1occasion
		0.017546 ms for last occasion
		X1 = [2,5]
A ₂ /B ₂	60 kHz	0.071354 ms for front X2 occasion
		0.069596 ms for last occasion
		X2 = [1,2]
	120 kHz	0.035677 ms for front X2 occasion
		0.034798 ms for last occasion
		X2 = [1,2]
A ₃ /B ₃	60 kHz	0.107031 ms for first occasion
		0.104101 ms for second occasion
	120 kHz	0.053515 ms for first occasion
		0.052050 ms for second occasion
Co	60 kHz	0.026758 ms
	120 kHz	0.013379 ms
C2	60 kHz	0.083333 ms
	120 kHz	0.0416667 ms
		on PRACH occasion start from begin of 0ms or 0.5 ms boundary,
t	he measurer	nent period will plus 0.032552 μs

Table 6.3.3.4-1: PRACH ON power measurement period

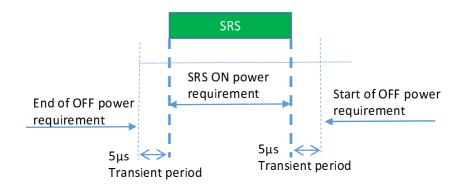




6.3.3.5 Void

6.3.3.6 SRS time mask

In the case a single SRS transmission, the ON power is defined as the mean power over the symbol duration excluding any transient period; Figure 6.3.3.6-1.





In the case multiple consecutive SRS transmission, the ON power is defined as the mean power for each symbol duration excluding any transient period. See Figure 7.7.4-2

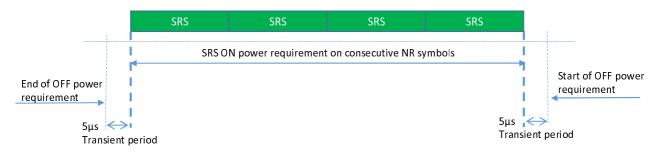


Figure 6.3.3.6-2: Consecutive SRS time mask for the case when no power change is required

When power change between consecutive SRS transmissions is required, then Figure 6.3.3.6-3 and Figure 6.3.3.6-4 apply.

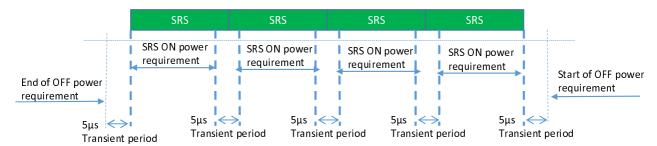
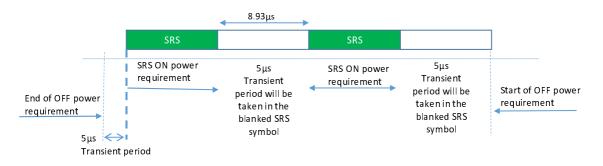
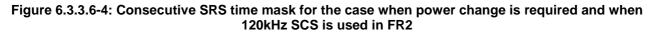


Figure 6.3.3.6-3: Consecutive SRS time mask for the case when power change is required and when 60kHz SCS is used in FR2





6.3.3.7 PUSCH-PUCCH and PUSCH-SRS time masks

The PUCCH/PUSCH/SRS time mask defines the observation period between sounding reference symbol (SRS) and an adjacent PUSCH/PUCCH symbol and subsequent UL transmissions. The time masks apply for all types of frame structures and their allowed PUCCH/PUSCH/SRS transmissions unless otherwise stated.

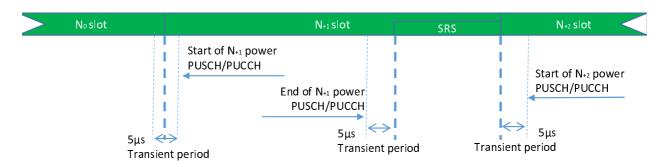


Figure 6.3.3.7-1: PUCCH/PUSCH/SRS time mask when there is a transmission before or after or both before and after SRS

When there is no transmission preceding SRS transmission or succeeding SRS transmission, then the same time mask applies as shown in Figure 6.3.3.7-1.

6.3.3.8 Transmit power time mask for consecutive slot or long subslot transmission and short subslot transmission boundaries

The transmit power time mask for consecutive slot or long subslot transmission and short subslot transmission boundaries defines the transient periods allowed between such transmissions.

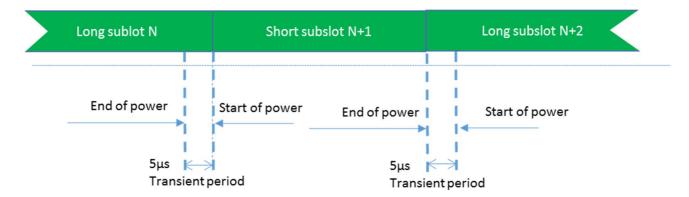


Figure 6.3.3.8-1: Consecutive slot or long subslot transmission and short subslot transmission time mask

6.3.3.9 Transmit power time mask for consecutive short subslot transmissions boundaries

The transmit power time mask for consecutive short subslot transmission boundaries defines the transient periods allowed between short subslot transmissions.

The transient period shall be equally shared as shown on Figure 6.3.3.9-2.

Figure 6.3.3.9-1: Void

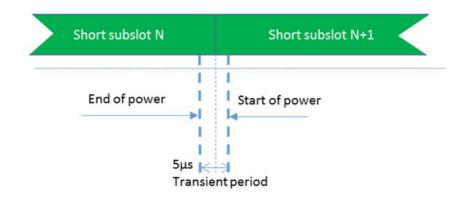


Figure 6.3.3.9-2: Consecutive short subslot transmissions time mask where DMRS is not the first symbol in the adjacent short subslot transmission

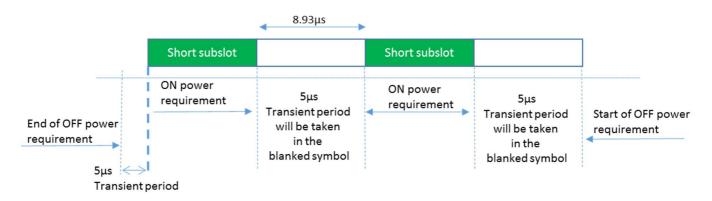


Figure 6.3.3.9-3: Consecutive short subslot (1 symbol gap) time mask for the case when transient period is required on both sides of the symbol and when 120 kHz SCS is used in FR2

6.3.4 Power control

6.3.4.1 General

The requirements on power control accuracy apply under normal conditions and are defined as a directional requirement. The requirements are verified in beam locked mode on beam peak direction.

6.3.4.2 Absolute power tolerance

The absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame (1 ms) at the start of a contiguous transmission or non-contiguous transmission with a transmission gap larger than 20 ms. The tolerance includes the channel estimation error RSRP estimate.

The minimum requirements specified in Table 6.3.4.2-1 apply in the power range bounded by the minimum output power as specified in sub-clause 6.3.1 (P_{min}) and the maximum output power as specified in sub-clause 6.2.1 as minimum peak EIRP (P_{max}). The intermediate power point P_{int} is defined in table 6.3.4.2-2

Power Range	Tolerance
$P_{int} \ge P \ge P_{min}$	± 14.0 dB
$P_{max} \ge P > P_{int}$	± 12.0 dB

Table 6.3.4.2-1:	Absolute	power	tolerance
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Table 0.3.4.2-2. Intermediate power point	Table 6.3.4.2-2:	Intermediate	power point
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Power Parameter	Value
Pint	P _{max} – 12.0 dB

6.3.4.3 Relative power tolerance

The relative power tolerance is the ability of the UE transmitter to set its output power in a target sub-frame (1 ms) relatively to the power of the most recently transmitted reference sub-frame (1 ms) if the transmission gap between these sub-frames is less than or equal to 20 ms.

The minimum requirements specified in Table 6.3.4.3-1 apply when the power of the target and reference sub-frames are within the power range bounded by the minimum output power as defined in sub-clause 6.3.1 and Pint as defined in sub-clause 6.3.4.2. The minimum requirements specified in Table 6.3.4.3-2 apply when the power of the target and reference sub-frames are within the power range bounded by Pint as defined in sub-clause 6.3.4.2 and the measured P_{UMAX} as defined in sub-clause 6.2.4.

For a test pattern that is either a monotonically increasing or monotonically decreasing power sweep over the range specified for Tables 6.3.4.3-1 and 6.3.4.3-2, 3 exceptions are allowed for each of the test patterns. For these exceptions, the power tolerance limit is a maximum of ± 11.0 dB.

Power step ∆P (Up or down) (dB)	All combinations of PUSCH and PUCCH, PUSCH/PUCCH and SRS transitions between sub- frames, PRACH (dB)		
ΔP < 2	±5.0		
2 ≤ ΔP < 3	±6.0		
3 ≤ ∆P < 4	±7.0		
4 ≤ ΔP < 10	±8.0		
10 ≤ ΔP < 15	±10.0		
15 ≤ ∆P	P ±11.0		
NOTE: The requirements apply with <i>ue- BeamLockFunction</i> enabled.			

Power step ∆P (Up or down) (dB)	All combinations of PUSCH and PUCCH, PUSCH/PUCCH and SRS transitions between sub- frames, PRACH (dB)		
ΔP < 2	± 3.0		
2 ≤ ∆P < 3	± 4.0		
3 ≤ ΔP < 4	± 5.0		
4 ≤ ΔP < 10	± 6.0		
10 ≤ ΔP < 15	± 8.0		
15 ≤ ∆P	± 9.0		
NOTE 1: The requirements apply with <i>ue-BeamLockFunction</i> enabled. NOTE 2: For PUSCH to PUSCH transitions with the allocated resource blocks fixed in frequency and no transmission gaps other than those generated by downlink subframes, guard periods: for a power step $\Delta P = 1$ dB, the relative power			
tolerance for transmission is ± 1.0 dB.			

6.3.4.4 Aggregate power tolerance

The aggregate power control tolerance is the ability of the UE transmitter to maintain its power in a sub-frame (1 ms) during non-contiguous transmissions within 21ms in response to 0 dB TPC commands with respect to the first UE transmission and all other power control parameters as specified in 38.213 kept constant.

The minimum requirements specified in Table 6.3.4.4-1 apply when the power of the target and reference sub-frames are within the power range bounded by the minimum output power as defined in sub-clause 6.3.1 and P_{int} as defined in sub-clause 6.3.4.2. The minimum requirements specified in Table 6.3.4.4-2 apply when the power of the target and reference sub-frames are within the power range bounded by Pint as defined in sub-clause 6.3.4.2 and the maximum output power as specified in sub-clause 6.2.1.

Table 6.3.4.4-1: Aggregate power tolerance	e, Pi	$int \ge P \ge P_m$	nin
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TPC command	UL channel	Aggregate power tolerance within 21 ms
0 dB	PUCCH	± 5.5 dB
0 dB	PUSCH	± 5.5 dB

TPC command	UL channel	Aggregate power tolerance within 21 ms
0 dB	PUCCH	± 3.5 dB
0 dB	PUSCH	± 3.5 dB

6.3A Output power dynamics for CA

6.3A.1 Minimum output power for CA

Table 6.3A.1-1: Void

6.3A.1.0 General

For intra-band contiguous and non-contiguous carrier aggregation, the minimum controlled output power of the UE is defined as the transmit power of the UE per component carrier, i.e., EIRP in the channel bandwidth of each component carrier for all transmit bandwidth configurations (resource blocks), when the power on both component carriers are set to a minimum value.

The minimum output power is defined as the mean power in at least one sub frame (1ms).

6.3A.1.1 Minimum output power for power class 1

For intra-band contiguous and non-contiguous carrier aggregation, the minimum output power shall not exceed the values specified in Table 6.3A.1.1-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n260, n261, n262	50	4	47.58
	100	4	95.16
	200	4	190.20
	400	4	380.28
n263	100	4	95.16
	400	4	381.12
	800	4	715.20
	1600	4	1429.44
	2000	4	1705.92

Table 6.3A.1.1-1: Minimum output power for power class 1

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the minimum output power is defined per carrier and is specified in clause 6.3.1.1.

6.3A.1.2 Minimum output power for power class 2, 3, and 4

For intra-band contiguous and non-contiguous carrier aggregation, the minimum output power shall not exceed the values specified in Table 6.3A.1.2-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Channel bandwidth Minimum output power (MHz) (dBm)		Measurement bandwidth (MHz)	
n257, n258, n259, n260, n261, n262	50	-13	47.58	
	100	-13	95.16	
	200	-13	190.20	
	400	-13	380.28	
n263	100	-13	95.16	
	400	-13	381.12	
	800	-13	715.20	
	1600	-13	1429.44	
Γ	2000	-13	1705.92	
NOTE 1: n260 is not appli NOTE 2: n259 is not appli	ed for power class 2. ed for power class 4.	•	•	

Table 6.3A.1.2-1: Minimum output power for CA for power class 2, 3, and 4

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the minimum output power is defined per carrier and is specified in clause 6.3.1.2.

6.3A.1.3 Minimum output power for power class 5

For intra-band contiguous and non-contiguous carrier aggregation, the minimum output power shall not exceed the values specified in Table 6.3A.1.3-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n259	50	-6	47.52
	100	-6	95.04
	200	-6	190.08
	400	-6	380.16

Table 6.3A.1.2-1: Minimum output power for CA for power class 5

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the minimum output power is defined per carrier and is specified in clause 6.3.1.3.

6.3A.2 Transmit OFF power for CA

For intra-band contiguous and non-contiguous carrier aggregation, the transmit OFF power is defined as the TRP in the channel bandwidth per component carrier when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of it sports.

The transmit OFF power shall not exceed the values specified in Table 6.3A.2-1 and Table 6.3A.2-2 for each operating band supported.

Operating band	Channel bandwidth / Transmit OFF power (dBm) / measurement bandwidth			
	50 MHz	100 MHz	200 MHz	400 MHz
n257, n258, n259, n260, n261, n262	-35	-35	-35	-35
	47.58 MHz	95.16 MHz	190.20 MHz	380.28 MHz

Table 6.3A.2-1: Transmit OFF power for CA for FR2-1

Operating band		Channel bandwidth / Transmit OFF power (dBm) / measurement bandwidth				
	100 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz	
n263	-35	-35	-35	-35	-35	
	95.16 MHz	381.12 MHz	715.20	1429.44	1705.92	

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the transmit OFF power specified in clause 6.3.2.1 is applicable for each CC when the transmitter is OFF on all CCs. The transmitter is considered to be OFF when the UE is not allowed to transmit on any of its ports.

6.3A.3 Transmit ON/OFF time mask for CA

For intra-band contiguous and non-contiguous UL carrier aggregation, the general output power ON/OFF time mask specified in clause 6.3.3.2 is applicable for each component carrier during the ON power period and the transient periods. The OFF period as specified in clause 6.3.3.2 shall only be applicable for each component carrier when all the component carriers are OFF.

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the general output power ON/OFF time mask specified in clause 6.3.3.1 is applicable for each CC during the ON power period and the transient periods. The OFF period is specified in clause 6.3.3.1 for each CC separately when all the CCs are OFF.

6.3A.4 Power control for CA

6.3A.4.1 General

The requirements in this clause apply to a UE when it has at least one of UL or DL configured for CA operation. The requirements on power control accuracy in CA operation apply under normal conditions and are defined as a directional requirement. The requirements are verified in beam locked mode on beam peak direction. The requirements apply for one single PUCCH, PUSCH or SRS transmission of contiguous PRB allocation per configured UL CC with power setting in accordance with Clause 7.1 of [10]

6.3A.4.2 Absolute power tolerance

For intra-band contiguous and non-contiguous UL carrier aggregation, the absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame at the start of a contiguous transmission or non-contiguous transmission with a transmission gap on each active component carriers larger than 20 ms. For SRS switching, the absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame at the start of a contiguous transmission or non-contiguous transmission with a transmission or non-contiguous transmission with a transmission or non-contiguous transmission with a transmission gap on component carriers (to which SRS switching occurs) larger than 20 ms. The requirement can be tested by time aligning any transmission gaps on the component carriers. For intra-band contiguous CA, the absolute power control tolerance per configured UL CC is given in Tables 6.3.4.2-1 and 6.3.4.2-2.

6.3A.4.3 Relative power tolerance

For intra-band contiguous and non-contiguous UL carrier aggregation, the relative power tolerance is the ability of the UE transmitter to set its output power in a target sub-frame relative to the power of the most recently transmitted reference sub-frame if the transmission gap between these sub-frames is less than or equal to 20ms.

For intra-band contiguous CA, the requirements apply when the power of the target and reference sub-frames on each component carrier exceed the minimum output power as defined in clause 6.3A.1 and the total power is limited by P_{UMAX} as defined in clause 6.2A.4. For the purpose of these requirements, the power in each component carrier is specified over only the transmitted resource blocks. The UE shall meet the requirements in tables 6.3.4.3-1 and 6.3.4.3-2 for transmission on each assigned component carrier, when the average PSDs over each CC are aligned with each other in the reference sub-frame. The requirements apply per component carrier to:

- a. All possible combinations of PUSCH and PUCCH transitions
- b. SRS and PUSCH/PUCCH transitions, only with simultaneous SRS of constant SRS bandwidth allocated in the target and reference subrames
- c. RACH, primary component carrier

When applicable, the power step ΔP between the reference and target subframes shall be set by a TPC command and/or an uplink scheduling grant transmitted by means of an appropriate DCI Format.

6.3A.4.4 Aggregate power tolerance

For intra-band contiguous and non-contiguous UL carrier aggregation, the aggregate power control tolerance is the ability of the UE transmitter to maintain its power during non-contiguous transmissions within 21 ms in response to 0 dB TPC commands with respect to the first UE transmission and all other power control parameters as specified in [10] kept constant.

For intra-band contiguous CA, the aggregate power tolerance per CC is given in Tables 6.3.4.4.1-1 and 6.3.4.4.1-2, with simultaneous PUSCH configured. The average PSDs over each assigned CC shall be aligned before the start of the test. The requirement can be tested with the transmission gaps time aligned between component carriers.

6.3D Output power dynamics for UL MIMO

6.3D.0 General

The requirements in subclause 6.3D shall be met with configurations specified in sub-clause 6.2D.1.x, where 'x' depends on power class. Unless otherwise specified, the requirements shall be verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

6.3D.1 Minimum output power for UL MIMO

6.3D.1.0 General

The minimum output power is defined as the mean power in at least one sub frame (1ms). The minimum controlled output power is defined as the EIRP, i.e. the sum of the power in the channel bandwidth for all transmit bandwidth configurations (resource blocks), when the UE power is set to a minimum value.

6.3D.1.1 Minimum output power for UL MIMO for power class 1

For UE supporting UL MIMO, the minimum output power shall not exceed the sum of the values specified in Table 6.3.1.1-1 and the quantity 10*log₁₀(Number of Layers).

6.3D.1.2 Minimum output power for UL MIMO for power class 2, 3 and 4

minimum output power shall not exceed the sum of the values specified in Table 6.3.1.2-1 and the quantity $10*\log_{10}(Number \text{ of Layers})$.

6.3D.1.3 Minimum output power for UL MIMO for power class 5 and 6

For UE supporting UL MIMO, the minimum controlled output power is defined as the EIRP, i.e. the sum of the power in the channel bandwidth for all transmit bandwidth configurations (resource blocks), when the UE power is set to a minimum value. The minimum output power shall not exceed the values specified in Table 6.3.1.3-1. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

6.3D.2 Transmit OFF power for UL MIMO

For UE supporting UL MIMO, the transmit OFF power is defined as the TRP in the channel bandwidth when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of its ports. During DTX and measurements gaps, the transmitter is not considered OFF. The minimum output power shall not exceed the values specified in Table 6.3.2-1. The requirement is verified with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

6.3D.3 Transmit ON/OFF time mask for UL MIMO

For UE supporting UL MIMO, the ON/OFF time mask requirements in clause 6.3.3 apply.

6.4 Transmit signal quality

6.4.1 Frequency Error

The UE basic measurement interval of modulated carrier frequency is 1 UL slot. The mean value of basic measurements of UE modulated carrier frequency shall be accurate to within \pm 0.1 PPM observed over a period of 1 msec of cumulated measurement intervals compared to the carrier frequency received from the NR gNB.

The frequency error is defined as a directional requirement. The requirement is verified in beam locked mode with the test metric of Frequency (Link=TX beam peak direction, Meas=Link angle).

6.4.2 Transmit modulation quality

6.4.2.0 General

Transmit modulation quality defines the modulation quality for expected in-channel RF transmissions from the UE. The transmit modulation quality is specified in terms of:

- Error Vector Magnitude (EVM) for the allocated resource blocks (RBs)
- EVM equalizer spectrum flatness derived from the equalizer coefficients generated by the EVM measurement process
- Carrier leakage
- In-band emissions for the non-allocated RB

All the parameters defined in clause 6.4.2 are defined using the measurement methodology specified in Annex F.

All the requirements in 6.4.2 are defined as directional requirement. The requirements are verified in beam locked mode on beam peak direction, with parameter *maxRank* (as defined in TS 38.331 [13]) set to 1. The requirements are applicable to UL transmission from each configurable antenna port (as defined in TS 38.331 [13]) of UE, enabled one at a time.

In case the parameter 3300 or 3301 is reported from UE via the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrentList* IE (as defined in TS 38.331 [13]), carrier leakage measurement requirement in clause 6.4.2.2 and 6.4.2.3 shall be waived, and the RF correction with regard to the carrier leakage and IQ image shall be omitted during the calculation of transmit modulation quality.

6.4.2.1 Error vector magnitude

The Error Vector Magnitude is a measure of the difference between the reference waveform and the measured waveform. This difference is called the error vector. Before calculating the EVM, the measured waveform is corrected by the sample timing offset and RF frequency offset. Then the carrier leakage shall be removed from the measured waveform before calculating the EVM.

The measured waveform is further equalised using the channel estimates subjected to the EVM equaliser spectrum flatness requirement specified in sub-clauses 6.4.2.4 and 6.4.2.5. For DFT-s-OFDM waveforms, the EVM result is defined after the front-end FFT and IDFT as the square root of the ratio of the mean error vector power to the mean reference power expressed as a %. For CP-OFDM waveforms, the EVM result is defined after the front-end FFT as the square root of the mean reference power expressed as a %.

The basic EVM measurement interval in the time domain is one preamble sequence for the PRACH and one slot for PUCCH and PUSCH in the time domain. The EVM measurement interval is reduced by any symbols that contains an allowable power transient in the measurement interval as as defined in clause 6.3.3.

The RMS average of the basic EVM measurements over 10 subframes for the average EVM case, and over 60 subframes for the reference signal EVM case, for the different modulation schemes shall not exceed the values specified in Table 6.4.2.1-1 for the parameters defined in Table 6.4.2.1-2 or 6.4.2.1-3, depending on UE power class. For EVM evaluation purposes, all 13 PRACH preamble formats and all 5 PUCCH formats are considered to have the same EVM requirement as QPSK modulated.

The requirement is verified with the test metric of EVM (Link=TX beam peak direction, Meas=Link angle).

Parameter	Unit	Average EVM level	Reference signal EVM level
Pi/2 BPSK	%	30.0	30.0
QPSK	%	17.5	17.5
16 QAM	%	12.5	12.5
64 QAM	%	8.0	8.0

Table 6.4.2.1-2: Parameters for Error Vector Magnitude for power class 1 in FR2-1

Parameter	Unit	Level
UE EIRP	dBm	≥ 4
UE EIRP for UL 16 QAM	dBm	≥7
UE EIRP for UL 64 QAM	dBm	≥ 11
Operating conditions		Normal conditions

Table 6.4.2.1-2a: Parameters for Error Vector Magnitude for power class 1 in FR2-2

		Level				
Parameter	Unit	100 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
UE EIRP	dBm	≥ 4	≥[2]	≥[5]	≥ [8]	≥[9]
UE EIRP for UL 16 QAM	dBm	≥7	≥ [5]	≥[8]	≥[11]	≥ [12]
UE EIRP for UL 64 QAM	dBm	≥ 11	≥ [9]	≥[12]	≥ [15]	≥[16]
Operating conditions	Normal Conditions					
NOTE 1: PTRS is configured for 16 QAM and 64 QAM						

Table 6.4.2.1-3: Parameters for Error Vector Magnitude for power class 2, 3, 4 and 7 in FR2-1

Parameter	Unit	Level
UE EIRP	dBm	≥ -13
UE EIRP for UL 16 QAM	dBm	≥ -10
UE EIRP for UL 64 QAM	dBm	≥ -6
Operating conditions		Normal conditions

Table 6.4.2.1-3a: Parameters for Error Vector Magnitude for power class 3 in FR2-2

				Level		
Parameter	Unit	100 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
UE EIRP	dBm	≥ -13	[≥ -11]	[≥ -8]	[≥ -5]	[≥ -4]
UE EIRP for UL 16 QAM	dBm	≥ -10	[≥ -8]	[≥ -5]	[≥ -2]	[≥ -1]
UE EIRP for UL 64 QAM	dBm	≥ -6	[≥ -4]	[≥ -1]	[≥ 2]	[≥ 3]
Operating conditions		Normal Conditions				
NOTE 1: PTRS is configured for 16 QAM and 64 QAM						

Table 6.4.2.1-3b: Parameters for Error Vector Magnitude for power class 2 in FR2-2

		Level				
Parameter	Unit	100 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
UE EIRP	dBm	≥ -13	≥[-11]	≥[-8]	≥[-5]	≥ [-4]
UE EIRP for UL 16 QAM	dBm	≥ -10	≥ [-8]	≥ [-5]	≥[-2]	≥[-1]
UE EIRP for UL 64 QAM	dBm	≥ -6	≥[-4]	≥[-1]	≥ [2]	≥[3]
Operating conditions	Normal Conditions					
NOTE 1: PTRS is configured for 16 QAM and 64 QAM						

Parameter	Unit	Level
UE EIRP	dBm	≥ -6
UE EIRP for UL 16 QAM	dBm	≥ -3
UE EIRP for UL 64 QAM	dBm	≥ 1
Operating conditions		Normal conditions

Table 6.4.2.1-4: Parameters for Error Vector Magnitude for power class 5

6.4.2.2 Carrier leakage

6.4.2.2.1 General

Carrier leakage is an additive sinusoid waveform. The carrier leakage requirement is defined for each component carrier. The measurement interval is one slot in the time domain. The relative carrier leakage power is a power ratio of the additive sinusoid waveform to the power in the modulated waveform.

The requirement is verified with the test metric of Carrier Leakage (Link=TX beam peak direction, Meas=Link angle).

6.4.2.2.2 Carrier leakage for power class 1

When carrier leakage is contained inside the spectrum confined within the configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.2-1 and Table 6.4.2.2.2-2 for power class 1 UEs.

Table 6.4.2.2.2-1: Minimum requirements for relative carrier leakage power for power class 1 in FR2-1

Parameters	Relative Limit (dBc)	
EIRP > 17 dBm	-25	
4 dBm ≤ EIRP ≤ 17 dBm	-20	

Table 6.4.2.2.2-2: Minimum requirements for relative carrier leakage power for power class 1 in FR2-2

Parameters	Relative Limit (dBc)
EIRP > 13.4 dBm	-25
0.4 dBm ≤ EIRP ≤ 13.4 dBm	-20

6.4.2.2.3 Carrier leakage for power class 2

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.3-1 and Table 6.4.2.2.3-2 for power class 2.

Table 6.4.2.2.3-1: Minimum requirements for relative carrier leakage power for power class 2 in FR2-1

Parameters	Relative Limit (dBc)
EIRP > 6 dBm	-25
-13 dBm ≤ EIRP ≤ 6 dBm	-20

Table 6.4.2.2.3-2: Minimum requirements for relative carrier leakage power for power class 2 in FR2-2

Parameters	Relative Limit (dBc)
EIRP > 5.8 dBm	-25
-13.2 dBm ≤ EIRP ≤ 5.8 dBm	-20

6.4.2.2.4 Carrier leakage for power class 3

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.4-1 and Table 6.4.2.2.4-2 for power class 3 UEs.

Table 6.4.2.2.4-1: Minimum requirements for relative carrier leakage power for power class 3 in FR2-1

Parameters	Relative Limit (dBc)
EIRP > 0 dBm	-25
-13 dBm ≤ EIRP ≤ 0 dBm	-20

Table 6.4.2.2.4-2: Minimum requirements for relative carrier leakage power for power class 3 in FR2-2

Parameters	Relative Limit (dBc)
EIRP > -1.9 dBm	-25
-14.9 dBm ≤ EIRP ≤ -1.9 dBm	-20

6.4.2.2.5 Carrier leakage for power class 4

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.5-1 for power class 4.

Table 6.4.2.2.5-1: Minimum requirements for relative carrier leakage power for power class 4

Parameters	Relative Limit (dBc)
EIRP > 11 dBm	-25
-13 dBm ≤ EIRP ≤ 11 dBm	-20

6.4.2.2.6 Carrier leakage for power class 5

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.6-1 for power class 5.

Table 6.4.2.2.6-1: Minimum requirements for relative carrier leakage power for power class 5

Parameters	Relative Limit (dBc)
EIRP > 7 dBm	-25
-6 dBm ≤ EIRP ≤ 7 dBm	-20

6.4.2.2.7 Carrier leakage for power class 6

For power class 6, the carrier leakage requirement specified in clause 6.4.2.2.6 for power class 5 applies.

6.4.2.2.8 Carrier leakage for power class 7

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power specified in subclause 6.4.2.2.4 applies.

6.4.2.3 In-band emissions

6.4.2.3.1 General

The in-band emission is defined as the average across 12 sub-carriers and as a function of the RB offset from the edge of the allocated UL transmission bandwidth. The in-band emission is measured as the ratio of the UE output power in a non–allocated RB to the UE output power in an allocated RB. The IBE requirement does not apply if UE declares support for *mpr-PowerBoost-FR2-r16*, UL transmission is QPSK,MPR_{f,c} = 0 and when NS_200 applies, and the network configures the UE to operate with *mpr-PowerBoost-FR2-r16*.

The basic in-band emissions measurement interval is identical to that of the EVM test.

The requirement is verified with the test metric of In-band emission (Link=TX beam peak direction, Meas=Link angle).

6.4.2.3.2 In-band emissions for power class 1

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.2-1 for power class 1 UEs.

Parameter description			Limit (NOTE 1)		Applicable Frequencies
General	dB		$-25 - 10.\log_{10}($	$\left(\frac{N_{RB}}{L_{CRB}}\right),$	Any non-allocated (NOTE 2)
			$\frac{max}{20.\log_{10}(\text{EVM})} - 5$	$\frac{(\Delta_{RB} -1)}{L_{CRB}}$,	
			-55.1dBm –	$\overline{P_{RB}}$	
			Output power for FR2-1	Output Power for FR2-2	
IQ Image	dB	-25	> 27 dBm	> 23.4 dBm	Image frequencies (NOTES 2, 3)
		-20	≤ 27 dBm	≤ 23.4 dBm	
Carrier leakage	dBc	-25	> 17 dBm	> 13.4 dBm	Carrier frequency (NOTES 4, 5)
		-20	4 dBm ≤ Output power ≤ 17 dBm	≤ 13.4 dBm	
NOTE 1: A	An in-ban	d emissions	combined limit is evaluated in e	each non-allocated RB. For e	each such RB, the
n	ninimum	requirement	is calculated as the higher of (P _{RB} - 25 dB) and the powe	er sum of all limit values
	<u> </u>				
(General,	IQ Image of	r Carrier leakage) that apply. P	_{RB} is defined in NOTE 10.	
			ndwidth is 1 RB and the limit is		
			easured average power per allo 2 BPSK with Spectrum Shaping		
			RB to the measured power in the		
			ncies for this limit are those that		
b	andwidth	, based on	symmetry with respect to the ca	rrier frequency, but excluding	g any allocated RBs.
			ndwidth is 1 RB and the limit is a		sured power in one non-
			easured total power in all alloca ncies for this limit depend on the		l ocation in
			<i>t</i> IE, and are those that are encl		
e	excluding	any allocate	ed RB.		
NOTE 6: L	- _{CRB} is the	Transmiss	ion Bandwidth (see Clause 5.3).		
			on Bandwidth Configuration (see		
			e modulation format used in the		
			uency offset between the alloca		on-allocated RB (e.g. $\Delta_{\rm RB}$
=	= 1 or Δ_{RB}	= -1 for the	first adjacent RB outside of the	allocated bandwidth).	
NOTE 10:	P _{RB} is a	in average o	of the transmitted power over 10	sub-frames normalized by t	he number of allocated
		sured in dB	m. n beam peak direction.		
NOTE II. P	in powers		n beam pear unection.		

Table 6.4.2.3.2-1: Requirements for in-band emissions for power class 1

6.4.2.3.3 In-band emissions for power class 2

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.3-1 for power class 2.

Parameter	Unit		Limit (NOTE	1)	Applicable
description					Frequencies
General	dB		$\begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \end{bmatrix}$		Any non-allocated
					RB in allocated
			max	$(\Delta_{PP} -1)$	component carrier
			$\frac{max}{20.\log_{10}(\text{EVM}) - 5}$	$\frac{1}{1}$, $\frac{1}{1}$, $\frac{1}{1}$	and not allocated
			-55.1 <i>dBm</i>	$-\frac{E_{CRB}}{P_{RB}}$	component carriers (NOTE 2)
			Output power for FR2-1	Output Power for FR2-2	,
IQ Image	dB	-25	Output power > 16 dBm	Output power > 15.8 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 16 dBm	Output power ≤ 15.8 dBm	
Carrier leakage	dBc	-25	Output power > 6 dBm	Output power > 5.8 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 6 dBm	-13.2 dBm ≤ Output power ≤ 5.8 dBm	
NOTE 1: An	in-ban	d emissions	combined limit is evaluated in each	n non-allocated RB. For each such l	RB, the minimum
rec	nuireme	ent is calcula	ted as the higher of (P_{PR}) - 25 dB) and the power sum of all limit valu	ies (General IQ
	1000				
Im	age or	Carrier leak	age) that apply. P_{RB} is defined in	NOTE 9.	
RE Pi/	3 to the 2 BPSł	measured a K with Spect	verage power per allocated RB, wh	ressed as a ratio of measured powe nere the averaging is done across a as a ratio of measured power in or D.	Il allocated RBs. For
NOTE 3: Im	age free	quencies foi	UL CA are specified in relation to e	either UL or DL carrier frequency.	
				ressed as a ratio of measured powe	er in one non-allocated
			otal power in all allocated RBs.	e enclosed in the RBs containing the	DC frequency or in
			tely adjacent to the DC frequency b		e DC frequency, of in
				ponent carrier (see Figure 5.3.3-1)	
			e modulation format used in the allo		
NOTE 8: Δ_p	_R is the	starting free	quency offset between the allocated	RB and the measured non-allocate	ed RB (e.g. $\Delta_{RR} = 1$ or
Δ_R	_B = -1 fe	or the first a		bandwidth), and may take non-inte	
NOTE 9: P	is a	an average o	of the transmitted power over 10 su	b-frames normalized by the number	of allocated RBs,
		in dBm.	-	-	
			n beam peak direction.		

Table 6.4.2.3.3-1: Requirements for in-band emissions for power class 2

Table 6.4.2.3.3-2: Void

6.4.2.3.4 In-band emissions for power class 3

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.4-1 for power class 3 UEs.

descriptior	Unit	Limit (NOTE 1)		Applicable Frequencies	
General	dB		$max \begin{bmatrix} -25 - 10. \ log_{10}(EVM) \\ -55.1 \ dE \end{bmatrix}$	$\begin{array}{l} \begin{array}{c} Pg_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ - 5.\frac{\left(\Delta_{RB} -1\right)}{L_{CRB}}, \\ Pm - \overline{P_{RB}} \end{array}$	Any non-allocated (NOTE 2)
			Output power for FR2-1	Output Power for FR2-2	
IQ Image	dB	-25	> 10 dBm	> 8.1 dBm	Image frequencies (NOTES 2, 3)
		-20	≤ 10 dBm	≤ 8.1 dBm	
Carrier leakage	dBc	-25	> 0 dBm	> -1.9dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 0 dBm	-14.9 dBm ≤ Output power ≤ - 1.9 dBm	
NOTE 2: T	he meas			P_{RB} is defined in NOTE 10. it is expressed as a ratio of meas	sured power in one non-
a a ii NOTE 3: T	llocated llocated n one nor The applic	surement I RB to the RBs. For n-allocate cable freq	bandwidth is 1 RB and the lim measured average power pe Pi/2 BPSK with Spectrum Sha d RB to the measured power uencies for this limit are those	it is expressed as a ratio of meas r allocated RB, where the averag aping, the limit is expressed as a in the allocated RB with highest F e that are enclosed in the reflection	ing is done across all ratio of measured power PSD on of the allocated
a ii NOTE 3: T b NOTE 4: T a	llocated llocated o one nor he applic andwidth he meas llocated	surement I RB to the RBs. For n-allocate cable freq n, based c surement I RB to the	bandwidth is 1 RB and the lim measured average power per Pi/2 BPSK with Spectrum Sha d RB to the measured power uencies for this limit are those on symmetry with respect to the bandwidth is 1 RB and the lim measured total power in all a	it is expressed as a ratio of meas r allocated RB, where the averag aping, the limit is expressed as a in the allocated RB with highest F e that are enclosed in the reflection the carrier frequency, but excludin- it is expressed as a ratio of meas llocated RBs.	ing is done across all ratio of measured power PSD on of the allocated g any allocated RBs. sured power in one non-
a in NOTE 3: T b NOTE 4: T NOTE 5: T U e	Ilocated Ilocated o one nor The applic andwidth The meas Ilocated The applic <i>IplinkTxL</i> xcluding	surement I RB to the RBs. For n-allocate cable freq n, based c surement I RB to the cable freq DirectCurr any alloc	bandwidth is 1 RB and the lim measured average power pe Pi/2 BPSK with Spectrum Sha d RB to the measured power uencies for this limit are those on symmetry with respect to the bandwidth is 1 RB and the lim measured total power in all a uencies for this limit depend of ent IE, and are those that are ated RB.	it is expressed as a ratio of measured real and the allocated RB, where the average aping, the limit is expressed as a in the allocated RB with highest P that are enclosed in the reflection e carrier frequency, but excluding it is expressed as a ratio of measured RBs. In the parameter <i>txDirectCurrent</i> and the RBs containing the reflection of the RBs contain of the RBs containing the reflection of the RBs contain of	ing is done across all ratio of measured power PSD on of the allocated g any allocated RBs. sured power in one non-
NOTE 3: T NOTE 4: T NOTE 5: T NOTE 5: T U NOTE 5: L	Ilocated Ilocated n one nor The applic andwidth The meas Ilocated The applic <i>IplinkTxL</i> xcluding _{CRB} is the	surement I RB to the RBs. For n-allocate cable freq n, based c surement I RB to the cable freq <i>DirectCurr</i> any alloc e Transmi	bandwidth is 1 RB and the lim measured average power pe Pi/2 BPSK with Spectrum Sha d RB to the measured power uencies for this limit are those on symmetry with respect to the bandwidth is 1 RB and the lim measured total power in all a uencies for this limit depend of ent IE, and are those that are ated RB. ssion Bandwidth (see Clause	it is expressed as a ratio of measured reallocated RB, where the average aping, the limit is expressed as a in the allocated RB with highest Re that are enclosed in the reflection e carrier frequency, but excluding it is expressed as a ratio of measured RBs. In the parameter <i>txDirectCurrent</i> enclosed in the RBs containing t 5.3).	ing is done across all ratio of measured power PSD on of the allocated g any allocated RBs. sured power in one non- <i>Location</i> in
NOTE 3: T NOTE 4: T NOTE 4: T NOTE 5: T U NOTE 5: L NOTE 6: L	Ilocated Ilocated n one nor The applic andwidth The meas Ilocated The applic <i>IplinkTxL</i> xcluding _{CRB} is the	surement I RB to the RBs. For n-allocate cable freq n, based c surement I RB to the cable freq DirectCurr any alloc e Transmi	bandwidth is 1 RB and the lim measured average power per Pi/2 BPSK with Spectrum Sha d RB to the measured power uencies for this limit are those on symmetry with respect to the bandwidth is 1 RB and the lim measured total power in all a uencies for this limit depend of ent IE, and are those that are ated RB. ssion Bandwidth (see Clause ssion Bandwidth Configuration	it is expressed as a ratio of measure allocated RB, where the average aping, the limit is expressed as a a in the allocated RB with highest Fe that are enclosed in the reflection the carrier frequency, but excluding it is expressed as a ratio of measure and the parameter <i>txDirectCurrent</i> enclosed in the RBs containing to 5.3).	ing is done across all ratio of measured power PSD on of the allocated g any allocated RBs. sured power in one non-
NOTE 3: T NOTE 4: T NOTE 4: T NOTE 5: T U NOTE 5: L NOTE 6: L NOTE 7: N NOTE 8: E	Ilocated Ilocated n one nor The applic andwidth The meas Ilocated The applic JplinkTxL xcluding _{CRB} is the SVM s the	surement I RB to the RBs. For m-allocate cable freq n, based c surement I RB to the cable freq DirectCurr any alloc e Transmis e limit for	bandwidth is 1 RB and the lim measured average power pe Pi/2 BPSK with Spectrum Sha d RB to the measured power on symmetry with respect to the bandwidth is 1 RB and the lim measured total power in all a uencies for this limit depend of ent IE, and are those that are ated RB. ssion Bandwidth (see Clause ssion Bandwidth Configuration the modulation format used in	it is expressed as a ratio of measured approximate the average approximate the limit is expressed as a limit the allocated RB with highest Field that are enclosed in the reflection e carrier frequency, but excluding it is expressed as a ratio of measured RBs. In the parameter <i>txDirectCurrent</i> and the parameter <i>txDirectCurrent</i> for the	ing is done across all ratio of measured power PSD on of the allocated g any allocated RBs. sured power in one non- <i>Location</i> in he DC frequency but
NOTE 3: T NOTE 4: T NOTE 5: T NOTE 5: T NOTE 6: L NOTE 6: L NOTE 7: N NOTE 8: E NOTE 9: Δ	Ilocated Ilocated n one nor the applic andwidth the meas Ilocated the applic <i>IplinkTxE</i> xcluding _{CRB} is the VM s the _{RB} is the	surement I RB to the RBs. For n-allocate cable freq n, based c surement I RB to the cable freq DirectCurr any allocate Transmis e limit for the starting fr	bandwidth is 1 RB and the lim measured average power per Pi/2 BPSK with Spectrum Sha d RB to the measured power uencies for this limit are those on symmetry with respect to the bandwidth is 1 RB and the lim measured total power in all a uencies for this limit depend of ent IE, and are those that are ated RB. ssion Bandwidth (see Clause ssion Bandwidth Configuration the modulation format used in requency offset between the a	it is expressed as a ratio of measured RB, where the average aping, the limit is expressed as a a in the allocated RB with highest Re that are enclosed in the reflection the carrier frequency, but excluding it is expressed as a ratio of measured RBs. In the parameter <i>txDirectCurrenti</i> enclosed in the RBs containing to 5.3).	ing is done across all ratio of measured power PSD on of the allocated g any allocated RBs. sured power in one non- <i>Location</i> in he DC frequency but
NOTE 3: T NOTE 4: T NOTE 4: T NOTE 5: T NOTE 5: L NOTE 6: L NOTE 7: N NOTE 8: E NOTE 9: 4	Ilocated Ilocated n one nor The applic andwidth The meas Ilocated The applic <i>LplinkTxL</i> xcluding $_{RB}$ is the $_{RB}$ is the $_{RB}$ is the the applic of the	surement I RB to the RBs. For n-allocate cable freq n, based c surement I RB to the cable freq DirectCurr any allocate Transmis e limit for t starting fr $_{3}$ = -1 for th	bandwidth is 1 RB and the lim measured average power pe Pi/2 BPSK with Spectrum Sha d RB to the measured power uencies for this limit are those on symmetry with respect to the bandwidth is 1 RB and the lim measured total power in all a uencies for this limit depend of <i>ent</i> IE, and are those that are ated RB. ssion Bandwidth (see Clause ssion Bandwidth Configuration the modulation format used in requency offset between the a ne first adjacent RB outside of	it is expressed as a ratio of measured RB, where the average aping, the limit is expressed as a a in the allocated RB with highest Re that are enclosed in the reflection are carrier frequency, but excluding it is expressed as a ratio of measured RBs. In the parameter <i>txDirectCurrenti</i> enclosed in the RBs containing to 5.3). In (see Clause 5.3). the allocated RBs. In the allocated RBs.	ing is done across all ratio of measured power PSD on of the allocated g any allocated RBs. sured power in one non- <i>Location</i> in he DC frequency but on-allocated RB (e.g. $\Delta_{\rm RF}$
NOTE 3: T NOTE 4: T NOTE 4: T NOTE 5: T NOTE 5: T NOTE 6: L NOTE 7: N NOTE 8: E NOTE 9: 2 NOTE 10: T	Ilocated Ilocated in one nor the applic andwidth the meas Ilocated the applic ZRB is the RB is the RB is the RB is the TOT Δ_{RB} P RB is a	surement I RB to the RBs. For n-allocate cable freq n, based c surement I RB to the cable freq DirectCurr any allocate Transmis e limit for t starting fr $_{3}$ = -1 for th	bandwidth is 1 RB and the lim measured average power pe Pi/2 BPSK with Spectrum Sha d RB to the measured power uencies for this limit are those on symmetry with respect to the bandwidth is 1 RB and the lim measured total power in all a uencies for this limit depend of <i>ent</i> IE, and are those that are ated RB. ssion Bandwidth (see Clause ssion Bandwidth Configuration the modulation format used in requency offset between the a ne first adjacent RB outside of e of the transmitted power over	it is expressed as a ratio of measured RB, where the average aping, the limit is expressed as a a in the allocated RB with highest Re that are enclosed in the reflection the carrier frequency, but excluding it is expressed as a ratio of measured RBs. In the parameter <i>txDirectCurrenti</i> enclosed in the RBs containing to 5.3).	ing is done across all ratio of measured power PSD on of the allocated g any allocated RBs. sured power in one non- <i>Location</i> in he DC frequency but on-allocated RB (e.g. $\Delta_{\rm RI}$

Table 6.4.2.3.4-1: Requirements for in-band emissions for power class 3

6.4.2.3.5 In-band emissions for power class 4

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.5-1 for power class 4 UEs.

Unit Limit (NOTE 1) Parameter Applicable description Frequencies General dB Any non-allocated $max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(|\Delta_{RB}| - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$ (NOTE 2) IQ Image dB -25 Output power > 21 dBm Image frequencies (NOTES 2, 3) -20 Output power ≤ 21 dBm dBc Carrier Carrier frequency -25 Output power > 11 dBm leakage (NOTES 4, 5) -20 -13 dBm ≤ Output power ≤ 11 dBm NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (P RB - 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. $\overline{P_{RB}}$ is defined in NOTE 10. NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs. NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs. NOTE 5: The applicable frequencies for this limit depend on the parameter txDirectCurrentLocation in UplinkTxDirectCurrent IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB. NOTE 6: L_{CRB} is the Transmission Bandwidth (see Clause 5.3). NOTE 7: N_{RB} is the Transmission Bandwidth Configuration (see Clause 5.3). NOTE 8: EVM s the limit for the modulation format used in the allocated RBs. NOTE 9: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. Δ_{RB} = 1 or Δ_{RB} = -1 for the first adjacent RB outside of the allocated bandwidth). NOTE 10: \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm. NOTE 11: All powers are EIRP in beam peak direction.

Table 6.4.2.3.5-1: Requirements for in-band emissions for power class 4

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6.4.2.3.6 In-band emissions for power class 5

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.6-1 for power class 5 UEs.

Parameter Applicable Unit Limit (NOTE 1) description Frequencies $max \begin{bmatrix} -25 & -10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(|\Delta_{RB}| - 1)}{L_{CRB}}, \end{bmatrix}$ Any non-allocated dB General (NOTE 2) -25 Output power > 17 dBm Image frequencies IQ Image dB -20 Output power ≤ 17 dBm (NOTES 2, 3) Carrier -25 Output power > 7 dBmCarrier frequency dBc -20 -6 dBm \leq Output power \leq 7 dBm leakage (NOTES 4, 5) NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (\overline{P}_{RB} - 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. $\overline{P_{RB}}$ is defined in NOTE 10. NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs. NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs. NOTE 5: The applicable frequencies for this limit depend on the parameter txDirectCurrentLocation in UplinkTxDirectCurrent IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB. NOTE 6: L_{CRB} is the Transmission Bandwidth (see Clause 5.3). NOTE 7: N_{RB} is the Transmission Bandwidth Configuration (see Clause 5.3). NOTE 8: EVM s the limit for the modulation format used in the allocated RBs. NOTE 9: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. Δ_{RB} = 1 or Δ_{RB} = -1 for the first adjacent RB outside of the allocated bandwidth). NOTE 10: \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm. NOTE 11: All powers are EIRP in beam peak direction.

Table 6.4.2.3.6-1: Requirements for in-band emissions for power class 5

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6.4.2.3.7 In-band emissions for power class 6

For power class 6, the in-band emissions requirement specified in clause 6.4.2.3.6 for power class 5 applies.

6.4.2.3.8 In-band emissions for power class 7

The average of the in-band emission specified in subclause 6.4.2.3.4 applies.

6.4.2.4 EVM equalizer spectrum flatness

The EVM measurement process (as described in Annex F) entails generation of a zero-forcing equalizer. The EVM equalizer spectrum flatness is defined in terms of the maximum peak-to-peak ripple of the equalizer coefficients (dB) across the allocated uplink block. The basic measurement interval is the same as for EVM.

For Pi/2 BPSK modulation, the minimum requirements are defined in Clause 6.4.2.5.

The peak-to-peak variation of the EVM equalizer coefficients contained within the frequency range of the uplink allocation shall not exceed the maximum ripple specified in Table 6.4.2.4-1 for normal conditions. For uplink allocations contained within both Range 1 and Range 2, the coefficients evaluated within each of these frequency ranges shall meet the corresponding ripple requirement and the following additional requirements: the relative difference between the maximum coefficient in Range 1 and the minimum coefficient in Range 2 (Table 6.4.2.4-1) must not be larger than 7 dB, and the relative difference between the maximum coefficient in Range 1 must not be larger than 8 dB (see Figure 6.4.2.4-1).

The requirement is verified with the test metric of EVM SF (Link=TX beam peak direction, Meas=Link angle).

Table 6.4.2.4-1: Minimum requirements for EVM equalizer spectrum flatness (normal conditions)

Frequency range	Maximum ripple (dB)	
F _{UL_Meas} – F_center ≤ X MHz	6 (p-p)	
(Range 1)		
F _{UL_Meas} – F_center > X MHz	9 (p-p)	
(Range 2)		
NOTE 1: FUL_Meas refers to the sub-carrier frequency for which the equalizer coefficient is evaluated		
NOTE 2: F_center refers to the center frequency of the CC		
NOTE 3: X, in MHz, is equal to 30 % of the CC bandwidth		

Table 6.4.2.4-2: (Void)

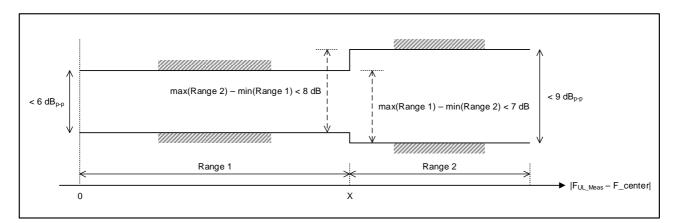


Figure 6.4.2.4-1: The limits for EVM equalizer spectral flatness with the maximum allowed variation of the coefficients indicated under normal conditions

6.4.2.5 EVM spectral flatness for Pi/2 BPSK modulation

These requirements are defined for Pi/2 BPSK modulation. The EVM equalizer coefficients across the allocated uplink block shall be modified to fit inside the mask specified in Table 6.4.2.5-1 for normal conditions, prior to the calculation of EVM. The limiting mask shall be placed to minimize the change in equalizer coefficients in a sum of squares sense.

Frequency range	Parameter	Maximum ripple (dB)
F _{UL_Meas} – F_center ≤ X MHz (Range 1)	X1	6 (p-p)
Ful_Meas – F_center > X MHz	X2	14 (p-p)
(Range 2)		
NOTE 1: FUL_Meas refers to the sub-carrier frequency for which the equalizer coefficient is evaluated NOTE 2: F_center refers to the center frequency of an allocated block of PRBs NOTE 3: X, in MHz, is equal to 25% of the bandwidth of the PRB allocation NOTE 4: See Figure 6.4.2.5-1 for description of X1, X2 and X3		



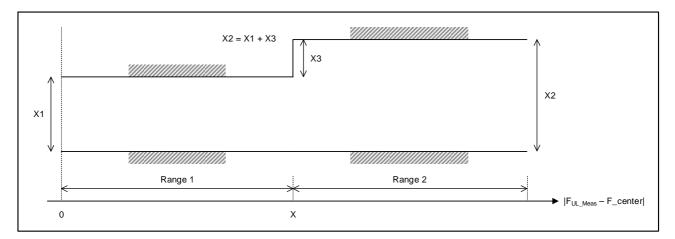


Figure 6.4.2.5-1: The limits for EVM equalizer spectral flatness with the maximum allowed variation. F_center denotes the center frequency of the allocated block of PRBs.

This requirement does not apply to other modulation types. The UE shall be allowed to employ spectral shaping for Pi/2 BPSK. The shaping filter shall be restricted so that the impulse response of the transmit chain shall meet

$$\left| \begin{array}{l} \tilde{a}_{t}(t,0) \right| \geq \left| \begin{array}{l} \tilde{a}_{t}(t,\tau) \right| \quad \forall \tau \neq 0 \\ 20 \log_{10} \left| \begin{array}{l} \tilde{a}_{t}(t,\tau) \right| < -15 \text{ dB} \quad 1 < \tau < \text{M} - 1, \end{array} \right.$$

Where:

 $|\tilde{a}_t(t,\tau)| = IDFT\{ |\tilde{a}_t(t,f)| e^{j\varphi(t,f)} \},$

f is the frequency of the M allocated subcarriers,

 $\tilde{a}(t,f)$ and $\phi(t,f)$ are the amplitude and phase response, respectively of the transmit chain

0dB reference is defined as $20\log_{10}$ [$\tilde{a}_t(t,0)$]

6.4.2.6 Phase continuity requirements for DMRS bundling

For bands that UE indicates the support of DMRS bundling, the maximum allowable difference between the measured phase value in any slot *p*-1 and slot *p* shall satisfy the requirements as listed in Table 6.4.2.6-1 for the measurement conditions defined in Table 6.4.2.6-2, within a measurement time window limited by the UE capability of maximum duration for DMRS bundling [maxDurationDMRS-Bundling-r17], and defined for each frequency band separately. The phase value for each slot is measured as shown in Annex F.8. These requirements apply to PUCCH and PUSCH transmissions with DFT-s-OFDM and CP-OFDM waveforms.

UL cł	nannel	Modulation order	Phase difference between any slot <i>p-1</i> and slot <i>p</i> (NOTE 2)
PU	SCH	Pi/2 BPSK, QPSK	[2E] degrees
PU	ССН	Pi/2 BPSK, BPSK, QPSK	[25] degrees
NOTE 1:	E 1: The UE capability of the length of maximum duration refers to the maximum time duration during which UE is		
	able to meet the phase continuity requirements, assuming no phase consistency violating events defined in		
	TS 38.214 in between.		
NOTE 2:	: This requirement applies for TDD bands, for supported DMRS bundling configurations ≤ 8 slots.		

Table 6.4.2.6-1: Maximum allowable phase difference for DMRS bundling

The above requirements are applicable when all the following conditions are met within the measurement time window.

- RB allocation in terms of length and frequency position does not change, and intra-slot and inter-slot frequency hopping is not activated.
- Modulation order does not change.
- No network commanded TA takes effect.
- The TPMI precoder does not change.
- There is no change in UE EIRP level, and no change in the level of P-MPR applied by the UE.
- UE is not scheduled with uplink transmission of other physical channel/signal in-between the PUSCH or PUCCH transmissions.
- For TDD, no downlink slot(s) or downlink symbol(s) or flexible symbol(s) with/without DL monitoring occasion configured in-between the PUSCH or PUCCH transmissions.
- No uplink beam switching occurs.

Table 6.4.2.6-2: Measurement conditions for the maximum allowable phase difference

Parameter	Unit	Level
UE EIRP	dBm	PUMAX, f, c in clause 6.2.4, P-
		MPR = 0
UE downlink received power		Not change
Operating conditions		Normal conditions
Transmission bandwidth		Confined within Ful_low + [4]
		MHz and FUL_high – [4] MHz
DL signal frequency		Not change before and during
		the measurement window
DL signal timing		Maintained constant before
		and during the measurement
		window
UL slots for testing		Tested on consecutive UL
		slots
PUSCH waveform for testing		DFT-s-OFDM

NOTE: Phase continuity requirements for DMRS bundling is defined only within FR2-1 in this release of the specification.

6.4A Transmit signal quality for CA

6.4A.0 General

For intra-band contiguous and non-contiguous carrier aggregation, the requirements in this clause apply if the UE has at least one of UL or DL configured for CA.

6.4A.1 Frequency error

The requirements in this clause apply to UEs of all power classes.

For intra-band contiguous and non-contiguous carrier aggregation, the UE basic measurement interval of modulated carrier frequency is 1 UL slot. The mean value of basic measurements of UE modulated carrier frequencies per band shall be accurate to within \pm 0.1 PPM observed over a period of 1ms of cumulated measurement intervals compared to the carrier frequency of primary component carrier received from the gNB.

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the frequency error requirement is specified in clause 6.4.1 and is applicable for each CC with all CCs active with non-zero UL RB allocation.

The frequency error is defined as a directional requirement. The requirement is verified in beam locked mode on beam peak direction.

6.4A.2 Transmit modulation quality

6.4A.2.0 General

For intra-band contiguous and non-contiguous carrier aggregation, the requirements in clauses 6.4A.2.1, 6.4A.2.2, and 6.4A.2.3.

All the parameters defined in clause 6.4A.2 are defined using the measurement methodology specified in Annex F.

All the requirements in 6.4A.2 are defined as directional requirement. The requirements are verified in beam locked mode on beam peak direction.

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the transmit modulation quality requirements are specified in clause 6.4.2 and are applicable for each CC with all CCs active with non-zero UL RB allocation.

6.4A.2.1 Error Vector magnitude

The requirements in this clause apply to UEs of all power classes. For intra-band contiguous and non-contiguous carrier aggregation, the Error Vector Magnitude requirement of clause 6.4.2.2 is defined for each component carrier. Requirements only apply with PRB allocation in one of the component carriers. Similar transmitter impairment removal procedures are applied for CA waveform before EVM calculation as is specified for non-CA waveform.

In case the parameter 3300 or 3301 is reported from UE via the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrenList* IE (as defined in TS 38.331 [13]), carrier leakage measurement requirement in clause 6.4A.2.2 and 6.4A.2.3 shall be waived, and the RF correction with regard to the carrier leakage and IQ image shall be omitted during the calculation of transmit modulation quality.

For intra-band contiguous and non-contiguous carrier aggregation, the UE is defined to be configured for CA operation when it has at least one of UL or DL configured for CA.

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the Error Vector Magnitude requirements are specified in clause 6.4.2.1 and are applicable for each CC with all CCs active with non-zero UL RB allocation.

6.4A.2.2 Carrier leakage

6.4A.2.2.1 General

Carrier leakage is an additive sinusoid waveform. The carrier leakage requirement is defined for each component carrier and is measured on the component carrier with PRBs allocated. The measurement interval is one slot in the time domain.

Note: When UE has DL configured for intra-band non-contiguous CA, carrier leakage may land outside the spectrum occupied by all configured UL and DL CC.

The relative carrier leakage power is a power ratio of the additive sinusoid waveform and the modulated waveform. The requirement is verified with the test metric of Carrier Leakage (Link=TX beam peak direction, Meas=Link angle).

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6.4A.2.2.2 Carrier leakage for power class 1

For intra-band contiguous and non-contiguous carrier aggregation, when carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.2-1 and Table 6.4A.2.2.2-2 for power class 1 UEs.

Table 6.4A.2.2.2-1: Minimum requirements for relative carrier leakage for power class 1 in FR2-1

Parameters	Relative Limit (dBc)
EIRP > 17 dBm	-25
4 dBm ≤ EIRP ≤ 17 dBm	-20

Table 6.4A.2.2.2-2: Minimum requirements for relative carrier leakage for power class 1 in FR2-2

Parameters	Relative Limit (dBc)
EIRP > 13.4 dBm	-25
0.4 dBm ≤ EIRP ≤ 13.4 dBm -20	
NOTE: Not applicable for Intraband non-contiguous carrier aggregation	

6.4A.2.2.3 Carrier leakage for power class 2

For intra-band contiguous and non-contiguous carrier aggregation, when carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.3-1 and Table 6.4A.2.2.3-2 for power class 2.

Table 6.4A.2.2.3-1: Minimum requirements for relative carrier leakage power class 2 in FR2-1

Parameters	Relative limit (dBc)
EIRP > 6 dBm	-25
-13 dBm ≤ EIRP ≤ 6 dBm	-20

Table 6.4A.2.2.3-2: Minimum requirements for relative carrier leakage power class 2 in FR2-2

Parameters	Relative limit (dBc)
EIRP > 5.8 dBm	-25
-13.2 dBm ≤ EIRP ≤ 5.8 dBm	-20
NOTE: Not applicable for Intraband non-contiguous carrier aggregation	

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the carrier leakage requirements are specified in clause 6.4.2.2.3 and are applicable for each CC with all CCs active with non-zero UL RB allocation.

6.4A.2.2.4 Carrier leakage for power class 3

For intra-band contiguous and non-contiguous carrier aggregation, when carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.4-1 and Table 6.4A.2.2.4-2 for power class 3 UEs.

Table 6.4A.2.2.4-1: Minimum requirements for relative carrier leakage power class 3 in FR2-1

Parameters	Relative limit (dBc)
Output power > 0 dBm	-25
-13 dBm ≤ Output	-20
power EIRP ≤ 0 dBm	

Table 6.4A.2.2.4-2: Minimum requirements for relative carrier leakage power class 3 in FR2-2

Parameters	Relative limit (dBc)
Output power > -1.9 dBm	-25
-14.9 dBm ≤ Output power EIRP ≤ -1.9 dBm -20	
NOTE: Not applicable for Intraband non-contiguous carrier aggregation	

6.4A.2.2.5 Carrier leakage for power class 4

For intra-band contiguous and non-contiguous carrier aggregation, when carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.5-1 for power class 4 UEs.

Table 6.4A.2.2.5-1: Minimum requirements for relative carrier leakage power class 4

Parameters	Relative limit (dBc)
Output power > 11 dBm	-25
-13 dBm ≤ Output	-20
power EIRP ≤ 11 dBm	-20

6.4A.2.2.6 Carrier leakage for power class 5

For intra-band contiguous and non-contiguous carrier aggregation, when carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.6-1 for power class 5 UEs.

Table 6.4A.2.2.6-1: Minimum requirements for relative carrier leakage power class 5

Parameters	Relative limit (dBc)
Output power > 7 dBm	-25
-6 dBm ≤ Output power EIRP ≤ 7 dBm	-20

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the carrier leakage requirements are specified in clause 6.4.2.2.6 and are applicable for each CC with all CCs active with non-zero UL RB allocation.

6.4A.2.3 Inband emissions

6.4A.2.3.1 General

For intra-band contiguous and non-contiguous carrier aggregation, the Inband emission requirement is defined over the spectrum occupied by all configured UL and DL CCs. The measurement interval is as defined in clause 6.4.2.4. The requirement is verified with the test metric of In-band emission (Link=TX beam peak direction, Meas=Link angle).

For intra-band contiguous and non-contiguous carrier aggregation, the requirements in this clause apply with all component carriers active and with one single contiguous PRB allocation in one of uplink component carriers. The inband emission is defined as the interference falling into the non-allocated resource blocks for all component carriers.

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the in-band emissions requirements are applicable for each CC with all CCs active with non-zero UL RB allocation.

6.4A.2.3.2 Inband emissions for power class 1

For intra-band contiguous and non-contiguous carrier aggregation, the average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.2-1 for power class 1 UEs.

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the in-band emissions requirements are specified in clause 6.4.2.3.2 and are applicable for each CC with all CCs active with non-zero UL RB allocation.

Parameter description	Unit		Limit (NOTE 1)		Applicable Frequencies		
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$		Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)		
			Output power for FR2-1	Output Power for FR2-2			
IQ Image	dB	-25	Output power > 27 dBm	> 23.4 dBm	Image frequencies (NOTES 2, 3)		
		-20	Output power ≤ 27 dBm	≤ 23.4 dBm			
Carrier leakage	dBc	-25	Output power > 17 dBm	> 13.4 dBm	Carrier frequency (NOTES 4, 5)		
		-20	4 dBm ≤ Output power ≤ 17 dBm	0.4 dBm ≤ Output power ≤ 13.4 dBm			
 NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD. NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RBs. NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB. NOTE 6: L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1). NOTE 7: EVM s the limit for the modulation format used in the allocated RBs. NOTE 8: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. Δ_{RB} = 1 or Δ_{RB} = -1 for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the 							
	·	0	is not a multiple of RB. mitted power over 10 sub-fran	nes normalized by the number	r of allocated RBs,		
		in dBm. s are EIRP in beam pea	ak direction.				

6.4A.2.3.3 Inband emissions for power class 2

For intra-band contiguous and non-contiguous carrier aggregation, the average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.3-1 for power class 2.

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the in-band emissions requirements are specified in clause 6.4.2.3.3 and are applicable for each CC with all CCs active with non-zero UL RB allocation.

Parameter description	Unit		Applicable Frequencies						
General	dB		Г (Маг	· \ 7	Any non-allocated				
Contrai	чъ		$\begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RE}}{L_{CR}}\right) \end{bmatrix}$	<u>,</u>),	RB in allocated				
			U.S.	B	component carrier				
			$\max \left 20. \log_{10}(\text{EVM}) - 5. \frac{(\Delta_{RI})}{L_0} \right $	$\frac{B}{B} = \frac{1}{2}$,	and not allocated				
				CRB	component carriers				
			$-55.1 dBm - \overline{P_{RB}}$		(NOTE 2)				
			Output power for FR2-1	Output Power for FR2-2					
IQ Image	dB	-25	Output power > 16 dBm	Output power > 15.8 dBm	Image frequencies (NOTES 2, 3)				
		-20	Output power ≤ 16 dBm	Output power ≤ 15.8 dBm					
Carrier leakage	dBc	-25	Output power > 6 dBm	Output power > 5.8 dBm	Carrier frequency (NOTES 4, 5)				
		-20	6 dBm	-13.2 dBm ≤ Output power ≤ 5.8 dBm					
NOTE 1: An	in-ban	d emissions combined	limit is evaluated in each non-	allocated RB. For each such I	RB, the minimum				
			higher of $(P_{RB} - 25 \text{ dB})$ and oply. P_{RB} is defined in NOTE	-	ies (General, IQ				
RE Pi/	3 to the /2 BPSk	measured average pov (with Spectrum Shapir	1 RB and the limit is expressed wer per allocated RB, where th ng, the limit is expressed as a ated RB with highest PSD.	ne averaging is done across a	II allocated RBs. For				
			e specified in relation to either	UL or DL carrier frequency.					
NOTE 4: Th	e meas	urement bandwidth is ?	1 RB and the limit is expressed	d as a ratio of measured powe	er in one non-allocated				
		measured total power							
			is limit are those that are encl		e DC frequency, or in				
			nt to the DC frequency but exc						
			dth for kth allocated compone n format used in the allocated						
					ed RR (e.g. $\Lambda_{nn} = 1$ or				
Δ_R	$_{B}^{-} = -1$ fo	The starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the spacing between the CCs is not a multiple of RB.							
NOTE 9: P	_{RB} is a	in average of the transi	mitted power over 10 sub-fram	nes normalized by the number	of allocated RBs,				
		in dBm.							
NOTE 10: All	powers	are EIRP in beam pea	ak direction.						

Table 6.4A.2.3.3-1: Requirements for in-band emissions for power class 2

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6.4A.2.3.4 Inband emissions for power class 3

For intra-band contiguous and non-contiguous carrier aggregation, the average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.4-1 for power class 3 UEs.

Parameter description	Unit		Applicable Frequencies Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)		
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$			
			Output power for FR2-1	Output Power for FR2-2	
IQ Image	dB	-25	Output power > 10 dBm	> 8.1 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 10 dBm	≤ 8.1 dBm	
Carrier leakage	dBc	-25	Output power > 0 dBm	> -1.9dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 0 dBm	-14.9 dBm ≤ Output power ≤ -1.9 dBm	

Table 6.4A.2.3.4-1: Requirements for in-band emissions for power class 3

NOTE 1:	An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum
	requirement is calculated as the higher of ($\overline{P_{RB}}$ - 25 dB) and the power sum of all limit values (General, IQ
	Image or Carrier leakage) that apply. P_{RB} is defined in NOTE 9.
NOTE 2:	The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
NOTE 3:	Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency.
NOTE 4:	The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
NOTE 5:	The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
NOTE 6:	L _{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
NOTE 7:	EVM s the limit for the modulation format used in the allocated RBs.
NOTE 8:	Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
NOTE 9:	P RB is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs,
	measured in dBm.
NOTE 10:	All powers are EIRP in beam peak direction.

6.4A.2.3.5 Inband emissions for power class 4

For intra-band contiguous and non-contiguous carrier aggregation, the average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.5-1 for power class 4 UEs.

Parameter description	Unit		Applicable Frequencies	
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}}, \end{bmatrix}$		Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25	Output power > 21 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 21 dBm	
Carrier leakage	dBc	-25	Output power > 11 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 11 dBm	

Table 6.4A.2.3.5-1: Requirements for in-band emissions for power class 4

NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (P RB - 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. $\overline{P_{RB}}$ is defined in NOTE 9. NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD. Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. NOTE 3: NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs. NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB. L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1). NOTE 6: EVM s the limit for the modulation format used in the allocated RBs. NOTE 7: NOTE 8: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. Δ_{RB} = 1 or Δ_{RB}^{-} = -1 for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB. NOTE 9: $\overline{P_{RB}}$ is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm. NOTE 10: All powers are EIRP in beam peak direction.

6.4A.2.3.6 Inband emissions for power class 5

For intra-band contiguous and non-contiguous carrier aggregation, the average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.6-1 for power class 6 UEs.

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the in-band emissions requirements are specified in clause 6.4.2.3.6 and are applicable for each CC with all CCs active with non-zero UL RB allocation.

Parameter description	Unit		Applicable Frequencies	
General	dB		Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)	
IQ Image	dB	-25 -20	Image frequencies (NOTES 2, 3)	
Carrier leakage	dBc	-25 -20	Output power > 7 dBm -6 dBm ≤ Output power ≤ 7 dBm	Carrier frequency (NOTES 4, 5)

Table 6.4A.2.3.6-1: R	Requirements for in-band	emissions for power class 5
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NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB. the minimum requirement is calculated as the higher of (P RB - 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. P_{RB} is defined in NOTE 9. NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD. NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs. NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB. NOTE 6: L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1). NOTE 7: EVM s the limit for the modulation format used in the allocated RBs. NOTE 8: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or Δ_{RB}^{-} = -1 for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB. NOTE 9: P_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm. NOTE 10: All powers are EIRP in beam peak direction.

6.4A.2.4 EVM equalizer spectrum flatness

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the EVM equalizer spectrum flatness requirements are specified in clause 6.4.2.4 and are applicable for each CC with all CCs active with non-zero UL RB allocation.

6.4D Transmit signal quality for UL MIMO

6.4D.0 General

references to sub-clauses 6.3.1.x in clause 6.4 redirected to sub-clauses 6.3D.1.x, where 'x' depends on power class. The requirements apply when the UE is configured for 2-layer UL MIMO transmission as specified in Table 6.2D.1.0-1.

The requirement may alternatively be verified in each of the single layer UL MIMO configurations as specified in Table 6.4D.0-1. In this case, the transmit modulation quality requirements in clause 6.4 apply without modification.

 Table 6.4D.0-1: Alternative UL MIMO configuration for transmit signal quality tests

Transmission scheme	DCI format	TPMI Index
Codebook based uplink	DCI format 0_1	0
Codebook based uplink	DCI format 0_1	1

6.4D.1 Frequency error for UL MIMO

For a UE supporting UL MIMO, the UE basic measurement interval of modulated carrier frequency is 1 UL slot. The mean value of basic measurements of UE modulated carrier frequency at each layer shall be accurate to within \pm 0.1 PPM observed over a period of 1ms of cumulated measurement intervals compared to the carrier frequency received from the NR Node B.

6.4D.2 Transmit modulation quality for UL MIMO

For UE supporting UL MIMO, the transmit modulation quality requirements are specified per layer in terms of:

Error Vector Magnitude (EVM) for the allocated resource blocks (RBs)

EVM equalizer spectrum flatness derived from the equalizer coefficients generated by the EVM measurement process

Carrier leakage (caused by IQ offset)

For UE supporting UL MIMO, the transmit modulation quality requirements are specified as the total component of EIRP in terms of:In-band emissions for the non-allocated RB

The requirements are defined as directional requirements. The requirements are verified in beam locked mode in the TX beam peak direction (Link=TX beam peak direction, Meas=Link angle).

In case the parameter 3300 or 3301 is reported from UE via the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrentList* IE (as defined in TS 38.331 [13]), carrier leakage measurement requirement in clause 6.4D.2.2 and 6.4D.2.3 shall be waived, and the RF correction with regard to the carrier leakage and IQ image shall be omitted during the calculation of transmit modulation quality.

6.4D.3 Time alignment error for UL MIMO

For a UE with multiple physical antenna ports supporting UL MIMO, this requirement applies to frame timing differences between transmissions on multiple physical antenna ports in the codebook transmission scheme.

The time alignment error (TAE) is defined as the average frame timing difference between any two transmissions on different physical antenna ports.

For a UE with multiple physical antenna ports, the Time Alignment Error (TAE) shall not exceed 130 ns.

6.4D.4 Requirements for coherent UL MIMO

For coherent UL MIMO, Table 6.4D.4-1 lists the maximum allowable difference between the measured relative power and phase errors between different physical antenna ports in any slot within the specified time window from the last transmitted SRS on the same antenna ports, for the purpose of uplink transmission (codebook or non-codebook usage) and those measured at that last SRS. The requirements in Table 6.4D.4-1 apply when the UL transmission power at each physical antenna port is larger than 0 dBm for SRS transmission and for the duration of time window. The requirement is verified with the test metric of EIRP (Link=TX Beam peak direction, Meas=Link angle).

Table 6.4D.4-1: Maximum allowable difference of relative phase and power errors in a given slot compared to those measured at last SRS transmitted

Difference of relative phase error	Difference of relative power error	Time window
40 degrees	4 dB	20 msec

The above requirements apply when all of the following conditions are met within the specified time window:

- UE is not signaled with a change in number of SRS ports in SRS-config, or a change in PUSCH-config
- UE remains in DRX active time (UE does not enter DRX OFF time)
- No measurement gap occurs
- No instance of SRS transmission with the usage antenna switching occurs
- Active BWP remains the same
- EN-DC and CA configuration is not changed for the UE (UE is not configured or de-configured with PScell or SCell(s))

6.5 Output RF spectrum emissions

6.5.1 Occupied bandwidth

Occupied bandwidth is defined as the bandwidth containing 99 % of the total integrated mean power of the transmitted spectrum on the assigned channel. The occupied bandwidth for all transmission bandwidth configurations (Resources Blocks) shall be less than the channel bandwidth specified in Table 6.5.1-1.

The occupied bandwidth is defined as a directional requirement. The requirement is verified in beam locked mode with the test metric of OBW (Link=TX beam peak direction, Meas=Link angle).

Table 6.5.1-1: Occupied channel bandwidth	
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	Occupied channel bandwidth / Channel bandwidth								
	50	50 100 200 400 800 MHz 1600 MHz 2000 MHz							
	MHz	MHz	MHz	MHz					
Channel bandwidth (MHz)	50	100	200	400	800	1600	2000		

6.5.2 Out of band emissions

6.5.2.0 General

The Out of band emissions are unwanted emissions immediately outside the assigned channel bandwidth resulting from the modulation process and non-linearity in the transmitter but excluding spurious emissions. This out of band emission limit is specified in terms of a spectrum emission mask and an adjacent channel leakage power ratio. Additional requirements to protect specific bands are also considered.

The requirements in clause 6.5.2.1 only apply when both UL and DL of a UE are configured for single CC operation, and they are of the same bandwidth. For a UE that is configured for single CC operation with different channel bandwidths in UL and DL, the requirements in clause 6.5A.2.1 apply.

All out of band emissions for frequency range 2 are TRP.

6.5.2.1 Spectrum emission mask

The spectrum emission mask of the UE applies to frequencies (Δf_{OOB}) starting from the ± edge of the assigned NR channel bandwidth. For frequencies offset greater than F_{OOB} as specified in Table 6.5.2.1-1 the spurious requirements in clause 6.5.3 are applicable.

The power of any UE emission shall not exceed the levels specified in Table 6.5.2.1-1 for the specified channel bandwidth. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

	Spectrum emission limit (dBm) / Channel bandwidth							
Δf _{оов} (MHz)	50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz	Measurement bandwidth
± 0-5	-5	-5	-5	-5	-5	-5	-5	1 MHz
± 5-10	-13	-5	-5	-5	-5	-5	-5	1 MHz
± 10-20	-13	-13	-5	-5	-5	-5	-5	1 MHz
± 20-40	-13	-13	-13	-5	-5	-5	-5	1 MHz
± 40-80	-13	-13	-13	-13	-5	-5	-5	1 MHz
± 80-100	-13	-13	-13	-13	-13	-5	-5	1 MHz
± 100-160		-13	-13	-13	-13	-5	-5	1 MHz
± 160-200		-13	-13	-13	-13	-13	-5	1 MHz
± 200-400			-13	-13	-13	-13	-13	1 MHz
± 400-800				-13	-13	-13	-13	1 MHz
± 800-1600					-13	-13	-13	1 MHz
± 1600-						-13	-13	1 MHz
3200								
± 3200-							-13	1 MHz
4000								
NOTE 1: Vo	id							

Table 6.5.2.1-1: General NR spectrum emission mask for frequency range 2.

6.5.2.2 Void

6.5.2.3 Adjacent channel leakage ratio

Adjacent Channel Leakage power Ratio (ACLR) is the ratio of the filtered mean power centred on the assigned channel frequency to the filtered mean power centred on an adjacent channel frequency. ACLR requirement is specified for a scenario in which adjacent carrier is another NR channel.

NR Adjacent Channel Leakage power Ratio (NR_{ACLR}) is the ratio of the filtered mean power centred on the assigned channel frequency to the filtered mean power centred on an adjacent channel frequency at nominal channel spacing. The assigned NR channel power and adjacent NR channel power are measured with rectangular filters with measurement bandwidths specified in Table 6.5.2.3-1 for FR2-1 and in Table 6.5.2.3-2 for FR2-2.

If the measured adjacent channel power is greater than -35 dBm then the NR_{ACLR} shall be higher than the value specified in Table 6.5.2.3-1. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

	Channel ba	ndwidth / NRA	CLR / Measureme	ent bandwidth
	50 MHz	100 MHz	200 MHz	400 MHz
NR _{ACLR} for band n257, n258, n261	17 dB	17 dB	17 dB	17 dB
NR _{ACLR} for band n259, n260, n262	16 dB	16 dB	16 dB	16 dB
NR channel measurement bandwidth (MHz)	47.58	95.16	190.20	380.28
Adjacent channel centre frequency offset (MHz)	+50 / -50	+100 / -100	+200 / -200	+400 / -400

	Char	nnel bandwidt	h / NR _{ACLR} / Me	easurement ban	dwidth
	100 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
NR _{ACLR} for band n263	15dB	15 dB	15 dB	15 dB	15 dB
NR channel measurement bandwidth (MHz)	95.16	381.12	715.20	1429.44	1705.92
Adjacent channel centre frequency offset (MHz)	+100 / -100	+400 / -400	+800 / -800	+1600 / -1600	+2000 / -2000

Table 6.5.2.3-2: General requirements for NR_{ACLR} for FR2-2

6.5.3 Spurious emissions

Spurious emissions are emissions which are caused by unwanted transmitter effects such as harmonics emission, parasitic emissions, intermodulation products and frequency conversion products, but exclude out of band emissions unless otherwise stated. The spurious emission limits are specified in terms of general requirements in line with SM.329 [7] and NR operating band requirement to address UE co-existence. Spurious emissions are measured as TRP.

To improve measurement accuracy, sensitivity and efficiency, the resolution bandwidth may be smaller than the measurement bandwidth. When the resolution bandwidth is smaller than the measurement bandwidth, the result should be integrated over the measurement bandwidth in order to obtain the equivalent noise bandwidth of the measurement bandwidth.

Unless otherwise stated, the spurious emission limits apply for the frequency ranges that are more than F_{OOB} (MHz) in Table 6.5.3-1 starting from the edge of the assigned NR channel bandwidth. The spurious emission limits in Table 6.5.3-2 apply for all transmitter band configurations (NRB) and channel bandwidths. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

Channel bandwidth	50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
OOB boundary F _{OOB} (MHz)	100	200	400	800	1600	3200	4000

Table 6.5.3-1: Boundary between NR out of band and spurious emission domain

Table 6.5.3-2: Spurious emissions limits	S
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Frequency Range	Maximum Level	Measurement bandwidth
30 MHz ≤ f < 1000 MHz	-36 dBm	100 kHz
1 GHz ≤ f < 12.75 GHz	-30 dBm	1 MHz
12.75 GHz ≤ $f ≤ 2^{nd}$ harmonic of the upper frequency edge of the UL operating band in GHz	-13 dBm	1 MHz

6.5.3.1 Spurious emission band UE co-existence

This clause specifies the requirements for the specified NR band, for coexistence with protected bands.

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NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

NR Band	Spurious emission								
	Protected band/frequency range	Frequency range (MHz)			Maximum Level (dBm)	MBW (MHz)	NOTE		
n257	NR Band n260	F _{DL_low}	-	F_{DL_high}	-2	100			
	NR Band n263	F_{DL_low}	-	F_{DL_high}	TBD	100			
	Frequency range	57000	-	66000	2	100			
	Frequency range	23600	-	24000	1	200	3		
n258	NR Band n263	$F_{DL_{low}}$	-	F_{DL_high}	TBD	100			
	Frequency range	57000	-	66000	2	100			
n259	NR Band 257	FDL_low	-	FDL_high	-5	100			
	NR Band 261	F _{DL_low}	-	F _{DL_high}	-5	100			
	NR Band 262	F _{DL_low}	-	F _{DL_high}	-5	100			
	NR Band n263	F _{DL_low}	-	F _{DL_high}	TBD	100			
	Frequency range	36000	-	37000	7	1000			
F	Frequency range	57000	-	66000	2	100			
n260	NR Band 257	F _{DL_low}	-	F _{DL_high}	-5	100			
	NR Band 261	F _{DL_low}	-	FDL_high	-5	100			
	NR Band 262	F _{DL_low}	-	F _{DL_high}	-5	100			
	NR Band n263	F _{DL_low}	-	FDL_high	TBD	100			
	Frequency range	57000	-	66000	2	100			
n261	NR Band 260	F _{DL_low}	-	F_{DL_high}	-2	100			
	NR Band n263	F _{DL_low}	-	FDL_high	TBD	100			
	Frequency range	57000	-	66000	2	100			
n262	NR Band 260	$F_{DL_{low}}$	-	F_{DL_high}	-2	100			
	NR Band 261	F _{DL_low}	-	FDL_high	-5	100			
	NR Band n263	F _{DL_low}	-	FDL_high	TBD	100			
	Frequency range	57000	-	66000	2	100			
n263	NR Band 257	F _{DL_low}	-	FDL_high	-5	100			
	NR Band 258	F _{DL_low}	-	FDL_high	-5	100			
	NR Band 259	F _{DL_low}	-	F _{DL_high}	-5	100			
	NR Band 260	FDL low	-	FDL_high	-2	100			
	NR Band 261	F _{DL_low}	-	FDL_high	-5	100			
	NR Band 262	F _{DL_low}	-	F _{DL_high}	-5	100			
NOTE 2:	F _{DL_low} and F _{DL_high} refer to each NR f Void The protection of frequency range 23					of satellite passive	services.		

Table 6.5.3.1-1: Requirements

6.5.3.2 Additional spurious emissions

6.5.3.2.1 General

These requirements are specified in terms of an additional spectrum emission requirement. Additional spurious emission requirements are signalled by the network to indicate that the UE shall meet an additional requirement for a specific deployment scenario as part of the cell handover/broadcast message.

6.5.3.2.2 Void

Table 6.5.3.2.2-1: (Void)

6.5.3.2.3 Additional spurious emission requirements for NS_202

When "NS_202" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.3-1.

Frequency Range	Maximum Level	Measurement bandwidth	NOTE				
7.25 GHz \leq f \leq 2 nd harmonic of the upper frequency edge of the UL operating band	-10 dBm	100 MHz					
23.6 GHz ≤ f ≤ 24.0 GHz	+1 dBm	200 MHz	1				
NOTE 1: This requirement also applies for the frequency ranges that are less than F _{OOB} (MHz) in Table 6.5.3-1 from the edge of the channel bandwidth. The protection of frequency range 23600 - 24000 MHz is meant for protection of satellite passive services.							

Table 6.5.3.2.3-1: Additional requirements (NS_202)

6.5.3.2.4 Additional spurious emission requirements for NS_203

When "NS_203" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.4-1. This requirement also applies for the frequency ranges that are less than F_{OOB} (MHz) in Table 6.5.3-1 from the edge of the channel bandwidth.

Frequency band (GHz)	Spectrum emission limit (dBm)	Measurement bandwidth
$23.6 \le f \le 24.0$	+1	200 MHz

6.5.3.2.5 Additional spurious emission requirements for NS_204

When "NS_204" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.5-1. This requirement also applies for the frequency ranges that are less than F_{OOB} (MHz) in Table 6.5.3-1 from the edge of the channel bandwidth.

Frequency band (GHz)	Spectrum emission limit (dBm)	Measurement bandwidth
TBD	TBD	TBD

6.5A Output RF spectrum emissions for CA

6.5A.1 Occupied bandwidth for CA

6.5A.1.0 General

The occupied bandwidth for UL CA is defined as a directional requirement. The requirement is verified in beam locked mode on beam peak direction. In case the intra-band CA configuration consists of a single UL CC, the occupied bandwidth requirement defined in subclause 6.5.1 applies.

6.5A.1.1 Occupied bandwidth for intra-band contiguous UL CA

For intra-band contiguous UL carrier aggregation, the occupied bandwidth is a measure of the bandwidth containing 99 % of the total integrated power of the transmitted spectrum. The occupied bandwidth for UL CA shall be less than the UL aggregated channel bandwidth defined in clause 5.3A.

6.5A.1.2 Occupied bandwidth for intra-band non-contiguous UL CA

For intra-band non-contiguous UL carrier aggregation, the occupied bandwidth requirement is met when the ratio of the transmitted power in all sub-blocks of the UL CA configuration to the total integrated power of the transmitted spectrum is greater than 99%.

6.5A.1.3 Occupied bandwidth for inter-band UL CA

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the occupied bandwidth requirements is specified in clause 6.5.1 and is applicable for each CC with all CCs active with non-zero UL RB allocation.

6.5A.2 Out of band emissions

6.5A.2.1 Spectrum emission mask for CA

6.5A.2.1.0 General

For intra-band CA, the requirements specified in this clause shall apply if the UE has at least one of UL or DL configured for CA or if the UE is configured for single CC operation with different channel bandwidths in UL and DL carriers. In case the CA configuration consists of a single UL CC, spectrum emission mask defined in subclause 6.5.2.1 applies. Spectral emission mask requirements do not apply at any frequency where IBE requirements of clause 6.4A.2.3 apply.

The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

6.5A.2.1.1 Spectrum emission mask for intra-band contiguous UL CA

For intra-band contiguous UL carrier aggregation, the spectrum emission mask of the UE applies to frequencies (Δf_{OOB}) starting from the \pm edge of the UL aggregated channel bandwidth (Table 5.3A.5-1). For any bandwidth class defined in Table 5.3A.5-1, the UE emission shall not exceed the levels specified in Table 6.5A.2.1-1.

Table 6.5A.2.1.1-1: General NR spectrum emission mask for intra-band contiguous CA in FR2-1 and FR2-2

<u> </u> Δfоов (MHz)	Any carrier aggregation bandwidth class	Measurement bandwidth
\pm 0-0.1*BW _{Channel_CA}	-5	1 MHz
$\pm0.1^*BW_{Channel_CA}$ -	-13	1 MHz
2*BWChannel_CA		
NOTE 1: (void)		

6.5A.2.1.2 Spectrum emission mask for intra-band non-contiguous UL CA

For intra-band non-contiguous UL carrier aggregation, the spectrum emission mask requirement is defined as a composite spectrum emissions mask. Composite spectrum emission mask applies to frequencies up to $\pm \Delta f_{OOB}$ starting from the edge of each UL sub-block. Composite spectrum emission mask is defined as follows:

- a) Composite spectrum emission mask is a combination of individual spectrum emissions masks defined for each sub-block. If for some frequency, spectrum emission masks from multiple sub-blocks overlap, the spectrum emission mask allowing the highest power spectral density applies for that frequency
- b) In case a sub-block comprises of multiple component carriers, the spectrum emissions mask is defined in subclause 6.5A.2.1.1 or in case of a single component carrier, the sub-block spectrum emission mask is defined in subclause 6.5.2.1
- c) If for some frequency the spectrum emission mask of one sub-block overlaps another sub-block, the emission mask does not apply for that frequency.

d) If carrier leakage or I/Q image lands inside the spectrum occupied by the configured UL and DL CCs, exception to the general spectrum emission mask limit applies. For carrier leakage the requirements specified in section 6.4A.2.2 shall apply. For I/Q image the requirements specified in section 6.4A.2.3 shall apply.

6.5A.2.1.3 Spectrum emission mask for inter-band UL CA

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the spectrum emission mask is specified in Table 6.5.2.1-1 for each CC separately while both CCs are active with non-zero UL RB allocation. If for some frequency spectrum emission masks of CCs overlap, then spectrum emission mask allowing higher power spectral density applies for that frequency. If for some frequency a CC spectrum emission mask overlaps with the channel bandwidth of another CC, then the emission mask does not apply for that frequency.

6.5A.2.3 Adjacent channel leakage ratio for CA

6.5A.2.3.1 Adjacent channel leakage ratio for CA intra-band contiguous UL CA

In case the CA configuration consists of a single UL CC, the adjacent channel leakage ratio defined in subclause 6.5.2.3 applies. For intra-band contiguous UL carrier aggregation, the carrier aggregation NR adjacent channel leakage power ratio (CA NR_{ACLR}) is the ratio of the filtered mean power centred on the UL aggregated channel bandwidth to the filtered mean power centred on an adjacent UL aggregated channel bandwidth at spacing equal to the UL aggregated channel bandwidth. The assigned UL aggregated channel bandwidth power and adjacent UL aggregated channel bandwidth power are measured with rectangular filters with measurement bandwidths specified in Table 6.5A.2.3.1-1. If the measured adjacent channel power is greater than -35 dBm then the CA NR_{ACLR} shall be higher than the value specified in Table 6.5A.2.3.1-1.

	CA bandwidth class / CA NR _{ACLR} / Measurement bandwidth
	Any CA bandwidth class
CA NR _{ACLR} for band n257, n258, n261	17 dB
CA NR _{ACLR} for band n259, n260, n262	16 dB
CA NR _{ACLR} for band n263	15 dB
NR channel measurement bandwidth ¹	BW _{Channel_CA} - 2*BW _{GB}
Adjacent channel centre frequency offset (in MHz)	+ BW _{Channel_CA} /
	- BWChannel_CA
NOTE 1: BW _{GB} is defined in clause 5.3A.2.	

Table 6.5A.2.3.1-1: General requirements for contiguous UL CA NR_{ACLR}

6.5A.2.3.2 Adjacent channel leakage ratio for CA intra-band non-contiguous UL CA

For intra-band non-contiguous carrier aggregation, adjacent channel leakage power ratio (CA NR_{ACLR}) is the ratio of the sum of the filtered mean powers centred on each sub-block bandwidth to the filtered mean power centred on an adjacent sub-block frequency at nominal spacing equal to the sub-block bandwidth. The power in the configured UL CCs and power in the sub-block bandwidth adjacent to each sub-block of configured UL CCs are measured with rectangular filters with measurement bandwidths specified in Table 6.5A.2.3.1-2. In case a sub-block consists of a single component carrier, the measurement bandwidths and adjacent frequency offset from subclause 6.5.2.3 shall be used. If the measured adjacent sub-block power is greater than -35 dBm then the CA NR_{ACLR} shall be higher than the value specified in Table 6.5A.2.3.1-2.

No requirement applies in the gap between neighbouring sub-blocks if the frequency span between the lowest edge of the upper sub-block and the highest edge of the lower sub-block is smaller than the bandwidth of either sub-block.

	CA bandwidth class / CA NR _{ACLR} / Measurement bandwidth
	Any CA bandwidth class
CA NR _{ACLR} for band n257, n258, n261	17 dB
CA NR _{ACLR} for band n260	16 dB
CA NR _{ACLR} for band n263	15 dB
NR channel measurement bandwidth ¹	$\Sigma(BW_{Channel,block})$
Adjacent sub-block centre frequency offset (in MHz)	+ BW _{Channel,block} / - BW _{Channel_block}
NOTE 1: BWChannel_block is defined in clause NOTE 2: 'Adjacent sub-block centre frequency off configuration	

Table 6.5A.2.3.1-2: General requirements for NC UL CA NR_{ACLR}

6.5A.2.3.3 Adjacent channel leakage ratio for CA inter-band UL CA

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the NR Adjacent Channel Leakage power Ratio (NR_{ACLR}) is applicable for each CC while both CCs are active with non-zero UL RB allocation and the requirement is specified in clause 6.5.2.3.

6.5A.3 Spurious emissions for CA

6.5A.3.0 General spurious emissions for CA

6.5A.3.0.0 General

This clause specifies the spurious emission requirements for carrier aggregation. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

For intra-band CA, in case the CA configuration consists of a single UL CC, spurious emissions requirements defined in subclause 6.5.3 apply. Spurious emissions requirements do not apply at any frequency where IBE requirements of clause 6.4A.2.3 apply.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

6.5A.3.0.1 Spurious emissions for intra-band contiguous UL CA

For intra-band contiguous UL carrier aggregation, the spurious emission limits apply for the frequency ranges that are more than F_{OOB} (MHz) from the edge of the UL aggregated channel bandwidth, where F_{OOB} is defined as the twice the UL aggregated channel bandwidth. For frequencies Δf_{OOB} greater than F_{OOB} , the spurious emission requirements in Table 6.5.3-2 are applicable.

6.5A.3.0.2 Spurious emissions for intra-band non-contiguous UL CA

For intra-band non-contiguous UL carrier aggregation, the spurious emission requirement is defined as a composite spurious emission requirement which is a combination of individual spurious emission requirements defined for each UL sub-block. The limits in Table 6.5.3-2 apply for the frequency ranges that are more than F_{OOB} (MHz) from the edge of each UL sub-block but excludes frequency ranges that coincide with another UL sub-block. No spurious emission limit applies in the gap between neighbouring UL sub-blocks if the frequency span between the lowest edge of the upper sub-block and the highest edge of the lower sub-block is smaller than $F_{OOB_L} + F_{OOB_H}$.

6.5A.3.0.3 Spurious emissions for inter-band UL CA

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, the spurious emission requirements are specified in clause 6.5.3 and are applicable for each CC with all CCs active with non-zero UL RB allocation.

6.5A.3.1 Spurious emission band UE co-existence for UL CA

This clause specifies the requirements for the specified contiguous or non-contiguous UL carrier aggregation configurations for coexistence with protected bands.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

For intra-band contiguous, non-contiguous carrier aggregation and inter-band carrier aggregation, the requirements in Table 6.5A.3-1 apply.

CA operating band	Spurious emission						
	Protected band / frequency range		Frequency range (MHz)		Maximum Level (dBm)	MBW (MHz)	NOTE
CA_n257	NR Band n260	FDL_low	-	FDL_high	-2	100	
	Frequency range	57000	•	66000	2	100	
	Frequency range	23600	-	24000	1	200	2
CA_n258	Frequency range	57000	-	66000	2	100	
CA_n259	NR Band 257	FDL_low	-	FDL_high	-5	100	
	NR Band 261	FDL_low	-	FDL_high	-5	100	
	Frequency range	36000	-	37000	7	1000	
	Frequency range	57000	-	66000	2	100	
CA_n260	NR Band 257	F _{DL_low}	-	$F_{\text{DL}_{high}}$	-5	100	
	NR Band 261	F _{DL_low}	-	FDL_high	-5	100	
	NR Band 262	FDL_low	-	FDL_high	-5	100	
	Frequency range	57000	-	66000	2	100	
CA_n261	NR Band 260	F _{DL} low	-	F _{DL_high}	-2	100	
	NR Band 262	FDL_low	-	FDL_high	-5	100	
	Frequency range	57000	-	66000	2	100	
CA_n262	NR Band 260	F _{DL_low}	-	F _{DL_high}	-2	100	
_	NR Band 261	F _{DL_low}	-	FDL_high	-5	100	
	Frequency range	57000	-	66000	2	100	
CA_n257_n2593	NR Band n260	FDL_low	-	FDL_high	-2	100	
	Frequency range	57000	-	66000	2	100	
	Frequency range	23600	-	24000	1	200	
	NR Band 257	F _{DL_low}	-	F _{DL_high}	-5	100	
	NR Band 261	F _{DL_low}	-	F _{DL_high}	-5	100	
	Frequency range	36000	-	37000	7	1000	
CA_n260_n261 ³	NR Band 257	FDL_low	-	FDL_high	-5	100	
	NR Band 262	F _{DL_low}	-	F _{DL_high}	-5	100	
	Frequency range	57000	-	66000	2	100	
NOTE 2: The pro- services	nd F _{DL_high} refer to each NR freq tection of frequency range 23600 3. nd UL carrier aggregation is app	0-24000 M	lHz i	s meant fo	r protection of	·	ssive

Table 6.5A.3.1-1: Requirements for CA

6.5A.3.2 Additional spurious emissions

6.5A.3.2.1 General

These requirements are specified in terms of an additional spectrum emission requirement. Additional spurious emission requirements are signalled by the network to indicate that the UE shall meet an additional requirement for a specific deployment scenario as part of the cell handover/broadcast message.

6.5A.3.2.2 Void

6.5A.3.2.3 Additional spurious emission requirements for CA_NS_202

When "CA_NS_202" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.3-1.

6.5A.3.2.4 Additional spurious emission requirements for CA_NS_203

When "CA_NS_203" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.4-1. This requirement also applies for the frequency ranges that are less than F_{OOB} (MHz) as defined in section 6.5A.3.

6.5D Output RF spectrum emissions for UL MIMO

6.5D.1 Occupied bandwidth for UL MIMO

For UE(s) supporting UL MIMO, the occupied bandwidth requirement in clause 6.5.1 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.0-1.

6.5D.2 Out of band emissions for UL MIMO

For UE(s) supporting UL MIMO, the out of band emissions requirements in clause 6.5.2 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.0-1.

6.5D.3 Spurious emissions for UL MIMO

For UE(s) supporting UL MIMO, the spurious emissions requirements in clause 6.5.3 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.0-1.

6.6 Beam correspondence

6.6.1 General

Beam correspondence is the ability of the UE to select a suitable beam for UL transmission based on DL measurements with or without relying on UL beam sweeping. Unless explicitly addressed in subclauses below, the beam correspondence requirement is fulfilled if the UE meets the corresponding minimum peak EIRP and spherical coverage requirement for that power class with its autonomously chosen UL beams and without uplink beam sweeping.

- 6.6.2 (Void)
- 6.6.3 (Void)

6.6.4 Beam correspondence for power class 3

6.6.4.1 General

The beam correspondence requirement for power class 3 UEs consists of three components: UE minimum peak EIRP (as defined in Clause 6.2.1.3), UE spherical coverage (as defined in Clause 6.2.1.3), and beam correspondence tolerance (as defined in Clause 6.6.4.2). The beam correspondence requirement is fulfilled if the UE satisfies one of the following conditions, depending on the UE's beam correspondence capability IE *beamCorrespondenceWithoutUL-BeamSweeping*, as defined in TS 38.306 [14]:

UEs supporting FR2-2 shall support beamCorrespondenceWithoutUL-BeamSweeping.

- If *beamCorrespondenceWithoutUL-BeamSweeping* is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with its autonomously chosen UL beams and without uplink beam sweeping. Such a UE is considered to have met the beam correspondence tolerance requirement.
- If *beamCorrespondenceWithoutUL-BeamSweeping* and *beamCorrespondenceSSB-based-r16* are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 using the side conditions for SSB based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.2.
- If *beamCorrespondenceWithoutUL-BeamSweeping* and *beamCorrespondenceCSI-RS-based-r16* are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 using the side conditions for CSI-RS based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.3.
- If *beamCorrespondenceWithoutUL-BeamSweeping* is not present, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].
- If *beamCorrespondenceWithoutUL-BeamSweeping* is not present and *beamCorrespondenceSSB-based-r16* is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping using the side conditions for SSB based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.2. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].
- If *beamCorrespondenceWithoutUL-BeamSweeping* is not present and *beamCorrespondenceCSI-RS-based-r16* is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping using the side conditions for CSI-RS based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.3. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].

6.6.4.2 Beam correspondence tolerance for power class 3

The beam correspondence tolerance requirement $\Delta EIRP_{BC}$ for power class 3 UEs is defined based on a percentile of the distribution of $\Delta EIRP_{BC}$, defined as $\Delta EIRP_{BC} = EIRP_2 - EIRP_1$ over the link angles spanning a subset of the spherical coverage grid points, such that

- EIRP₁ is the total EIRP in dBm calculated based on the beam the UE chooses autonomously (corresponding beam) to transmit in the direction of the incoming DL signal, which is based on beam correspondence without relying on UL beam sweeping.

- EIRP₂ is the best total EIRP (beam yielding highest EIRP in a given direction) in dBm which is based on beam correspondence with relying on UL beam sweeping.
- The link angles are the ones corresponding to the top N^{th} percentile of the EIRP₂ measurement over the whole sphere, where the value of N is according to the test point of EIRP spherical coverage requirement for power class 3, i.e. N = 50.

For power class 3 UEs, the requirement is fulfilled if the UE's corresponding UL beams satisfy the maximum limit in Table 6.6.4.2-1.

Operating band	Max ∆EIRP _{BC} at 85 th %-tile ∆EIRP _{BC} CDF (dB)
n257	3.0
n258	3.0
n259	3.2
n260	3.2
n261	3.0
n262	3.2
	nents in this table are verified ormal temperature conditions as nnex E.2.1

Table 6.6.4.2-1: UE beam correspondence tolerance for power class 3

6.6.4.3 Side Conditions

6.6.4.3.1 Side Condition for beam correspondence based on SSB and CSI-RS

The beam correspondence requirements are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided and Type D QCL shall be maintained between SSB and CSI-RS.
- The reference measurement channel for beam correspondence are fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-1 and Table 6.6.4.3.1-2.

Table 6.6.4.3.1-1: Conditions for SSB based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot
		dBm / SCS _{SSB}	dB
		SCS _{SSB} = 120 kHz	
All angles Note 1	n257	-96.2	≥6
	n258	-96.2	
	n259	-90.7	
	n260	-91.9	
	n261	-96.2	
	n262	-88.5	
NOTE 1: Fo	or UEs that support mult	iple FR2 bands, the Minimum SSB_RP values for all ang	les are
NOTE 2: Va		UE multi-band relaxation factor in dB specified in clause of diated requirements reference point to give minimum SSE	

Table 6.6.4.3.1-2: Conditions for CSI-RS based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum CSI-RS_RP Note 2	CSI-RS Ês/lot
		dBm / SCS _{CSI-RS}	dB
		SCS _{CSI-RS} = 120 kHz	
All angles Note 1	n257	-96.2	≥6
	n258	-96.2	
	n259	-90.7	
	n260	-91.9	
	n261	-96.2	
	n262	-88.5	
NOTE 1: Fo	r UEs that support multip	le FR2 bands, the Minimum SSB_RP values for all ang	les are
NOTE 2: Va	creased by ∆MBs,n, the U lues specified at the radia th no applied noise.	E multi-band relaxation factor in dB specified in clause (ated requirements reference point to give minimum CSI	6.2.1. -RS Ês/lot,

6.6.4.3.2 Side Condition for SSB based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on SSB are only applied under the following side conditions:

- The downlink reference signal SSB is provided, and CSI-RS is not provided.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-1.

6.6.4.3.3 Side Condition for CSI-RS based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on CSI-RS are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-2 and SSB signal is provided according to Table 6.6.4.3.3-1.

Table 6.6.4.3.3-1: SSB signal conditions for CSI-RS based beam correspondence requirements

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot
		dBm / SCS _{SSB}	dB
		SCS _{SSB} = 120 kHz	
All angles Note 1	n257	-101,4	≥1
	n258	-101,4	
	n259	-97,1	
	n260	-97,1	
	n261	-101,4	
	n262	-93,5	
NOTE 1: Fo	or UEs that support mult	tiple FR2 bands, the Minimum SSB_RP values for all ang	les are
inc	creased by $\Delta MB_{S,n}$, the	UE multi-band relaxation factor in dB specified in clause	6.2.1.
NOTE 2: Va wit	lues specified at the ra th no applied noise.	diated requirements reference point to give minimum SSI	B Ês/lot,

6.6.4.4 Applicability

For UEs supporting more than one type of beam correspondence, the following applicability rules apply:

- If a UE meets enhanced beam correspondence requirements either based on SSB or based on CSI-RS, it is considered to have met the beam correspondence requirements based on SSB and CSI-RS.

- For a UE supporting either SSB based or CSI-RS based enhanced beam correspondence, the UE shall meet the supported enhanced beam correspondence requirements.
- For a UE supporting both SSB based and CSI-RS based enhanced beam correspondence, the UE shall meet both SSB based and CSI-RS based enhanced beam correspondence requirements and the following applicability rules for verifying the requirements apply:
 - The enhanced beam correspondence requirements shall be verified with the SSB based enhanced beam correspondence side conditions in clause 6.6.4.3.2. If the UE meets the SSB based enhanced beam correspondence requirements using the side conditions in clause 6.6.4.3.2 and meets the minimum peak EIRP requirement as defined in clasue 6.2.1.3 using the CSI-RS based side conditions in clause 6.6.4.3.3, where the link direction is determined in the SSB based enhanced beam correspondence test, the UE is considered to have met both the SSB based and CSI-RS based enhanced beam correspondence requirements.
 - Otherwise, if UE does not meet the minimum peak EIRP requirement as defined in clasue 6.2.1.3 using the CSI-RS based side conditions in clause 6.6.4.3.3, the enhanced beam correspondence requirements shall be further verified for the UE with the CSI-RS based enhanced beam correspondence side conditions in clause 6.6.4.3.3.

6.6.5 (Void)

6.6.6 Beam correspondence for power class 5

6.6.6.1 General

The beam correspondence requirement for power class 5 UEs consists of two components: UE minimum peak EIRP (as defined in Clause 6.2.1.5), and UE spherical coverage (as defined in Clause 6.2.1.5). The beam correspondence requirement is fulfilled if the UE satisfies one of the following conditions, depending on the UE's beam correspondence capability IE *beamCorrespondenceWithoutUL-BeamSweeping*, as defined in TS 38.306 [14]:

- -- If *beamCorrespondenceWithoutUL-BeamSweeping* is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.5-1 and spherical coverage requirement according to Table 6.2.1.5-3 with its autonomously chosen UL beams and without uplink beam sweeping. Such a UE is considered to have met the beam correspondence tolerance requirement.
- If *beamCorrespondenceWithoutUL-BeamSweeping* and *beamCorrespondenceSSB-based-r16* are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.5-1 and spherical coverage requirement according to Table 6.2.1.5-3 using the side conditions for SSB based enhanced beam correspondence requirements as defined in Clause 6.6.6.3.2.
- If *beamCorrespondenceWithoutUL-BeamSweeping* and *beamCorrespondenceCSI-RS-based-r16* are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.5-1 and spherical coverage requirement according to Table 6.2.1.5-3 using the side conditions for CSI-RS based enhanced beam correspondence requirements as defined in Clause 6.6.6.3.3.

6.6.6.2 (Reserved)

Editor's note: FFS if power class 5 UE can rely on UL beam sweeping to meet min peak EIRP and spherical requirements.

6.6.6.3 Side Conditions

6.6.6.3.1 Side Condition for beam correspondence based on SSB and CSI-RS

The beam correspondence requirements are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided and Type D QCL shall be maintained between SSB and CSI-RS.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.

- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.6.3.1-1 and Table 6.6.6.3.1-2.

Table 6.6.6.3.1-1: Conditions for SSB based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot
		dBm / SCS _{SSB}	dB
		SCS _{SSB} = 120 kHz	
All angles Note 1	n257	-103.6	≥6
	n258	-103.6	
	n259	-100.5	
NOTE 1: Fo	or UEs that support mult	tiple FR2 bands, the Minimum SSB_RP values for all ang	les are
ind	creased by ΔMBs , the \Box	UE multi-band relaxation factor in dB specified in clause 6	5.2.1.5
	alues specified at the ra th no applied noise.	diated requirements reference point to give minimum SSE	B Ês/lot,

Table 6.6.6.3.1-2: Conditions for CSI-RS based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum CSI-RS_RP Note 2	CSI-RS Ês/lot			
		dBm / SCS _{CSI-RS}	dB			
		SCS _{CSI-RS} = 120 kHz				
All angles Note 1	n257	-103.6	≥6			
	n258	-103.6	Ι			
	n259	-100.5				
	NOTE 1: For UEs that support multiple FR2 bands, the Minimum CSI-RS_RP values are increased by ΔMBs, the UE multi-band relaxation factor in dB specified in clause 6.2.1.5					
NOTE 2: V		ues specified at the radiated requirements reference point to give minimum CSI-RS Ês/lot,				

6.6.6.3.2 Side Condition for SSB based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on SSB are only applied under the following side conditions:

- The downlink reference signal SSB is provided, and CSI-RS is not provided.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.6.3.1-1.

6.6.6.3.3 Side Condition for CSI-RS based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on CSI-RS are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-2 and SSB signal is provided according to Table 6.6.6.3.3-1.

Table 6.6.6.3.3-1: SSB signal conditions for CSI-RS based beam correspondence requirements

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot		
		dBm / SCS _{SSB}	dB		
		SCS _{SSB} = 120 kHz			
All angles Note 1	n257	-108.6	≥1		
	n258	-108.6			
	n259	-105.5			
	NOTE 1: For UEs that support multiple FR2 bands, the Minimum SSB_RP values for all angles are increased by ∆MB _s , the UE multi-band relaxation factor in dB specified in clause 6.2.1.5				
	alues specified at the ra ith no applied noise.	diated requirements reference point to give minimum SSI	3 Ês/lot,		

6.6.6.4 Applicability

For UEs supporting more than one type of beam correspondence, the following applicability rules apply:

- If a UE meets enhanced beam correspondence requirements either based on SSB or based on CSI-RS, it is considered to have met the beam correspondence requirements based on SSB and CSI-RS.
- For a UE supporting either SSB based or CSI-RS based enhanced beam correspondence, the UE shall meet the supported enhanced beam correspondence requirements.
- For a UE supporting both SSB based and CSI-RS based enhanced beam correspondence, the UE shall meet both SSB based and CSI-RS based enhanced beam correspondence requirements and the following applicability rules for verifying the requirements apply:
 - The enhanced beam correspondence requirements shall be verified with the SSB based enhanced beam correspondence side conditions in clause 6.6.6.3.2. If UE meets the SSB based enhanced beam correspondence requirements using the side conditions in clause 6.6.6.3.2 and meets the minimum peak EIRP requirement as defined in clause 6.2.1.5 using the CSI-RS based side conditions in clause 6.6.6.3.3, where the link direction is determined in the SSB based enhanced beam correspondence test, the UE is considered to have met both the SSB based and CSI-RS based enhanced beam correspondence requirements.
 - Otherwise, if UE does not meet the minimum peak EIRP requirement as defined in clasue 6.2.1.3 using the CSI-RS based side conditions in clause 6.6.6.3.3, the enhanced beam correspondence requirements shall be further verified for the UE with the CSI-RS based enhanced beam correspondence side conditions in clause 6.6.6.3.3.

6.6.7 Beam correspondence for power class 6

6.6.7.1 General

The beam correspondence requirement for power class 6 UEs consists of two components: UE minimum peak EIRP (as defined in Clause 6.2.1.6), and UE spherical coverage (as defined in Clause 6.2.1.6).

Power class 6 UE shall mandatorily support *beamCorrespondenceWithoutUL-BeamSweeping* and *beamCorrespondenceSSB-based-r16*. The UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.6-1 and spherical coverage requirement according to Table 6.2.1.6-3 using the side conditions for SSB based enhanced beam correspondence requirements as defined in Clause 6.6.7.3.2.

If the UE also support *beamCorrespondenceCSI-RS-based-r16*, the UE shall also meet the minimum peak EIRP requirement according to Table 6.2.1.6-1 and spherical coverage requirement according to Table 6.2.1.6-3 using the side conditions for CSI-RS based enhanced beam correspondence requirements as defined in Clause 6.6.7.3.3.

6.6.7.2 (Void)

Editor's note: Not need to define beam correspondence tolerance requirement because power class 6 UE shall mandatorily support beamCorrespondenceWithoutUL-BeamSweeping.

6.6.7.3 Side Conditions

6.6.7.3.1 (Void)

Editor's note: Not need to define the side condition for beam correspondence based on SSB and CSI-RS, because power class 6 UE shall mandatorily support SSB based enhanced beam correspondence.

6.6.7.3.2 Side Condition for SSB based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on SSB are only applied under the following side conditions:

- The downlink reference signal SSB is provided, and CSI-RS is not provided.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.7.3.2-1.

Table 6.6.7.3.2-1: Conditions for SSB based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot	
		dBm / SCS _{SSB}	dB	
		SCS _{SSB} = 120 kHz		
All angles Note 1	n257	-101.4	≥6	
	n258	-101.6		
	n261	-101.4		
NOTE 1: For UEs that support multiple FR2 bands, the Minimum SSB_RP values for all angles are increased by ^Δ MB _{S,n} , the UE multi-band relaxation factor in dB specified in clause 6.2.1.6.				
NOTE 2: Values specified at the radiated requirements reference point to give minimum SSB Ês/lot, with no applied noise.				

6.6.7.3.3 Side Condition for CSI-RS based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on CSI-RS are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.7.3.3-2 and SSB signal is provided according to Table 6.6.7.3.3-1.

Table 6.6.7.3.3-1: SSB signal conditions for CSI-RS based beam correspondence requirements

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot		
		dBm / SCS _{SSB}	dB		
		SCS _{SSB} = 120 kHz			
All angles Note 1	n257	-106.4	≥1		
	n258	-106.6			
	n261	-106.4			
NOTE 1: For UEs that support multiple FR2 bands, the Minimum SSB_RP values for all angles are					
increased by $\Delta MB_{s,n}$, the UE multi-band relaxation factor in dB specified in clause 6.2.1.6					
	Values specified at the radiated requirements reference point to give minimum SSB Ês/lot, with no applied noise.				

Table 6.6.7.3.3-2: Conditions for CSI-RS based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	CSI-RS Ês/lot					
	dBm / SCS _{CSI-RS}						
	SCS _{CSI-RS} = 120 kHz						
All angles Note 1	n257	-101.4	≥6				
	n258 -101.6						
	n261 -101.4						
NOTE 1: For UEs that support multiple FR2 bands, the Minimum CSI-RS_RP values are increased by ΔMB _{S.n} , the UE multi-band relaxation factor in dB specified in clause 6.2.1.6							
	alues specified at the radi	ated requirements reference point to give minimum CSI	I-RS Ês/Iot,				

6.6.7.4 Applicability

For UEs supporting more than one type of beam correspondence, the following applicability rules apply:

- If a UE meets enhanced beam correspondence requirements either based on SSB or based on CSI-RS, it is considered to have met the beam correspondence requirements based on SSB and CSI-RS.
- For a UE supporting either SSB based or CSI-RS based enhanced beam correspondence, the UE shall meet the supported enhanced beam correspondence requirements.
- For a UE supporting both SSB based and CSI-RS based enhanced beam correspondence UE shall meet the both SSB based and CSI-RS based enhanced beam correspondence requirements and the following applicability rules for verifying the requirements apply:
 - The enhanced beam correspondence requirements shall be verified with the SSB based enhanced beam correspondence side conditions in clause 6.6.7.3.2. If the UE meets the SSB based enhanced beam correspondence requirements using the side conditions in clause 6.6.7.3.2 and meets the minimum peak EIRP requirement as defined in clause 6.2.1.6 using the CSI-RS based side conditions in clause 6.6.7.3.3, where the link direction is determined in the SSB based enhanced beam correspondence test, the UE is considered to have met both the SSB based and CSI-RS based enhanced beam correspondence requirements.
 - Otherwise, if UE does not meet the minimum peak EIRP requirement as defined in clause 6.2.1.6 using the CSI-RS based side conditions in clause 6.6.7.3.3, the enhanced beam correspondence requirements shall be further verified for the UE with the CSI-RS based enhanced beam correspondence side conditions in clause 6.6.7.3.3.

6.6.8 Beam correspondence for power class 7

6.6.8.1 General

The beam correspondence requirement for power class 7 UEs consists of two components: UE minimum peak EIRP (as defined in Clause 6.2.1.7), and UE spherical coverage (as defined in Clause 6.2.1.7). The beam correspondence requirement is fulfilled if the UE satisfies one of the following conditions, depending on the UE's beam correspondence capability IE *beamCorrespondenceWithoutUL-BeamSweeping*, as defined in TS 38.306 [14]:

- -- If *beamCorrespondenceWithoutUL-BeamSweeping* is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.7-1 and spherical coverage requirement according to Table 6.2.1.7-3 with its autonomously chosen UL beams and without uplink beam sweeping. Such a UE is considered to have met the beam correspondence tolerance requirement.
- If *beamCorrespondenceWithoutUL-BeamSweeping* and *beamCorrespondenceSSB-based-r16* are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.7-1 and spherical coverage requirement according to Table 6.2.1.7-3 using the side conditions for SSB based enhanced beam correspondence requirements as defined in Clause 6.6.8.3.2.

- If *beamCorrespondenceWithoutUL-BeamSweeping* and *beamCorrespondenceCSI-RS-based-r16* are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.7-1 and spherical coverage requirement according to Table 6.2.1.7-3 using the side conditions for CSI-RS based enhanced beam correspondence requirements as defined in Clause 6.6.8.3.3.
- 6.6.8.2 Void

6.6.8.3 Side Conditions

6.6.8.3.1 Side Condition for beam correspondence based on SSB and CSI-RS

The beam correspondence requirements are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided and Type D QCL shall be maintained between SSB and CSI-RS.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.8.3.1-1 and Table 6.6.8.3.1-2.

Table 6.6.8.3.1-1: Conditions for SSB based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum SSB_RP ^{Note 2}	SSB Ês/lot					
		dBm / SCS _{SSB}	dB					
		SCS _{SSB} = 120 kHz						
All angles Note 1	n257	-93.2	≥6					
	n258	-93.2						
	n261	-93.2						
NOTE 2: Va	NOTE 1: Void NOTE 2: Values specified at the radiated requirements reference point to give minimum SSB Ês/lot, with no applied noise.							

Table 6.6.8.3.1-2: Conditions for CSI-RS based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands Minimum CSI-RS_RP Note 2						
	dBm / SCS _{CSI-RS}						
	SCS _{CSI-RS} = 120 kHz						
All angles n257 Note 1		-93.2	≥6				
	n258 -93.2						
	n261 -93.2						
NOTE 1: F	NOTE 1: For UEs that support multiple FR2 bands, the Minimum SSB_RP values for all angles are						
increased by $\Delta MB_{S,n}$, the UE multi-band relaxation factor in dB specified in clause 6.2.1. NOTE 2: Values specified at the radiated requirements reference point to give minimum CSI-RS \hat{E} s/lot,							
	alues specified at the radi	ated requirements reference point to give minimum CSI	-KS ES/101,				

6.6.8.3.2 Side Condition for SSB based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on SSB are only applied under the following side conditions:

- The downlink reference signal SSB is provided, and CSI-RS is not provided.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.8.3.1-1.

6.6.8.3.3 Side Condition for CSI-RS based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on CSI-RS are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.8.3.1-2 and SSB signal is provided according to Table 6.6.8.3.3-1.

Table 6.6.8.3.3-1: SSB signal conditions for CSI-RS based beam correspondence requirements

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot			
	dBm / SCS _{SSB}					
		SCS _{SSB} = 120 kHz				
All angles Note 1	n257	-98.2	≥1			
	n258 -98.2					
	n261	-98.2				
 NOTE 1: For UEs that support multiple FR2 bands, the Minimum SSB_RP values for all angles are increased by ΔMB_{S,n}, the UE multi-band relaxation factor in dB specified in clause 6.2.1. NOTE 2: Values specified at the radiated requirements reference point to give minimum SSB Ês/lot, with no applied noise. 						

6.6.8.4 Applicability

For UEs supporting more than one type of beam correspondence, the following applicability rules apply:

- If a UE meets enhanced beam correspondence requirements either based on SSB or based on CSI-RS, it is considered to have met the beam correspondence requirements based on SSB and CSI-RS.
- For a UE supporting either SSB based or CSI-RS based enhanced beam correspondence, the UE shall meet the supported enhanced beam correspondence requirements.
- For a UE supporting both SSB based and CSI-RS based enhanced beam correspondence, the UE shall meet both SSB based and CSI-RS based enhanced beam correspondence requirements and the following applicability rules for verifying the requirements apply:
 - The enhanced beam correspondence requirements shall be verified with the SSB based enhanced beam correspondence side conditions in clause 6.6.8.3.2. If UE meets the SSB based enhanced beam correspondence requirements using the side conditions in clause 6.6.8.3.2 and meets the minimum peak EIRP requirement as defined in clause 6.2.1.7 using the CSI-RS based side conditions in clause 6.6.8.3.3, where the link direction is determined in the SSB based enhanced beam correspondence test, the UE is considered to have met both the SSB based and CSI-RS based enhanced beam correspondence requirements.
 - Otherwise, if UE does not meet the minimum peak EIRP requirement as defined in clasue 6.2.1.7 using the CSI-RS based side conditions in clause 6.6.8.3.3, the enhanced beam correspondence requirements shall be further verified for the UE with the CSI-RS based enhanced beam correspondence side conditions in clause 6.6.8.3.3.

6.6A Beam correspondence for CA

For intra-band CA in FR2, the same beam correspondence relationship for beam management is supported across CCs in this release of the specification and no requirement is specified. Beam correspondence performance for intra-band CA is fulfilled if the beam correspondence requirements defined in clause 6.6 is met for non-CA case.

For inter-band carrier aggregation with uplink assigned to two NR bands, and each UL band is configured with a single CC, with all CCs active with non-zero UL RB allocation, the following beam correspondence requirements apply for each CC:

- 1 The minimum peak EIRP requirement specified for UL inter-band CA in 6.2A, based on test conditions in clause 6.6. Reference signal power adjustments by $\Delta MB_{S,n}$ are replaced by $\Delta R_{IB,S,n}$, where referenced.
- 2 The common spherical coverage requirement specified for UL inter-band CA in 6.2A, based on test conditions in clause 6.6. Reference signal power adjustments by $\Delta MB_{S,n}$ are replaced by $\Delta R_{IB,S,n}$, where referenced.

7 Receiver characteristics

7.1 General

Unless otherwise stated, the receiver characteristics are specified over the air (OTA). The reference receive sensitivity (REFSENS) is defined assuming a 0 dBi reference antenna located at the center of the quiet zone.

7.2 Diversity characteristics

The minimum requirements on effective isotropic sensitivity (EIS) apply to two measurements, corresponding to DL signals in orthogonal polarizations.

7.3 Reference sensitivity

7.3.1 General

The reference sensitivity power level REFSENS is defined as the EIS level at the centre of the quiet zone in the RX beam peak direction, at which the throughput shall meet or exceed the requirements for the specified reference measurement channel.

7.3.2 Reference sensitivity power level

7.3.2.1 Reference sensitivity power level for power class 1

The throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.1-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating	REFSENS (dBm) / Channel bandwidth									
band	50	100	200	400	800	1600	2000			
	MHz	MHz	MHz	MHz	MHz	MHz	MHz			
n257	-97.5	-94.5	-91.5	-88.5	N/A	N/A	N/A			
n258	-97.5	-94.5	-91.5	-88.5	N/A	N/A	N/A			
n260	-94.5	-91.5	-88.5	-85.5	N/A	N/A	N/A			
n261	-97.5	-94.5	-91.5	-88.5	N/A	N/A	N/A			
n262	-92.5	-89.5	-86.5	-83.5	N/A	N/A	N/A			
n263	N/A	-85	N/A	-79	-76	-73	-72			
NOTE 1: Th	ne transmitte	r shall be set	t to PUMAX as	defined in cl	ause 6.2.4					

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Operating		NR Band / Channel bandwidth / NRB / SCS / Duplex mode							
band	50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz	SCS	Duplex mode
n257	32	64	128	256	N/A	N/A	N/A	120 kHz	TDD
n258	32	64	128	256	N/A	N/A	N/A	120 kHz	TDD
n260	32	64	128	256	N/A	N/A	N/A	120 kHz	TDD
n261	32	64	128	256	N/A	N/A	N/A	120 kHz	TDD
n262	32	64	128	256	N/A	N/A	N/A	120 kHz	TDD
n263	N/A	64	N/A	256	N/A	N/A	N/A	120 kHz	TDD
	N/A	N/A	N/A	[64]	120	[240]	N/A	480 kHz	
	N/A	N/A	N/A	[32]	[60]	[120]	144	960 kHz	

Table 7.3.2.1-2: Uplink configuration for reference sensitivity

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

Operating band	Network Signalling value

7.3.2.2 Reference sensitivity power level for power class 2

The throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.2-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating band	REFSENS (dBm) / Channel bandwidth								
	50 MHz 100 MHz 200 MHz 400 MHz 800 MHz 1600 MHz 2000								
n257	-92.0	-89.0	-86.0	-83.0	N.A	N.A	N.A		
n258	-92.0	-89.0	-86.0	-83.0	N.A	N.A	N.A		
n259	-88.7	-85.7	-82.7	-79.7	N.A	N.A	N.A		
n261	-92.0	-89.0	-86.0	-83.0	N.A	N.A	N.A		
n262	-86.8	-83.8	-80.8	-77.8	N.A	N.A	N.A		
n263	N.A	-86.3	N.A	-80.3	-77.3	-74.3	-73.3		
n263		-86.3	N.A	-80.3	-				

Table 7.3.2.2-1: Reference sensitivity for power class 2

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.2.3 Reference sensitivity power level for power class 3

The throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.3-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

For the UEs that support multiple FR2 bands, the minimum requirement for Reference sensitivity in Table 7.3.2.3-1 shall be increased per band, respectively, by the reference sensitivity relaxation parameter $\Delta MB_{P,n}$ as specified in clause 6.2.1.3. The requirement for the UE which supports a single FR2 band is specified in Table 7.3.2.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 7.3.2.3-1 and Table 6.2.1.3-4.

Operating band	REFSENS (dBm) / Channel bandwidth									
	50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz			
n257	-88.3	-85.3	-82.3	-79.3	N.A	N.A	N.A			
n258	-88.3	-85.3	-82.3	-79.3	N.A	N.A	N.A			
n259	-84.7	-81.7	-78.7	-75.7	N.A	N.A	N.A			
n260	-85.7	-82.7	-79.7	-76.7	N.A	N.A	N.A			
n261	-88.3	-85.3	-82.3	-79.3	N.A	N.A	N.A			
n262	-82.8	-79.8	-76.8	-73.8	N.A	N.A	N.A			
n263	N.A	-78	N.A	-72	-69	-66	-65			
NOTE 1: The	e transmitter s	hall be set to F	P _{UMAX} as define	ed in clause 6.	2.4					

Table 7.3.2.3-1: Reference sensitivity

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.2.4 Reference sensitivity power level for power class 4

The throughput shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.4-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating band	REFSENS (dBm) / Channel bandwidth					
-	50 MHz	100 MHz	200 MHz	400 MHz		
n257	-97.0	-94.0	-91.0	-88.0		
n258	-97.0	-94.0	-91.0	-88.0		
n260	-95.0	-92.0	-89.0	-86.0		
n261	-97.0	-94.0	-91.0	-88.0		
n262	-91.0	-88.0	-85.0	-82.0		
NOTE 1: The transr	nitter shall be set to	PUMAX as defined in c	lause 6.2.4			

Table 7.3.2.4-1: Reference sensitivity for power class 4

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.2.5 Reference sensitivity power level for power class 5

The throughput shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.5-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating band	REFSENS (dBm) / Channel bandwidth							
	50 MHz	50 MHz 100 MHz 200 MHz 400 MHz						
n257	-92.6	-89.6	-86.6	-83.6				
n258	-92.8	-89.8	-86.8	-83.8				
n259	-89.7	-86.7	-83.7	-80.7				
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4								

Table 7.3.2.5-1: Reference sensitivity for power class 5

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.2.6 Reference sensitivity power level for power class 6

The throughput shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.6-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating band	REFSENS (dBm) / Channel bandwidth						
	50 MHz	50 MHz 100 MHz 200 MHz 40					
n257	-92.6	-89.6	-86.6	-83.6			
n258	-92.8	-89.8	-86.8	-83.8			
n261	-92.6	-89.6	-86.6	-83.6			
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4							

Table 7.3.2.6-1: Reference	sensitivity for	power class 6
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The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.2.7 Reference sensitivity power level for power class 7

The throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.7-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating band	REFSENS (dBm) / Channel bandwid				
	50 MHz	100 MHz			
n257	-85.3	-82.3			
n258	-85.3	-82.3			
n261	-85.3	-82.3			
NOTE 1: The transmitter shall be set to PUMAX as defined in					
clause 6.2.4					

Table 7.3.2.7-1: Reference sensitivity

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth of 50MHz and 100MHz specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.3 Void

7.3.4 EIS spherical coverage

7.3.4.1 EIS spherical coverage for power class 1

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.1

The maximum EIS at the 85th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.1-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Operating	EIS at 85 th %-tile CCDF (dBm) / Channel bandwidth						
band	50	100	200	400	800	1600	2000
	MHz	MHz	MHz	MHz	MHz	MHz	MHz
n257	-89.5	-86.5	-83.5	-80.5	N/A	N/A	N/A
n258	-89.5	-86.5	-83.5	-80.5	N/A	N/A	N/A
n260	-86.5	-83.5	-80.5	-77.5	N/A	N/A	N/A
n261	-89.5	-86.5	-83.5	-80.5	N/A	N/A	N/A
n262	-84.3	-81.3	-78.3	-75.3	N/A	N/A	N/A
n263	N/A	-73.5	N/A	-67.5	-64.5	-61.5	-60.5

Table 7.3.4.1-1: EIS spherical coverage for power class 1

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.2 EIS spherical coverage for power class 2

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.2

The maximum EIS at the 60th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.2-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Operating band	EIS at 60 th %-tile CCDF (dBm) / Channel bandwidth								
	50 MHz	50 MHz 100 MHz 200 MHz 400 MHz 800 MHz 1600 MHz 2000							
n257	-81.0	-78.0	-75.0	-72.0	N.A	N.A	N.A		
n258	-81.0	-78.0	-75.0	-72.0	N.A	N.A	N.A		
n259	-76.2	-73.2	-70.2	-67.2	N.A	N.A	N.A		
n261	-81.0	-78.0	-75.0	-72.0	N.A	N.A	N.A		
n262	-74.9	-71.9	-68.9	-65.9	N.A	N.A	N.A		
n263	N.A	-71.2	N.A	-65.2	-62.2	-59.2	-58.2		
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4									
NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in									
Anne	x E.2.1.			-					

Table 7.3.4.2-1: EIS spherica	al coverage for power class 2
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The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.3 EIS spherical coverage for power class 3

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.3

The maximum EIS at the 50th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.3-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

For the UEs that support multiple FR2 bands, the minimum requirement for EIS spherical coverage in Table 7.3.4.3-1 shall be increased per band, respectively, by the EIS spherical coveragerelaxation parameter $\Delta MB_{S,n}$ as specified in clause 6.2.1.3. The requirement for the UE which supports a single FR2 band is specified in Table 7.3.4.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 7.3.4.3-1 and Table 6.2.1.3-4.

Operating band			EIS a	t 50 th %-tile	CCDF (dBm) / Cha	annel bandwidth	
	50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
n257	-77.4	-74.4	-71.4	-68.4	N.A	N.A	N.A
n258	-77.4	-74.4	-71.4	-68.4	N.A	N.A	N.A
n259	-71.9	-68.9	-65.9	-62.9	N.A	N.A	N.A
n260	-73.1	-70.1	-67.1	-64.1	N.A	N.A	N.A
n261	-77.4	-74.4	-71.4	-68.4	N.A	N.A	N.A
n262	-69.7	-66.7	-63.7	-60.7	N.A	N.A	N.A
n263	N.A	-66.2	N.A	-60.2	-57.2	-54.2	-53.2
NOTE 1: The	e transmitte	er shall be s	set to PUM	AX as define	d in clause 6.2.4		
	e EIS sphe nex E.2.1.	rical covera	age require	ements are	verified only under r	normal thermal conditi	ons as defined in

 Table 7.3.4.3-1: EIS spherical coverage for power class 3

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.4 EIS spherical coverage for power class 4

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.4

The maximum EIS at the 20th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.4-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Operating band	EIS at 20 th %-tile CCDF (dBm) / Channel bandwidth									
	50 MHz	100 MHz	200 MHz	400 MHz						
n257	-88.0	-85.0	-82.0	-79.0						
n258	-88.0	-85.0	-82.0	-79.0						
n260	-83.0	-80.0	-77.0	-74.0						
n261	-88.0	-85.0	-82.0	-79.0						
n262	-78.9	-75.9	-72.9	-69.9						
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4										
NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal										
			-	conditions as defined in Annex E.2.1.						

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.5 EIS spherical coverage for power class 5

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.4

The maximum EIS at the 85th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.5-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Operating band	EIS at 85 th %-tile CCDF (dBm) / Channel bandwidth						
	50 MHz	100 MHz	200 MHz	400 MHz			
n257	-84.6	-81.6	-78.6	-75.6			
n258	-84.8	-81.8	-78.8	-75.8			
n259	-81.7	-78.7	-75.7	-72.7			
NOTE 1: The transmitter shall be set to P _{UMAX} as defined in clause 6.2.4 NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.							

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.6 EIS spherical coverage for power class 6

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.6

The maximum EIS measured over the spherical coverage evaluation areas is defined as the spherical coverage requirement and is found in Table 7.3.4.6-1 below. UE spherical coverage evaluation areas are found in Table 6.2.1.6-3a in clause 6.2.1.6, by consisting of Area-1 and Area-2, in the reference coordinate system in Annex J.1. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Operating band	Max EIS over UE spherical coverage evaluation areas (dBm) / Channel bandwidth					
	50 MHz	100 MHz	200 MHz	400 MHz		
n257	-82.6	-79.6	-76.6	-73.6		
n258	-82.8	-79.8	-76.8	-73.8		
n261	-82.6 -79.6 -76.6 -73.6					
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4						
NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal						
conditions as defined in Annex E.2.1.						
NOTE 3: The requirements in this table are applicable to FR2 PC6 UE with the network signalling						
[highSpeedMeasFlag-r17] configured as [set2].						

 Table 7.3.4.6-1: EIS spherical coverage for power class 6

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.7 EIS spherical coverage for power class 7

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.7.

The maximum EIS at the 50th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.7-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Operating ba	nd EIS at 50 th %-tile CCDF (dBm) / Channel bandwidth				
	50 MHz 100 MHz				
n257	-74.4	-71.4			
n258	-74.4	-71.4			
n261	-74.4	-71.4			
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4					
	E 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.				

Table 7.3.4.7-1: EIS spherical coverage for power class 7

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth of 50MHz and 100MHz specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3A Reference sensitivity for DL CA

7.3A.1 General

7.3A.2 Reference sensitivity power level for CA

7.3A.2.1 Intra-band contiguous CA

For each component carrier in the intra-band contiguous carrier aggregation, the throughput in QPSK R = 1/3 shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity values determined from clause 7.3.2, and relaxation applied to peak reference sensitivity requirement as specified in Table 7.3A.2.1-1.

Table 7.3A.2.1-1: ΔR_{IBC} EIS Relaxation for CA operation by aggregated channel bandwidth

Aggregated Channel BW 'BW _{Channel_CA} ' (MHz)	ΔR _{IBC} (dB)
BW _{Channel_CA} ≤ 800	0.0
800 < BW _{Channel_CA} ≤ 1200	0.5
1200 < BW _{Channel_CA} ≤ 1600	1.0
1600 < BW _{Channel_CA} ≤ 2000	[1.5]

7.3A.2.2 Intra-band non-contiguous CA

For each component carrier in the intra-band non-contiguous carrier aggregation, the throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity values determined from clause 7.3.2, and relaxation applied to peak reference sensitivity requirement as specified in Table 7.3A.2.2-1. The configured downlink spectrum is defined as the frequency band from the lowest edge of the lowest CC to the upper edge of the highest CC of all UL and DL configured CCs.

Configured DL spectrum (MHz)	ΔR_{IBNC} (dB)
≤ 800	0.0
> 800 and ≤ 1400	0.5
> 1400 and ≤ 2400	1.5

Table 7.3A.2.2-1: ΔR_{IBNC} EIS Relaxation for CA operation

7.3A.2.3 Inter-band CA

The inter-band requirement applies for all active component carriers. The throughput for each component carrier shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity for each carrier specified in section 7.3.2, and relaxation $\Delta R_{IB,P,n}$ applied to peak reference sensitivity requirement. $\Delta R_{IB,P,n}$ is specified in Table 7.3A.2.3-1. The requirement on each component carrier shall be met when the power in the component carrier in the other band is set to its EIS spherical coverage requirement for interband CA specified in sub-clause 7.3A.3.3.

For the combination of intra-band and inter-band carrier aggregation, the intra-band CA relaxation, ΔR_{IBC} and ΔR_{IBNC} , are also applied according to the clause 7.3A.2.1 and 7.3A.2.2.

NR CA band combinations	NR band	ΔR _{IB,P,n} (dB)				
		PC1	PC2	PC3	PC5	
CA_n257-n259	n257		3.5	4.0	3.0	
	n259		3.5	4.0	3.0	
CA_n258-n260	n258			3.5		
	n260			3.5		
CA_n258-n261	n258			3.5		
	n261			3.5		
CA_n260-n261	n260	2.5		3.5		
	n261	2.5		3.5		
Note: For each pow inter-bar			ns without specifi ation in this releas		ot enabled for	

Table 7.3A.2.3-1: $\Delta R_{IB,P,n}$ reference sensitivity relaxation for inter-band CA

7.3A.3 EIS spherical coverage for DL CA

- 7.3A.3.1 Void
- 7.3A.3.2 Void

7.3A.3.3 EIS spherical coverage for inter-band CA

The inter-band CA requirement applies per operating band, for all active component carriers with UL assigned to one band and one DL component carrier per band. The requirement on each component carrier shall be met when the power in the component carrier in the other band is set to its EIS spherical coverage requirement for inter-band CA specified in this sub-clause.

The inter-band CA spherical coverage requirement for each power class will be satisfied if the intersection set of spherical coverage areas exceeds the common coverage requirement. Intersection set of spherical coverage areas is defined as a fraction of area of full sphere measured around the UE where both bands meet their defined individual EIS spherical coverage requirements for inter-band CA operation. The common coverage requirement is determined as <100-percentile rank> %, where 'percentile rank' is the percentile value in the specification of spherical coverage for that power class from clause 7.3.4. The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link angle).

The reference measurement channels and throughput criterion shall be as specified in clause 7.3A.2.3. The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in clause 7.3.2.

Unless otherwise specified, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3.1-1) configured.

The required spherical coverage EIS for each band in inter-band CA operation is given in clause 7.3.4 and modified by $\Delta R_{IB,S,n}$. The value of $\Delta R_{IB,S,n}$ is defined in Table 7.3A.3.3-1.

NR CA band combination	NR band	ΔR _{IB,S,n} (dB)				
		PC1	PC2	PC3	PC5	
CA_n257-n259	n257		3.5	3.5	[2.5]	
	n259		3.5	3.5	[2.5]	
CA_n258-n260	n258			3.5		
	n260			3.5		
CA_n258-n261	n258			3.5		
	n261			3.5		
CA_n260-n261	n260	[2.5]		3.5		
	n261	[2.5]		3.5		
Note: For each power class, band combinations without specified ΔR _{IB,S,n} are not enabled for inter-band downlink carrier aggregation in this release.						

7.3D Void

7.4 Maximum input level

The maximum input level is defined as the maximum mean power, for which the throughput shall meet or exceed the minimum requirements for the specified reference measurement channel.

The maximum input level is defined as a directional requirement. The requirement is verified in beam locked mode in the direction where peak gain is achieved.

The throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annex A (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with parameters specified in Table 7.4.-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.	4-1: Maximur	n input level
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Rx Parameter		Channel bandwidth						
		50	100	200	400	800	1600	2000
		MHz	MHz	MHz	MHz	MHz	MHz	MHz
Power in transmission	dBm				25 (NOTE 2))		
bandwidth configuration		-27 (NOTE 3)						
NOTE 1: The transmitter shall be set to 4 dB below the P _{UMAX,f,c} as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.								
NOTE 2: Reference measurement channel is specified in Annex A.3.3.2: QPSK, R=1/3 variant with one sided dynamic OCNG Pattern as described in Annex A.								
	 Reference measurement channel is specified in Annex A.3.3.5: 256QAM, R=4/5 variant with one sided dynamic OCNG Pattern as described in Annex A. 							

Table 7.4-2: Void

7.4A Maximum input level for DL CA

Table 7.4A-1: Void

Table 7.4A-2: Void

7.4A.1 Maximum input level for Intra-band contiguous CA

For intra-band contiguous carrier aggregation the input level is defined as the cumulative received power, summed over the transmission bandwidth configurations of each active DL CC. All DL CCs shall be active throughout the test. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. At the maximum input level, the specified relative throughput shall meet or exceed the minimum requirements for the specified reference measurement channel over each component carrier. The minimum requirement is specified in Table 7.4A-1.

The maximum input level is defined as a directional requirement. The requirement is verified in beam locked mode in the direction where peak gain is achieved. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

	Rx Parameter	Units	Level		
Power su	mmed over transmission bandwidth	dBm	-25 (NOTE 2)		
conf	figurations of all active DL CCs		-27 (NOTE 3)		
NOTE 1:	NOTE 1: The transmitter shall be set to 4 dB below the PUMAX,f,c as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2				
NOTE 2: Reference measurement channel in each CC is specified in Annex A.3.3.2: QPSK, R=1/3 variant with one sided dynamic OCNG Pattern as described in Annex A.					
NOTE 3:	NOTE 3: Reference measurement channel is specified in Annex A.3.3.5: 256QAM, R=4/5 variant with one sided dynamic OCNG Pattern as described in Annex A.				

Table 7.4A.1-1: Maximum input level for	r Intra-band contiguous CA
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7.4A.2 Maximum input level for Intra-band non-contiguous CA

For intra-band non-contiguous carrier aggregation the requirement of section 7.4A.1 applies

7.4A.3 Maximum input level for Inter-band CA

For inter-band carrier aggregation with one component carrier per operating band and the uplink assigned to one NR band, the maximum input level is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.4 for each component carrier while all downlink carriers are active.

For the combination of intra-band and inter-band carrier aggregation and uplink carrier(s) assigned to one NR band, the requirement is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.4A.1 and 7.4A.2 for each band while all downlink carriers are active.

7.4D Void

7.5 Adjacent channel selectivity

Adjacent Channel Selectivity (ACS) is a measure of a receiver's ability to receive a NR signal at its assigned channel frequency in the presence of an adjacent channel signal at a given frequency offset from the centre frequency of the assigned channel. ACS is the ratio of the receive filter attenuation on the assigned channel frequency to the receive filter attenuation on the adjacent channel(s).

The requirement applies at the RIB when the AoA of the incident wave of the wanted signal and the interfering signal are both from the direction where peak gain is achieved.

The wanted and interfering signals apply to all supported polarizations, under the assumption of polarization match.

The UE shall fulfil the minimum requirement specified in Table 7.5-1 for all values of an adjacent channel interferer up to -25 dBm. However, it is not possible to directly measure the ACS, instead the lower and upper range of test parameters are chosen in Table 7.5-2 and Table 7.5-3 where the throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2, with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Operating band	Units	Ad	Adjacent channel selectivity / Channel bandwidth					
		50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
n257, n258, n261	dB	23	23	23	23	N/A	N/A	N/A
n259, n260, n262	dB	22	22	22	22	N/A	N/A	N/A
n263	dB	N/A	21	N/A	21	20	20	20

Table 7 5-2 Ad	iacent channel	selectivity test	parameters	Case 1
TUDIC 1.0-2. Au	jacent channel	Scicolivity tost	parameters,	

Rx Parameter	Units	Channel bandwidth						
Falameter		50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
Power in Transmission Bandwidth Configuration	dBm			R	EFSENS + 14	4 dB		
P _{Interferer} for band n257, n258, n261	dBm	REFSENS + 35.5 dB	REFSENS +35.5 dB	REFSENS +35.5 dB	REFSENS +35.5 dB	N/A	N/A	N/A
P _{Interferer} for band n259, n260, n262	dBm	REFSENS + 34.5 dB	REFSENS +34.5 dB	REFSENS +34.5 dB	REFSENS +34.5 dB	N/A	N/A	N/A
P _{Interferer} for band n263	dBm	N/A	REFSENS +33.5 dB	N/A	REFSENS +33.5 dB	REFSENS + 32.5 dB	REFSENS + 32.5 dB	REFSENS + 32.5 dB
BWInterferer	MHz	50	100	200	400			
F _{Interferer} (offset)	MHz	50 / -50 NOTE 3	100 / -100 NOTE 3	200 / -200 NOTE 3	400 / -400 NOTE 3	800 / -800 NOTE 3	1600 / -1600 NOTE 3	2000 / -2000 NOTE 3
 NOTE 1: The interferer consists of the Reference measurement channel specified in Annex A.3.2 with one sided dynamic OCNG Pattern as described in Annex A.3.2 and set-up according to Annex C. NOTE 2: The REFSENS power level is specified in Clause 7.3.2, which are applicable to different UE power classes. NOTE 3: The absolute value of the interferer offset F_{Interferer} (offset) shall be further adjusted to (CEIL(F_{Interferer}/SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same SCS. NOTE 4: The transmitter shall be set to 4 dB below the P_{UMAX,f,c} as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2. 								

Rx Parameter	Units			C	hannel bandv	vidth		
		50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
Power in Transmission Bandwidth Configuration for band n257, n258, n261	dBm	-46.5	-46.5	-46.5	-46.5	N/A	N/A	N/A
Power in Transmission Bandwidth Configuration for band n259, n260, n262	dBm	-45.5	-45.5	-45.5	-45.5	N/A	N/A	N/A
Power in Transmission Bandwidth Configuration for band n263	dBm	N/A	-44.5	N/A	-44.5	-43.5	-43.5	-43.5
PInterferer	dBm				-25			
BWInterferer	MHz	50	100	200	400	800	1600	2000
Finterferer (offset)	MHz	50 / -50 NOTE 2	100 / -100 NOTE 2	200 / -200 NOTE 2	400 / -400 NOTE 2	800 / -800 NOTE 2	1600 / -1600 NOTE 2	2000 / -2000 NOTE 2
NOTE 1: The interferer consists of the Reference measurement channel specified in Annex 3.2 with one sided dynamic OCNG Pattern TDD as described in Annex A and set-up according to Annex C. NOTE 2: The absolute value of the interferer offset F _{Interferer} (offset) shall be further adjusted to (CEIL(F _{Interferer} //SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same SCS. NOTE 3: The transmitter shall be set to 4 dB below the PuMAX,f,c as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.								

Table 7.5-3: Adjacent channel selectivi	ity test parameters, C	ase 2
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7.5A Adjacent channel selectivity for DL CA

Table 7.5A-1: Void

Table 7.5A-2: Void

Table 7.5A-3: Void

7.5A.1 Adjacent channel selectivity for Intra-band contiguous CA

For intra-band contiguous carrier aggregation, the SCC(s) shall be configured at nominal channel spacing to the PCC. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. The UE shall fulfil the minimum requirement specified in Table 7.5A.1-1 for an adjacent channel interferer on either side of the aggregated downlink signal at a specified frequency offset and for an interferer power up to -25 dBm.

The throughput of each carrier shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1). The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Operating band	Units	Adjacent channel selectivity / CA bandwidth class
		All CA bandwidth class
n257, n258, n261	dB	23
n259, n260, n262	dB	22
n263	dB	21 for BW _{Channel_CA} ≤ 400 MHz. 20 for BW _{Channel_CA} > 400 MHz.

Table 7.5A.1-1: Adjacent channel selectivity for intra-band contiguous CA

Table 7.5A.1-2: Adjacent channel selectivity test parameters for intra-band contiguous CA, Case 1

Rx Parameter	Units	All CA bandwidth Classes					
Pw in Transmission Bandwidth		REFSENS + 14 dB					
Configuration, per CC							
PInterferer for band n257, n258, n261	dBm	Aggregated power + 21.5					
PInterferer for band n259, n260, n262	dBm	Aggregated power + 20.5					
PInterferer for band n263	dBm	Aggregated power + 19.5					
		for BW _{Channel_CA} ≤ 400 MHz.					
		Aggregated power + 18.5					
		for BW _{Channel_CA} > 400 MHz.					
BWInterferer	MHz	BWChannel_CA					
F _{Interferer} (offset)	MHz						
		+ BW _{channel CA}					
		/					
		- BW _{channel CA}					
		NOTE 3					
		NOTE 3					
NOTE 1: The interferer consists of the	Reference r	neasurement channel specified in Annex					
		rn as described in Annex A and set-up					
according to Annex C.							
NOTE 2: The Finterferer (offset) is the free	quency sepa	aration between the center of the					
aggregated CA bandwidth an	d the center	r frequency of the Interferer signal					
NOTE 3: The absolute value of the inte	rferer offset	t FInterferer (offset) shall be further adjusted to					
(CEIL(FInterferer /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the							
carrier closest to the interferer in MHz. The interfering signal has the same SCS as							
that of the closest carrier.	that of the closest carrier.						
		v the $P_{UMAX,f,c}$ as defined in clause 6.2.4,					
with uplink configuration spec	ified in Tabl	e 7.3.2.1-2.					

Table 7.5A.1-3: Adjacent channel selectivity test parameters for intra-band contiguous CA, Case 2

Rx Parameter	Units	All CA bandwidth classes
Pw in Transmission Bandwidth Configuration, aggregated power for band n257, n258, n261	dBm	- 46.5
Pw in Transmission Bandwidth Configuration, aggregated power for band n259, n260, n262	dBm	- 45.5
Pw in Transmission Bandwidth Configuration, aggregated power for band n263	dBm	-44.5 for $BW_{Channel_CA} \le 400 \text{ MHz}$ -43.5 for $BW_{Channel_CA} > 400 \text{ MHz}$.
Pinterferer	dBm	- 25
BWInterferer	MHz	BW _{Channel_CA}
F _{Interferer} (offset)	MHz	+ BW _{channel} CA / - BW _{channel} CA
		NOTE 3

NOTE 1:	The interferer consists of the Reference measurement channel specified in Annex A.3.3.2 with
	one sided dynamic OCNG Pattern OP.1 TDD as described in Annex A.5.2.1 and set-up according to
	Annex C.
NOTE 2:	The Finterferer (offset) is the frequency separation between the center of the aggregated CA bandwidth
	and the center frequency of the Interferer signal
NOTE 3:	The absolute value of the interferer offset FInterferer (offset) shall be further adjusted to
	(CEIL(FInterferer /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the carrier closest to the
	interferer in MHz. The interfering signal has the same SCS as that of the closest carrier.
NOTE 4:	The transmitter shall be set to 4 dB below the PUMAX,f,c as defined in clause 6.2.4, with uplink
	configuration specified in Table 7.3.2.1-2.

7.5A.2 Adjacent channel selectivity for Intra-band non-contiguous CA

For intra-band non-contiguous carrier aggregation with two component carriers, two different requirements apply for out-of-gap and in-gap. For out-of-gap, the UE shall meet the requirements for each component carrier as specified in clauses 7.5. For in-gap, the requirement applies if the following minimum gap condition is met:

$$\Delta f_{ACS} \geq \mathbf{BW}_1/2 + \mathbf{BW}_2/2 + \max(\mathbf{BW}_1, \mathbf{BW}_2),$$

where Δf_{ACS} is the frequency separation between the center frequencies of the component carriers and BW_k are the channel bandwidths of carrier k, k = 1, 2.

If the minimum gap condition is met, the UE shall meet the requirements specified in clauses 7.5 for each component carrier considered. The respective channel bandwidth of the component carrier under test will be used in the parameter calculations of the requirement. In case of more than two component carriers, the minimum gap condition is computed for any pair of adjacent component carriers following the same approach as the two component carriers. The in-gap requirement for the corresponding pairs shall apply if the minimum gap condition is met.

For every component carrier to which the requirements apply, the UE shall meet the requirement with one active interferer signal (in-gap or out-of-gap) while all downlink carriers are active and the input power shall be distributed among the active DL CCs so their PSDs are aligned with each other.

7.5A.3 Adjacent channel selectivity for Inter-band CA

For inter-band carrier aggregation with one component carrier per operating band and the uplink assigned to one NR band, the adjacent channel requirements are defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.5 for each component carrier while all downlink carriers are active.

For the combination of intra-band and inter-band carrier aggregation and uplink carrier(s) assigned to one NR band, the requirement is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clauses 7.5A.1 and 7.5A.2 for each band while all downlink carriers are active.

7.5D Void

7.6 Blocking characteristics

7.6.1 General

The blocking characteristic is a measure of the receiver's ability to receive a wanted signal at its assigned channel frequency in the presence of an unwanted interferer on frequencies other than those of the spurious response or the adjacent channels, without this unwanted input signal causing a degradation of the performance of the receiver beyond a specified limit. The blocking performance shall apply at all frequencies except those at which a spurious response occurs.

The requirement applies at the RIB when the AoA of the incident wave of the wanted signal and the interfering signal are both from the direction where peak gain is achieved.

The wanted and interfering signals apply to all supported polarizations, under the assumption of polarization match.

7.6.2 In-band blocking

In-band blocking is a measure of a receiver's ability to receive a NR signal at its assigned channel frequency in the presence of an interferer at a given frequency offset from the centre frequency of the assigned channel.

The throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1). The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Rx parameter	Units	Channel bandwidth						
		50 MHz	100 MHz	200 MHz	400 MHz	800 MHz	1600 MHz	2000 MHz
Power in	dBm			•	REFSENS + 1	4 dB		
Transmission								
Bandwidth								
Configuration				r				
BWInterferer	MHz	50	100	200	400	800	1600	2000
PInterferer	dBm	REFSENS	REFSENS +	REFSEN	REFSENS +	N/A	N/A	N/A
for bands n257,		+ 35.5 dB	35.5 dB	S + 35.5	35.5 dB			
n258, n261				dB				
PInterferer	dBm	REFSENS	REFSENS +	REFSEN	REFSENS +	N/A	N/A	N/A
for bands n259,		+ 34.5 dB	34.5 dB	S + 34.5	34.5 dB			
n260, n262	dBm	N/A	REFSENS +	dB N/A	REFSENS +	REFSENS +	REFSENS +	REFSENS +
P _{Interferer} for band n263	ubm	IN/A	33.5 dB	IN/A	33.5 dB	33.5 dB	33.5 dB	33.5 dB
	MHz	≤ -100 & ≥		≤ -400 &				
Floffset		≤-100 & ≥ 100	≤ -200 & 2 200	≤ -400 & ≥ 400	≤ -800 & ≥ 800	≤ -1600 & ≥ 1600	≤ -3200 & 2 3200	≤ -4000 & ≥ 4000
		NOTE 5	NOTE 5	NOTE 5	NOTE 5	NOTE 5	3200	4000
FInterferer	MHz	$F_{DL_{low}} + 25$	F _{DL_low} + 50	F _{DL_low} +	F _{DL low} + 200	F _{DL low} + 400	F _{DL_low} + 800	F _{DL_low} +
	101112	to	to	100	to	to	to	1600
		F _{DL_high} - 25	FDL high - 50	to	F _{DL_high} - 200	F _{DL_high} - 400	FDL high - 800	to
			g.,	F _{DL_high} -		g.:		F _{DL high} -
				100				1600
NOTE 1: The inte	rferer con	sists of the Re	ference measur	ement chani	nel specified in A	Annex A.3.3.2 wi	th one sided dyn	amic OCNG
					according to A			
							fferent UE power	
	NOTE 3: The wanted signal consists of the reference measurement channel specified in Annex A.3.3.2 with one sided dynamic							
	OCNG pattern OP.1 TDD as described in Annex A.5.2.1 and set-up according to Annex C.							
NOTE 4: Floffset is signal.	NOTE 4: Floffset is the frequency separation between the center of the channel bandwidth and the center frequency of the Interferer signal.							
NOTE 5: The abs	5						Hz with SCS	
						ignal have same		
						er center freque		
NOTE 7: The tran		nall be set to 4	dB below the P	UMAX,f,c as de	fined in clause 6	.2.4, with uplink	configuration sp	ecified in
Table 7.	3.2.1-2.							

Table 7.6.2-1: In band blocking requirements

- 7.6.3 Void
- 7.6A Blocking characteristics for DL CA
- 7.6A.1 General
- 7.6A.2 In-band blocking

Table 7.6A.2-1: Void

Table 7.6A.2-2: Void

7.6A.2.1 In-band blocking for Intra-band contiguous CAFor intra-band contiguous carrier aggregation, the SCC(s) shall be configured at nominal channel spacing to the PCC. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. The UE shall fulfil the minimum requirement specified in Table 7.6A.2-1 for in the presence of an interferer at a given frequency offset from the centre frequency of the assigned channel and an interferer power shall not exceed -25 dBm. The throughput of each carrier shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1). The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.6A.2.1-1: In band blocking minimum requirements for intra-band contiguous CA

Rx Parameter	Units	All CA bandwidth classes			
Power in Transmission Bandwidth Configuration, per CC	dBm	REFSENS + 14 dB			
Pinterferer for bands n257, n258, n261	dBm	Aggregated power + 21.5 dB			
Pinterferer for bands n260, n262	dBm	Aggregated power + 20.5 dB			
Pinterferer for band n263	dBm	Aggregated power + 19.5 dB			
BWInterferer	MHz	BW _{Channel_CA}			
Floffset	MHz	+2*BW _{Channel_CA} / -2*BW _{Channel_CA}			
		NOTE 5			
FInterferer	MHz	F _{DL_low} + 0.5*BW _{Channel_CA} To F _{DL_high} - 0.5*BW _{Channel_CA}			
NOTE 1: The interferer consists of the Reference measurement channel specified in Annex A.3.3.2 with one sided dynamic OCNG Pattern OP.1 TDD as described in Annex A.5.2.1. and set-up according to Annex C.					
 NOTE 2: The REFSENS power level is specified in Table 7.3.2-1. NOTE 3: The wanted signal consists of the reference measurement channel specified in Annex A.3.3.2 QPSK, R=1/3 with one sided dynamic OCNG pattern OP.1 TDD as described in Annex A.5.2.1 and set-up according to Annex C. 					
NOTE 4: The Finterferer (offset) is the free bandwidth and the center free		eparation between the center of the aggregated CA f the Interferer signal.			
NOTE 5: The absolute value of the interferer offset F _{Interferer} (offset) shall be further adjusted to (CEIL(F _{Interferer} /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the carrier closest to the interferer in MHz. The interfering signal has the same SCS as that of the closest carrier.					
 NOTE 6: Finterferer range values for unwanted modulated interfering signals are interferer center frequencies. NOTE 7: The transmitter shall be set to 4 dB below the PUMAX,fc as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2. 					

7.6A.2.2 In-band blocking for Intra-band non-contiguous CA

For intra-band non-contiguous carrier aggregation with two component carriers, the requirement applies to out-of-gap and in-gap. For out-of-gap, the UE shall meet the requirements for each component carrier with parameters as specified

in 7.6.2-1. The requirement associated to the maximum channel between across the component carriers is selected. For in-gap, the requirement shall apply if the following minimum gap condition is met:

$$\Delta f_{IBB} \geq 0.5(BW_1 + BW_2) + 2 \max(BW_1, BW_2),$$

where Δf_{IBB} is the frequency separation between the center frequencies of the component carriers and BW_k are the channel bandwidths of carrier k, k = 1,2.

If the minimum gap condition is met, the UE shall meet the requirement specified in Table 7.6.2-1 for each component carrier. The respective channel bandwidth of the component carrier under test will be used in the parameter calculations of the requirement. In case of more than two component carriers, the minimum gap condition is computed for any pair of adjacent component carriers following the same approach as the two component carriers. The in-gap requirement for the corresponding pairs shall apply if the minimum gap condition is met. For every component carrier to which the requirements apply, the UE shall meet the requirement with one active interferer signal (in-gap or out-of-gap) while all downlink carriers are active and the input power shall be distributed among the active DL CCs so their PSDs are aligned with each other.

7.6A.2.3 In-band blocking for Inter-band CA

For inter-band carrier aggregation with one component carrier per operating band and the uplink assigned to one NR band, the in-band blocking requirements are defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.6.2 for each component carrier while all downlink carriers are active.

For the combination of intra-band and inter-band carrier aggregation and uplink carrier(s) assigned to one NR band, the requirement is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clauses 7.6A.2.1 and 7.6A.2.2 for each band while all downlink carriers are active.

- 7.6D Void
- 7.7 Void
- 7.8 Void

7.9 Spurious emissions

The spurious emissions power is the power of emissions generated or amplified in a receiver. The spurious emissions power level is measured as TRP.

The power of any narrow band CW spurious emission shall not exceed the maximum level specified in Table 7.9-1. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

Table 7.9-1: General receiver spurious emission requirements

Frequency range	Measurement bandwidth	Maximum level	NOTE						
$30MHz \le f < 1GHz$	100 kHz	-57 dBm (NOTE 2)	1						
$1 GHz \le f \le 2^{nd}$ harmonic of the upper frequency edge of the DL operating band in GHz	1 MHz	-47 dBm (NOTE 3)							
GHz Image: GHz NOTE 1: Unused PDCCH resources are padded with resource element groups with power level given by PDCCH as defined in Annex C.3.1. NOTE 2: This maximum level does not apply for Band n263 for which -36 dBm applies. NOTE 3: This maximum level does not apply for Band n263 for which -30 dBm applies.									

7.10 Void

Annex A (normative): Measurement channels

- A.1 General
- A.2 UL reference measurement channels
- A.2.1 General
- A.2.2 Void

A.2.3 Reference measurement channels for TDD

For UL RMCs defined below, TDD slot pattern defined in Table A.2.3-1 will be used for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, TDD slot patterns defined for reference sensitivity tests in Table A.3.3.1-1 will be used.

Table A.2.3-1:	Additional reference	channels paran	neters for TDD

	Parameter		Val	ue	
		SCS 60 kHz	SCS 120 kHz	SCS 480 kHz	SCS 960 kHz
		(µ=2)	(µ=3)	(µ=5)	(µ=6)
TDD Slot	Configuration pattern (Note 1)	DDDSUUUU	7DS8U	31DS32U	63DS64U
Special	Slot Configuration (Note 2)	S=4D+6G+4U	S=12D+2G	S=2D+12G	S=2D+12G
refe	renceSubcarrierSpacing	60 kHz	120 kHz	480 kHz	960 kHz
UL-DL configuration	dl-UL-TransmissionPeriodicity	2 ms	2 ms	2 ms	2ms
	nrofDownlinkSlots	3	7	31	63
	nrofDownlinkSymbols	4	12	2	2
	nrofUplinkSlot	4	8	32	64
	nrofUplinkSymbols	4	0	0	0
Ind	dexes of active UL slots	mod(slot index, 40) = {36,,39}	mod(slot index, 80) = {72,,79}	mod(slot index, 320) = {288,,319}	mod(slot index 640) = {576,,639}
Indexes of	active UL slots for UL Gap test	mod(slot index, 40) = {12,,15, 36,,39}	mod(slot index, 80) = {24,,31 ,72,,79}		
	UL slots for UL Gap when UL gap ation 3 (IE UL-GapFR2-Config-r17) is configured	mod(slot index,40)={7, 28}	mod(slot index, 80) = {15,56}		
pattern configura	e UL slots for UL Gap when UL gap ation 1 (IE <i>UL-GapFR2-Config-r17</i>) is configured	mod(slot index,160)={20, 21, 22,23, 28, 29,30,31}	mod(slot index, 320) = {8, ,15}		

NOTE 1: D denotes a slot with all DL symbols; S denotes a slot with a mix of DL, UL and guard symbols; U denotes a slot with all UL symbols. The field is for information.

NOTE 2: D, G, U denote DL, guard and UL symbols, respectively. The field is for information.

A.2.3.1 DFT-s-OFDM Pi/2-BPSK

Parameter	Allocated resource blocks (Lcrb)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits9	
	1	11	pi/2 BPSK	0	24	16	2	1	132	132
	16	11	pi/2 BPSK	0	504	16	2	1	2112	2112
	32	11	pi/2 BPSK	0	1032	16	2	1	4224	4224
	60	11	pi/2 BPSK	0	1864	16	2	1	7920	7920
	64	11	pi/2 BPSK	0	2024	16	2	1	8448	8448
	120	11	pi/2 BPSK	0	3752	16	2	1	15840	15840
	128	11	pi/2 BPSK	0	3976	24	2	2	16896	16896
	144	11	pi/2 BPSK	0	4488	24	2	2	19008	19008
	243	11	pi/2 BPSK	0	7560	24	2	2	32076	32076
	256	11	pi/2 BPSK	0	7944	24	2	3	33792	33792
D NOTE 2: M NOTE 3: If	M-RS positio	ns are set to based on MC ne Code Bloo	ind single-syml symbols 2, 7, CS table 6.1.4. ck is present, a	11. DMRS 1-1 defined	is [TDM'ed] in 38.214.	with PUSCH	data. DM-F	RS symbols	are not cou	nted.

NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.
 NOTE 5: The RMCs apply to all channel bandwidth where L_{CRB} ≤ N_{RB}.

Table A.2.3.1-2: Void

A.2.3.2 DFT-s-OFDM QPSK

Table A.2.3.2-1: Reference Channels for DFT-s-OFDM QPSK

Parameter	Allocated resource blocks (Lcrb)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	QPSK	2	48	16	2	1	264	132
	16	11	QPSK	2	808	16	2	1	4224	2112
	20	11	QPSK	2	1032	16	2	1	5280	2640
	32	11	QPSK	2	1608	16	2	1	8448	4224
	60	11	QPSK	2	2976	16	2	1	15840	7920
	64	11	QPSK	2	3240	16	2	1	16896	8448
	120	11	QPSK	2	5896	24	2	2	31680	15840
	128	11	QPSK	2	6408	24	2	2	33792	16896
	144	11	QPSK	2	7176	24	2	2	38016	19008
	243	11	QPSK	2	12040	24	2	4	64152	32076
	256	11	QPSK	2	12808	24	2	4	67584	33792
NOTE 2: M NOTE 3: I NOTE 4: I	DM-RS position MCS Index is I f more than or otherwise L = ndexes of action equiring at lea	ons are set to based on MO ne Code Blo 0 Bit) ive UL slots ast one sub f	and single-syml symbols 2, 7, CS table 6.1.4. ck is present, a are given by Ta rame (1ms) for g mod(slot inde	11. DMRS 1-1 defined in additiona able A.2.3-1 the measu	is [TDM'ed] in 38.214. I CRC sequ with TDD U rement peri	with PUSCH ence of L = 2 JL-DL configu od. For other	data. DM-F 4 Bits is att iration spec requiremer	RS symbols ached to ea bified in A2.3 hts, indexes	are not cou ch Code Blo 3 for the req of active UL	nted. ock uirements
			nnel bandwidth			seringe	op oo			

Table A.2.3.2-2: Void

A.2.3.3 DFT-s-OFDM 16QAM

Parameter	Allocated resource blocks (L _{CRB})	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	16QAM	10	176	16	2	1	528	132
	16	11	16QAM	10	2792	16	2	1	8448	2112
	32	11	16QAM	10	5632	24	1	1	16896	4224
	60	11	16QAM	10	10504	24	1	2	31680	7920
	64	11	16QAM	10	11272	24	1	2	33792	8448
	120	11	16QAM	10	21000	24	1	3	63360	15840
	128	11	16QAM	10	22536	24	1	3	67584	16896

	144	11	16QAM	10	25104	24	1	3	76032	19008										
	243	11	16QAM	10	43032	24	1	6	128304	32076										
	256	11	16QAM	10	45096	24	1	6	135168	33792										
NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the																				
DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data. DM-RS symbols are not counted.																				
NOTE 2:	NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.																			
NOTE 3:	If more than or	ne Code Blo	ck is present, a	n additiona	I CRC sequ	ence of $L = 24$	4 Bits is atta	ached to eached	ch Code Blo	ck										
	(otherwise L =																			
NOTE 4:	Indexes of acti																			
	requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are																			
	given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.																			
NOTE 5:	The RMCs app	oly to all cha	nnel bandwidth	where L _{CR}	_B ≤ N _{RB.}					The RMCs apply to all channel bandwidth where $L_{CRB} \leq N_{RB}$.										

Table A.2.3.3-2: Void

A.2.3.4 DFT-s-OFDM 64QAM

Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot		
Unit					Bits	Bits			Bits			
	1	11	64QAM	18	408	16	2	1	792	132		
	16	11	64QAM	18	6400	24	1	1	12672	2112		
	32	11	64QAM	18	12808	24	1	2	25344	4224		
	60	11	64QAM	18	24072	24	1	3	47520	7920		
	64	11	64QAM	18	25608	24	1	4	50688	8448		
	120	11	64QAM	18	48168	24	1	6	95040	15840		
	128	11	64QAM	18	51216	24	1	7	101376	16896		
	144	11	64QAM	18	57376	24	1	7	114048	19008		
	243	11	64QAM	18	96264	24	1	12	192456	32076		
	256	11	64QAM	18	102416	24	1	13	202752	33792		
I	NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data. DM-RS symbols are not counted.											
NOTE 3:	If more than or (otherwise L =	ne Code Blo 0 Bit)	CS table 6.1.4.7 ck is present, a	in additiona	I CRC sequ							
NOTE 4:	indexes of acti	ive UL slots :	are given by Ta	able A.2.3-1	with IDD L	JE-DE configu	iration spec	litied in A2.3	s for the real	Jirements		

Table A.2.3.4-1: Reference Channels for DFT-s-OFDM 64QAM

NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

NOTE 5: The RMCs apply to all channel bandwidth where $L_{CRB} \leq N_{RB}$.

Table A.2.3.4-2: Void

A.2.3.5 CP-OFDM QPSK

Table A.2.3.5-1: Reference Channels for CP-OFDM QPSK

Parameter	Allocated resource blocks (L _{CRB)}	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	QPSK	2	48	16	2	1	264	132

	16	11	QPSK	2	808	16	2	1	4224	2112
	32	11	QPSK	2	1608	16	2	1	8448	4224
	33	11	QPSK	2	1672	16	2	1	8712	4356
	62	11	QPSK	2	3104	16	2	1	16368	8184
	66	11	QPSK	2	3368	16	2	1	17424	8712
	124	11	QPSK	2	6152	24	2	2	32736	16368
	132	11	QPSK	2	6536	24	2	2	34848	17424
	148	11	QPSK	2	7304	24	2	2	39072	19536
	248	11	QPSK	2	12296	24	2	4	65472	32736
	264	11	QPSK	2	13064	24	2	4	69696	34848
NOTE 1:	PUSCH mappi	ing Type-A a	ind single-symb	ol DM-RS	configuratio	n Type-1 with	2 additiona	al DM-RS sy	mbols, sucl	n that the
	DM-RS positio	ns are set to	symbols 2, 7,	11. DMRS	is [TDM'ed]	with PUSCH	data. DM-R	S symbols	are not cour	nted.
NOTE 2:	MCS Index is b	based on MC	CS table 5.1.3.1	I-1 defined	in 38.214.					
NOTE 3:	If more than or	ne Code Blo	ck is present, a	n additiona	I CRC sequ	ence of $L = 2$	4 Bits is atta	ached to ea	ch Code Blo	ock
	(otherwise L =	0 Bit)								
NOTE 4:	Indexes of acti									
	requiring at lea	ast one sub f	rame (1ms) for	the measu	rement peri	od. For other	requiremen	ts, indexes	of active UL	slots are
	given by the sl	ots satisfying	g mod(slot inde	x+1, 5) = 0	with TDD L	IL-DL configu	ration speci	fied in A.3.3	3.1.	
NOTE 5:	The RMCs app	oly to all chai	nnel bandwidth	where LCR	B ≤ N _{RB.}					

Table A.2.3.5-2: Void

A.2.3.6 CP-OFDM 16QAM

Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	16QAM	10	176	16	2	1	528	132
	16	11	16QAM	10	2792	16	2	1	8448	2112
	32	11	16QAM	10	5632	24	1	1	16896	4224
	33	11	16QAM	10	5760	24	1	1	17424	4356
	62	11	16QAM	10	10760	24	1	2	32736	8184
	66	11	16QAM	10	11528	24	1	2	34848	8712
	124	11	16QAM	10	21504	24	1	3	65472	16368
	132	11	16QAM	10	23040	24	1	3	69696	17424
	148	11	16QAM	10	26120	24	1	4	78144	19536
	248	11	16QAM	10	43032	24	1	6	130944	32736
	264	11	16QAM	10	46104	24	1	6	139392	34848
NOTE 2: M NOTE 3: I (NOTE 4: I	DM-RS position MCS Index is I f more than or otherwise L = ndexes of action	ns are set to based on MC ne Code Blo 0 Bit) ive UL slots	and single-syml symbols 2, 7, CS table 5.1.3. ck is present, a are given by Ta rame (1ms) for	11. DMRS 1-1 defined in additiona able A.2.3-1	is [TDM'ed] in 38.214. I CRC sequ with TDD U	with PUSCH ence of L = 2 JL-DL configu	data. DM-F 4 Bits is att iration spec	RS symbols ached to ea cified in A2.3	are not cou ch Code Blo 3 for the req	nted. ock uirements

given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1. NOTE 5: The RMCs apply to all channel bandwidth where $L_{CRB} \leq N_{RB}$.

Table A.2.3.6-2: Void

A.2.3.7 CP-OFDM 64QAM

Table A.2.3.7-1: Reference Channels for CP-OFDM 64QAM

Parameter	Allocated resource blocks (L _{CRB})	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	64QAM	19	408	16	2	1	792	132
	16	11	64QAM	19	6400	24	1	1	12672	2112
	32	11	64QAM	19	12808	24	1	2	25344	4224
	33	11	64QAM	19	13064	24	1	2	26136	4356
	62	11	64QAM	19	24576	24	1	3	49104	8184
	66	11	64QAM	19	26120	24	1	4	52272	8712
	124	11	64QAM	19	49176	24	1	6	98208	16368
	132	11	64QAM	19	53288	24	1	7	104544	17424
	148	11	64QAM	19	59432	24	1	8	117216	19536
	248	11	64QAM	19	98376	24	1	12	196416	32736
	264	11	64QAM	19	106576	24	1	13	209088	34848
NOTE 2: M NOTE 3: I NOTE 4: I	DM-RS position MCS Index is I f more than or otherwise L = ndexes of action equiring at leas given by the sl	ns are set to based on MC ne Code Bloo 0 Bit) ve UL slots a ast one sub f ots satisfying	and single-syml symbols 2, 7, CS table 5.1.3. ck is present, a are given by Ta rame (1ms) for g mod(slot inde nnel bandwidth	11. DMRS 1-1 defined in additiona able A.2.3-1 the measu ex+1, 5) = 0	is [TDM'ed] in 38.214. I CRC sequ with TDD I rement peri with TDD L	with PUSCH ence of L = 2- JL-DL configu od. For other	data. DM-F 4 Bits is att ration spec requiremer	RS symbols ached to ea cified in A2.3 nts, indexes	are not cou ch Code Blo 3 for the req of active UL	nted. ock uirements

Table A.2.3.7-2: Void

A.3 DL reference measurement channels

A.3.1 General

Unless otherwise stated, Tables A.3.3.2-1 and A.3.3.2-2 are applicable for measurements of the Receiver Characteristics (clause 7).

Unless otherwise stated, Tables A.3.3.2-1 and A.3.3.2-2 also apply for the modulated interferer used in Clauses 7.5 and 7.6 with test specific bandwidths.

CSI-RS configuration parameter defined in Table A.3.1-2 and Table A.3.1-3 are used for verifying the beam correspondence requirement, 2 slots of CSI-RS shall be provided at each test grid point. The DL channel shall be configured for zero power on all tones except those used by CSI-RS in slots containing CSI-RS for beam refinement, and the DL and UL channel sizes shall be the same during verification.

Para	imeter	Unit	Value		
CORESET frequen	cy domain allocation		Full BW		
CORESET time	domain allocation		2 OFDM symbols at the begin of each slot		
PDSCH m	apping type		Туре А		
PDSCH start symbol index (S)			2		
Number of consecutiv	ve PDSCH symbols (L)		12		
PDSCH PI	RB bundling	PRBs	2		
Dynamic P	RB bundling		false		
MCS table for T	BS determination		64QAM		
Overhead value fo	r TBS determination		0		
First DMRS position for	Type A PDSCH mapping		2		
DMR	S type		Туре 1		
Number of ac	Iditional DMRS		2		
FDM between D	FDM between DMRS and PDSCH		Disable		
CSI-RS for tracking	First subcarrier index in				
	the PRB used for CSI-RS		0 for CSI-RS resource 1,2		
	(k0)				
	OFDM symbols in the		$l_0 = 8$ for CSI-RS resource 1		
	PRB used for CSI-RS		$l_0 = 12$ for CSI-RS resource 2		
	Number of CSI-RS ports		1 for CSI-RS resource 1,2		
	CDM Type		'No CDM' for CSI-RS resource 1,2		
	Density (ρ)		3 for CSI-RS resource 1,2		
	CSI-RS periodicity	Slots	60 kHz SCS: 80 for CSI-RS resources 1 and 2		
			120 kHz SCS: 160 for CSI-RS resources 1 and 2		
	CSI-RS offset	Slots	60 kHz SCS: 40 for CSI-RS resources 1 and 2		
			120kHz SCS: 80 for CSI-RS resources 1 and 2		
	Frequency Occupation		Start PRB 0		
			Number of PRB = BWP size		
	QCL info		TCI state #0		
PTRS co	nfiguration		PTRS is not configured		

Table A.3.1-1: Test parameters

Resource Type	aperiodic
Resource Set Config	•
repetition	on
aperiodicTriggeringOffset	Depending on UE capability
Resource Config	
nzp-CSI-RS-Resourceld	30 for resource #0
	31 for resource #1
	32 for resource #2
	33 for resource #3
	34 for resource #4
	35 for resource #5
	36 for resource #6
	37 for resource #7
powerControlOffset	0
powerControlOffsetSS	db0
nrofPorts	1
firstOFDMSymbolInTimeDomain	6 for resource #0
	7 for resource #1
	8 for resource #2
	9 for resource #3
	10 for resource #4
	11 for resource #5
	12 for resource #6
	13 for resource #7
cdm-Type	noCDM
density	3
nrofRBs	48 for channel
	bandwidth≥100MHz
	32 for channel
	bandwidth=50MHz
qcl-info	Type D to SSB

Table A.3.1-2: CSI-RS parameters for beam correspondence based on SSB and CSI-RS

CSI-RS configuration parameter defined in Table A.3.1-3 is used for verifying the beam correspondence requirement, CSI-RS shall be provided once every 10msec.

Resource Type	aperiodic
Resource Set Config	•
repetition	on
aperiodicTriggeringOffset	Depending on UE capability
Resource Config	
nzp-CSI-RS-ResourceId	30 for resource #0
	31 for resource #1
	32 for resource #2
	33 for resource #3
	29+N for resource #(N-1), where N is maxNumberRxBeam in UE capability IE of
	MIMO-ParametersPerBand
powerControlOffset	0
powerControlOffsetSS	db0
nrofPorts	1
firstOFDMSymbolInTimeDomain	6 for resource #0
	7 for resource #1
	8 for resource #2
	9 for resource #3
	5+N for resource #(N-1), where N=maxNumberRxBeam-1 in UE capability IE of
	MIMO-ParametersPerBand
cdm-Type	noCDM
density	3
nrofRBs	48 for channel bandwidth≥100MHz
	32 for channel bandwidth=50MHz
qcl-info	Type D to SSB

 Table A.3.1-3: CSI-RS parameters for CSI-RS based beam correspondence

A.3.2 Void

A.3.3 DL reference measurement channels for TDD

A.3.3.1 General

Pa	rameter	Value						
		SCS 60 kHz (µ=2)	SCS 120 kHz (μ=3))	SCS 480 kHz (µ=5)	SCS 960 kHz (µ=6)			
TDD Slot Configu	uration pattern (Note 1)	DDDSU	DDDSU	DDDSU	DDDSU			
	onfiguration (Note 2)	S=4D+6G+4U	S=10D+2G+2U	S=10D+2G+2U	S=10D+2G+2U			
referenceSubcarrierSpacing		60 kHz	120 kHz	120 kHz 480 kHz				
UL-DL configuration	dl-UL- TransmissionPeriodicity	1.25 ms	0.625 ms	0.3125 ms	0.15625 ms			
, i i i i i i i i i i i i i i i i i i i	nrofDownlinkSlots	3	3	3	3			
	nrofDownlinkSymbols	4	10	10	10			
	nrofUplinkSlot	1	1	1	1			
	nrofUplinkSymbols	4	2	2	2			
Number of HARQ Processes		8	8	8	8			
The number of slo	ts between PDSCH and	K1 = 4 if						
corresponding HAR	Q-ACK information (Note	mod(i,5) = 0	mod(i,5) = 0	mod(i,5) = 0	mod(i,5) = 0			
	3)	K1 =3 if mod(i,5)						
		= 1	= 1	= 1	= 1			
		K1 =7 if mod(i,5) = 2						
		where i is slot						
		index per frame;		index per frame;	index per frame;			
		$i = \{0,, 39\}$	$i = \{0,, 79\}$	$i = \{0, \dots, 319\}$	$i = \{0, \dots, 639\}$			
	s a slot with all DL symbols L symbols. The field is for i	s; S denotes a slot v						
NOTE 2: D, G, U d	lenote DL, guard and UL sy	mbols, respectively	. The field is for info	ormation.				
NOTE 3: i is the slo	ot index per frame.							

Table A.3.3.1-1. Additional test parameters for TDD

A.3.3.2 FRC for receiver requirements for QPSK

Parameter	Unit		Value	
Channel bandwidth	MHz	50	100	200
μ		2	2	2
Subcarrier spacing configuration				
Allocated resource blocks		66	132	264
Subcarriers per resource block		12	12	12
Allocated slots per Frame		23	23	23
MCS index		4	4	4
Modulation		QPSK	QPSK	QPSK
Target Coding Rate		1/3	1/3	1/3
Maximum number of HARQ transmissions		1	1	1
Information Bit Payload per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for	Bits	N/A	N/A	N/A
i from {0,,79} (NOTE 5)	Dite	400.4	0.450	40000
For Slot i, if mod(i, 5) = $\{0,1,2\}$ for i from	Bits	4224	8456	16896
{1,,79} (NOTE 6)	Dite	0.1	0.1	0.1
Transport block CRC	Bits	24	24	24
LDPC base graph		1	1	1
Number of Code Blocks per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for	CBs	N/A	N/A	N/A
i from {0,,79} (NOTE 5)				
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79} (NOTE 6)	CBs	1	2	2
Binary Channel Bits Per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for	Bits	N/A	N/A	N/A
i from {0,,79} (NOTE 5)				
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79} (NOTE 6)	Bits	10.138	20.294	40.550
Max. Throughput averaged over 1 frame	Mbps	9.715	19.449	38.861
NOTE 1: Additional parameters are specifie		3.1-1 and Tal	ble A.3.3.1-1	
NOTE 2: If more than one Code Block is pre	esent, an addi	itional CRC s	sequence of	L = 24 Bits
is attached to each Code Block (ot	herwise L = 0) Bit).		
NOTE 3: SS/PBCH block is transmitted in sl	lot 0 with peri	odicity 20 ms	3	
NOTE 4: Slot i is slot index per 2 frames	-	-		
NOTE 5: When this DL RMC used together	with the UL R	MC for the t	ransmitter re	quirements
requiring at least one sub frame (1	ms) for the m	easurement	period, Slot	i, if mod(i,
8) = $\{3,4,5,6,7\}$ for i from $\{0,\ldots,79\}$	together with	the TDD UL	-DL configur	ation
specified in A2.3.	-		Ū.	
NOTE 6: When this DL RMC used together				
requiring at least one sub frame (1	ms) for the m	easurement	period, Slot	i, if mod(i,
8) = $\{0,1,2\}$ for i from $\{0,,79\}$ toge				
in A2.3.			-	•

Table A.3.3.2-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

Parameter	lue						
Channel bandwidth	MHz	50	100	200	400		
Subcarrier spacing configuration $^{\mu}$		3	3	3	3		
Allocated resource blocks		32	66	132	264		
Subcarriers per resource block		12	12	132	12		
Allocated slots per Frame		47	47	47	47		
MCS index		4	4	4	4		
Modulation		QPSK	QPSK	QPSK	QPSK		
Target Coding Rate		1/3	1/3	1/3	1/3		
Maximum number of HARQ transmissions		1	1	1	1		
Information Bit Payload per Slot							
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159} (NOTE 5)	Bits	N/A	N/A	N/A	N/A		
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159} (NOTE 6)	Bits	2088	4224	8456	16896		
Transport block CRC	Bits	16	24	24	24		
LDPC base graph		2	1	1	1		
Number of Code Blocks per Slot							
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159} (NOTE 5)	CBs	N/A	N/A	N/A	N/A		
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159} (NOTE 6)	CBs	1	1	2	2		
Binary Channel Bits Per Slot							
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159} (NOTE 5)	Bits	N/A	N/A	N/A	N/A		
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159} (NOTE 6)	Bits	6912	14256	28512	57024		
Max. Throughput averaged over 1 frame	Mbps	10.022	20.275	40.589	81.101		
 NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1. NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 with periodicity 20 ms NOTE 4: Slot i is slot index per 2 frames NOTE 5: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if mod(i, 16) = {7,,15} for i from {0,,159} together with the TDD UL-DL configuration specified in A2.3. NOTE 6: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if mod(i, 16) = {0,,6} for i 							

Table A.3.3.2-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

A.3.3.3 FRC for receiver requirements for 16QAM

A.3.3.4 FRC for receiver requirements for 64QAM

Parameter	Unit		Value	
Channel bandwidth	MHz	50	100	200
Subcarrier spacing configuration $^{\mu}$		2	2	2
Allocated resource blocks		66	132	264
Subcarriers per resource block		12	12	12
Allocated slots per Frame		23	23	23
MCS index		19	19	19
Modulation		64QAM	64QAM	64QAM
Target Coding Rate		1/2	1/2	1/2
Maximum number of HARQ transmissions		1	1	1
Information Bit Payload per Slot				
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}	Bits	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0, 1, 2\}$ for i from $\{1,, 79\}$	Bits	20496	40976	81976
Transport block CRC	Bits	24	24	24
LDPC base graph		1	1	1
Number of Code Blocks per Slot				
For Slot i, if $mod(i, 10) = \{0, 1, 2\}$ for i from	CBs	N/A	N/A	N/A
{1,,79} For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}	CBs	3	5	10
Binary Channel Bits Per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for	Bits	N/A	N/A	N/A
i from {0,,79}				
For Slot i, if $mod(i, 5) = \{0, 1, 2\}$ for i from $\{1,, 79\}$	Bits	40986	81972	163944
Max. Throughput averaged over 1 frame	Mbps	49.190	98.343	196.742
NOTE 1: Additional parameters are specifie				
NOTE 2: If more than one Code Block is pre-				
is attached to each Code Block (of				
NOTE 3: SS/PBCH block is transmitted in s			6	
NOTE 4: Slot i is slot index per 2 frames		,		
NOTE 5: PTRS is configured on symbols co	ntaining PDS	SCH with 1 pc	ort, per 2PRE	3 in
frequency domain, per symbol in ti				
assumed to be 6.				

Table A.3.3.4-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

Parameter	Unit		Va	lue	
Channel bandwidth	MHz	z 50 100 200			400
Subcarrier spacing configuration $^{\mu}$		3	3	3	3
Allocated resource blocks		32	66	132	264
Subcarriers per resource block		12	12	12	12
Allocated slots per Frame		47	47	47	47
MCS index		19	19	19	19
Modulation		64QAM	64QAM	64QAM	64QAM
Target Coding Rate		1/2	1/2	1/2	1/2
Maximum number of HARQ transmissions		1	1	1	1
Information Bit Payload per Slot					
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159}	Bits	N/A	N/A	N/A	N/A
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159}	Bits	9992	20496	40976	81976
Transport block CRC	Bits	24	24	24	24
LDPC base graph		1	1	1	1
Number of Code Blocks per Slot					
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159}	CBs	N/A	N/A	N/A	N/A
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159}	CBs	2	3	5	10
Binary Channel Bits Per Slot					
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159}	Bits	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0, 1, 2\}$ for i from $\{1,, 159\}$	Bits	19872	40986	81972	163944
Max. Throughput averaged over 1 frame	Mbps	47.962	98.381	196.685	393.485
 NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1. NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame NOTE 4: Slot i is slot index per frame 					
NOTE 5: PTRS is configured on symbols co domain, per symbol in time domain					

Table A.3.3.4-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

A.3.3.5 FRC for receiver requirements for 256QAM

$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Parameter	Unit		Value			
Subcarrier spacing configuration μ $ -$ Allocated resource blocks66132264Subcarriers per resource block121212Allocated slots per Frame (NOTE 6)23 / 2423 / 2423 / 24MCS index242424Modulation256QAM256QAMTarget Coding Rate4/54/5Maximum number of HARQ transmissions11Information Bit Payload per Slot-For Slots 0 and Slot i, if mod(i, 5) = {3,4} forBitsN/AN/AN/Ai from {0,,79}-For Slot i, if mod(i, 5) = {0,1,2} for i fromBits2424LDPC base graph111Number of Code Blocks per SlotFor Slots 0 and Slot i, if mod(i, 5) = {3,4} forCBsN/AN/AN/Ai from {0,,79}For Slot i, if mod(i, 5) = {0,1,2} for i fromCBs61121Mumber of Code Blocks per SlotFor Slots 0 and Slot i, if mod(i, 5) = {3,4} forCBsN/AN/AN/Ai from {0,,79}For Slot i, if mod(i, 5) = {0,1,2} for i fromBits53856107712215424 $(1,,79)$ For Slots 0 and Slot i, if mod(i, 5) = {3,4} forBitsN/AN/AN/AN/Ai, from {0,,79}For Slots 0 and Slot i, if mod(i, 5	Channel bandwidth	MHz	50	100	200		
Allocated resource blocks66132264Subcarriers per resource block12121212Allocated slots per Frame (NOTE 6)23 / 2423 / 2423 / 2423 / 24MCS index24242424Modulation256QAM256QAM256QAMTarget Coding Rate4/54/54/5Maximum number of HARQ transmissions111Information Bit Payload per Slot	Subcarrier spacing configuration μ		2	2	2		
Allocated slots per Frame (NOTE 6) $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ $23/24$ 24 26 QAM $256QAM$ N/A			66	132	264		
Allocated slots per Frame (NOTE 6)23 / 2423 / 2423 / 24MCS index24242424Modulation256QAM256QAM256QAMTarget Coding Rate4/54/54/5Maximum number of HARQ transmissions111Information Bit Payload per Slot111For Slots 0 and Slot i, if mod(i, 5) = {3,4} forBitsN/AN/AFor Slot i, if mod(i, 5) = {0,1,2} for i fromBits4404088064176208 $\{1,,79\}$ Transport block CRCBits242424LDPC base graph1111Number of Code Blocks per Slot1111For Slots 0 and Slot i, if mod(i, 5) = {3,4} forCBsN/AN/AN/AIf from {0,,79}11111For Slots 0 and Slot i, if mod(i, 5) = {3,4} forCBs61121 $\{1,,79\}$ If from {0,,79If from {0,,79}If from {0,,79}If from {0,,79}For Slots 0 and Slot i, if mod(i, 5) = {0,1,2} for i from {0,,79}BitsN/AN/AN/AFor Slots 0 and Slot i, if mod(i, 5) = {0,1,2} for i from {0,,79}Bits53856107712215424 $\{1,,79\}$ Max. Throughput averaged over 1 frame {0,,79}Mbps105.696211.354422.899Max. Throughput averaged over 1 frame {0,,79}Mbps105.696211.354422.899NOTE 1:Additional parameters are specified in Table A	Subcarriers per resource block		12	12	12		
MCS index24242424Modulation256QAM256QAM256QAMTarget Coding Rate4/54/54/5Maximum number of HARQ transmissions111Information Bit Payload per Slot111For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}BitsN/AN/AFor Slots 0, if mod(i, 5) = {0,1,2} for i from $\{1,,79\}$ Bits242424Transport block CRCBits242424LDPC base graph1111Number of Code Blocks per SlotImmod(i, 5) = {3,4} for i from {0,,79}N/AN/AN/AFor Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}CBs61121For Slots 0 and Slot i, if mod(i, 5) = {3,4} for $\{1,,79\}$ CBs61121For Slots 0 and Slot i, if mod(i, 5) = {3,4} for $\{1,,79\}$ BitsN/AN/AN/AFor Slots 0 and Slot i, if mod(i, 5) = {3,4} for $\{1,,79\}$ Bits107712215424For Slots 0 and Slot i, if mod(i, 5) = {3,4} for $\{1,,79\}$ Bits53856107712215424Max. Throughput averaged over 1 frame (NOTE 7)Mbps105.696211.354422.899NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.NOTE 3: SS/PBCH block is transmitted in slot 0 of each frameNOTE 4: Slot i is slot index per 2 framesNOTE 4: Slot i is slot index per 2 framesNOTE 5: FTRS is configured on	Allocated slots per Frame (NOTE 6)		23 / 24	23 / 24	23 / 24		
Target Coding Rate4/54/54/5Maximum number of HARQ transmissions111Information Bit Payload per Slot			24	24	24		
Maximum number of HARQ transmissions111Information Bit Payload per SlotInformation Bit Payload per SlotInformation Bit Payload per SlotFor Slots 0 and Slot i, if mod(i, 5) = {3,4} forBitsN/AN/AN/AI from {0,,79}If mod(i, 5) = {0,1,2} for i fromBits4404088064176208Transport block CRCBits24242424LDPC base graph1111Number of Code Blocks per SlotInform {0,,79}Inform {0,,79}Inform {0,,79}For Slots 0 and Slot i, if mod(i, 5) = {3,4} forCBsN/AN/AN/AI from {0,,79}Inform {0,,79}Inform {0,,79}Inform {0,,79}For Slots 0, if mod(i, 5) = {0,1,2} for i fromCBs61121{1,,79}Inform {0,,79}Inform {0,,79}Inform {0,,79}Inform {0,,79}Binary Channel Bits Per SlotInform {0,,79}Inform {0,,79}Inform {0,,79}For Slots 0 and Slot i, if mod(i, 5) = {0,1,2} for i fromBits53856107712215424{1,,79}Inform {0,,79}Inform {0,,79}Inform {0,,79}Inform {0,,79}Max. Throughput averaged over 1 frame (NOTE 7)Mbps105.696211.354422.899NOTE 1:Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.NOTE 3:SS/PBCH block is transmitted in slot 0 of each frameNOTE 3:SS/PBCH block is transmitted in slot 0 of each frameNT, per 2PRB in frequen	Modulation		256QAM	256QAM	256QAM		
Information Bit Payload per SlotBitsN/AN/AFor Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}BitsN/AN/AN/AFor Slot i, if mod(i, 5) = {0,1,2} for i from ${1,,79}$ Bits4404088064176208Transport block CRCBits242424LDPC base graph111Number of Code Blocks per Slot	Target Coding Rate		4/5	4/5	4/5		
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}BitsN/AN/AN/AFor Slot i, if mod(i, 5) = {0,1,2} for i from $\{1,,79\}$ Bits4404088064176208Transport block CRCBits242424LDPC base graph111Number of Code Blocks per SlotImmodiaN/AN/AFor Slots 0 and Slot i, if mod(i, 5) = {3,4} for if rom {0,,79}CBsN/AN/AN/AFor Slots 0 and Slot i, if mod(i, 5) = {3,4} for $\{1,,79\}$ CBs61121Binary Channel Bits Per SlotImmodiaImmodiaImmodiaImmodiaImmodiaFor Slots 0 and Slot i, if mod(i, 5) = {3,4} for $\{1,,79\}$ BitsN/AN/AN/AFor Slots 0 and Slot i, if mod(i, 5) = {3,4} for $\{1,,79\}$ ImmodiaImmodiaImmodiaFor Slots 0 and Slot i, if mod(i, 5) = {3,4} for $\{1,,79\}$ BitsN/AN/AN/AFor Slot i, if mod(i, 5) = {0,1,2} for i from $(NOTE 7)$ Bits53856107712215424Max. Throughput averaged over 1 frame $(NOTE 7)$ Mbps105.696211.354422.899NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.NOTE 3: $SS/PBCH block is transmitted in slot 0 of each frameNOTE 3:SS/PBCH block is transmitted in slot 0 of each frameImmediaImmediaImmediaNOTE 4:Slot i is slot index per 2 framesImmediaImmediaImmediaImmediaNOTE 5:PTRS is configured on symb$	Maximum number of HARQ transmissions		1	1	1		
i from $\{0,, 79\}$ Bits4404088064176208For Slot i, if mod(i, 5) = $\{0, 1, 2\}$ for i from $\{1,, 79\}$ Bits242424LDPC base graph1111Number of Code Blocks per SlotImage: Constraint of Code Blocks per SlotImage: Constraint of Code Blocks per SlotImage: Constraint of Code Blocks per SlotFor Slots 0 and Slot i, if mod(i, 5) = $\{3,4\}$ for $\{1,, 79\}$ CBsN/AN/AN/AFor Slot i, if mod(i, 5) = $\{0,1,2\}$ for i from $\{1,, 79\}$ CBs61121Binary Channel Bits Per SlotImage: Constraint of Constr	Information Bit Payload per Slot						
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}Bits4404088064176208Transport block CRCBits242424LDPC base graph1111Number of Code Blocks per Slot1111For Slots 0 and Slot i, if mod(i, 5) = {3,4} for $1 \mod (0,,79)$ CBsN/AN/AN/AFor Slots 0 and Slot i, if mod(i, 5) = {0,1,2} for i from $\{1,,79\}$ CBs61121Binary Channel Bits Per Slot	i from {0,,79}	Bits	N/A	N/A	N/A		
LDPC base graph1111Number of Code Blocks per SlotImage: Slot Slot Slot Slot Slot Slot Slot Slot	For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from	Bits	44040	88064	176208		
Number of Code Blocks per Slot Number of Code Blocks per Slot For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79} CBs N/A N/A N/A For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79} CBs 6 11 21 Binary Channel Bits Per Slot Image: Channel Bits Per Slot Image: Channel Bits Per Slot Image: Channel Bits Per Slot For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79} Bits N/A N/A N/A For Slots 0, inf mod(i, 5) = {0,1,2} for i from i from {0,,79} Bits 53856 107712 215424 For Slots 0, i mod(i, 5) = {0,1,2} for i from {1,,79} Bits 53856 107712 215424 Max. Throughput averaged over 1 frame (NOTE 7) Mbps 105.696 211.354 422.899 NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1. NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame NOTE 4: Slot i is slot index per 2 frames NOTE 4: Slot i is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is	Transport block CRC	Bits	24	24	24		
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For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}CBsN/AN/AN/AFor Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}CBs61121Binary Channel Bits Per SlotImage: Channel Bits Per SlotImage: Channel Bits Per SlotImage: Channel Bits Per SlotFor Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}BitsN/AN/AN/AFor Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}Bits53856107712215424Max. Throughput averaged over 1 frame (NOTE 7)Mbps105.696211.354422.899NOTE 1: is attached to each Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit).Image: CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit).NOTE 3: NOTE 4: SS/PBCH block is transmitted in slot 0 of each frame MOTE 4: Slot i is slot index per 2 framesImage: CRC sequence of TBS calculation is assumed to be 6.NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.	Number of Code Blocks per Slot						
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}CBs61121Binary Channel Bits Per SlotImage: Signature of the second frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.CBs61121Binary Channel Bits Per SlotImage: Signature of the RMC.Image: Signature of the RMC.Image: Signature of the RMC.Image: Signature of the RMC.Binary Channel Bits Per SlotImage: Signature of the RMC.Image: Signature of the RMC.Image: Signature of the RMC.Binary Channel Bits Per SlotImage: Signature of the RMC.Image: Signature of the RMC.Image: Signature of the RMC.Binary Channel Bits Per SlotImage: Signature of the RMC.Image: Signature of the RMC.Image: Signature of the RMC.Binary Channel Bits Per SlotImage: Signature of the RMC.Image: Signature of the RMC.Image: Signature of the RMC.Binary Channel Bits Per SlotImage: Signature of the RMC.Image: Signature of the RMC.Image: Signature of the RMC.Binary Channel Bits Per SlotImage: Signature of the RMC.Image: Signature of the RMC.Image: Signature of the RMC.	For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}	CBs	N/A	N/A	N/A		
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}BitsN/AN/AN/AFor Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}Bits53856107712215424Max. Throughput averaged over 1 frame (NOTE 7)Mbps105.696211.354422.899NOTE 1: 	For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}	CBs	6	11	21		
i from {0,,79} Bits 53856 107712 215424 {1,,79} Max. Throughput averaged over 1 frame Mbps 105.696 211.354 422.899 NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1. NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame NOTE 4: Slot i is slot index per 2 frames NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6. NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.							
{1,,79} Max. Throughput averaged over 1 frame (NOTE 7) More 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1. NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame NOTE 4: Slot i is slot index per 2 frames NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6. NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.	i from {0,,79}	Bits	N/A	N/A	N/A		
 (NOTE 7) NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1. NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame NOTE 4: Slot i is slot index per 2 frames NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6. NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC. 	{1,,79}	Bits	53856	107712	215424		
 NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame NOTE 4: Slot i is slot index per 2 frames NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6. NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC. 		Mbps	105.696	211.354	422.899		
 NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame NOTE 4: Slot i is slot index per 2 frames NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6. NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC. 	NOTE 2: If more than one Code Block is pre	esent, an add	itional CRC s				
 NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6. NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC. 	NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame						
 frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6. NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC. 							
RMC; second number corresponds to the number slots allocated in the second frame of the RMC.	frequency domain, per symbol in time domain. Overhead for TBS calculation is						
	RMC; second number corresponds to the number slots allocated in the second						
		frame of RMC					

Table A.3.3.5-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

	Parameter	Unit		Va	lue	
	Channel bandwidth	MHz	50	100	200	400
Subcarrier spacing configuration μ			3	3	3	3
l	Allocated resource blocks		32	66	132	264
Su	bcarriers per resource block		12	12	12	12
Alloca	ated slots per Frame (NOTE 6)		47 / 48	47 / 48	47 / 48	47 / 48
	MCS index		24	24	24	24
	Modulation		256QAM	256QAM	256QAM	256QAM
	Target Coding Rate		4/5	4/5	4/5	4/5
Maximun	n number of HARQ transmissions		1	1	1	1
Info	rmation Bit Payload per Slot					
For Slots	0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159}	Bits	N/A	N/A	N/A	N/A
For Slot	t i, if mod(i, 5) = {0,1,2} for i from {1,,159}	Bits	21504	44040	88064	176208
	Transport block CRC	Bits	24	24	24	24
LDPC base graph			1	1	1	1
	nber of Code Blocks per Slot					
For Slots	0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159}	CBs	N/A	N/A	N/A	N/A
	t i, if mod(i, 5) = {0,1,2} for i from {1,,159}	CBs	3	6	11	21
Bi	nary Channel Bits Per Slot					
For Slots	0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159}	Bits	N/A	N/A	N/A	N/A
For Slot	t i, if mod(i, 5) = {0,1,2} for i from {1,,159}	Bits	26112	53856	107712	215424
Max. Th	roughput averaged over 1 frame (NOTE 7)	Mbps	103.219	211.392	422.707	845.798
 NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1. NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). 						
 NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame NOTE 4: Slot i is slot index per 2 frames NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6. 						
NOTE 6: First number corresponds to the number slots allocated in the second frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.						

Table A.3.3.5-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

NOTE 7: Throughput is averaged over 2nd frame of RMC.

- A.4 Void
- A.5 OFDMA Channel Noise Generator (OCNG)
- A.5.1 OCNG Patterns for FDD
- A.5.2 OCNG Patterns for TDD
- A.5.2.1 OCNG TDD pattern 1: Generic OCNG TDD Pattern for all unused REs

Table A.5.2.1-1: OP.1 TDD: Generic OCNG TDD Pattern for all unused REs

OCNG Appliance OCNG Parameters	Control Region (Core Set)	Data Region			
Resources allocated	All unused REs (Note 1)	All unused REs (Note 2)			
Structure	PDCCH	PDSCH			
Content	Uncorrelated pseudo random QPSK modulated data	Uncorrelated pseudo random QPSK modulated data			
Transmission scheme for multiple antennas ports transmission	Single Tx port transmission	Spatial multiplexing using any precoding matrix with dimensions same as the precoding matrix for PDSCH			
Subcarrier Spacing	Same as for RMC PDCCH in the active BWP	Same as for RMC PDSCH in the active BWP			
Power Level	Same as for RMC PDCCH	Same as for RMC PDSCH			
Note 1: All unused REs in the active CORESETS appointed by the search spaces in use. Note 2: Unused available REs refer to REs in PRBs not allocated for any physical channels, CORESETs, synchronization signals or reference signals in channel bandwidth.					

Annex B (informative): Void

Annex C (normative): Downlink physical channels

C.1 General

C.2 Setup

Table C.2-1 describes the downlink Physical Channels that are required for connection set up.

Physical Channel
PBCH
SSS
PSS
PDCCH
PDSCH
PBCH DMRS
PDCCH DMRS
PDSCH DMRS
CSI-RS
PTRS

Table C.2-1: Downlink Physical Channels required for connection set-up

C.3 Connection

C.3.1 Measurement of Receiver Characteristics

Unless otherwise stated, Table C.3.1-1 is applicable for measurements on the Receiver Characteristics (clause 7).

Table C.3.1-1: Downlink Physical Channels transmitted	d during	a connection (TDD)
Parameter	Unit	Valuo

	Parameter	Unit	Value			
SSS transmit power		W	Test specific			
	EPRE ratio of PSS to SSS	dB	0			
	EPRE ratio of PBCH to SSS	dB	0			
	EPRE ratio of PBCH to PBCH DMRS	dB	0			
	EPRE ratio of PDCCH to SSS	dB	0			
	EPRE ratio of PDCCH to PDCCH DMRS	dB	0			
	EPRE ratio of PDSCH to SSS	dB	0			
	EPRE ratio of PDSCH to PDSCH DMRS (Note 1)	dB	-3			
	EPRE ratio of CSI-RS to SSS	dB	0			
	EPRE ratio of PTRS to PDSCH	dB	Test specific			
	EPRE ratio of OCNG DMRS to SSS	dB	0			
	EPRE ratio of OCNG to OCNG DMRS (Note 1)	dB	0			
Note 1:	Note 1: No boosting is applied to any of the channels except PDSCH DMRS. For PDSCH DMRS, 3 dB power					
	boosting is applied assuming DMRS Type 1 configuration when DMRS and PDSCH are TDM'ed and only					
	half of the DMRS REs are occupied.					
Note 2:	Number of DMRS CDM groups without data for PDSCH DMRS	configura	tion for OCNG is set to 1.			

Annex D (normative): Characteristics of the interfering signal

D.1 General

Unless otherwise stated, a modulated full bandwidth NR downlink signal, which equals to channel bandwidth of the wanted signal for Single Carrier case is used as interfering signals when RF performance requirements for NR UE receiver are defined. For intra-band contiguous CA case, a modulated NR downlink signal which equals to the aggregated channel bandwidth of the wanted signal is used.

D.2 Interference signals

Table D.2-1 describes the modulated interferer for different channel bandwidth options.

	С	Intra band contiguous CA					
	50 MHz						
BWInterferer	50 MHz	BWChannel_CA					
RB	NOTE1						
	NOTE 1: The RB configured for interfering signal is the same as maximum RB number						
de	fined in Table	e 5.3.2-1 for ea	ch sub-carrier	spacing.			

Table D.2-1: Description of modulated NR interferer

Annex E (normative): Environmental conditions

E.1 General

This annex specifies the environmental requirements of the UE. Within these limits the requirements of the present documents shall be fulfilled.

E.2 Environmental

The requirements in this clause apply to all types of UE(s).

E.2.1 Temperature

All RF requirements for UEs operating in FR2 are defined over the air and can only be tested in an OTA chamber.

The UE shall fulfil all the requirements in the temperature range for extreme conditions, as defined in Table E.2.1-1, unless explicitly stated otherwise in any requirement.

Table E.2.1-1: Temperature conditions

+ 25 °C ± 10 °C	For normal (room temperature) conditions with relative humidity of 25 % to 75 %
-10°C to +55°C	For extreme conditions

Outside this temperature range the UE, if powered on, shall not make ineffective use of the radio frequency spectrum. In no case shall the UE exceed the transmitted levels as defined in clause 6.2 for extreme operation.

E.2.2 Voltage

Editor's note: This requirement is incomplete. The following aspects are either missing or not yet determined:

Methodology to control the voltage in a case which a power cable is not connected to DUT is FFS since it is not agreed whether we can connect the power cable to DUT at the OTA measurement situation yet.

The UE shall fulfil all the requirements in the full voltage range, i.e. the voltage range between the extreme voltages.

The manufacturer shall declare the lower and higher extreme voltages and the approximate shutdown voltage. For the equipment that can be operated from one or more of the power sources listed below, the lower extreme voltage shall not be higher, and the higher extreme voltage shall not be lower than that specified below.

Power source	Lower extreme voltage	Higher extreme voltage	Normal conditions voltage
AC mains	0,9 * nominal	1,1 * nominal	nominal
Regulated lead acid battery	0,9 * nominal	1,3 * nominal	1,1 * nominal
Nonregulated batteries:			
Leclanché	0,85 * nominal	Nominal	Nominal
Lithium	0,95 * nominal	1,1 * Nominal	1,1 * Nominal
Mercury/nickel & cadmium	0,90 * nominal		Nominal

Table E.2.2-1: Voltage conditions

Outside this voltage range the UE if powered on, shall not make ineffective use of the radio frequency spectrum. In no case shall the UE exceed the transmitted levels as defined in clause 6.2 for extreme operation. In particular, the UE shall inhibit all RF transmissions when the power supply voltage is below the manufacturer declared shutdown voltage.

E.2.3 Void

Annex F (normative): Transmit modulation

F.1 Measurement Point

Figure F.1-1 shows the measurement point for the unwanted emission falling into non-allocated RB(s) and the EVM for the allocated RB(s).

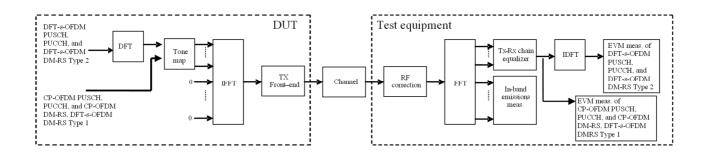


Figure F.1-1: EVM measurement points

F.2 Basic Error Vector Magnitude measurement

The EVM is the difference between the ideal waveform and the measured waveform for the allocated RB(s)

$$EVM = \sqrt{\frac{\sum_{v \in T_m} |z'(v) - i(v)|^2}{|T_m| \cdot P_0}},$$

where

 T_m is a set of $|T_m|$ modulation symbols with the considered modulation scheme being active within the measurement period,

z'(v) are the samples of the signal evaluated for the EVM,

i(v) is the ideal signal reconstructed by the measurement equipment, and

 P_0 is the average power of the ideal signal. For normalized modulation symbols P_0 is equal to 1.

The basic EVM measurement interval is defined over one slot in the time domain for PUCCH and PUSCH and over one preamble sequence for the PRACH.

F.3 Basic in-band emissions measurement

The in-band emissions are a measure of the interference falling into the non-allocated resources blocks. The in-band emission requirement is evaluated for PUCCH and PUSCH transmissions. The in-band emission requirement is not evaluated for PRACH transmissions.

The in-band emissions are measured as follows

$$Emissions_{absolute}(\Delta_{RB}) = \begin{cases} \frac{1}{|T_s|} \sum_{t \in T_s} \sum_{\substack{max(f_{\min}, f_l + 12 \cdot \Delta_{RB} + \Delta f) \\ max(f_{\max}, f_l + 12 \cdot \Delta_{RB} + \Delta f) \\ min(f_{\max}, f_h + 12 \cdot \Delta_{RB} + \Delta f) \\ \frac{1}{|T_s|} \sum_{t \in T_s} \sum_{\substack{f_h + (12 \cdot \Delta_{RB} - 11) + \Delta f \\ f_h + (12 \cdot \Delta_{RB} - 11) + \Delta f}} |Y(t, f)|^2, \Delta_{RB} > 0 \end{cases}$$

where

 T_s is a set of $|T_s|$ OFDM symbols with the considered modulation scheme being active within the measurement period,

 Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB),

 f_{\min} (resp. f_{\max}) is the lower (resp. upper) edge of the UL system BW,

 f_l and f_h are the lower and upper edge of the allocated BW, and

Y(t, f) is the frequency domain signal evaluated for in-band emissions as defined in the clause (ii)

The relative in-band emissions are, given by

$$Emissions_{relative}(\Delta_{RB}) = \frac{Emissions_{absolute}(\Delta_{RB})}{\frac{1}{|T_s| \cdot N_{RB}} \sum_{t \in T_s} \sum_{f_l}^{f_l + (12 \cdot N_{RB} - 1)\Delta f} |Y(t, f)|^2}$$

where

 N_{RB} is the number of allocated RBs

The basic in-band emissions measurement interval is defined over one slot in the time domain. When the PUSCH or PUCCH transmission slot is shortened due to multiplexing with SRS, the in-band emissions measurement interval is reduced by one OFDM symbol, accordingly.

In the evaluation of in-band emissions, the timing is set according to $\Delta \tilde{t} = \Delta \tilde{c}$, where sample time offsets $\Delta \tilde{t}$ and $\Delta \tilde{c}$ are defined in clause F.4.

F.4 Modified signal under test

Implicit in the definition of EVM is an assumption that the receiver is able to compensate a number of transmitter impairments.

The DFT-s-OFDM modulated signals or PRACH signal under test is modified and, in the case of DFT-s-OFDM modulated signals, decoded according to:

$$Z'(t,f) = IDFT\left\{\frac{FFT\left\{z(v - \Delta \tilde{t}) \cdot e^{-j2\pi \Delta \tilde{f}v}\right\}e^{j2\pi f\Delta \tilde{t}}}{\tilde{a}(t,f) \cdot e^{j\tilde{\varphi}(t,f)}}\right\}$$

where

Z(V) is the time domain samples of the signal under test.

The CP-OFDM modulated signals or PUSCH demodulation reference signal or CP-OFDM modulated signals under test is equalised and, in the case of PUCCH data signal decoded according to:

$$Z'(t,f) = \frac{FFT\left\{z(v - \Delta \tilde{t}) \cdot e^{-j2\pi\Delta \tilde{f}v}\right\}}{\tilde{a}(t,f) \cdot e^{j\tilde{\varphi}(t,f)}}$$

where

 $\mathcal{Z}(\mathcal{V})$ is the time domain samples of the signal under test.

To minimize the error, the signal under test should be modified with respect to a set of parameters following the procedure explained below.

Notation:

 $\Delta \tilde{t}$ is the sample timing difference between the FFT processing window in relation to nominal timing of the ideal signal.

 $\Delta \tilde{f}$ is the RF frequency offset.

 $\widetilde{\varphi}(t,f)$ is the phase response of the TX chain.

 $\widetilde{a}(t, f)$ is the amplitude response of the TX chain.

In the following $\Delta \tilde{c}$ represents the middle sample of the EVM window of length W (defined in the next clauses) or the last sample of the first window half if W is even.

The EVM analyser shall

- detect the start of each slot and estimate $\Delta \tilde{t}$ and $\Delta \tilde{f}$,
- determine $\Delta \widetilde{c}$ so that the EVM window of length W is centred
 - on the time interval determined by the measured cyclic prefix minus 16κ samples of the considered OFDM symbol for symbol l for subcarrier spacing configuration μ in a subframe, with l = 0 or $l = 7*2^{\mu}$ for normal CP, i.e. the first 16κ samples of the CP should not be taken into account for this step. In the determination of the number of excluded samples, a sampling rate of $1/T_c$ is assumed. If a different sampling rate is used, the number of excluded samples is scaled linearly.
 - on the measured cyclic prefix of the considered OFDM symbol symbol for all other symbols for normal CP and for symbol 0 to 11 for extended CP.
 - on the measured preamble cyclic prefix for the PRACH

To determine the other parameters a sample timing offset equal to $\Delta \tilde{c}$ is corrected from the signal under test. The EVM analyser shall then

- correct the RF frequency offset $\Delta \tilde{f}$ for each time slot, and

apply an FFT of appropriate size. The chosen FFT size shall ensure that in the case of an ideal signal under test, there is no measured inter-subcarrier interference.

The carrier leakage shall be removed from the evaluated signal before calculating the EVM and the in-band emissions; however, the removed relative carrier leakage power also has to satisfy the applicable requirement.

At this stage the allocated RBs shall be separated from the non-allocated RBs. In the case of PUCCH and PUSCH EVM, the signal on the non-allocated RB(s), Y(t, f), is used to evaluate the in-band emissions.

Moreover, the following procedure applies only to the signal on the allocated RB(s).

- In the case of PUCCH and PUSCH, the UL EVM analyzer shall estimate the TX chain equalizer coefficients $\widetilde{a}(t,f)$ and $\widetilde{\varphi}(t,f)$ used by the ZF equalizer for all subcarriers by time averaging at each signal subcarrier of the amplitude and phase of the reference and data symbols. The time-averaging length is 1 slot. This process creates an average amplitude and phase for each signal subcarrier used by the ZF equalizer. The knowledge of data modulation symbols may be required in this step because the determination of symbols by demodulation is not reliable before signal equalization.
- In the case of PRACH, the UL EVM analyzer shall estimate the TX chain coefficients $\tilde{a}(t)$ and $\tilde{\phi}(t)$ used for phase and amplitude correction and are seleted so as to minimize the resulting EVM. The TX chain coefficients are not dependent on frequency, i.e. $\widetilde{a}(t, f) = \widetilde{a}(t)$ and $\widetilde{\varphi}(t, f) = \widetilde{\varphi}(t)$. The TX chain coefficient are chosen independently for each preamble transmission and for each $\Delta \widetilde{t}$.

At this stage estimates of $\Delta \tilde{f}$, $\tilde{a}(t,f)$, $\tilde{\varphi}(t,f)$ and $\Delta \tilde{c}$ are available. $\Delta \tilde{t}$ is one of the extremities of the window W, i.e. $\Delta \tilde{t}$ can be $\Delta \tilde{c} + \alpha - \left| \frac{W}{2} \right|$ or $\Delta \tilde{c} + \left| \frac{W}{2} \right|$, where $\alpha = 0$ if W is odd and $\alpha = 1$ if W is even.

The EVM analyser shall then

- calculate EVM₁ with
$$\Delta \tilde{t}$$
 set to $\Delta \tilde{c} + \alpha - \left\lfloor \frac{W}{2} \right\rfloor$

- calculate EVM_h with $\Delta \tilde{t}$ set to $\Delta \tilde{c} + \left| \frac{W}{2} \right|$.

F 5 Window length

F.5.1 Timing offset

As a result of using a cyclic prefix, there is a range of $\Delta \tilde{t}$, which, at least in the case of perfect Tx signal quality, would give close to minimum error vector magnitude. As a first order approximation, that range should be equal to the length of the cyclic prefix. Any time domain windowing or FIR pulse shaping applied by the transmitter reduces the $\Delta \tilde{t}$ range within which the error vector is close to its minimum.

Window length F.5.2

The window length W affects the measured EVM and is expressed as a function of the configured cyclic prefix length. In the case where equalization is present, as with frequency domain EVM computation, the effect of FIR is reduced. This is because the equalization can correct most of the linear distortion introduced by the FIR. However, the time domain windowing effect can't be removed.

F.5.3 Window length for normal CP

Table F.5.3-1 and Table F.5.3-2 below specify the EVM window length (W) for normal CP for FR2.

 Table F.5.3-1: EVM window length for normal CP for 60 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length ¹ (%)	
50	1024	72	36	50	
100	2048	144	72	50	
200	4096	288	144	50	
Note 1: These percentages are informative and apply to all OFDM symbols within subframe except for symbol 0 of slot 0 and slot 2. Symbol 0 of slot 0 and slot 2 may have a longer CP and therefore a lower percentage.					

Table F.5.3-2: EVM window length for normal CP for 120 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length ¹ (%)	
50	512	36	18	50	
100	1024	72	36	50	
200	2048	144	72	50	
400	4096	288	144	50	
Note 1: These percentages are informative and apply to all OFDM symbols within subframe except for symbol 0 of slot 0 and slot 4. Symbol 0 of slot 0 and slot 4 may have					
		P and therefore a			

F.5.4 Window length for Extended CP

Table F.5.4-1 below specifies the EVM window length (W) for extended CP. The number of CP samples excluded from the EVM window is the same as for normal CP length.

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length ¹ (%)
50	1024	256	220	85.9
100	2048	512	440	85.9
200	4096	1024	880	85.9

Table F.5.4-1: EVM window length for extended CP for 60 kHz SCS

F.5.5 Window length for PRACH

Note 1:

The table below specifies the EVM window length for PRACH preamble formats for $L_{RA} = 139$ and $\Delta f^{RA} = 15 \cdot 2^{\mu} \text{ kHz}_{\text{where }} \mu \in \{2,3\}$.

These percentages are informative.

Preamble format	$\begin{array}{c} \textbf{Cyclic} \\ \textbf{prefix} \\ N_{cp} \\ \textbf{length} \end{array}$	Nominal FFT size ¹	EVM window length <i>W</i> in FFT samples	Ratio of <i>W</i> to CP ²						
A1	1152·2 ^{-µ}	8192·2 ^{-µ}	576·2 ^{-µ}	50.0%						
A2	2304·2 ^{-µ}	8192·2 ^{-µ}	1728·2 ^{-µ}	75.0%						
A3	3456·2 ^{-µ}	8192·2 ^{-µ}	2880·2 ^{-µ}	83.3%						
B1	864·2 ^{-µ}	8192·2 ^{-µ}	288·2 ^{-µ}	33.3%						
B2	1440·2 ^{-µ}	8192·2 ^{-µ}	864·2 ^{-µ}	60.0%						
B3	2016·2 ^{-µ}	8192·2 ^{-µ}	1440·2 ^{-µ}	71.4%						
B4	3744·2 ^{-µ}	8192·2 ^{-µ}	3168·2 ^{-µ}	84.6%						
C0	4960·2 ^{-µ}	8192·2 ^{-µ}	4384·2 ^{-µ}	88.4%						
C2	8192·2 ^{-µ}	8192·2 ^{-µ}	7616·2 ^{-µ}	93.0%						
	The use of other			appropriate						
	scaling of the window length is applied									

Table F.5.5-1: EVM window length for PRACH formats for L_{RA} = 139

F.6 Averaged EVM

The general EVM is averaged over basic EVM measurements for n slots in the time domain.

$$\overline{EVM} = \sqrt{\frac{1}{n} \sum_{i=1}^{n} EVM_{i}^{2}}$$

where n is

$$n = \begin{cases} 40, for \ 60 \ kHz \ SCS \\ 80, for \ 120 \ kHz \ SCS \end{cases}$$

for PUCCH, PUSCH.

The EVM requirements shall be tested against the maximum of the RMS average at the window W extremities of the EVM measurements:

Thus $\overline{\text{EVM}}$ is calculated using $\Delta \tilde{t} = \Delta \tilde{t}_l$ in the expressions above and $\overline{\text{EVM}}_h$ is calculated using $\Delta \tilde{t} = \Delta \tilde{t}_h$. Thus we get:

$$EVM = \max(EVM_1, EVM_h)$$

The calculation of the EVM for the demodulation reference signal, EVM_{DMRS} , follows the same procedure as calculating the general EVM, with the exception that the modulation symbol set T_m defined in clause F.2 is restricted to symbols containing uplink demodulation reference signals.

The basic EVM_{DMRS} measurements are first averaged over n slots in the time domain to obtain an intermediate average \overline{EVM}_{DMRS} .

$$\overline{EVM}_{DMRS} = \sqrt{\frac{1}{n} \sum_{i=1}^{n} EVM_{DMRS,i}^2}$$

In the determination of each $EVM_{DMRS,i}$, the timing is set to $\Delta \tilde{t} = \Delta \tilde{t}_l$ if $\overline{EVM}_l > \overline{EVM}_h$, and it is set to $\Delta \tilde{t} = \Delta \tilde{t}_h$ otherwise, where \overline{EVM} and \overline{EVM}_h are the general average EVM values calculated in the same n slots

over which the intermediate average EVM_{DMRS} is calculated. Note that in some cases, the general average EVM may be calculated only for the purpose of timing selection for the demodulation reference signal EVM.

Then the results are further averaged to get the EVM for the demodulation reference signal, EVM_{DMRS} ,

$$EVM_{DMRS} = \sqrt{\frac{1}{6} \sum_{j=1}^{6} \overline{EVM}_{DMRS,j}^2}$$

The PRACH EVM, EVM_{PRACH} , is averaged over 2 preamble sequence measurements for long preamble formats as defined in table 6.3.3.1-1 in [9] and averaged over 10 preamble sequence measurements for short preamble formats as defined in table 6.3.3.1-2 in [9].

The EVM requirements shall be tested against the maximum of the RMS average at the window *W* extremities of the EVM measurements:

Thus $\overline{\text{EVM}}_{\text{PRACH,l}}$ is calculated using $\Delta \tilde{t} = \Delta \tilde{t}_l$ and $\overline{\text{EVM}}_{\text{PRACH,h}}$ is calculated using $\Delta \tilde{t} = \Delta \tilde{t}_h$.

Thus we get:

$$EVM_{PRACH} = \max(EVM_{PRACH,1}, EVM_{PRACH,h})$$

F.7 Spectrum Flatness

The data shall be taken from FFT coded data symbols and the demodulation reference symbols of the allocated resource block.

F.8 Phase offset measurement for DMRS bundling

F.8.1 Measurement point

The measurement point for phase offset measurement is defined in Figure F.8.1-1.

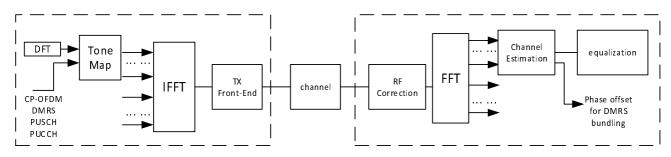


Figure F.8.1-1: Measurement point for phase offset for DMRS bundling

F.8.2 Symbols used

Phase offset is determined based on DMRS REs (3 DMRS symbols per slot) with the option to use data symbols.

F.8.3 Modified test signal

[editor notes: updates based on LS reply from RAN5]

F.8.4 Phase offset measurement

The phase offset measurement is based on the phase response of the Tx chain $\tilde{\varphi}(t, f)$ as derived based on Annex F.4.

The phase difference $\Delta \tilde{\varphi}(f)$ for each subcarrier between a reference timeslot t_{ref} and the measurement timeslot t_m -is then calculated as defined below:

$$\Delta \tilde{\varphi}(f) = \tilde{\varphi}(t_m, f) - \tilde{\varphi}(t_{ref}, f)$$

The phase offset between the reference and measurement timeslots are then calculated as the maximum over the results for all subcarriers as shown below:

$$PhaseOffset = \max_{f} (\Delta \tilde{\varphi}(f))$$

Annex G (normative):

Difference of relative phase and power errors

G.0 General

This annex gives further information needed for understanding and implementing 6.4D.4. The following terms should be understood as follows:

- Relative phase error: refers to the phase difference between signals at different antenna ports, which should be ideally 0. It should be understood as for a slot i.e. (slot) relative phase. It is calculated based on DMRS symbols of that slot or on SRS symbols.
- Difference of relative phase error: refers to the difference between the relative phase error determined per slot and the relative phase error determined based on the SRS transmitted.

G.1 Measurement Point

Figure G.1-1 shows the measurement point for the difference of relative phase and power errors. To separate signals from the two transmitters, it is necessary for the test equipment to perform joint demodulation by inverting the 2x2 composite channel ('HGW') resulting from DUT precoding 'W' and antenna virtualization 'G' and OTA channel between DUT and test equipment 'H'.

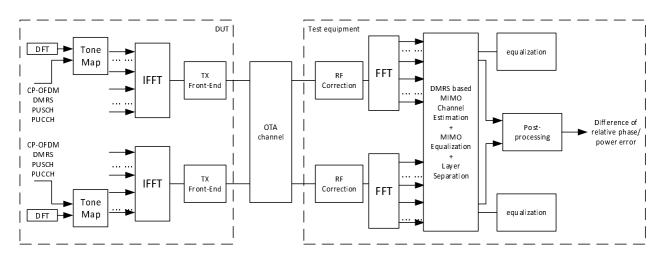


Figure G.1-1 - Measurement point for difference of relative phase/power error for UL coherent MIMO

G.2 Relative Phase Error Measurement

Here are listed the different aspects that may lead to different interpretations.

G.2.1 Symbols used

Phase error is determined based on DMRS REs (3 DMRS symbols per slot).

G.2.2 CFO (carrier frequency offset) correction

The TE performs a CFO correction on a slot-by-slot basis using a common frequency correction at the two uplink layers.

G.2.3 Steps of the measurement method

Below are detailed the steps necessary to obtain the maximum difference of relative phase error during the 20ms time window.

1 Determination for each subcarrier and at each antenna port, the SRS relative phase error based on the last SRS transmitted on Ant1 and Ant2, that relative phase error serves as a reference for the calculation of the difference of relative phase error for each slot inside the 20 ms time window.

The output is the "SRS relative phase error" vector for the last SRS transmitted: $[1 \times number_of_subcarriers]$.

2 Calculation for the last SRS transmitted, for each RB of the SRS relative phase errors based on the arithmetic mean of the subcarrier SRS relative phase errors determined in previous step.

The output is the "SRS relative phase error" vector for the last SRS transmitted: $[1 \times number_of_RBs]$.

- 3 CFO correction on slot-by-slot basis using a common frequency correction for both antenna ports.
- 4 Determination for each subcarrier and at each antenna, the phase over the slot being analyzed. The phase is extracted from the channel estimate derived from the 3 DMRS symbols of the slot using the LSE technique.

The output is one vector of dimension $[1 \times number_of_subcarriers]$ for each antenna port.

5 Calculation for a slot for each subcarrier of the relative phase error (difference between the vectors determined in the previous step).

The output is subcarrier relative phase errors of a slot: $[1 \times number_of_subcarriers]$.

6 Calculation for a slot, for each RB of the relative phase errors based on the arithmetic mean of the subcarrier relative phase errors determined in previous step.

The output is a "slot relative phase error" vector for a slot: $[1 \times number_of_RBs]$.

7 Calculation for a slot of the difference of relative phase errors based on the "SRS relative phase error" (reference) determined in step 2 and the "slot relative phase error" determined in previous step.

The output is a "difference of relative phase error" vector for a slot: $[1 \times number_of_RBs]$.

8 Calculation for a slot of the arithmetic mean value of the "difference of relative phase error" vector determined in previous step, this value corresponds to an RB.

The output is a "difference of relative phase error" value for a slot: $[1 \times 1]$.

9 Perform for each slot of the 20ms time window, steps 3 to 8.

The output is a "difference of relative phase error" vector: $[1 \times number_of_slots]$.

10 Calculation of the maximum value of the "difference of relative phase error".

The output is the "difference of relative phase error" that should be verified as complying with the 40° maximum allowable difference of relative phase error requirement: $[1 \times 1]$.

Annex H (Normative): Modified MPR behavior

H.1 Indication of modified MPR behavior

This annex contains the definitions of the bits in the field *modifiedMPR-Behavior* indicated per supported NR band in the IE *RF-Parameters* [13] by a UE supporting an MPR or A-MPR modified in a given version of this specification. A modified MPR or A-MPR behaviour can apply to a supported NR band in stand-alone operation (including CA and NN-DC operation) or in non-standalone operation with the said NR band as part of an EN-DC or NE-DC band combination. Moreover, the bits in the field can explicitly indicate NS value(s) supported by a UE.

NOTE 1: In the present release, the *modifiedMPR-Behavior* is indicated [13] by an 8-bit bitmap per supported NR band.

NR Band	Index of field	Definition	Notes
	(bit number)	(description of the supported functionality if	
		indicator set to one)	
n257	0 (leftmost bit)	 FR2 power class 3 MPR as defined in clause 	- This bit may be set to 1 by
		6.2.2.3 of 38.101-2 v16.2.0	a UE supporting n257
n258	0 (leftmost bit)	 FR2 power class 3 MPR as defined in clause 	- This bit may be set to 1 by
		6.2.2.3 of 38.101-2 v16.2.0	a UE supporting n258
	1	Void	
	2	- NS_203 as defined in clause 6.5.3.2.4 or both	- This bit shall be set to 1
		NS_203 and CA_NS_203 as defined in clause	by a UE supporting n258 or
		6.5A.3.2.4 of 38.101-2 v15.11.0	both n258 and CA_n258
n260	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause	- This bit may be set to 1 by
		6.2.2.3 of 38.101-2 v16.2.0	a UE supporting n260
n261	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause	- This bit may be set to 1 by
		6.2.2.3 of 38.101-2 v16.2.0	a UE supporting n261

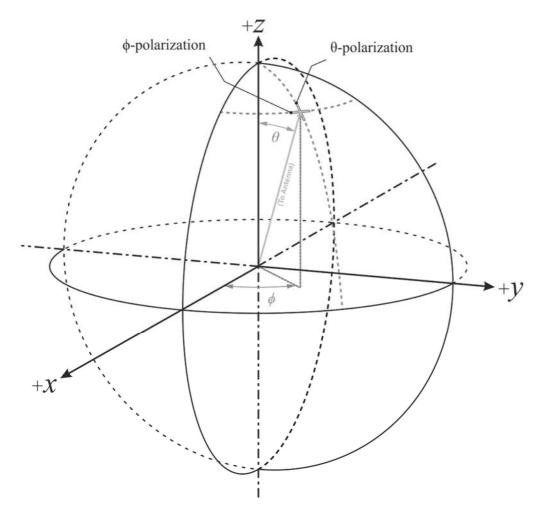
Table H.1-1: Definitions of the bits in the field modifiedMPRbehavior

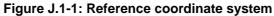
Annex I (informative): Void

Annex J (normative): UE coordinate system

J.1 Reference coordinate system

This annex defines the measurement coordinate system for the NR UE. The reference coordinate system as defined in IEEE Std 149 [15] is provided in Figure J.1-1 below while Figure J.1.-2 shows the DUT in the default alignment, i.e., the DUT and the reference coordinate systems are aligned with $\alpha = 0^{\circ}$ and $\beta = 0^{\circ}$ and $\gamma = 0^{\circ}$ where α , β , and γ describe the relative angles between the two coordinate systems.





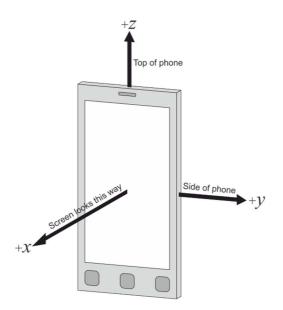


Figure J.1-2: DUT default alignment to coordinate system

The following aspects are necessary:

- A basic understanding of the top and bottom of the device is needed in order to define unambiguous DUT positioning requirements for the test, e.g., in the drawings used in this annex, the three buttons are on the bottom of the device (front) and the camera is on the top of the device (back).
- An understanding of the origin and alignment the coordinate system inside the test system i.e. the directions in which the x, y, z -axes points inside the test chamber is needed in order to define unambiguous DUT orientation, DUT beam, signal, interference, and measurement angles

J.2 Test conditions and angle definitions

Tables J.2-1 through J.2-3 below provides the test conditions and angle definitions for three permitted device alignment for the default test condition, DUT orientation 1, and two different options for each permitted device alignment to reposition the device for DUT Orientation 2 as outlined in Figures J.2-1 and J.2-3.

Test condition	DUT orientation	Link angle	Measurement angle	Diagram
Free space DUT Orientation 1 (default)	$ \begin{aligned} \alpha &= 0^{\circ}; \\ \beta &= 0^{\circ}; \\ \gamma &= 0^{\circ} \end{aligned} $	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	Rotation Matrix $R_{z}(y)$ + χ Rotation Matrix $R_{x}(\alpha)$ + χ Rotation Matrix $R_{y}(\beta)$
Free space DUT Orientation 2 – Option 1 (based on re- positioning approach)	$\alpha = 180^{\circ};$ $\beta = 0^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link} ; φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	Rotation Matrix $R_x(\alpha)$ + χ Rotation Matrix $R_y(\beta)$
Free space DUT Orientation 2 – Option 2 (based on re- positioning approach)	$ \begin{aligned} \alpha &= 0^{\circ}; \\ \beta &= 180^{\circ}; \\ \gamma &= 0^{\circ} \end{aligned} $	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	Rotation Matrix $R_x(\alpha)$ + χ Rotation Matrix $R_y(\beta)$
each	signal angle, link	k or interferer ang	relation to the refer le, and measurem d by matrix $M=R_z(\gamma)$	

 Table J.2-1: Test conditions and angle definitions for Alignment Option 1

Test condition	DUT orientation	Link angle	Measurement angle	Diagram
Free space DUT Orientation 1 (default)	$ \begin{aligned} \alpha &= 0^{\circ}; \\ \beta &= -90^{\circ}; \\ \gamma &= 0^{\circ} \end{aligned} $	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(\gamma)$ +X Rotation Matrix $R_{x}(\alpha)$ Rotation Matrix $R_{y}(\beta)$
Free space DUT Orientation 2 – Option 1 (based on re- positioning approach)	$\alpha = 180^{\circ};$ $\beta = 90^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(\gamma)$ Rotation +X Rotation Matrix $R_{x}(\alpha)$ Rotation Matrix $R_{y}(\beta)$
Free space DUT Orientation 2 – Option 2 (based on re- positioning approach)	$ \begin{aligned} \alpha &= 0^{\circ}; \\ \beta &= 90^{\circ}; \\ \gamma &= 0^{\circ} \end{aligned} $	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(y)$ +X Rotation Matrix $R_{x}(\alpha)$ Rotation Matrix $R_{y}(\beta)$
each	signal angle, link	or interferer angle	elation to the refer e, and measureme by matrix $M=R_z(\dot{\gamma})$	

Table J.2-2: Test conditions and angle definitions for Alignment Option 2

Test	DUT	Link	Measurement	Diagram
condition Free space DUT Orientation 1 (default)	$\begin{array}{l} \textbf{orientation} \\ \alpha = 90^{\circ}; \\ \beta = 0^{\circ}; \\ \gamma = 0^{\circ} \end{array}$	angle θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	angle θ _{Meas;} φMeas with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_z(y)$ Rotation Matrix $R_x(\alpha)$ +X Rotation Matrix $R_y(\beta)$
Free space DUT Orientation 2 – Option 1 (based on re- positioning approach)	$\alpha = -90^{\circ};$ $\beta = 0^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(y)$ Fotation Matrix $R_{x}(\alpha)$ +X +X
Free space DUT Orientation 2 – Option 2 (based on re- positioning approach)	$\alpha = 90^{\circ};$ $\beta = 180^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(\gamma)$ Rotation Matrix $R_{x}(\alpha)$ +X Rotation Matrix $R_{y}(\beta)$
each	signal angle, link	or interferer angle	elation to the refere, and measurements of the measurement of the measurement of the matrix M= <i>R</i> _z (*	

 Table J.2-3: Test conditions and angle definitions for Alignment Option 3

For each UE requirement and test case, each of the parameters in Table J.2-1 through J.2-3 need to be recorded, such that DUT positioning, DUT beam direction, and angles of the signal, link/interferer, and measurement are specified in terms of the fixed coordinate system.

Due to the non-commutative nature of rotations, the order of rotations is important and needs to be defined when multiple DUT orientations are tested.

The rotations around the x, y, and z axes can be defined with the following rotation matrices

$$R_{x}(\alpha) = \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & \cos \alpha & -\sin \alpha & 0 \\ 0 & \sin \alpha & \cos \alpha & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

$$R_{y}(\beta) = \begin{vmatrix} \cos \beta & 0 & \sin \beta & 0 \\ 0 & 1 & 0 & 0 \\ -\sin \beta & 0 & \cos \beta & 0 \\ 0 & 0 & 0 & 1 \end{vmatrix}$$

and

$$R_{z}(\gamma) = \begin{bmatrix} \cos \gamma & -\sin \gamma & 0 & 0 \\ \sin \gamma & \cos \gamma & 0 & 0 \\ 0 & 0 & 1 & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

with the respective angles of rotation, α , β , γ , and

$$\begin{bmatrix} x'\\y'\\z'\\1 \end{bmatrix} = R \begin{bmatrix} x\\y\\z\\1 \end{bmatrix}$$

Additionally, any translation of the DUT can be defined with the translation matrix

$$T(t_x, t_y, t_z) = \begin{bmatrix} 1 & 0 & 0 & t_x \\ 0 & 1 & 0 & t_y \\ 0 & 0 & 1 & t_z \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

with offsets t_x , t_y , t_z in x, y, and z, respectively and with

$$\begin{bmatrix} x' \\ y' \\ z' \\ 1 \end{bmatrix} = T \begin{bmatrix} x \\ y \\ z \\ 1 \end{bmatrix}$$

The combination of rotations and translation is captured by the multiplication of rotation and translation matrices.

For instance, the matrix M

$$M = T(t_x, t_y, t_z) \cdot R_z(\gamma) \cdot R_y(\beta) \cdot R_x(\alpha)$$

describes an initial rotation of the DUT around the x axis with angle α , a subsequent rotation around the y axis with angle β , and a final rotation around the z axis with angle γ . After those rotations, the DUT is translated by t_x , t_y , t_z in x, y, and z, respectively.

J.3 DUT positioning guidelines

The centre of the reference coordinate system shall be aligned with the geometric centre of the DUT in order to minimize the offset between antenna arrays integrated at any position of the UE and the centre of the quiet zone.

Near-field coupling effects between the antenna and the pedestals/positioners/fixtures generally cause increased signal ripples. Re-positioning the DUT by directing the beam peak away from those areas can reduce the effect of signal ripple on EIRP/EIS measurements. Figure J.3-1 and J.3-2 illustrate how to reposition the DUT in distributed axes and combined axes system, when the beam peak is directed to the DUTs upper hemisphere (DUT orientation 1) or the DUTs lower hemisphere (DUT orientation 2). While these figures are examples of different positioning systems and other implementations are not precluded, the relative orientation of the coordinate system with respect to the antennas/reflectors and the axes of rotation shall apply to any measurement setup.

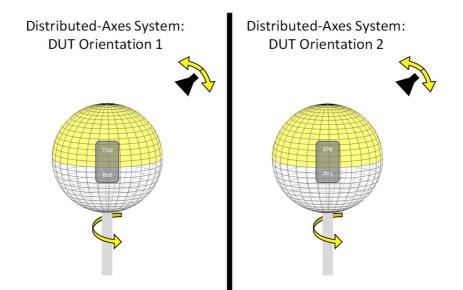


Figure J.3-1: DUT re-positioning for an example of distributed-axes system

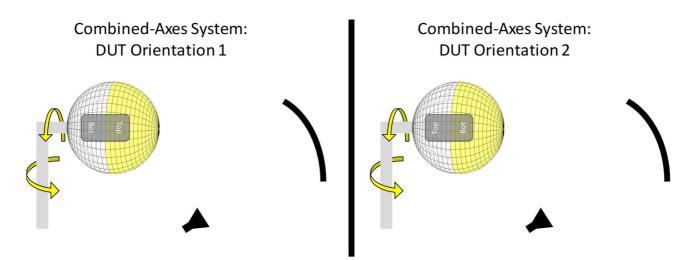


Figure J.3-2: DUT re-positioning for an example of combined-axes system

For EIRP/EIS measurements, re-positioning the DUT makes sure the pedestal is not obstructing the beam path and that the pedestal is not in closer proximity to the measurement antenna/reflector than the DUT. For TRP measurements, re-positioning the DUT makes sure that the beam peak direction is not obstructed by the pedestal and the pedestal is in the measurement path only when measuring the back-hemisphere. No re-positioning during the TRP measurement is required.

Annex K (informative): Void

Annex L (informative): Change history

	Change history							
Date	Meeting	TDoc	CR	Rev	Cat	Subject/Comment	New versio n	
2017-08	RAN4#84					Initial Skeleton	0.0.1	
2017-10	RAN4#84 Bis	R4- 1711979				TPs from R4#84Bis by editors	0.1.0	
2017-12	RAN4#85	R4- 1713806				Approved TPs from R4#85 R4-1714537, TP for TS 38.101-2: Channel Bandwidth Definition, Qualcomm Incorporated R4-1714115, TP for TS 38.101-2: Channel Arrangement, : Qualcomm Incorporated (Note: this TP was further discussed and edited in the reflector) R4-1713205, TP on general parts for 38.101-2 NR FR, : Ericsson R4-1712884, TP to TS38.101-2 on environmental conditions, Intel Corporation R4-1714018, TP to TS 38.101-2 for definition of UE RF terminologies, Anritsu Corporation R4-1714447, TP on UE power class for FR2, Intel Corporation R4-1714372, TP to TS38.101-2 on EVM equalizer spectrum flatness requirements, Intel Corporation R4-1714330, TP to TR 38.101-02 v0.1.0: ON/OFF mask design for NR UE transmissions for FR2, Ericsson R4-1714364, TP to TR 38.101-2 on spurious emissions requirements for FR2, Intel Corporation (Note: this TP was further discussed and edited in the reflector) R4-1714357, TP to TS 38.101-2 ACS requirement for mmW (section 7.5), Qualcomm Incorporated R4-171438, TP to TS 38.101-2 ACS requirement for mmW (section 7.5), Qualcomm Incorporated R4-1714348, TP to TS 38.101-2 IBB requirement for mmW (section 7.6.1), Qualcomm Incorporated R4-1714348, TP to TS 38.101-2 on Rx spurious emissions for FR2, Intel Corporation Min power for EVM requirement according to R4-1711568, TP to TR 38.xxx - UE minimum transmit power for range 2, CATT Band list according to R4-1714542, List of bands and band combinations to be introduced into RAN4 NR core requirements by December 2017, RAN4 Chairmen Further corrections and alignments with 38.104 after email review	0.2.0	
2017-12	KAIN4#03	1714570				Further conections and alignments with 36, 104 after email review	0.3.0	
2017-12		RP-172476				v1.0.0 submitted for plenary approval. Contents same as 0.3.0	1.0.0	
2017-12 2018-03	RAN#78 RAN#79	RP-180264	0004		F	Approved by plenary – Rel-15 spec under change control Implementation of endorsed CR on to 38.101-2 Endorsed draft CRs in RAN4-NR-AH#1801 F: R4-1800918, Draft CR to 38.101-2 on channel bandwidth corrections (5.3.5), Nokia F: R4-1801097, Modification for TS38.101-2, CATT F: R4-1801098 Draft CR for TS38.101-2; On requirement metrics. Sumitomo Elec. Industries, Ltd F: R4-1800401, Editorial corections to 38.101-2, Qualcomm F: R4-1801122: Draft pCR for TS 38.101-2 version 15.0.0: Remaining ON/OFF masks for FR2 NR UE transmissions, Ericsson F: R4-1800418, Correction of NR SEM for FR2 table, vivo F: R4-1800316 Draft CR to 38.101-2: Tx spurious emission for NR FR2 (section 6.5.3), ZTE Corporation F: R4-1800918 Draft CR to 38.101-2 on channel bandwidth corrections (5.3.5), Nokia F: R4-1801013, Draft CR to 38.101-2: Clarifications to UE spectrum utilization section 5.3, Ericsson F: R4-1801229, Draft CR to 38.101-2: Channel spacing for CA for NR FR2(section 5.4.1.2), ZTE Corporation F: R4-1801232, Correction CR for channel spacing:38.101-2, Samsung	15.0.0	

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					R4-1803238, Draft CR for TS 38.101-2: ACLR requirement	
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2018-12 RAN462 RP-182899 0016 F Endorced draft CR s from RAN448881s: R4-181222, Draft CR for FR2 ACLR Measurement BW, Qualcomm R4-181224, CR on Out of Band Blocking for FR2, IntR2, LG Electronics 154.0 2018-12 RF E F Endorced draft CR s from RAN448881s: R4-181224, craft CR of MRR for Power Class 2 In FR2, LG Electronics 154.0 R4-181224, craft CR of MR for Power Class 2 In FR2, LG Electronics R4-181242, draft CR of Tassinit signal quality for Power Class 2 In FR2, LG Electronics 164.0 R4-181242, draft CR to TS 38.101-2 Adjust placement of 0dB MFR reference waveform, Intel Corporation R4-1813470, draftCR on applicability of TDD configuratiin for CA in TS 38.101-2, Huawei R4-1813470, draftCR on CA spectrum Emission for TS 38.101-2, Huawei R4-1813472, draftCR on CA spectrum Emission requirement, Notia R4-1813472, draftCR to 38.101-2; Corrections on configurations for intra-band non-configurations CA, ZTE Corporation R4-18134180, Draft CR to 38.101-2; Corrections on configurations for intra-band non-configurations CA, ZTE Corporation R4-1813416, Draft CR to 38.101-2; Corrections on channel arangement descriptions, LG Electronics Inc. R4-1814149, Draft CR to 38.101-2; Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814148, Change CR to 133.101-2; Luawei R4-1814148, Change CR to 133.101-2; Huawei R4-1814148, draftCR on MR for TS 38.101-2, Huawei <t< td=""><td></td><td></td><td></td><td></td><td></td><td></td><td></td><td></td></t<>								
2018-12 RAN#62 RP-182899 O016 F Endorced draft CR s from RAN4#68Bis: R4-1812122, Draft CR for FR2 ACLR Measurement BW, Qualcomm R4-1812134, CR on Out 6 Band Blocking for FR2, Intel Corporation R4-1812426, draft CR of MPR for Power Class 2 in FR2, LG Electronics 15.4.0 R4-1812428, draft CR of transmit signal quality for Power Class 2 in FR2, LG Electronics R4-1812428, draft CR of transmit signal quality for Power Class 2 in FR2, LG Electronics R4-1812428, draft CR of Ts 38.101-2, August placement of 0dB MPR reference waveform, Intel Corporation R4-181243, Draft CR to 33, 101-2. Corrections on channel raster & SS raster, TE Corporation R4-181247, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813473, draftCR on Coherent UL MIMO for TS 38.101-2, Huawei R4-1813473, draftCR to 15.2000 (POP R4-1814183, Draft CR to 15.2000 (POP R4-18141480, Draft CR to 15.3000, OPPO R4-18141480, Change to FR2 UL MIMO, OPPO R4-18141480, Change to FR2 UL MIMO, OPPO R4-18141480, Change to RF2 UL MIMO, CPPO R4-18141480, Change to RF2 UL Conig for EIS Testing, Qualcomm Incorporated R4-1814580, Qualcomm Incorporated R4-1814580, Qualcomm Incorporated R4-1814580, Qualcomm Incorporated R4-1814580, Qualcomm Incor								
2018-12 RAN#62 RP-182899 0016 F Endorced draft CR s from RAN4#68Bis: R4-1812122, Draft CR for PR2 ACLR Measurement BW, Qualcomm R4-181222, Draft CR for PR2 ACLR Measurement BW, Qualcomm R4-181224, Craft CR of MR for Power Class 2 in FR2, LG Electronics 15.4.0 R4-181224, Craft CR of MR for Power Class 2 in FR2, LG Electronics R4-181224, Craft CR of transmit signal quality for Power Class 2 in FR2, LG Electronics 16.4.0 R4-181224, Craft CR of B3,101-2. Adjust placement of 0dB MFR reference waveform, Intel Corporation R4-1813420, CraftCR on applicability of TDD configuratiin for CA in TS 38,101-2. Huawei R4-1813427, CraftCR on Aspectrum Emission for TS 38,101-2, Huawei R4-1813427, CraftCR on Coherent UL MIMO for TS 38,101-2, Huawei R4-1813427, Correction to FR2 spurious emission requirement, Net-1813427, Correction to FR2 spurious emission requirement, R4-1813437, Correction to FR2 spurious emission requirement, R4-18134160, Draft CR to 38,101-2. Corrections on channel arangement descriptions, LG Electronics Inc. R4-18134160, Draft CR to TS 38,101-2 Organition R4-18144180, Orator CR to TS 38,101-2 Organition R4-18144180, Draft CR to TS 38,101-2 Organition R4-18144180, Draft CR to TS 38,101-2 Corrections on the descriptions of UE channel bandwidth for CA, 2TE Corporation R4-18144180, Changes to FR2 UL MMO, OPPO R4-18144180, Draft CR to TS 38,101-2. Chanae for R4.181448 Channel bandwidth for CA, 2TE Corporation R4-18144180, Chan TSA CR to TS 38,101-2. Huawei R4-181453, draft CR to TS 38,101-2. Huawei R4-181454, draftCR on MFR for TS 38,101-2. Huawei R4-181454, draftCR on MFR for TS 38,101-2. Huawei R4-1814551, dCR to TS 38,101-2. FR2 Power Control for CA, Qualcomm Incorporated R4-1814561, draft CR to TS 38,101-2. Huawei R4-1814561, draft CR to TS 38,101								
 R4-1812134, CR on Out of Band Blocking for FR2, LG R4-1812246, Graft CR of MRR for Power Class 2 in FR2, LG Electronics R4-1812428, Graft CR of Transmit signal quality for Power Class 2 in FR2, LG Electronics R4-1812430, Draft CR to TS 38,101-2, Adjust placement of 0dB MPR reference waveform, Intel Corporation R4-1812430, Draft CR to 38,101-2; Corrections on channel raster & SS raster, ZTE Corporation R4-1813470, draftCR on a paplicability of TDD configuratin for CA in TS 38,101-2, Huawei R4-1813470, draftCR on coherent UL MIMO for TS 38,101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38,101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38,101-2, Huawei R4-1813473, draftCR to to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-1813485, Draft CR to 38,101-2; Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-181414140, Changes to FR2 UL MIMO, OPPO R4-18141480, Traft CR to 38,101-2; corrections on the descriptions of UE channel bandwindt for CA, ZTE Corporation R4-18141480, Traft CR to 38,101-2; corrections on the descriptions of UE channel bandwindt for CA, ZTE Corporation R4-18141480, Traft CR to 38,101-2; Corrections on the descriptions of UE channel bandwindt for CA, ZTE Represer Control for CA, Qualcomm Incorporated R4-18141460, Traft CR to 38,101-2; Plower Control for CA, Qualcomm Incorporated R4-18141460, Traft CR to 38,101-2; Prez Power Control for CA, Qualcomm Incorporated R4-1814580, Traft CR to 38,101-2; Prez Power Control for CA, Qualcomm Incorporated R4-1814580, Traft CR to 38,101-2; Lexeson R4-1814580, Traft CR to 38,101-2; Lexeson R4-1814580, Traft CR to 38,101-2; Lexeson R4-1814580, Traft CR to 38,101-2; Loroling for EIS Testing, Qualcomm In	2018-12	RAN#82	RP-182899	0016		F	Endorced draft CR s from RAN4#88Bis:	15.4.0
R4-1812426, traft CR of MPR for Power Class 2 in FR2, LG Electronics R4-1812428, traft CR of transmit signal quality for Power Class 2 in FR2, LG Electronics R4-1812450, Draft CR to TS 38.101-2 Adjust placement of OdB MPR reference waveform, Intel Corporation R4-1812495, Draft CR to 38.301-2 Corrections on channel raster & SS raster, ZTE Corporation R4-1813470, draftCR on applicability of TDD configuratin for CA in TS 38.101-2, Huawei R4-1813472, draftCR on chapectrum Emission for TS 38.101-2, Huawei R4-1813472, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813472, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813472, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813680, Draft CR to S8.101-2: Corporation for R2 REFSENS Test Cases, Keysight R4-1813414480, Draft CR to 38.101-2: Corporation for intra-band non-contiguous CA, ZTE Corporation R4-1814480, Draft CR to 38.101-2: Corporation on the descriptions of UE channel bandwidth for CA, ZTE Corporation of UE channel bandwidth for CA, ZTE Corporation on Configurations of UE channel bandwidth for CA, ZTE Corporation for CA, CL CE class 2 in FR2, LG Electronics inc. R4-181465, draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-181465, draft CR to 38.101-2: Corporation for CA, CL Caleronic for CA, CL Caleronin Incorporated R4-1814								
 Electronics R4-1812428, draft CR of transmit signal quality for Power Class 2 in FR2, LG Electronics R4-1812428, draft CR to TS 38, 101-2. Adjust placement of 0dB MPR reference waveform, Intel Corporation R4-1812430, Draft CR to 38, 101-2: Corrections on channel raster & SS raster, ZTE Corporation R4-1813470, draftCR on applicability of TDD configuratin for CA in TS 38, 101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38, 101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38, 101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38, 101-2, Huawei R4-1813473, draftCR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-1813485, Draft CR to 38, 101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-1814181, Draft CR to 38, 101-2: Corrections on the descriptions, LG Electronics Inc. R4-18141480, Changes to FR2 UL MIMO, OPPO R4-18141480, Traft CR to 38, 101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-18141480, Traft CR to 38, 101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-18141480, Traft CR to 38, 101-2: Lobate of Annex F, Rohde & Schwarz R4-18141450, Traft CR to 38, 101-2: P2 Power Control for CA, Qualcomm Incorporated R4-18141467, Orrect to 38, 101-2: PR2 Power Control for CA, Qualcomm Incorporated R4-1814580, Traft CR to 38, 101-2: PR2 Power control for CA, Qualcomm Incorporated R4-1814580, Traft CR to 38, 101-2: PR2 Power Control for CA, Qualcomm Incorporated R4-1814580, Traft CR to 38, 101-2: PR2 Power Control for CA, Qualcomm Incorporated R4-1814580, Traft CR to 38, 101-2: Locating for ElS Testing, Qualcomm Incorporated R4-1814580, Traft CR to 38, 101-2: Locating for RE2, Int								
R4-1812428, draft CR of transmit signal quality for Power Class 2 in FR2, LG Electronics R4-1812433, Draft CR to TS 38, 101-2. Adjust placement of 0dB MPR reference waveform, Intel Corporation R4-1812495, Draft CR to 38, 101-2: Corrections on channel raster & SS raster, ZTE Corporation R4-1813470, draftCR on applicability of TDD configuratiin for CA in TS 38, 101-2, Huawei R4-1813472, draftCR on coherent UL MIMO for TS 38, 101-2, Huawei R4-1813472, draftCR on coherent UL MIMO for TS 38, 101-2, Huawei R4-1813572, Correction to FR2 spurious emission requirement, Nokia R4-1813456, Draft CR to S8, 101-2: Corrections on configurations for intra-band non-configuous CA, ZTE Corporation R4-1814149, Onanges to FR2 /LL MIMO, OPPO R4-1814149, Oranges to FR2 /LL MIMO, OPPO R4-1814143, Joraft CR to 38, 101-2: Corrections on the descriptions, to Electronics in configurations for intra-band non-configuration for the configuration for CA, 2TE Corporation R4-1814143, Joraft CR to 38, 101-2: Corrections on the descriptions, to Electronics in configuration for CA, 2TE Corporation R4-1814143, Joraft CR to 38, 101-2: Update of Annex F, Rohde & Schwarz R4-18141463, Oraft CR to 38, 101-2: LPR2 VL Config for EIS Testing, Qualcomm Incorporated R4-1814165, Draft CR to 38, 101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814165, Draft CR to 38, 101-2: LPR2 VL Conf							· · · · ·	
 FR2, LG Electronics R4-1812430, Dritt CR to TS 38, 101-2. Adjust placement of 0dB MPR reference awareform, Intel Corporation R4-1812496, Dritt CR to 38, 101-2: Corrections on channel raster & SS raster, ZTE Corporation R4-1813470, drittCR on applicability of TDD configuratiin for CA in TS 38, 101-2, Huawei R4-1813472, draftCR on coherent UL MIMO for TS 38, 101-2, Huawei R4-1813472, draftCR on coherent UL MIMO for TS 38, 101-2, Huawei R4-1813472, draftCR to Spectrum Emission requirement, Nokia R4-1813472, draftCR to Specify UL Power for FR2 REFSENS Test Cases. Keyaight R4-1813480, Draft CR to 38, 101-2: Corrections on configurations for intra-band non-configuous CA, ZTE Corporation R4-1814140, Draft CR to 38, 101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814140, Draft CR to 38, 101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-18141481, Draft CR to 38, 101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814180, Draft CR to 38, 101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814180, Draft CR to 38, 101-2: Update of Annex F, Rohde & Schwarz R4-18141461, draftCR on MPR for TS 38, 101-2, Huawei R4-18141461, draftCR on S38, 101-2: PR2 Power Control for CA, Qualcomm Incorporated R4-181470, Draft CR to 38, 101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-181470, Draft CR to TS 38, 101-2: Huawei R4-181470, Draft CR to TS 38, 101-2: UL CA power control in FR2, Intel Corporation R4-1814930, Draft CR to TS 38, 101-2: UL CA power control in FR2, Intel Corporation R4-1814930, Draft CR to TS 38, 101-2: UL CA power Control in FR2, Intel Corporation R4-1814930, Draft CR to T								
R4-1812433, Draft CR to TS 38.101-2. Adjust placement of 0dB MPR reference waveform, Intel Corporation R4-1812495, Draft CR to 38.101-2: Corrections on channel raster & SS raster, ZTE Corporation R4-1813470, draftCR on applicability of TDD configuratiin for CA in TS 38.101-2, Huawei R4-1813472, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813482, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keyajdh R4-1813485, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keyajdh R4-1814180, Draft CR to 38.101-2: Corrections on configurations for intra-band non-configuras 6A, 2TE Corporation R4-18141480, Dranges to FR2 UL MIMO, OPPO R4-1814180, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidt for CA, 2TE Corporations R4-1814180, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814163, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814170, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814470, Crant CR to TS 38.101-2 updating references, Apple Inc. R4-1814497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814497,								
R4-1812485, Draft CR to 38.101-2: Corrections on channel raster & SS raster, ZTE Corporation R4-1813470, draftCR on applicability of TDD configuratin for CA in TS 38.101-2, Huawei R4-1813472, draftCR on CA spectrum Emission for TS 38.101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813827, Correction to FR2 spurious emission requirement, Nokia R4-1813815, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-1814140, Draft CR to 38.101-2: Corrections on configurations for intra-band non-configuous CA, ZTE Corporation R4-18141410, Draft CR to TS 38.101-2 on channel arrangement descriptions, LG Electronics Inc. R4-1814141, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation 2 LG Electronics Inc. R4-1814143, draft CR to 09.8.101-2: Update of Annex F, Rohde & Schwarz R4-1814163, draft CR to 38.101-2: Creations on the descriptions of UE channel bandwidth for CA, ZTE Corporation 2 LG Electronics R4-1814163, draft CR to 38.101-2: ER2 Power Control for CA, Qualcomm Incorporated R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814164, draft CR to TS 38.101-2: RE2 UL Config for ELS Testing, Qualcomm Incorporated R4-1814497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-18145851, dCR on TS38.101-2: Updating referenc							R4-1812453, Draft CR to TS 38.101-2 Adjust placement of 0dB MPR	
Sr raster. ZTE Corporation R4-1813470, draftCR on applicability of TDD configuratin for CA in TS 38.101-2, Huawei R4-1813472, draftCR on CA spectrum Emission for TS 38.101-2, Huawei R4-1813472, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-18134527, Correction to FR2 spurious emission requirement, Nokia R4-181385, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-181385, Draft CR to 38.101-2: Corrections on configurations for intra-band non-configuous CA, ZTE Corporation R4-1814180, Changes to FR2 UL MIMO, OPPO R4-1814181, Draft CR to TS 38.101-2: Corrections on the descriptions of UE channel bandwith for CA, ZTE Corporation R4-1814181, Draft CR to TS 38.101-2: Corrections on the descriptions of UE channel bandwith for CA, ZTE Corporation R4-1814180, draft CR to TS 38.101-2: Corrections on the descriptions of UE channel bandwith for CA, ZTE Corporation R4-1814181, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwith for CA, ZTE Corporation R4-1814181, Draft CR to 38.101-2: LP2 Power Control for CA, Qualcomm Incorporated R4-1814164, draftCR on MPR for TS 38.101-2. Huawei R4-1814180, Draft CR to 38.101-2: FF2 UL Config for EIS Testing, Qualcomm Incorporated R4-1814487, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814898, Draft CR to TS 38.101-2 updating references, Apple Inc. R4-1814898, Draft CR to TS 38.101-2 updating references, Apple Inc.								
R4-1813470, draftCR on applicability of TDD configuratin for CA in TS 38.101-2, Huawei R4-1813472, draftCR on CA spectrum Emission for TS 38.101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813827, Correction to FR2 spurious emission requirement, Nokia R4-181385, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-1814149, Draft CR to 38.101-2: Corrections on configurations for intra-band non-configuous CA, ZTE Corporation R4-1814140, Draft CR to TS 38.101-2 on channel arrangement descriptions, LG Electronics Inc. R4-1814141, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation 2 R4-1814141, Draft CR to 38.101-2: corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation 2 R4-1814163, draft CR ot operating band for Power Class 2 in FR2, LG Electronics 3 R4-1814163, Draft CR to 38.101-2: H2 Power Control for CA, Qualcomm Incorporated R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814170, Draft CR to 38.101-2: RE2 UL Config for EIS Testing, Qualcomm Incorporated R4-18144847, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814895, Draft CR to TS 38.101-2 Updating references, Apple Inc. R4-1814896, Draft CR to TS 38.101-2: Uncludent for PC1 UE, Samsung R4-1814800, draft Re 15 CR to 38.101-2:								
TS 38.101-2, Huawei R4-1813472, dratCR on CA spectrum Emission for TS 38.101-2, Huawei R4-1813473, drattCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813472, Correction to FR2 spurious emission requirement, Nokia R4-1813805, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-1813815, Draft CR to 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-1814140, Draft CR to TS 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-1814140, Draft CR to TS 38.101-2: Corrections on the descriptions to UE channel bandwidth for CA, ZTE Corporation R4-181418, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-181418, Draft CR to 38.101-2: Draver Class 2 in FR2, LG Electronics R4-1814383, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-18141464, draftCR on MPR for TS 38.101-2; Huawei R4-1814383, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-1814497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814498, Draft CR to TS 38.101-2: Draver control in FR2, Intel Corporation R4-1814980, Draft CR to TS 38.101-2: UL CA power control in FR2, Intel Corporation R4-1814980, Draft CR to TS 38.101-2: Draver outrol in FR2, Intel Corporation R4-1814980, Draft CR to TS 38.101-2: LEX Max. Input Power UL Configuration, Cualcomm								
R4-1813472, draftCR on CA spectrum Emission for TS 38.101-2, Huawei R4-1813473, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-181327, Correction to FR2 spurious emission requirement, Nokia R4-1813385, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-1813481, Draft CR to 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-18141418, Draft CR to 38.101-2: corrections on the descriptions, LG Electronics Inc. R4-18141418, Draft CR to 38.101-2: corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-18141418, draftCR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-18141416, draftCR on MPR for TS 38.101-2. Huawei R4-18141416, draftCR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814416, draftCR on S8.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-1814498, Dualer CR to 38.101-2: Reging draft CRs from RAN4#89, Qualcomm Incorporated R4-1814498, Draft CR to 38.101-2: updating references, Apple Inc. R4-1814498, Draft CR to TS 38.101-2: updating references, Apple Inc. R4-1814502, Draft CR to 38.101-2: Program in Repuirement for PC1 UE, Samsung R4-1814698, Draft CR to TS 38.101-2: updating references, Apple Inc. R4-1814698, Draft CR to TS 38.101-2: updating references, Apple Inc. R4-1815623, Draft CR to TS 38.101-2: to include n260 fallbacks needed, Ericoson R4-								
 R4-1813473, draftCR on coherent UL MIMO for TS 38.101-2, Huawei R4-1813527, Correction to FR2 spurious emission requirement, Nokia R4-1813885, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-181385, Draft CR to 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-1814180, Draft CR to TS 38.101-2: Corrections on the descriptions, LG Electronics Inc. R4-1814181, Draft CR to TS 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814181, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814183, Joraft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814163, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-181470, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-181470, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814955, Draft CR to TS 38.101-2 updating references, Apple Inc. R4-1814950, draft CR to TS 38.101-2 updating references, Apple Inc. R4-1814950, draft CR to TS 38.101-2 updating references, Apple Inc. R4-1814950, draft CR to TS 38.101-2 updating references, Apple Inc. R4-1814950, draft CR to TS 38.101-2 updating references, Apple Inc. R4-1815620, draft CR to TS 38.101-2 updating references, Apple Inc. R4-1815620, draft CR to TS 38.101-2 updating references, Apple Inc. R4-1815620, draft CR to TS 38.101-2 updating references, Apple Inc. R4-1815620, draft CR to TS 38.101-2 updating references, Apple Inc. R4-1815620, draft CR to TS 38.101-2 to include n260 fallbacks needed, Ericsson R4-1815620, draft CR to TS 38.101-2 to include n260 fallbac								
Huawei R4-18135827, Correction to FR2 spurious emission requirement, Nokia R4-1813585, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-1813315, Draft CR to 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-1814180, Draft CR to TS 38.101-2: Corrections on the descriptions, LG Electronics Inc. R4-1814180, Draft CR to TS 38.101-2: Corporation R4-1814180, Draft CR to 38.101-2: Corporation R4-1814180, Draft CR to 38.101-2: Corporation 2 R4-1814180, Oraft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814180, draft CR to 38.101-2: Lipdate of Annex F, Rohde & Schwarz R4-1814160, draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814170, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814160, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814160, Oraft CR to TS 38.101-2: CP3 power control in FR2, Intel Corporation R4-1814160, Draft CR to TS 38.101-2: UL CA power control in FR2, Intel Corporation R4-1814686, Draft CR to TS 38.101-2: UL CA power control in FR2, Intel Corporation, Cualcomm Incorporated R4-1814688, Draft CR to TS 38.101-2: UL CA power curvel UL Configuration, Qualcomm Incorporated R4-1814689, Draft CR to TS 38.101-2: Updating references, Apple Inc. R4-1814680, Draft CR to TS 38.101-2: Conclude n260 fallbacks needed, Ericsson R4-1815902, dCR on P-MPR for FR2								
R4-1813527, Correction to FR2 spurious emission requirement, Nokia R4-1813585, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-1813585, Draft CR to 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-1813481, Draft CR to TS 38.101-2: Corrections on the descriptions, LG Electronics Inc. R4-1814180, Draft CR to TS 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation 2 R4-1814163, draft CR of operating band for Power Class 2 in FR2, LG Electronics 2 R4-1814163, draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-1814565, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-18145951, dCR on TS38.101-2 merging draft CRs from RAM489, Qualcorm Incorporated R4-18145951, dCR to TS 38.101-2: UL CA power control in FR2, Intel Corporation R4-1814585, Draft CR to TS 38.101-2 updating references, Apple Inc. R4-1814680, Draft CR to TS 38.101-2 updating references, Apple Inc. R4-1814580, Draft CR to TS 38.101-2: Concetion in R2, Intel Corporation R4-1814580, Draft CR to TS 38.101-2: Updating references, Apple Inc. R4-1814580, Draft CR to TS 38.101-2: Updating references, Apple Inc. R4-1815602, draft R4-15 CR to 38.101-2: Corporated R4-								
 Nokia R4-1813856, Draft CR to Specify UL Power for FR2 REFSENS Test Cases, Keysight R4-1813815, Draft CR to 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-1814149, Changes to FR2 UL MIMO, OPPO R4+1814180, Draft CR to TS 38.101-2: corrections on the descriptions, LG Electronics Inc. R4-1814180, Draft CR to TS 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814163, draft CR of operating band for Power Class 2 in FR2, LG Electronics R4-1814163, draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814163, draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-181497, Darft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated Endorsed draft CR's from RAN4#89 R4-1814997, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814688, Draft CR to TS 38.101-2: LCA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS 38.101-2: LCA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS 38.101-2: LCA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to 138.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to TS 38.101-2: ER2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to TS 38.101-2: ER2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to TS 38.101-2: ER2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to TS 38.101-2: ER2 Max. Input Power UL Configuration, Qualc								
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R4-1813815, Draft CR to 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation R4-1814149, Changes to FR2 UL MIMO, OPPO R4-1814140, Draft CR to TS 38.101-2: on channel arrangement descriptions, LG Electronics Inc. R4-18141163, draft CR of operating band for Power Class 2 in FR2, LG Electronics 2 R4-1814163, draft CR of operating band for Power Class 2 in FR2, LG Electronics 3 R4-1814163, draft CR of operating band for Power Class 2 in FR2, LG Electronics 4 R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814165, Draft CR's from RAN4#89 R4-1815951, dCR on TS38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-181497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-181468, Draft CR to TS 38.101-2: UL CA power control in FR2, Intel Corporation R4-181469, Draft CR to TS 38.101-2: UL CA power control in FR2, Intel. Corporation R4-1814698, Draft CR to TS 38.101-2: LCA power control in FR2, Intel. Corporation R4-1815801, draft CR to 38.101-2: LCA power control in FR2, Intel. Corporation R4-1815801, draft CR to TS 38.101-2: Log Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to TS 38.101-2: to include n260 fallbacks needed, Ericsson R4-1815942, dCR on P-MPR for FR2, Qualcomm Incorporated R4-1815943,							R4-1813585, Draft CR to Specify UL Power for FR2 REFSENS Test	
 intra-band non-contiguous CA, ZTE Corporation R4-1814149, Changes to FR2 UL MIMO, OPPO R4-1814180, Draft CR to TS 38.101-2 on channel arrangement descriptions, LG Electronics Inc. R4-18141413, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814181, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814181, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1813834, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-181497, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-1815951, dCR on TS38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-181497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-181497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814698, Draft CR to TS 38.101-2: UL CA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS 38.101-2. UL CA power UL Configuration, Qualcomm Incorporated R4-1814698, Draft CR to TS 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR editorial correction in 38.101-2, Fricsson R4-1815801, draft Rel-15 CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815942, dCR on P-MPR for FR2, Qualcomm Incorporated R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815943, dCD Coherent UL MIMO parameters for FR								
R4-1814149, Changes to FR2 UL MIMÖ, OPPO R4-1814180, Draft CR to TS 38.101-2 on channel arrangement descriptions, LG Electronics Inc. R4-1814181, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814181, Oraft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814163, draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 Duc Control for CA, Qualcomm Incorporated R4-1814165, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-181497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814658, Draft CR to TS 38.101-2 UL CA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS 38.101-2. Ericsson R4-1814698, Draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815623, Draft CR to 38.101-2: FR2, Qualcomm Incorporated R4-1814698, draft CR editorial correction in 38.101-2, Ericsson R4-1815801, draft Rel-15 CR to 38.101-2; to include n260 fallbacks								
R4-1814180, Draft ČR to TS 38, 101-2: on channel arrangement descriptions, LG Electronics Inc. R4-1814180, Draft CR to 38, 101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation R4-1814181, Draft CR to 38, 101-2: Update of Annex F, Rohde & Schwarz R4-1814181, Draft CR to 38, 101-2: Update of Annex F, Rohde & Schwarz R4-1814165, Draft CR to 38, 101-2; Huawei R4-1814165, Draft CR to 38, 101-2; FR2 Power Control for CA, Qualcomm Incorporated R4-1814170, Draft CR to 38, 101-2; FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-1814170, Draft CR to 38, 101-2; FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-1814950, Draft CR to TS 38, 101-2; UL Config for EIS Testing, Qualcomm Incorporated R4-181497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814868, Draft CR to TS 38, 101-2; UL CA power control in FR2, Intel Corporation R4-181498, Qualcomm Incorporated R4-181498, Draft CR to TS 38, 101-2; UL CA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS 38, 101-2; UL CA power UL Configuration, Qualcomm Incorporated R4-1815602, draft CR editorial correction in 38, 101-2; Ericsson R4-1815801, draft CR editorial correction in 38, 101-2; Ericsson R4-1815804, draft CR on P-MPR for FR2, Qualcomm Incorporated R4-1815804, draft CR editorial correction in 38, 101-2; Ericsson R4-1815804, draft CR editorial correction in 38, 101-2								
R4-1814181, Draft CR to 38.101-2: Corrections on the descriptions of UE channel bandwidth for CA, ZTE Corporation 2 R4-1814163, draft CR of operating band for Power Class 2 in FR2, LG Electronics R4-1813834, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1813834, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814170, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814170, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-1814591, dCR on TS38.101-2 merging draft CRs from RAN4#89, Qualcomm Incorporated R4-1814551, dCR on TS38.101-2 merging draft CRs from RAN4#89, Qualcomm Incorporated R4-1814585, Draft CR to TS 38.101-2 UL CA power control in FR2, Intel Corporation R4-1814585, Draft CR to TS38.101-2 updating references, Apple Inc. R4-1815623, Draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815623, Draft CR to 38.101-2: to include n260 fallbacks needed, Ericsson R4-1815801, draft Rel-15 CR to 38.101-2: to include n260 fallbacks needed, Ericsson R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815904, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815904, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated								
of UE channel bandwidth for CA, ZTE Corporation R4-1814163, draft CR of operating band for Power Class 2 in FR2, LG Electronics R4-1813834, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814165, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated R4-1815951, dCR on TS38.101-2 merging draft CRs from RAN4#89, Qualcomm Incorporated R4-1815951, dCR on TS38.101-2 merging draft CRs from RAN4#89, Qualcomm Incorporated R4-1814897, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814698, Draft CR to TS 38.101-2 UL CA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR editorial correction in 38.101-2, Ericsson R4-1815801, draft CR editorial correction in 38.101-2, Ericsson R4-1815942, dCR on P-MPR for FR2, Qualcomm Incorporated R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815045, Draft CR to TS38.101-2 correcting the Pcmax								
2R4-1814163, draft CR of operating band for Power Class 2 in FR2, LG Electronics R4-1813834, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814170, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated Endorsed draft CR's from RAN4#89 R4-18154151, dCR on TS38.101-2 merging draft CRs from RAN4#89, Qualcomm Incorporated R4-1814497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814585, Draft CR to TS 38.101-2 UL CA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS38.101-2 updating references, Apple Inc. R4-1815801, draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft Rel-15 CR to 38.101-2: FR2, Qualcomm Incorporated R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815945, Draft CR to TS38.101-2: correcting the Pcmax								
LG Electronics R4-1813834, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz R4-1814166, Draft CR to 38.101-2: FR2 Power Control for CA, Qualcomm Incorporated R4-1814170, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated Endorsed draft CR's from RAN4#89 R4-181497, Draft CR to 38.101-2 merging draft CRs from RAN4#89, Qualcomm Incorporated R4-1814497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814585, Draft CR to TS 38.101-2 UL CA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS38.101-2 UL CA power control in FR2, Intel Corporation R4-1816623, Draft CR to TS38.101-2 updating references, Apple Inc. R4-1815623, Draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR editorial correction in 38.101-2, Ericsson R4-1815810, draft CR to 38.101-2 to include n260 fallbacks needed, Ericsson R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated R4-181595, Draft CR to TS38.101-2 correcting the Pcmax					2			
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Qualcomm Incorporated R4-1814170, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated Endorsed draft CR's from RAN4#89 R4-1815951, dCR on TS38.101-2 merging draft CRs from RAN4#89, Qualcomm Incorporated R4-1814497, Correction on UL MIMO requirement for PC1 UE, Samsung R4-1814585, Draft CR to TS 38.101-2 UL CA power control in FR2, Intel Corporation R4-1814698, Draft CR to TS38.101-2 updating references, Apple Inc. R4-1815623, Draft CR to 38.101-2: FR2 Max. Input Power UL Configuration, Qualcomm Incorporated R4-1815801, draft CR editorial correction in 38.101-2, Ericsson R4-1815810, draft Rel-15 CR to 38.101-2 to include n260 fallbacks needed, Ericsson R4-1815942, dCR on P-MPR for FR2, Qualcomm Incorporated R4-1815945, DC Ocherent UL MIMO parameters for FR2, Qualcomm Incorporated								
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R4-1816205, Draft CR to TS38.101-2 correcting the Pcmax								
requirement, Apple Inc.							R4-1816205, Draft CR to TS38.101-2 correcting the Pcmax	
							requirement, Apple Inc.	

						R4-1816206, draft CR on Pcmax for ULCA and limitation on max	
						aggregated ULCA BW, Qualcomm Incorporated	
						R4-1816217, Draft CR to 38.101-2 on UE maximum output power	
						with additional requirements, ZTE Corporation R4-1816218, Draft CR for Introducing missing requirement for power	
						class 4 in FR2 for TS 38.101-2, NTT DOCOMO, INC.	
						R4-1816219, draft CR of MPR for Power Class 2 in FR2, LG	
						Electronics	
						R4-1816220, Draft CR to 38.101-2: On FR2 CA MPR v2, Qualcomm	
						Incorporated	
						R4-1816239, Draft CR to 38.101-2: On FR2 EESS A-MPR for n258,	
						Qualcomm Incorporated	
						R4-1816245, Draft CR to 38.101-2: FR2 EIS DL Signal Polarization	
						Clarification, Qualcomm Incorporated R4-1816257, Draft CR to TS38.101-2 to correct UL CA scope for	
						FR2 in Rel-15, Apple Inc.	
						R4-1816605, TDD configuration for UE Tx test in FR2, Ericsson	
						R4-1816664, Draft CR to 38.101-2 (5.3.4) RB alignment, Huawei	
						R4-1816751, Draft CR for RF exposure compliance in TS38.101-2,	
						LG Electronics France	
						R4-1816626, Draft CR to TS 38.101-2: Introducing multi-band	
						applicability for PC3, Apple Inc.	
						R4-1816634, Draft CR to 38.101-2: FR2 EIS Spherical Coverage	
						Requirement, Qualcomm Incorporated R4-1816639, Verification of beam correspondence, Ericsson, Sony	
						R4-1816633, draft CR on UE type for Power Class 2 in FR2, LG	
						Electronics	
						R4-1816644, Draft CR to TS 38.101-2: Temperature Condition for	
					L	testing EIRP Spherical Coverage requirement, Apple Inc.	
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						RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW	
						Endorced draft CRs from RAN4#90	
						R4-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm Incorporated	
						R4-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm	
						Incorporated	
						R4-1900131, draft CR to 38101-2 Correction to EVM equalizer	
						spectrum flatness for Pi2 BPSK, Intel Corporation	
						R4-1900132, draft CR to 38101-2 FR2 transmit modulation quality	
						for CA, Intel Corporation	
						R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in FR2, OPPO	
						R4-1900301, Draft CR: Introduction of Annex on Characteristics of	
						the Interfering Signal, Samsung	
						R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups,	
						Intel Corporation	
						Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated	
						Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra-	
						Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation	
						Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900535, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA,	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900535, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: IBB requirement update,	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679,Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679,Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900728, Update to PRACH EVM window length for FR2, Rohde	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679,Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900728, Update to PRACH EVM window length for FR2, Rohde & Schwarz	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900728, Update to PRACH EVM window length for FR2, Rohde	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: IBB requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: IBB requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900728, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on editorial error of TS38.101-2, LG Electronics Inc. R4-1900755, Draft CR on spurious emission limit in 38.101-2,	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900535, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: IBB requirement for PRACH, Qualcomm Incorporated R4-1900679,Draft CR to 38.101-2: IBB requirement update, Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900728, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on editorial error of TS38.101-2, LG Electronics Inc. R4-1900755, Draft CR on spurious emission limit in 38.101-2, Qualcomm Incorporated	
				1		Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra- band non-contiguous CA, ZTE Corporation R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG Electronics R4-1900533, draft CR on maximum output power reduction for CA for power class 2 in FR2, LG Electronics R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2, LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time mask, Qualcomm Incorporated R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA, Qualcomm Incorporated R4-1900678, Draft CR to 38.101-2: IBB requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: IBB requirement for PRACH, Qualcomm Incorporated R4-1900679, Draft CR to 38.101-2: Complete Pmin requirement for CA, Qualcomm Incorporated R4-1900728, Update to PRACH EVM window length for FR2, Rohde & Schwarz R4-1900736, Draft CR on editorial error of TS38.101-2, LG Electronics Inc. R4-1900755, Draft CR on spurious emission limit in 38.101-2,	

					Incorporated R4-1902180, Dr between minimu R4-1902345, dr. Skyworks Soluti R4-1902474, Dr in REFSENS for R4-1902490, dr. Huawei R4-1902491, Dr DOCOMO, INC. R4-1902492, Dr R4-1902590, Dr requirement on Further changes Changes in Sec Section 6.2.2.3 requirements	raft CR to 38.101-2: correction of multi-band aspects r PC3, Apple Inc. aftCR on maximum output power for TS 38.101-2, raft CR for Multi-band relaxation to TS 38.101-2, NTT raft CR on max input power in FR2, OPPO raft CR to TS 38.101-2: Introduction of the beam correspondence, Apple Inc s in RAN#83: tion 6.2.2.0 to modify the MPR=0dB waveform and to modify the MPR tables to accommodate the OBW	
2019-06	RAN#84	RP-191240	0021	F	CR to TS 38.10	1-2: Implementation of endorsed draft CRs from	15.6.0
2019-00	KAIN#04	KF-191240	0021		RAN4#90bis an Endorsed draft (13.0.0
						Blocking notes Intel Corporation	
					R4-1905003	Draft CR to 38.101-2: FR2 PC3 and PC1 MPR Qualcomm Incorporated	
					R4-1905005	Draft CR for 38.101-2 frequency separation class Huawei, HiSilicon	
					Endorsed draft (R4-1905504	CRs from RAN4#91: Change description 4.2(d) in Applicability of	
						minimum requirements for TS 38.101-2 vivo	
					R4-1905685	Draft CR to 38.101-2: FR2 Sensitivity Qualcomm Incorporated	
					R4-1905764	draft CR to 38.101-2 UE maximum output power	
					R4-1905765	reduction for UL-MIMOIntel Corporation draft CR to 38.101-2 UE maximum output power for UL-MIMO Intel Corporation	

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						R4-1905796 Correction to a description of PRB for in-band emission in FR2 Anritsu Corporation	
						R4-1905798 Correction to power control in FR2 Anritsu Corporation	
						R4-1905821 draft CR of loosening EIS for FR2 PC2 LG	
						Electronics Inc. R4-1907003 Draft CR for editorial corrections in TS 38.101-2	
						Google Inc. R4-1907420 draft CR of simple application for FR2 PC2 and 4	
						requirements with PC3 same requirements LG	
						Electronics Inc. R4-1907423 Draft CR for TS 38.101-2 Correction of channel	
						bandwidth set for NR CA Huawei, HiSilicon, CMCC	
						R4-1907437 Draft CR to 38.101-2: Insert definitions Qualcomm Incorporated	
						R4-1907443 Draft CR to TS38.101-2 Complete FR2 MPR/A- MPR Intel Corporation	
						R4-1907444 Amendment of the relative power tolerance	
						requirement Ericsson, Qualcomm Incorporated R4-1907446 Draft CR to 38.101-2: FR2 CA REFESNS	
						Qualcomm Incorporated R4-1907447 Draft CR to 38.101-2 on UL RMC slot patterns	
						Apple Inc.	
						R4-1907466 Draft CR to 38.101-2: FR2 CA MPR enhancement Qualcomm Incorporated	
						R4-1907468 Draft CR to 38.101-2: FR2 MPR Wording CleanUp Qualcomm Incorporated	
						R4-1907473 Draft CR to TS38.101-2 on FR2 PC3 UE maxUplinkDutyCycle Nokia, Nokia Shanghai Bell	
						R4-1907478 Draft CR to TS 38.101-2 on configurations for intra-	
						band contiguous CA ZTE Corporation R4-1907493 Correction to Pcmax and Pumax for CA Ericsson	
						R4-1907611 Draft CR to TS38.101-2 on beam correspondence Samsung, Apple, Verizon	
						R4-1907688 Correction to CA carrier spacing Ericsson	
2019-06	RAN#84	RP-191241	0020		В		16.0.0
2019-06	RAN#84	RP-191241	0022	1	В		16.0.0
2019-09	RAN#85	RP-192049	0028		А	38.101-2 CR to TS 38.101-2: Implementation of endorsed draft CRs from	16.1.0
						RAN4#92 (Rel-16) - Mirrors changes in R4-1910352 for Rel-15 TS 38.101-2	
						Endorsed draft CRs from RAN4#92 R4-1907999 Draft CR for NR non-contiguous CA configuration	
						Verizon, Nokia, Ericsson, Qualcomm	
						R4-1908082 draft CR to TS 38.101-2 on channel spacing for CA Samsung, ZTE	
						R4-1908137 Update to FR2 EVM definition ROHDE & SCHWARZ	
						R4-1908153 dCR to 38.101-2: Editorial corrections for 38.101-2	
						Qualcomm Incorporated R4-1908573 Draft CR to TS 38.101-2: corrections on Rx	
						requirements for intra-band CA ZTE Corporation R4-1908633 Draft CR to TS38.101-2: Corrections on EVM	
						window length (Section F.5)ZTE Corporation	
						R4-1908708 Draft CR to TS38.101-2: corrections on the receiver spurious emission (section 7.9) ZTE Corporation	
						R4-1909117 Draft CR for 38.101-2 applicability for intra-band CA	
						Huawei R4-1909316 Draft CR to TS 38.101-2 on symbols correction ZTE	
						Corporation R4-1910235 Draft CR to TS38.101-2 for Rx RF requirements LG	
						Electronics Finland	
						R4-1910238 CR for Handling of fallbacks for combined contiguous and non-contiguous CA in FR2 Apple	
						R4-1910241 Draft CR to TS 38.101-2 on NR CA configurations	
						for FR2 ZTE Corporation R4-1910259 dCR to 38.101-2: Reference signal clarifications	
						Qualcomm Incorporated	
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						ERC 74-01 changes Qualcomm Incorporated	
						R4-1910287 dCR to 38.101-2: FR2 CA MPR refinement Qualcomm Incorporated	

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						R4-1910328 Draft CR to TS 38.101-2: Corrections for UL and DL RMC for FR2 tests Intel Corporation	
						R4-1910333 Draft CR for 38.101-2 reference measurement	
						channel for beam correspondence Huawei	
						R4-1910334 Draft CR for TS38.101-2, Editorial corrections CATT	
						R4-1910412 Draft CR for 38.101-2 correction for channel raster Huawei	
						R4-1910614 Draft CR for TS 38.101-2: Channel spacing for	
						adjacent NR carriers ZTE Conditional agreements for BC for PC1/2/4 from R4-1902252	
2019-09	RAN#85	RP-192027	0025		F	Minor corrections of intra-band non-contiguous CA operating bands	16.1.0
2013-03	11/11/00	11-152021	0020	1		in TS 38.101-2	10.1.0
2019-09	RAN#85	RP-192027			D	Rel-16 CR for further simplification of 38.101-2 Table 5.5A.2-2	16.1.0
2019-12	RAN#86	RP-193030			Α	CR to 38.101-2: DMRS exceptions	16.2.0
2019-12	RAN#86	RP-193030			A	Sync raster to SSB resource element mapping	16.2.0
2019-12	RAN#86	RP-193030	0039		A	CR to 38.101-2 (Rel-16) to clarify measurement interval and observation window on frequency error	16.2.0
2019-12	RAN#86	RP-193031	0041		A	CR to TS 38.101-2 on beam correspondence side condition applicability	16.2.0
2019-12	RAN#86	RP-193031	0044		Α	CR to TS 38.101-2: Correctin on FInterferer (offset) for CA ACS	16.2.0
2019-12	RAN#86		0048	1	A	CR for TS 38.101-2: Editorial correction on MPR for contiguous CA	16.2.0
				ļ		notation	
2019-12	RAN#86	RP-193031	0050	L	A	CR for TS 38.101-2: CA bandwidth class definition amendment	16.2.0
2019-12	RAN#86	RP-193030	0052		A	CR to TS 38.101-2 on corrections to channel raster entries for NR	16.2.0
2019-12	RAN#86	RP-193030	0056	<u> </u>	A	band (Rel-16) CR to transmit modulation quality in FR2	16.2.0
2019-12	RAN#86	RP-193030		<u> </u>	A	Frequency separation class clarification REL-16	16.2.0
2019-12	RAN#86	RP-193012			B	CR introduction completed band combinations 38.716-01-01 ->	16.2.0
						38.101-2	
2019-12	RAN#86	RP-193011	0065	1	F	CR to 38.101-2-g10 Corrections to maximum output power reduction for power class 3	16.2.0
2019-12	RAN#86	RP-193030	0067		Α	CR for TS 38.101-2: power classes and maxUplinkDutyCycle-FR2	16.2.0
2019-12	RAN#86	RP-193031			Α	CR for agreed MPR CA for FR2 intra-band contiguous	16.2.0
2019-12	RAN#86	RP-193031	0075	1	Α	CR for 38.101-2 on NS_202 band definiton	16.2.0
2019-12	RAN#86	RP-193031			Α	CR to TS 38.101-2: Correctin on CA NRACLR	16.2.0
2020-03	RAN#87	RP-200395			A	Correction of the FR2 RMC slot patterns for MOP test cases	16.3.0
2020-03	RAN#87	RP-200395			A	CR to 38.101-2 (Rel-16) MPR for CA	16.3.0
2020-03 2020-03	RAN#87 RAN#87	RP-200395 RP-200395			F	CR FR2 CA tables REL16 CR to TS 38.101-2 on corrections to intra-band contiguous CA for	16.3.0 16.3.0
2020-03	RAN#87	RP-200395				FR2 bands (Rel-16) CR to 38.101-2: Align Rx CA requirements structure with TS38.101-	16.3.0
2020-03	KAN#87	RP-200395	0110		A	1	16.3.0
2020-03	RAN#87	RP-200395	0114		A	CR for TS 38.101-2: Editorial addition of CBW and CABW definitions in Abbreviations section	16.3.0
2020-03	RAN#87	RP-200395	0118		А	CR to TS 38.101-2: Correction on FRC table for FR2 DL 64QAM	16.3.0
2020-03	RAN#87	RP-200469		2	A	CR for 38.101-2 side condition for BC_Rel16	16.3.0
2020-03	RAN#87	RP-200380			F	Editorial corrections	16.3.0
2020-03	RAN#87	RP-200378			F	Correction of Inner Allocation Definition for Powerclass 3	16.3.0
2020-03	RAN#87	RP-200395			A	R16 CR to 38.101-2: TRS and SSB configurations in FR2	16.3.0
2020-04	DANUGO		0147		A	Change history corrected	16.3.1
2020-06	RAN#88	RP-200985 RP-201046			F	CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations	16.4.0
2020-06 2020-06	RAN#88 RAN#88	RP-201046 RP-200985		<u> </u>	A	CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam	<u>16.4.0</u> 16.4.0
2020-00	11/11/#00	111-200900	0104		~	correspondence side conditions R16	10.4.0
2020-06	RAN#88	RP-200985			Α	CR to 38.101-2 to correct Link and Meas Angles	16.4.0
2020-06	RAN#88	RP-200985			Α	CR to 38.101-2: NS_202 update after changes to EU regulations	16.4.0
2020-06	RAN#88	RP-200985			A	CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications	16.4.0
2020-06	RAN#88	RP-200985	0174		A	CR for TS 38.101-2: Correction for configured transmitted power for CA	16.4.0
	RAN#88	RP-200985	0175		F	CR for TS 38.101-2: Clarifications on transmitter power for receiver	16.4.0
2020-06			0181		А	CR for TS 38.101-2: Intra-band non-contiguous CA configuration	16.4.0
	RAN#88	RP-200959		1		clarifications	40.4.0
2020-06			0182		Δ	I Indate of CSI-RS definition for ER2 DL RMCs	16/1
2020-06 2020-06	RAN#88	RP-200985			A	Update of CSI-RS definition for FR2 DL RMCs	
2020-06 2020-06 2020-06	RAN#88 RAN#88	RP-200985 RP-200985	0184		F	Correction to FR2 QPSK UL RMC	16.4.0
2020-06 2020-06 2020-06 2020-06	RAN#88	RP-200985	0184 0188				16.4.0 16.4.0
2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88	RP-200985 RP-200985 RP-200985	0184 0188 0193		F B	Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs	16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88	RP-200985 RP-200985 RP-200985 RP-200972	0184 0188 0193 0198 0200		F B F	Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs CR to TS 38.101-2: Introduction of FR2 DL 256QAM	16.4.0 16.4.0 16.4.0

2020-06	RAN#88	RP-200959	0209		A	CR to 38.101-2: Introduce mmWave intra-band uplink CA	16.4.0
2020-06	RAN#88	RP-200985	0161	1	В	configurations CR to K1 value in Annex A.3.3 of 38.101-2	16.4.0
2020-00	RAN#88	RP-200985			A	CR to 38.101-2 on FR2 frequency separation class enhancement	16.4.0
2020-00	RAN#88	RP-200985		2	B	CR on Pcmax correction for CA	16.4.0
2020-06	RAN#88	RP-200978		1	B	CR to 38.101-2 for Introduction of band n259	16.4.0
2020-06	RAN#88	RP-201046			A	FR2 new MPR and modifiedmpr	16.4.0
2020-09	RAN#89	RP-201496		1	В	Introduction of MPE related P-MPR operation in sub-clause 6.2.4	16.5.0
2020-09	RAN#89	RP-201512			Α	CR on Minimum output power and Off power MBW definition in FR2	16.5.0
2020-09	RAN#89	RP-201496	0221	1	В	CR to 38.101-2 (Rel-16) intra-band non-cont. DL CA	16.5.0
2020-09	RAN#89	RP-201512	0224		Α	CR for R16 38.101-2: Correction of in-band emission tables	16.5.0
2020-09	RAN#89	RP-201512	0226	1	F	Correction for REL16 FR2 contiguous intra-band CA configuration	16.5.0
						table	
2020-09	RAN#89	RP-201512		1	F	modifiedMPR correction for FR2 REL16	16.5.0
2020-09	RAN#89	RP-201496		2	B	Beam correspondence enhancement	16.5.0
2020-09	RAN#89	RP-201512	0234		A	CR to TS 38.101-2 on corrections to operating bands for intra-band CA (Rel-16)	16.5.0
2020-09	RAN#89	RP-201506	0235		F	Correction of ACS requiremet for n259	16.5.0
2020-09	RAN#89	RP-201300		2	F	Introduction of FR2 inter-band DL CA	16.5.0
2020-09	RAN#89	RP-201512		2	A	CR for introduction of EESS protection for n257 into general	16.5.0
2020 00	10, 11, 100		0200		~	spurious emission	10.0.0
2020-09	RAN#89	RP-201512	0241		Α	CR to TS 38.101-2: Correction on the Aggregated Channel	16.5.0
						Bandwidth	
2020-09	RAN#89	RP-201512			Α	CR to TS 38.101-2: Correction on the PC3 MPR description	16.5.0
2020-09	RAN#89	RP-201512			Α	FR2 Minimum output power measurement period definition	16.5.0
2020-09	RAN#89	RP-201488	0249	2	F	CR to TS38.101-2 on ULFPTx and UE SRS port configuration	16.5.0
0000.00	DANIHOO	DD 004 400	0050	4	-	clarification	4050
2020-09	RAN#89	RP-201496		1	F	CR to 38.101-2: DL CA BW Enhancement and CA REFSENS	16.5.0
2020-09 2020-09	RAN#89 RAN#89	RP-201496 RP-201496		1	B	CR to 38.101-2: FR2 UE EIRP increase with IBE relaxation FR2 intra-band non-contiguous UL CA feature	16.5.0 16.5.0
2020-09	RAN#89	RP-201490			F	Correction of corrupted table	16.5.0
2020-03	RAN#90	RP-202485			A	EESS protection related requirements for FR2 bands	16.6.0
2020-12	RAN#90	RP-202485			A	CR to 38.101-2: ULCA clarifications	16.6.0
2020-12	RAN#90	RP-202485			A	CR for TS38.101-2 Rel-16, Correction for definition of P-MPR	16.6.0
2020-12	RAN#90	RP-202443		1	F	REL16 eBC capability alingment with 38.306	16.6.0
2020-12	RAN#90	RP-202443		1	F	CR to 38.101-2 (Rel-16) inter-band DL CA	16.6.0
2020-12	RAN#90	RP-202443	0272	1	F	Clarification of EIS spherical coverage for inter-band CA	16.6.0
2020-12	RAN#90	RP-202485	0274		Α	Transmission gap for relative power tolerance in FR2	16.6.0
2020-12	RAN#90	RP-202485			Α	CR to TS38.101-2 on DC location correction	16.6.0
2020-12	RAN#90	RP-202485			Α	CR for TS 38.101-2: Clarification for NS_202	16.6.0
2020-12	RAN#90	RP-202509	0282	1	F	CR to TS 38.101-2 on fallback group for intra-band contiguous CA	16.6.0
0000 40	DANIHOO	DD 000500	0000		_	(Rel-16)	10.0.0
2020-12	RAN#90	RP-202509 RP-202485		1	F	CR to TS 38.101-2 on simplification for inter-band CA configuration	16.6.0
2020-12 2020-12	RAN#90	RP-202485 RP-202485			A	Correction to Pcmax: total radiated power Correction to EIS definition	16.6.0 16.6.0
2020-12		RP-202465 RP-202428		1	F	CR for editorial corrections 38.101-2	16.6.0
2020-12	RAN#90	RP-202428			A	Mirror CR for 38.101-2: IBB and ACS corrections	16.6.0
2020-12	RAN#90	RP-202485			A	CR to DMRS position in UL RMC for FR2	16.6.0
2020-12	RAN#90	RP-202466			B	CR introduction completed band combinations Rel-17 NR Intra-band	17.0.0
		1 202100	020.		_	-	
2021-03	RAN#91	RP-210117	0315		Α	Removal of a remaining NS_201 related requirement	17.1.0
2021-03	RAN#91	RP-210117	0319		Α	CR to TS 38.101-2 on correction to intra-band non-contiguous CA	17.1.0
						configurations (Rel-17)	
2021-03	RAN#91	RP-210083			Α	P_cmax P_IBE wording refinement and termonology improvement	17.1.0
2021-03	RAN#91	RP-210117		L	Α	CR to 38.101-2: correction on UL MIMO	17.1.0
2021-03	RAN#91	RP-210117		<u> </u>	A	CR to 38.101-2 on beam correspondence	17.1.0
2021-03	RAN#91	RP-210117		<u> </u>	A	CR on FR2 intra-band UL CA	17.1.0
2021-03	RAN#91	RP-210737			B	CR for FR2 FWA RF requirements	17.1.0
2021-06	RAN#92	RP-211083			A	P_cmax fix for the CA applicability	17.2.0
2021-06	RAN#92	RP-211084			A	Update of FR2 UL RMC tables	17.2.0
2021-06 2021-06	RAN#92 RAN#92	RP-211104 RP-211117			A	Removal of CA_n260(*) notation and IE fix R17 CATA Correction of the channel raster of n259 for TS 38.101-2	17.2.0 17.2.0
2021-06	RAN#92 RAN#92	RP-211117 RP-211079		<u> </u>	F	CR to TS 38.101-2 on UE channel bandwidth per operating band	17.2.0
2021-06	RAN#92 RAN#92	RP-211079		<u> </u>	Б	Introduction of FR2 DL CA_n257+n259 and CA_n258-n260	17.2.0
2021-06	RAN#92 RAN#92	RP-211120		1	B	Introduction of n262 UE RF requirements	17.2.0
2021-00	RAN#92 RAN#92	RP-211121 RP-211117		<u> '</u>	A	CR to 38.101-2 on side conditions for beam correspondence based	17.2.0
202100	10.00002		5515			on SSB and CSI-RS for n259 (Rel-17)	
2021-06	RAN#92	RP-211080	0385	1	F	CR Rel-17 38.101-2 to correct some errors in Table 5.5A.2-2	17.2.0
2021-06	RAN#92	RP-211107		<u> </u>	A	CR to TS38.101-2: Some Corrections on for CA_n260-n261	17.2.0
2021-06	RAN#92	RP-211115			В	CR to reflect the completed NR inter band CA DC combinations for 2	17.2.0
						bands DL with up to 2 bands UL into TS 38.101-2	
2021-06	RAN#92	RP-211115	0389		В	CR 38.101-2 new combinations Rel-17 NR Intra-band	17.2.0

2021-06	RAN#92	RP-211114	0391		F	Rel-17 CR 38101-2-h10 corrections intra-band CA	17.2.0
2021-06	RAN#92	RP-211102	0396	1	Α	CR on FR2 inter-band DL CA CBM and IBM_R17 CatA	17.2.0
2021-06	RAN#92	RP-211091	0405		Α	CR to 38.101-2: CABW definition addition	17.2.0
2021-06	RAN#92	RP-211091	0408		A	CR for 38.101-2-h10: Removing ambiguity on MPRnarrow for PC3 MPR	17.2.0
2021-06	RAN#92	RP-211120	0409		В	CR for TS 38.101-2: Introduction of FR2 new CA BW classes	17.2.0
2021-09	RAN#93	RP-211921	0410		Α	CR to 38.101-2 on handling of fallbacks for FR2 CA	17.3.0
2021-09	RAN#93	RP-211900	0414		F	CR to TS 38.101-2 on corrections to intra-band non-contiguous CA	17.3.0
2021-09	RAN#93	RP-211900	0418		В	CR 38.101-2 new combinations Rel-17 NR Intra-band	17.3.0
2021-09	RAN#93	RP-211912	0419		F	Corrections of n262 UE RF requirements	17.3.0
2021-09	RAN#93	RP-211923	0423		Α	Big CR for TS 38.101-2 Maintenance part1 (Rel-17)	17.3.0
2021-09	RAN#93	RP-211900	0424		F	Rel-17 CR 38.101-2, band combination corrections	17.3.0
2021-09	RAN#93	RP-211902	0425		В	CR to 38.101-2: PC5 requirements in n259	17.3.0
2021-12	RAN#94	RP-212830	0427		В	Big CR to reflect the completed NR inter band CA DC combinations for 2 bands DL with up to 2 bands UL into TS 38.101-2	17.4.0
2021-12	RAN#94	RP-212830	0433		F	CR to TS 38.101-2 on configurations for inter-band CA	17.4.0
2021-12	RAN#94	RP-212845	0436		F	Big CR for TS 38.101-2 Maintenance (Rel-17)	17.4.0
2022-03	RAN#95	RP-220373	0441	1	В	CR to introduce UE RF requirement for FR2 PC 6 UE	17.5.0
2022-03	RAN#95	RP-220360	0442		В	CR on UE RF requirements for DMRS bundling in TS 38.101-2	17.5.0
2022-03	RAN#95	RP-220337	0445		Α	Big CR for TS 38.101-2 Maintenance (Rel-17)	17.5.0
2022-03	RAN#95	RP-220359	0446		F	Big CR to reflect the completed NR inter band CA DC combinations for 2 bands DL with up to 2 bands UL into TS 38.101-2	17.5.0
2022-03	RAN#95	RP-220360	0447		В	CR on measurement for DMRS bundling in TS 38.101-2	17.5.0
2022-03	RAN#95	RP-220360	0448		В	CR on measurement for DMRS bundling in TS 38.101-2 Note: The CR seems to be the same as CR as 0447	17.5.0
2022-03	RAN#95	RP-220371	0449		В	Big CR on RedCap UE FR2	17.5.0
2022-06	RAN#96	RP-221661	0450	1	В	CR to 38.101-2 FR2+FR2 ULCA Feature	17.6.0
2022-06	RAN#96	RP-221661	0451	1	В	CR to 38.101-2: FR2+FR2 IBM DLCA for PC1/2/5	17.6.0
2022-06	RAN#96	RP-221654	0452	1	F	CR 38101-2-h50 adding fallbacks	17.6.0
2022-06	RAN#96	RP-221661	0455		Α	CR for 38.101-2-h50: Correction for PC3 MPRnarrow	17.6.0
2022-06	RAN#96	RP-221686	0457		В	Big CR to reflect the completed NR inter band CA DC combinations for 2 bands DL with up to 2 bands UL into TS 38.101-2	17.6.0
2022-06	RAN#96	RP-221695	0458	1	В	Big CR to 38.101-2: update of simultaneous RxTx capability for band combinations	17.6.0
2022-06	RAN#96	RP-221661	0459	1	В	Addition of downlink CA_n258-n261 configuration	17.6.0
2022-06	RAN#96	RP-221676	0460	1	F	CR for 38.101-2 to correct the errors and add the missing requirements for FR2 RedCap UE	17.6.0
2022-06	RAN#96	RP-221677	0461		F	CR on DMRS bundling phase offset Requirment FR2	17.6.0
2022-06	RAN#96	RP-221677	0462	1	F	CR on DMRS bundling phase offset measurement FR2	17.6.0
2022-06	RAN#96	RP-221655	0468		Α	Big CR for TS 38.101-2 Maintenance (Rel-17)	17.6.0
2022-06	RAN#96	RP-221661	0469		F	Big CR on NR FR2 enhancement Rel-17	17.6.0
2022-00	RAN#90	RP-221001	0409	<u> </u>	В	Big CR on extending NR to 71GHz for TS 38.101-2	
2022-06						· · · ·	17.6.0
	RAN#96	RP-221676	0471		F	CR on RedCap FR2	17.6.0
2022-09	RAN#97	RP-222032			F	CR: Maintenance of phase continuity requirements for DMRS bundling in FR2	17.7.0
2022-09	RAN#97	RP-222036	0481	L	F	CR on PC2 UE RF requirements for FR2-1 inter-band UL CA	17.7.0
2022-09	RAN#97	RP-222036	0482		F	CR on PC2 UE RF requirements for FR2-1 inter-band DL CA	17.7.0
2022-09	RAN#97	RP-222028			F	CR 38.101-2: Rel-17 Adding missing fallback combinations	17.7.0
2022-09	RAN#97	RP-222036		1	F	Amendment of the requirement on TX power management	17.7.0
2022-09	RAN#97	RP-222023	0489		A	CR to 38.101-2 Corrections to tables with wrong unit declarations	17.7.0
2022-09	RAN#97	RP-222036	0493		F	Correction CR on UL Gap	17.7.0
2022-09	RAN#97	RP-222026	0496		F	Big CR for 38.101-2 maintenance (Rel-17)	17.7.0
2022-09	RAN#97	RP-222036	0497		F	R17 FR2 CR on separate REFSENS tables for different power classes	17.7.0
2022-09	RAN#97	RP-222557	0498	1	В	Big CR of TS38.101-2 for FR2-2 UE requirements	17.7.0

History

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